Selection guide 2017.

Discretes, Logic and MOSFETs

nexperia

EFFICIENCY WINS.

Introduction

Welcome to the 2017 edition of the Nexperia Selection Guide. For the first time, all our Discrete, Logic and MOSFET devices have been brought together in one single document to give you a complete overview of our portfolio. We hope that makes it even easier for you to find the right product for your design.

Our extensive portfolio offers a wide range of general purpose devices and those that meet the stringent standards set by the automotive industry. They are housed in some of the most advanced, industry-leading small packages that combine power and thermal efficiency with best-in-class quality levels.

Alongside quality and efficiency, Nexperia customers value reliability and a consistent supply they can trust. We produce consistently reliable semiconductor components at high volume (85 billion annually) and we work at every step to safeguard the long-term availability of our manufacturing processes and products, to ensure secure supply for all our customers.

Nexperia may be a new name, but we have a long history and broad experience. That ensures we can support you with the dedicated in-house technical support you need – from simplifying selection via quick-reference material to simple-to-use design tools and application insights. All to help drive up efficiency in your designs.

All the functionality you need in one spot

Just like on our website, you will find the selection guide is split into our five key product areas. There is also a dedicated section on packages, highlighting the latest package innovations and packing options.

Bipolar transistors
- Resistor-equipped, low V_{CEsat} and small-signal transistors
- Standard SMD, leadless and clip-bond packages

Diodes
- Broad choice of Zener, Schottky and switching diodes
- Ultra-small, low-profile surface-mount package options

ESD protection, filtering and signal conditioning
- Extensive range of protection in ultra-small form factors
- Optimized for signal integrity, robustness and system protection

MOSFETs
- Low R_{DSon} devices from < 20 V to > 200 V
- True power packages with solid wireless-clip for smart efficiency

Logic
- Comprehensive portfolio operating from 0.7 V to 15.0 V
- Unrivalled package innovation and lowest power logic solutions

Packages
- The next generation of packaging for volume production
- Package cross-reference and packing options

As a newly independent company we are bringing a fresh focus and renewed vigour to innovating our product areas and packages. So to discover all our latest product information, you should visit our website – www.nexperia.com

Our commitment:

quality and reliability

AEC-Q101 qualified

We qualify our products according to the automotive AEC-Q100/Q101 standard and even exceed it's requirements, for instance when doing extended lifetime testing.

Go for quality

All our processes and manufacturing plants are subject to regular international and internal audits, including the following:

- ISO9001
- ISO/TS 16949 for automotive sites
- ISO14001
- OHSAS18001

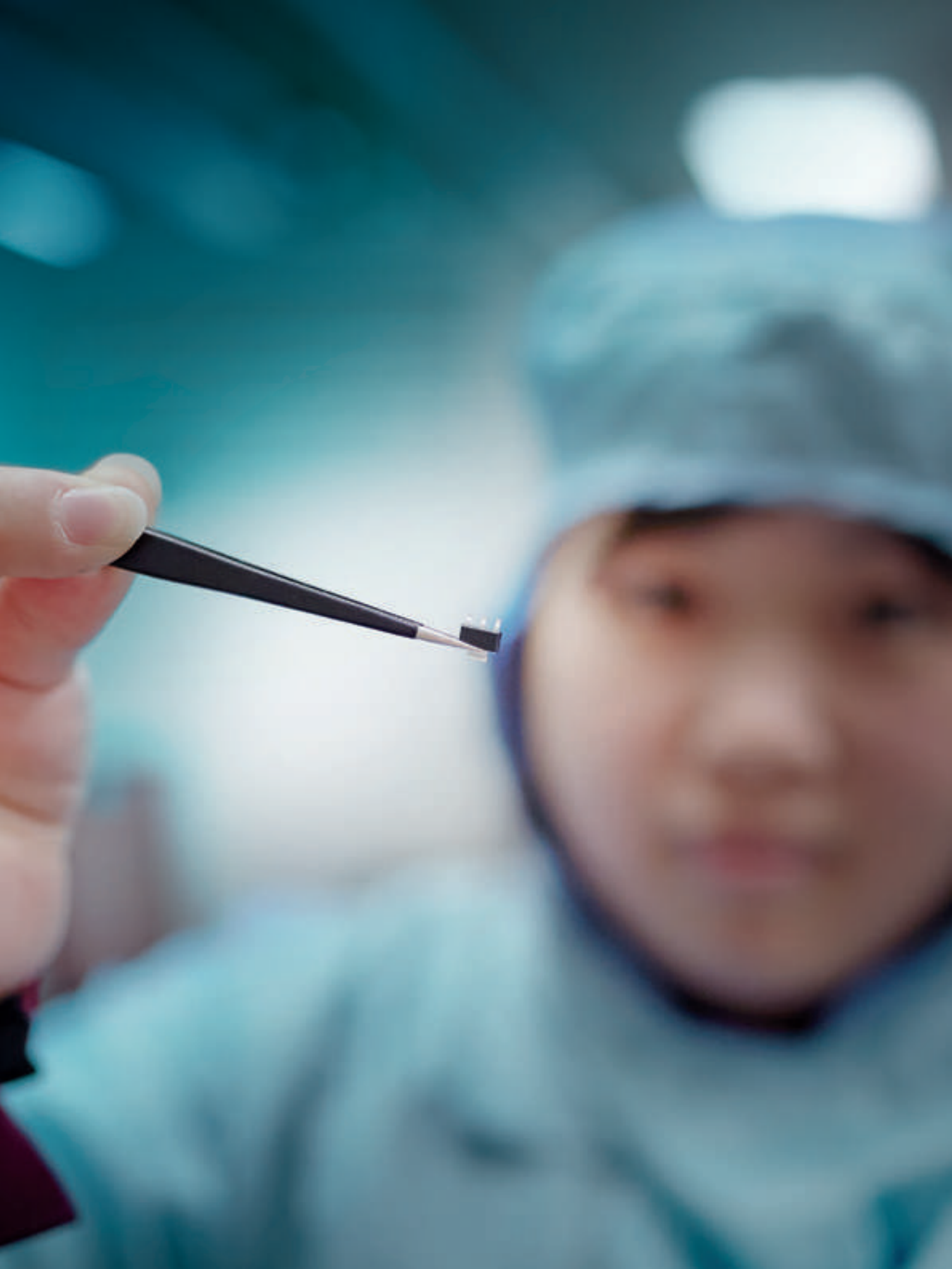
Design for excellence

Nexperia's Design for Excellence (DfX) program ensures that each new development builds on past learning and that best practices are always employed. The result is continual product improvement.

Zero defect

Zero defect is our goal. To ensure continuous improvement failure analysis and the determination to find root causes is performed at all stages of development and production by adoption of quality-analysis tools and methods (e.g. Six-Sigma, Safe-Launch).

Rigorous attention to detail and commitment to quality have yielded a very low product failure rate of a single-digit part per billion (ppb).



Selection guide 2017.

Discretes, Logic and MOSFETs

Contents

Bipolar transistors

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Transistors single NPN

Package					SOT23	SOT323 (SC-70)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
									
Size (mm)					2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
P_{tot} (mW)					250	200	750	250	250
V_{CEO} (V)	I_C (mA)	h_{FE} min/typ	h_{FE} max	f_T min (MHz)					
25	100	450	1200	100		PMST5089			
30	100	110 - 200	450 - 800	100	BC848B	BC848W			
		350	900	100		PMST5088			
32	100	110 - 420	220 - 800	100	BCW31 / 32 / 33				
		180 - 380	310 - 630	250	BCW60B / C / D				
45	100	110 - 420	220 - 800	100	BC847 / A / B / C	BC847W / AW / BW / CW	BC847AQA / BQA / CQA	BC847AM / BM / CM	BC847AMB / BMB / CMB
		120 - 380	220 - 630	100	BCX70G / H / J / K				
		110 - 200	220 - 450	100	BCW71 / 72				
		500	1250	100	PMBT6429	PMST6429			
50	100	210 - 290	340 - 460	100 - 150	2PD601ART 2PD601ARL 2PD601ASL	2PD601ARW / SW			
		250	650	100	PMBT6428	PMST6428			
60	100	110 - 200	220 - 450	100	BCV71 / 72				
65	100	110 - 200	220 - 450	100	BC846 / A / B	BC846W / AW / BW		BC846BM	BC846BMB
50	150	120 - 200	240 - 400	80	NXP3875Y / G				
	150	120 - 270	270 - 560	100		2PC4081Q / R / S		2PC4617QM / RM	2PC4617QMB / RMB
	200	210	340	100	2PD601BRL				
		290	460	100	2PD601BSL				
45	500	100 - 250	250 - 600	100	BC817 / -16 / -25 / -40	BC817W / -16W / -25W / -40W	BC817 / -25QA / -40QA		
		100	600	100	BCX19				
50	500	85 - 170	170 - 340	140 - 180	2PD602AQL 2PD602ARL 2PD602ASL	2PD1820AR / S			
60	500	50	-	100		PMSTA05			

Transistors single PNP

Package					SOT23	SOT323 (SC-70)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
									
Size (mm)					2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
P_{tot} (mW)					250	200	750	250	250
V_{CEO} (V)	I_C (mA)	h_{FE} min/typ	h_{FE} max	f_T min (MHz)					
30	100	125 - 220	500 - 800	100	BC858B	BC858W			
32	100	120 - 215	260 - 500	100	BCW29 / 30				
		180 - 380	310 - 630	100	BCW61B / C / D				
45	100	210 - 290	340 - 460	70 - 80	2PB709ART 2PB709ARL 2PB709ASL	2PB709ARW / SW			
		180 - 380	310 - 630	100	BCX71H / J / K				
		120 - 215	260 - 500	100	BCW69 / 70				
		125 - 420	250 - 800	100	BC857 / A / B / C	BC857W / AW / BW / CW	BC857AQA / BQA / CQA	BC857AM / BM / CM	BC857AMB / BMB / CMB
60	100	120	260	150	BCW89				
65	100	125 - 200	250 - 475	100	BC856 / A / B	BC856W / AW / BW		BC856BM	BC856BMB
100	100	30	-	50	BSS63				
50	150	120 - 270	270 - 560	100		2PA1576Q / R / S		2PA1774QM / RM / SM	2PA1774QMB / RMB / SMB
	200	210	340	100	2PB709BRL				
		290	460	100	2PB709BSL				
25	500	100	600	80	BCX18				
45	500	100 - 250	250 - 600	80	BC807 / -16 / -25 / -40	BC807W / -16W / -25W / -40W	BC807 / -25QA / -40QA		
		100	600	80	BCX17				
50	500	85 - 170	170 - 340	100 - 140	2PB710ARL 2PB710ASL	2PB1219AQ / R / S			
60	500	100	-	50		PMSTA55			
80	500	100	-	50	PMBTA06	PMSTA06			
		100	-	50	PMBTA56	PMSTA56			

Transistors double

Package						SOT457 (SC-74)	SOT363 (SC-88)	SOT666	DFN1412-6 (SOT1268)	DFN1010B-6 (SOT1216)
										
Size (mm)						2.9 x 1.5 x 1.0	2.0 x 1.25 x 0.95	1.6 x 1.2 x 0.55	1.4 x 1.2 x 0.5	1.0 x 1.0 x 0.37
P_{tot} (mW)						750	300	300	480	350
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	f_T min (MHz)					
NPN	40	100	120	450	100		PUMX1	PEMX1		
	45	100	200	450	100	BC847DS	BC847BS	BC847BV	BC847RA	BC847QAS
	65	100	110	-	100		BC846S			
			200	450	100	BC846DS	BC846BS			
	50	150	120	560	100		PUMX2			
	45	500	160	400	80	BC817DS			BC817RA	
PNP	40	100	120	450	100	PIMT1	PUMT1	PEMT1		
	45	100	200	450	100		BC857BS	BC857BV	BC857RA	BC857QAS
	65	100	110	-	100		BC856S			
			200	450	100		BC856BS			
	45	500	160	400	80	BC807DS			BC807RA	
NPN / PNP	40	100	120	450	100		PUMZ1	PEMZ1		
	45	100	200	450	100		BC847BPN	BC847BVN	BC847RAPN	BC847QAPN
	50	100	120	560	100	PIMZ2	PUMZ2			
	65	100	200	450	100		BC846BPN			
	12	500	200	-	250 / 100			PEMZ7		
	45	500	160	160	100 / 800	BC817DPN			BC817RAPN	

Switching transistors single

Package							SOT223 (SC-73)	SOT89 (SC-62)	SOT23	SOT323 (SC-70)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
												
Size (mm)							6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
P_{tot} (mW)							1700	1300	250	200	250	250
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	f_T min (MHz)	t_{off} (ns)						
NPN	40	200	100	300	180	1200			PMBS3904	PMSS3904		
	15	600	40	120	500	20			PMBT2369	PMST2369		
	40	200	100	300	300	250			MMBT3904			
									PMBT3904	PMST3904	PMBT3904M	PMBT3904MB
	30	600	100	300	250	250			PMBT2222	PMST2222		
	40	600	100	300	250	250	PZT4401	PXT4401	PMBT4401	PMST4401		
					300	250			MMBT2222A			
							PZT2222A	PXT2222A	PMBT2222A	PMST2222A		
	40	800	100	300	300	250			BSR14			
PNP	40	100	100	300	150	700			PMBS3906	PMSS3906		
	40	200	100	300	250	300			MMBT3906			
									PMBT3906	PMST3906	PMBT3906M	PMBT3906MB
	40	600	100	300	200	350	PZT4403	PXT4403	PMBT4403	PMST4403		
						365			PMBT2907			
	60	600	100	300	200	300				PMST2907A		
						365			BSR16			
							PZT2907A	PXT2907A	PMBT2907A			

Switching transistors double

Package							SOT363 (SC-88)	SOT666	SOT457 (SC-74)
									
Size (mm)							2.0 x 1.25 x 0.95	1.6 x 1.2 x 0.55	2.9 x 1.5 x 1.0
P_{tot} (mW)							300	300	750
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	f_T min(MHz)	t_{off} (ns)			
NPN	40	200	100	300	300	250	PMBT3904YS	PMBT3904VS	
	40	600	100	300	250	250	PMBT4401YS		
					300	250	PMBT2222AYS		
PNP	40	200	100	300	250	300	PMBT3906YS	PMBT3906VS	
	40	600	100	300	200	350	PMBT4403YS		
	60	600	100	300	200	365	PMBT2907AYS		
NPN / PNP	40	200	100	300	300 / 250	250 / 300	PMBT3946YPN	PMBT3946VPN	
					300 / 200	250 / 365			NMB2227A

Medium power transistors

Package						SOT223 (SC-73)	SOT89 (SC-62)	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)
									
Size (mm)						6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62
P_{tot} (mW)						1700	1300	1300	1300
Polarity	V_{CEO} (V)	I_C (A)	h_{FE} min	h_{FE} max	f_T min (MHz)				
NPN	20	2	85 - 160	375	40	BCP68 / -25	BC868 / -25	BC68PA / BC68-25PA	BC68PAS / BC68-25PAS
	45	1	63 - 100	160 - 250	100	BCP54 / -10 / -16	BCX54 / -10 / -16	BC54PA / BC54-10PA / BC54-16PA	BC54PAS / BC54-10PAS / BC54-16PAS
	60	1	63 - 100	160 - 250	100	BCP55 / -10 / -16	BCX55 / -10 / -16	BC55PA / BC55-10PA / BC55-16PA	BC55PAS / BC55-10PAS / BC55-16PAS
			100	300	100	BSP41	BSR41		
	80	1	63 - 100	160 - 250	100	BCP56 / -10 / -16	BCX56 / -10 / -16	BC56PA / BC56-10PA / BC56-16PA	BC56PAS / BC56-10PAS / BC56-16PAS
			40 - 100	120 - 300	100	BSP43	BSR43		
PNP	20	2	85 - 160	250 - 375	40	BCP69 / -16 / -25	BC869 / -16 / -25	BC69PA / BC69-16PA / BC69-25PA	BC69PAS / BC569-16PAS / BC69-25PAS
	45	1	63 - 100	160 - 250	115 [1] - 145 [1]	BCP51 / -10 / -16	BCX51 / -10 / -16	BC51PA / BC51-10PA / BC51-16PA	BC51PAS / BC51-10PAS / BC51-16PAS
	60	1	63 - 100	160 - 250	100	BCP52 / -10 / -16	BCX52 / -10 / -16	BC52PA / BC52-10PA / BC52-16PA	BC52PAS / BC52-10PAS / BC52-16PAS
			40 - 100	120 - 300	100	BSP31	BSR30 / 31		
	80	1	63 - 100	160 - 250	115 [1] - 145 [1]	BCP53 / -10 / -16	BCX53 / -10 / -16	BC53PA / BC53-10PA / BC53-16PA	BC53PAS / BC53-10PAS / BC53-16PAS
			40 - 100	120 - 300	100	BSP32 / 33	BSR33		

1) Typical value

Medium power transistors high performance (175 °C capable)

Package							SOT223 (SC-73)
							
Size (mm)							6.5 x 3.5 x 1.65
P_{tot} (mW)							1700
Polarity	V_{CEO} (V)	V_{ebo} (V)	I_C (A)	h_{FE} min	h_{FE} max	f_T min(MHz)	
NPN	80	7	1	63	160	100	BCP56-10H
					250	100	BCP56H
				100	250	100	BCP56-16H
PNP	80	70	1	63	100	100	BCP53-10H
					250	100	BCP53H
				100	250	100	BCP53-16H

High voltage transistors

Package						SOT223 (SC-73)	SOT89 (SC-62)	SOT457 (SC-74)	SOT23	SOT323 (SC-70)
										
Size (mm)						6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P_{tot} (mW)						1700	1300	750	250	200
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	f_T min (MHz)					
NPN	140	300	60	250	100				PMBT5550	PMST5550
	160	300	80	250	100				PMBT5551 / BSR19A	PMST5551
	250	100	50	-	60	BF722	BF622		BF822	
	300	100	50	-	60	BF720	BF620		BF820	BF820W
			40	-	50	PZTA42	PXTA42		PMBTA42	PMSTA42
	350	100	40	-	70	BSP19	BST39			
	400	300	50	200	20	PZTA44			PMBTA44	
PNP	100	100	30	-	50				BSS63	
	250	100	50	-	60	BF723				
			50	-	60		BF623		BF823	
	300	100	50	-	60		BF621		BF821	
			40	-	50	PZTA92	PXTA92		PMBTA92	PMSTA92
2 x NPN	300	100	40	-	50			PMBTA42DS		

For high-voltage transistors with increased performance please refer to our high-voltage low VCEsat (BISS) transistor portfolio on page 18.

LED driver

Package		SOT457	SOT23
			
Size (mm)		2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0
P_{tot} (mW)		750	480
Vs supply voltage [V]	LED drive current [mA] @ Vs=10V		
18	10		NCR401T
	20		NCR402T
40	10	NCR401U	
	20	NCR402U	
	50	NCR405U	

Constant current source

Package	SOT353 (SC-88A)				
					
Size (mm)	2.0 x 1.25 x 0.95				
P_{tot} (mW)	335				
Type	PSSI2021SAY				
Description	maximum supply voltage	maximum supply current	typical stabilized output current	minimum stabilized output current	maximum stabilized output current
Parameter	V_S max (V)	I_S max (mA)	I_{out} typ (µA)	I_{out} min (mA)	I_{out} max (mA)
Value	75	2.2	15	0.015	50

Darlington transistors

Package					SOT223 (SC-73)	SOT89 (SC-62)	SOT23
							
Size (mm)					6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.3 x 1.0
P_{tot} (mW)					1700	1300	250
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	f_T min (MHz)			
NPN	30	500	10000	125			PMBTA13
			20000		PZTA14	PXTA14	PMBTA14
				220		BCV29	BCV27
	45	1000	2000	200	BSP50	BST50	
	60	500	10000	220		BCV49	BCV47
		1000	2000	200	BSP51	BST51	
	80				BSP52	BST52	
PNP	30	500	20000	125			PMBTA64
				220		BCV28	BCV26
	45	1000	2000	200	BSP60	BST60	
	60	500	10000	220		BCV48	BCV46
		1000	2000	200	BSP61	BST61	
	80				BSP62	BST62	

Schmitt triggers

Package							SOT143B
							
Size (mm)							2.9 x 1.3 x 1.0
P_{tot} (mW)							250
Polarity	V_{CEO} (V) TR1	V_{CEO} (V) TR2	I_C (mA)	h_{FE} min	h_{FE} max	V_{CEsat} typ (mV)	
NPN	30	6	100	110	800	250	BCV63 / B
PNP	30	6	100	220	475	250	BCV64B

Low noise transistors

Package							SOT23	SOT323 (SC-70)
								
Size (mm)							2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P_{tot} (mW)							250	200
Polarity	V_{CEO} (V)	I_C (mA)	Noise figure max (dB)	h_{FE} min	h_{FE} max	f_T min (MHz)		
NPN	30	100	4	200	450	100	BC849B	BC849BW
				420	800	100	BC849C	BC849CW
	45	100	4	200	450	100	BC850B	BC850BW
				420	800	100	BC850C	BC850CW
PNP	30	100	4	220	475	100	BC859B	BC859BW
				420	800	100	BC859C	BC859CW
	45	100	4	220	475	100	BC860B	BC860BW
				420	800	100	BC860C	BC860CW

Matched pair transistors - part 1

Package							SOT143B	SOT457 (SC-74)		LFPAK56D (SOT1205)
										
Size (mm)							2.9 x 1.3 x 1.0	2.9 x 1.5 x 1.0		5 x 6 x 1.1
P_{tot} (mW)							250	750		1250
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	h_{FE1}/h_{FE2}	V_{BE1} - V_{BE2} (mV)				
NPN	30	100	110	800	0.7 [1]	n.a.	BCV61/A/B/C			
	45	100	200	450	0.9 [1]	n.a.	BCM61B			
						2			BCM847DS	
	80	100	63	250	0.95	n.a.		**BCM56DS**		
	100	3000	150	-	0.95	n.a.				PHPT610035NK
	Configuration									
PNP	30	100	100	800	0.7 [1]	n.a.	BCV62/A/B/C			
	45	100	200	450	0.9 [1]	n.a.	BCM62B			
						2			BCM857DS	
	65	100	200	450	0.9	2			BCM856DS	
	80	100	63	250	0.95	n.a.		**BCM53DS**		
	100	3000	150	-	0.9	n.a.				PHPT610035PK
	Configuration									

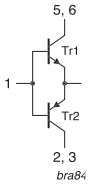
[1] I_{C1} / I_{E2}

Matched pair transistors - part 2

Package							SOT353 (SC-88A)	SOT363 (SC-88)		SOT666		SOT1216 (DFN1010B-6)	
													
Size (mm)							2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95		1.6 x 1.2 x 0.55		1.1x 1.0 x 0.37	
P_{tot} (mW)							300	300		300		350	
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	h_{FE1}/ h_{FE2}	V_{BE1} - V_{BE2} (mV)							
NPN	45	100	200	450	0.9 [1]	2		BCM847BS		BCM847BV			
					0.95	2	PMP4501G		PMP4501Y		PMP4501V	BCM847QAS	PMP4501QAS
					0.98	2	PMP4201G		PMP4201Y		PMP4201V		
	65	100	200	450	0.9	2		BCM846BS					
	Configuration												
PNP	45	100	200	450	0.9 [1]	2		BCM857BS		BCM857BV			
					0.95	2	PMP5501G		PMP5501Y		PMP5501V	BCM857QAS	PMP5501QAS
					0.98	2	PMP5201G		PMP5201Y		PMP5201V		
	65	100	200	450	0.9	2		BCM856BS					
	Configuration												

[1] I_{C1} / I_{E2}

MOSFET driver

V_{CEO} (V)	I_C (A)	I_{cm} [A]	Type	Package	Remark	Configuration
30	0.1	0.2	BCV65	SOT143B 	General-purpose transistors	
40	0.6	1	PMD2001D	SOT457 	Switching transistors with reduced storage time	
	1	2	PMD3001D		Low V_{CEsat}	

Medium frequency transistors

Package						SOT23 	SOT323 (SC-70) 
Size (mm)						2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95
P_{tot} (mW)						250	200
Polarity	V_{CEO} (V)	I_C (mA)	h_{FE} min	h_{FE} max	f_T typ (MHz)		
NPN	15	100	40	-	500	BF570	
	20	25		85	>275	BFS20	BFS20W
		30	65	225	260	BFS19	
	40	25	67	220	380	BF840	
PNP	30	25	25	50	250	BF824	BF824W
	40		50	-	>325	BF550	

Low V_{CEsat} (BISS) transistors single NPN up to 2000 mW

Package							SOT223 (SC-73)	SOT89 (SC-62)	SOT457 (SC-74)	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)
											
Size (mm)							6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.5 x 1.0	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62
P_{tot} (mW)							1700	1650	750	1300	1300
V_{CEO} (V)	I_C (A)	I_{CM} (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); I_C = 0.5 A; I_B = 0.05 A					
12	5.3	10.6	300 / 530	0.5	2	18		PBSS301NX			
	5.8	11.6	300 / 530	0.5	2	18	PBSS301NZ				
	6	7	280 / 440	0.5	2	20				PBSS4612PA	
20	3	5	220 / 390	0.5	2	40		PBSS4320X			
	4	15	300 / 450	0.5	2	30			PBSS301ND		
	5	10	300 / 450	0.5	2	35		PBSS4520X			
	5.3	10.6	300 / 570	0.5	2	20		PBSS302NX			
	5.8	10.2	300 / 570	0.5	2	20	PBSS302NZ				
	6	7	280 / 440	0.5	2	20				PBSS4620PA	
	7	15	300 / 550	0.5	2	12		PBSS4021NX			
	8	20	300 / 550	0.5	2	9	PBSS4021NZ				
30	3	5	300 / 490	0.5	2	45		PBSS4330X			
	3	5	300 / 465	0.5	2	40				PBSS4330PA	PBSS4330PAS
	3.5	6	300 / 500	0.5	2	70			PBSS4032ND [3]		
	4.7	10	300 / 500	0.5	2	57		PBSS4032NX [3]			
	5.1	10.2	300 / 480	0.5	2	20		PBSS303NX			
	5.4	10	300 / 500	0.5	2	57	PBSS4032NZ [3]				
	5.5	11	300 / 480	0.5	2	20	PBSS303NZ				
	6	7	280 / 450	0.5	2	21				PBSS4630PA	
40	2	3	300 / –	0.5	5	140		PBSS4240X			
	4	15	300 / 520	0.5	2	35			PBSS302ND		
		10	300 / 500	0.5	2	21		PBSS4540X			
	5	10	300 / 500	0.5	2	25	PBSS4540Z				
50	2	5	300 / –	0.5	2	90 [2]		PBSS4250X			
	3	5	200 / 280	0.5	2	65			PBSS4350D		
			300 / 460	0.5	2	50		PBSS4350X			
			200 / 280	0.5	2	60 [1]	PBSS4350Z				
60	3	6	200 / 360	0.5	5	45					PBSS4360PAS
			200 / –	0.5	5	45	PBSS4360Z				
			345 / 570	0.5	2	40			PBSS303ND		
	4.7	9.4	300 / 520	0.5	2	25		PBSS304NX			
	5.2	10.4	300 / 520	0.5	2	25	PBSS304NZ				
	6	7	280 / 440	0.5	2	22				PBSS4560PA	
	6.2	15	300 / 500	0.5	2	17		PBSS4041NX			
	7	15	300 / 500	0.5	2	13	PBSS4041NZ				
80	3	6	240 / 360	0.5	2	40			PBSS304ND		
	4	10	250 / 400	0.5	2	25		PBSS4480X			
	4.6	9.2	300 / 470	0.5	2	25		PBSS305NX			
	5.1	10.2	300 / 470	0.5	2	25	PBSS305NZ				
	5.6	7	270 / 425	0.5	2	25				PBSS4580PA	
100	1	3	150 / 290	0.25	10	75			PBSS8110D		
			150 / 290	0.25	10	73		PBSS8110X			
			150 / 290	0.25	10	73	PBSS8110Z				
	3	4	170 / 275	0.5	2	45			PBSS305ND		
	4.5	9	200 / 330	0.5	2	27		PBSS306NX			
	5.1	10.2	200 / 330	0.5	2	27	PBSS306NZ				
	5.2	6	180 / 285	0.5	2	30				PBSS8510PA	

[1] $I_C / I_B = 20$ [2] V_{CEsat} (max) [3] Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors single NPN up to 750 mW

Package							SOT23	SOT323 (SC-70)	SOT363 (SC-88)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)	DFN1010D-3 (SOT1215)
												
Size (mm)							2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37	1.1 x 1.0 x 0.37
P_{tot} (mW)							480	350	430	250	250	750
V_{CEO} (V)	I_C (A)	I_{CM} (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); I_C = 0.5 A; I_B = 0.05 A						
15	0.5	1	200 / 325	0.01	2	-				PBSS2515M	PBSS2515MB	
20	1	3	350 / 470	0.1	2	110 [2]	PBSS4120T					
	2	5	220 / 330	0.1	2	45	PBSS4320T					
	4.3	8	300 / 550	0.5	2	21	PBSS4021NT					
30	1	1.5	230 / 380	0.5	2	90						PBSS4130QA
		3	300 / 450	0.5	2	120 [2]	PBSS4130T					
	2	3	300 / 450	0.5	2	70	PBSS4230T					
			230 / 380	0.5	2	75						PBSS4230QA
	2.6	5	300 / 500	0.5	2	80	PBSS4032NT [3]					
40	0.5	1	200 / 550	0.01	2	200 [2]				PBSS2540M	PBSS2540MB	
	1	2	300 / 440	0.5	5	130		PBSS4140U				
			300 / 510	0.5	5	120	PMMT491A					
			300 / 420	0.5	5	130	PBSS4140T					
	2	3	350 / 470	0.1	2	70			PBSS4240Y			
			300 / 450	0.5	2	70	PBSS4240T					
50	2	5	300 / 495	0.5	2	60	PBSS4350T					
60	1	1.5	150 / 240	0.5	2	90						PBSS4160QA
		2	200 / 420	0.5	5	120		PBSS4160U				
			200 / 350	0.5	5	110	PBSS4160T					
	2	3	150 / 240	0.5	2	75						PBSS4260QA
	3.8	8	300 / 500	0.5	2	29	PBSS4041NT					
100	1	3	150 / 400	0.25	10	80			PBSS8110Y			
			150 / 300	0.25	10	70	PBSS8110T					

[1] I_C / I_B = 20 [2] V_{CEsat} (max) [3] Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors single PNP up to 2000 mW

Package							SOT223 (SC-73)	SOT89 (SC-62)	SOT457 (SC-74)	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)
											
Size (mm)							6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	2.9 x 1.5 x 1.0	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62
P_{tot} (mW)							1700	1650	750	1300	1300
V_{CEO} (V)	I_C (A)	I_{CM} (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); I_C = 0.5 A; I_B = 0.05 A					
12	5.3	10.6	250 / 400	0.5	2	20		PBSS301PX			
	5.7	11.4	250 / 400	0.5	2	20	PBSS301PZ				
	6	7	220 / 335	0.5	2	20				PBSS5612PA	
20	3	5	200 / –	0.5	2	80 [2]			PBSS5320D		
			220 / 450	0.5	2	50		PBSS5320X			
	4	15	250 / 400	0.5	2	35			PBSS301PD		
	5	10	300 / 430	0.5	2	45		PBSS5520X			
	5.1	10.2	250 / 370	0.5	2	25		PBSS302PX			
	5.5	11	250 / 370	0.5	2	25	PBSS302PZ				
	6	7	230 / 345	0.5	2	25				PBSS5620PA	
	6.2	15	250 / 400	0.5	2	18		PBSS4021PX			
	6.6	20	250 / 400	0.5	2	16	PBSS4021PZ				
30	2.7	5	200 / 350	0.5	2	87			PBSS4032PD [3]		
	3	5	200 / 380	0.5	2	50		PBSS5330X			
			200 / 320	0.5	2	45				PBSS5330PA	PBSS5330PAS
	4.2	10	200 / 350	0.5	2	70		PBSS4032PX [3]			
	4.4	10	200 / 350	0.5	2	70	PBSS4032PZ [3]				
	5.1	10.2	250 / 400	0.5	2	25		PBSS303PX			
	5.3	10.6	250 / 400	0.5	2	25	PBSS303PZ				
	6	7	200 / 335	0.5	2	25				PBSS5630PA	
40	2	3	215 / –	0.5	5	170		PBSS5240X			
	4	15	200 / 310	0.5	2	46			PBSS302PD		
		10	250 / 370	0.5	2	33		PBSS5540X			
	5		250 / 350	0.5	2	40 [1]	PBSS5540Z				
50	2	5	200 / –	0.5	2	90 [2]		PBSS5250X			
	3	5	200 / 300	0.5	2	70			PBSS5350D		
			200 / 375	0.5	2	70		PBSS5350X			
			200 / 300	0.5	2	70	PBSS5350Z				
60	3	6	130 / 220	0.5	5	55					PBSS5360PAS
			130 / –	0.5	5	55	PBSS5360Z				
			180 / 265	0.5	2	55			PBSS303PD		
	4.2	8.4	200 / 295	0.5	2	35		PBSS304PX			
	4.5	9	200 / 295	0.5	2	35	PBSS304PZ				
	5	6	170 / 260	0.5	2	35				PBSS5560PA	
	5	15	200 / 300	0.5	2	30		PBSS4041PX			
	5.7		200 / 300	0.5	2	22	PBSS4041PZ				
80	3	5	155 / 225	0.5	2	55			PBSS304PD		
	4		180 / 265	0.5	2	40				PBSS5580PA	
		10	200 / 300	0.5	2	35		PBSS5480X			
		8	200 / 280	0.5	2	36		PBSS305PX			
	4.5	9	200 / 280	0.5	2	36	PBSS305PZ				
100	1	3	150 / 350	0.5	5	100			PBSS9110D		
			150 / 350	0.5	5	90		PBSS9110X			
			150 / –	0.5	5	90	PBSS9110Z				
	2	3	175 / 275	0.5	2	65			PBSS305PD		
	2.7	4	180 / 295	0.5	2	45				PBSS9410PA	
	3.7	7.4	200 / 300	0.5	2	45		PBSS306PX			
	4.1	8.2	200 / 300	0.5	5	45	PBSS306PZ				

[1] $I_C / I_B = 20$ [2] V_{CEsat} (max) [3] Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors single PNP up to 750 mW

Package							SOT23	SOT323 (SC-70)	SOT363 (SC-88)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)	DFN1010D-3 (SOT1215)
												
Size (mm)							2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37	1.1 x 1.0 x 0.37
P_{tot} (mW)							480	350	430	250	250	750
V_{CEO} (V)	I_C (A)	I_{CM} (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); I_C = 0.5 A; I_B = 0.05 A						
15	0.5	1	200 / 260	0.01	2	150				PBSS3515M	PBSS3515MB	
20	1	2	300 / 450	0.1	2	125 [2]	PBSS5120T					
	2	3	225 / –	0.5	2	80 [2]	PBSS5220T					
		5	220 / 420	0.5	2	50	PBSS5320T					
	3.5	8	250 / 400	0.5	2	35	PBSS4021PT					
30	1	1.5	180 / 295	0.5	2	85						PBSS5130QA
		3	260 / 350	0.5	2	110	PBSS5130T					
	2		300 / 450	0.1	2	70	PBSS5230T					
			180 / 295	0.5	2	70						PBSS5230QA
	2.4	5	200 / 320	0.5	2	95	PBSS4032PT [3]					
40	0.5	1	200 / 380	0.01	2	220				PBSS3540M	PBSS3540MB	
	1	2	300 / 520	0.1	5	130		PBSS5140U				
			300 / 800	0.1	5	130	PMMT591A					
			300 / 510	0.1	5	130	PBSS5140T					
	2	3	300 / –	0.1	2	110 [2]			PBSS5240Y			
			300 / 450	0.1	2	70	PBSS5240T					
50	2	3	200 / –	0.5	2	90 [2]	PBSS5250T					
	2	5	200 / 360	0.5	2	55	PBSS5350T					
60	1	1.5	120 / 185	0.5	2	125						PBSS5160QA
		2	150 / 250	0.5	5	135		PBSS5160U				
			150 / 250	0.5	5	120	PBSS5160T					
	1.7	2.5	120 / 185	0.5	2	105						PBSS5260QA
	2.7	8	200 / 300	0.5	2	49	PBSS4041PT					
100	1	3	150 / –	0.25	5	93			PBSS9110Y			
			150 / 350	0.5	5	95	PBSS9110T					

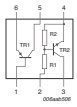
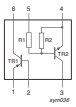
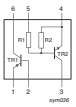
[1] IC / IB = 20 [2] V_{CEsat} (max) [3] Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors double

Package										SOT96 (SO8)	SOT457 (SC-74)	SOT666	DFN2020-6 (SOT1118)	DFN2020D-6 (SOT1118D)
														
Size (mm)										4.9 x 3.9 x 1.75	2.9 x 1.5 x 1.0	1.6 x 1.2 x 0.55	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62
P_{tot} (mW)										2000 [2]	750	500	1300	1300
V_{CEO} (V)	I_C (A)	Polarity	h_{FE} min/ typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); I_C = 0.5 A; I_B = 0.05 A	V_{CEsat} max (mV)	@ I_C (A)	@ I_B (A)					
15	0.5	2 x NPN	200	0.01	2	170 [1]	250	0.5	0.05			PBSS2515VS		
		2 x PNP	200	0.01	2	170 [1]	250	0.5	0.05			PBSS3515VS		
		NPN / PNP	200	0.01	2	170 [1]	250	0.5	0.05			PBSS2515VPN		
		NPN / PNP	200	0.01	2	170 [1]	250	0.5	0.05					
20	2	NPN / NPN	230	0.5	2	60	90	0.5	0.05					PBSS4220PANS
	2	PNP / PNP	210	0.5	2	70	110	0.5	0.05					PBSS5220PAPS
	7.5	NPN / NPN	300	0.5	2	15	150	4	0.2	PBSS4021SN				
	6.3	PNP / PNP	250	0.5	2	24	225	4	0.2	PBSS4021SP				
	7.5 / 6.3	NPN / PNP	300 / 250	0.5	2	15 / 24	150 / 225	4	0.2	PBSS4021SPN				
30	1	NPN / NPN	210	0.5	2	75	100	0.5	0.05				PBSS4130PAN	
		PNP / PNP	170	0.5	2	85	140	0.5	0.05				PBSS5130PAP	
		NPN / PNP	210 / 170	0.5	2	75 / 85	100 / 140	0.5	0.05				PBSS4130PANP	
	2	NPN / NPN	230	0.5	2	60	80	0.5	0.05				PBSS4230PAN	
		PNP / PNP	210	0.5	2	75	110	0.5	0.05				PBSS5230PAP	
		NPN / PNP	230 / 210	0.5	2	60 / 75	80 / 100	0.5	0.05				PBSS4230PANP	
	5.7	NPN / NPN	300	0.5	2	57	250	4	0.4	PBSS4032SN 3)				
	4.8	PNP / PNP	200	0.5	2	70	390	4	0.4	PBSS4032SP 3)				
	5.7 / 4.8	NPN / PNP	300 / 200	0.5	2	57 / 70	250 / 390	4	0.4	PBSS4032SPN 3)				
40	1	NPN / PNP	300 / 250	0.5	5	130 / 150	500	1	0.1		PBSS4140DPN			
	2	NPN / PNP	300 / 250	0.5	5	80 / 100	400 / 530	2	0.2		PBSS4240DPN			
50	2.7	2 x NPN	300	0.5	2	50	340	2.7	0.27	PBSS4350SS				
		2 x PNP	200	0.5	2	60	370	2.7	0.27	PBSS5350SS				
		NPN / PNP	300 / 200	0.5	2	50 / 60	340 / 370	2.7	0.27	PBSS4350SPN				
60	1	2 x NPN	200	0.5	5	115	250	1	0.1		PBSS4160DS			
		2 x PNP	150	0.5	5	120	330	1	0.1		PBSS5160DS			
		NPN / PNP	200 / 150	0.5	5	115 / 120	250 / 330	1	0.1		PBSS4160DPN			
	1	NPN / NPN	150	0.5	2	90	120	0.5	0.05				PBSS4160PAN	PBSS4160PANS
		PNP / PNP	120	0.5	2	125	180	0.5	0.05				PBSS5160PAP	PBSS5160PAPS
		NPN / PNP	150 / 120	0.5	2	90 / 125	120 / 180	0.5	0.05				PBSS4160PANP	PBSS4160PANPS
	2	NPN / NPN	210	0.5	2	70	90	0.5	0.05				PBSS4260PAN	PBSS4260PANS
		PNP / PNP	140	0.5	2	100	140	0.5	0.05				PBSS5260PAP	PBSS5260PAPS
		NPN / PNP	210 / 140	0.5	2	70 / 100	90 / 140	0.5	0.05				PBSS4260PANP	PBSS4260PANPS
	6.7	NPN / NPN	300	0.5	2	20	190	4	0.2	PBSS4041SN				
	5.9	PNP / PNP	200	0.5	2	35	330	4	0.2	PBSS4041SP				
	6.7 / 5.9	NPN / PNP	300 / 200	0.5	2	20 / 35	190 / 330	4	0.2	PBSS4041SPN				
120	1	NPN / NPN	240	0.1	2	90	120	0.5	0.05				PBSS4112PAN	
		PNP / PNP	190	0.1	2	150	220	0.5	0.05				PBSS5112PAP	
		NPN / PNP	240 / 190	0.1	2	90 / 150	120 / 220	0.5	0.05				PBSS4112PANP	

[1] I_c / I_b=20 [2] Device mounted on a ceramic PCB, Al2O3, standard footprint [3] Optimized for high-speed switching

Low V_{CEsat} (BISS) transistors load switches

Package				SOT457 (SC-74)		SOT363 (SC-88)
						
Size (mm)				2.9 x 1.5 x 1.0		2.0 x 1.25 x 0.95
P_{tot} (mW)				750 [1]	600 [1]	300 [2]
V_{CEO} (V)	I_C (A)	V_{CEsat} max (mV); I_C = 0.5 A; I_B = 0.05 A	R1, R2 (kΩ)			
15	0.5	250	2.2			PBLS1501Y
			4.7			PBLS1502Y
			10			PBLS1503Y
			22			PBLS1504Y
20	1	150	2.2		PBLS2001D	
			4.7		PBLS2002D	
			10		PBLS2003D	
			22		PBLS2004D	
	1.8	70	2.2	PBLS2021D		
			4.7	PBLS2022D		
			10	PBLS2023D		
			22	PBLS2024D		
40	0.5	350	2.2			PBLS4001Y
			4.7			PBLS4002Y
			10			PBLS4003Y
			22			PBLS4004Y
			47			PBLS4005Y
	1	170	2.2		PBLS4001D	
			4.7		PBLS4002D	
			10		PBLS4003D	
			22		PBLS4004D	
			47		PBLS4005D	
60	1	180	2.2		PBLS6001D	
			4.7		PBLS6002D	
			10		PBLS6003D	
			22		PBLS6004D	
			47		PBLS6005D	
	1.5	100	2.2	PBLS6021D		
			4.7	PBLS6022D		
			10	PBLS6023D		
			22	PBLS6024D		

[1] Device mounted on a ceramic PCB, Al2O3, standard footprint
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, and standard footprint

Low V_{CEsat} (BISS) high voltage transistors

Package				SOT223 (SC-73)	SOT89 (SC-62)	SOT1215	SOT23
							
Size (mm)				6.5 x 3.5 x 1.65	4.5 x 2.5 x 1.5	1.1 x 1.0 x 0.37	2.9 x 1.3 x 1.0
P_{tot} (mW)				1700	1300	750	250
Polarity	V_{CEO} [max] (V)	I_C (A)	hFE [min]				
NPN	150	0.5	100			PBHV8515QA	
		1	70				PBHV8115TLH
			100				PBHV8115T
					PBHV8115X		
				PBHV8115Z			
		2	100	PBHV8215Z			
	180	1	100				PBHV8118T
	400	1	100	PBHV8540Z			
		0.5	100				PBHV8540T
					PBHV8540X		
				PBHV8140Z			
	500	0.15	50				PMBTA45
	600	0.5	70	PBHV8560Z			
		0.1	70	PBHV2160Z			
PNP	140	4	100	PBHV9414Z			
	150	0.5	100			PBHV9515QA	
		1	70				PBHV9115TLH
			100				PBHV9115T
					PBHV9115X		
				PBHV9115Z			
		2	100	PBHV9215Z			
	400	0.25	100				PBHV9040T
					PBHV9040X		
				PBHV9040Z			
		0.5	100	PBHV9540Z			
	500	0.15	100				PBHV9050T
		0.25	100	PBHV9050Z			
	600	0.1	70	PBHV3160Z			
		0.5	70	PBHV9560Z			

Low V_{CEsat} (BISS) RETs

Package					SOT23	
						
Size (mm)					2.9 x 1.3 x 1.0	
P_{tot} (mW)					250	
V_{CEO} (V)	I_C (mA)		R1 (kΩ)	R2 (kΩ)	NPN	PNP
40	600	R1 = R2	1	1	PBRN113ET	PBRP113ET
			2.2	2.2	PBRN123ET	PBRP123ET
		R1 ≠ R2	1	10	PBRN113ZT	PBRP113ZT
			2.2	10	PBRN123YT	PBRP123YT

Low V_{CEsat} (BISS) transistors PNP - N-channel MOSFET combination

Package											DFN2020-6 (SOT1118)
Size (mm)											2.0 x 2.0 x 0.62
P_{tot} (mW)											1300
V_{CEO} (V)	I_C (A)	h_{FE} min	h_{FE} max	@ I_C (mA)	@ V_{CE} (V)	R_{CEsat} typ (mΩ)	V_{DS} (V)	V_{GS} (V)	I_D (A)	R_{Dson} typ (mΩ)	
40	2	300	800	100	5	240	30	0.7	0.66	390	PBSM5240PF
		100	-	100	5	240	30	0.7	0.66	390	PBSM5240PFH

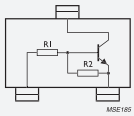
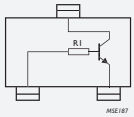
Low V_{CEsat} (BISS) power transistors single

Package						LFPAK56 (SOT669)
Size (mm)						5 x 6 x 1.1
V_{CEO} (V)	I_C (A)	h_{FE} min/typ	@ I_C (A)	@ V_{CE} (V)	Polarity	
40	6	200 / 400	0.5	2	NPN	PHPT60406NY
			0.5	2	PNP	PHPT60406PY
	10	200 / 400	0.5	2	NPN	PHPT60410NY
			0.5	2	PNP	PHPT60410PY
	15	200 / 400	0.5	2	NPN	PHPT60415NY
			0.5	2	PNP	PHPT60415PY
60	3	200 / 400	0.5	2	NPN	PHPT60603NY
			0.5	2	PNP	PHPT60603PY
	6	200 / 400	0.5	2	NPN	PHPT60606NY
		150 / 250	0.5	2	PNP	PHPT60606PY
	10	200 / 400	0.5	2	NPN	PHPT60610NY
		150 / 250	0.5	2	PNP	PHPT60610PY
100	2	150 / 250	0.5	10	NPN	PHPT61002NYC
		150 / 220	0.5	10	PNP	PHPT61002PYC
	3	150 / 250	0.5	10	NPN	PHPT61003NY
		150 / 220	0.5	10	PNP	PHPT61003PY
	6	150 / 250	0.5	10	NPN	PHPT61006NY
		150 / 220	0.5	10	PNP	PHPT61006PY
	10	150 / 250	0.5	10	NPN	PHPT61010NY
		150 / 220	0.5	10	PNP	PHPT61010PY

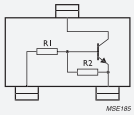
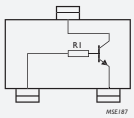
Low V_{CEsat} (BISS) power transistors double

Package												LFPAK56D (SOT1205)
Size (mm)												5 x 6 x 1.1
V_{CEO} (V)	I_C (A)	I_{CM} (A)	h_{FE} typ	@ I_C (A)	@ V_{CE} (V)	V_{CEsat} typ (mV); I_C = 0.5 A; I_B = 0.05 A	V_{CEsat} max (mV)	@ I_C (A)	@ I_B (A)	Polarity	h_{FE1}/h_{FE2}	
100	3	6	150	0.5	10	50	300	3	0.2	2XNPN	-	PHPT610030NK
						70	400	3	0.2	2XPNP	-	PHPT610030PK
						50 / 70	300 / 400	3	0.2	NPN/PNP	-	PHPT61003NPK
						50	300	3	0.2	2XNPN	0.95	PHPT610035NK
						70	400	3	0.2	2XPNP	0.9	PHPT610035PK

RETs 100 mA single - part 1

Package					SOT23		SOT323 (SC-70)	
								
Size (mm)					2.9 x 1.3 x 1.0		2.0 x 1.25 x 0.95	
P_{tot} (mW)					250		200	
V_{CEO} (V)	I_C (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN	PNP	NPN	PNP
50	100		1	1		PDTA113ET		PDTA113EU
			2.2	2.2	PDTC123ET	PDTA123ET	PDTC123EU	PDTA123EU
			4.7	4.7	PDTC143ET	PDTA143ET	PDTC143EU	PDTA143EU
			10	10	PDTC114ET	PDTA114ET	PDTC114EU	PDTA114EU
			22	22	PDTC124ET	PDTA124ET	PDTC124EU	PDTA124EU
			47	47	PDTC144ET	PDTA144ET	PDTC144EU	PDTA144EU
			100	100	PDTC115ET	PDTA115ET	PDTC115EU	PDTA115EU
			1	10		PDTA113ZT		PDTA113ZU
			2.2	10	PDTC123YT	PDTA123YT	PDTC123YU	PDTA123YU
			2.2	47	PDTC123JT	PDTA123JT	PDTC123JU	PDTA123JU
			4.7	10	PDTC143XT	PDTA143XT	PDTC143XU	PDTA143XU
			4.7	47	PDTC143ZT	PDTA143ZT	PDTC143ZU	PDTA143ZU
			10	47	PDTC114YT	PDTA114YT	PDTC114YU	PDTA114YU
			22	47	PDTC124XT	PDTA124XT	PDTC124XU	PDTA124XU
			47	10	PDTC144VT	PDTA144VT	PDTC144VU	PDTA144VU
			47	22	PDTC144WT	PDTA144WT	PDTC144WU	PDTA144WU
			2.2	-	PDTC123TT	PDTA123TT	PDTC123TU	PDTA123TU
			4.7	-	PDTC143TT	PDTA143TT	PDTC143TU	PDTA143TU
			10	-	PDTC114TT	PDTA114TT	PDTC114TU	PDTA114TU
			22	-	PDTC124TT	PDTA124TT	PDTC124TU	PDTA124TU
			47	-	PDTC144TT	PDTA144TT	PDTC144TU	PDTA144TU
			100	-	PDTC115TT	PDTA115TT	PDTC115TU	PDTA115TU

RETs 100 mA single - part 2

Package					DFN1006-3 (SOT883)		DFN1006B-3 (SOT883B)		SOT1215	
										
Size (mm)					1.0 x 0.6 x 0.48		1.0 x 0.6 x 0.37		1.1 x 1.0 x 0.37	
P_{tot} (mW)					250		250		750	
V_{CEO} (V)	I_C (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN	PNP	NPN	PNP	NPN	PNP
50	100		1	1		PDTA113EM		PDTA113EMB		
			2.2	2.2	PDTC123EM	PDTA123EM	PDTC123EMB	PDTA123EMB		
			4.7	4.7	PDTC143EM	PDTA143EM	PDTC143EMB	PDTA143EMB	PDTC143EQA	PDTA143EQA
			10	10	PDTC114EM	PDTA114EM	PDTC114EMB	PDTA114EMB	PDTC114EQA	PDTA114EQA
			22	22	PDTC124EM	PDTA124EM	PDTC124EMB	PDTA124EMB	PDTC124EQA	PDTA124EQA
			47	47	PDTC144EM	PDTA144EM	PDTC144EMB	PDTA144EMB	PDTC144EQA	PDTA144EQA
			100	100	PDTC115EM	PDTA115EM	PDTC115EMB	PDTA115EMB		
			1	10		PDTA113ZM		PDTA113ZMB		
			2.2	10	PDTC123YM	PDTA123YM	PDTC123YMB	PDTA123YMB		
			2.2	47	PDTC123JM	PDTA123JM	PDTC123JMB	PDTA123JMB	PDTC123XQA	PDTA123XQA
			4.7	10	PDTC143XM	PDTA143XM	PDTC143XMB	PDTA143XMB	PDTC143XQA	PDTA143XQA
			4.7	47	PDTC143ZM	PDTA143ZM	PDTC143ZMB	PDTA143ZMB	PDTC143ZQA	PDTA143ZQA
			10	47	PDTC114YM	PDTA114YM	PDTC114YMB	PDTA114YMB	PDTC114YQA	PDTA114YQA
			22	47	PDTC124XM	PDTA124XM	PDTC124XMB	PDTA124XMB		
			47	10	PDTC144VM	PDTA144VM	PDTC144VMB	PDTA144VMB		
			47	22	PDTC144WM	PDTA144WM	PDTC144WMB	PDTA144WMB		
			2.2	-	PDTC123TM	PDTA123TM	PDTC123TMB	PDTA123TMB		
			4.7	-	PDTC143TM	PDTA143TM	PDTC143TMB	PDTA143TMB		
			10	-	PDTC114TM	PDTA114TM	PDTC114TMB	PDTA114TMB		
			22	-	PDTC124TM	PDTA124TM	PDTC124TMB	PDTA124TMB		
			47	-	PDTC144TM	PDTA144TM	PDTC144TMB	PDTA144TMB		
			100	-	PDTC115TM	PDTA115TM	PDTC115TMB	PDTA115TMB		

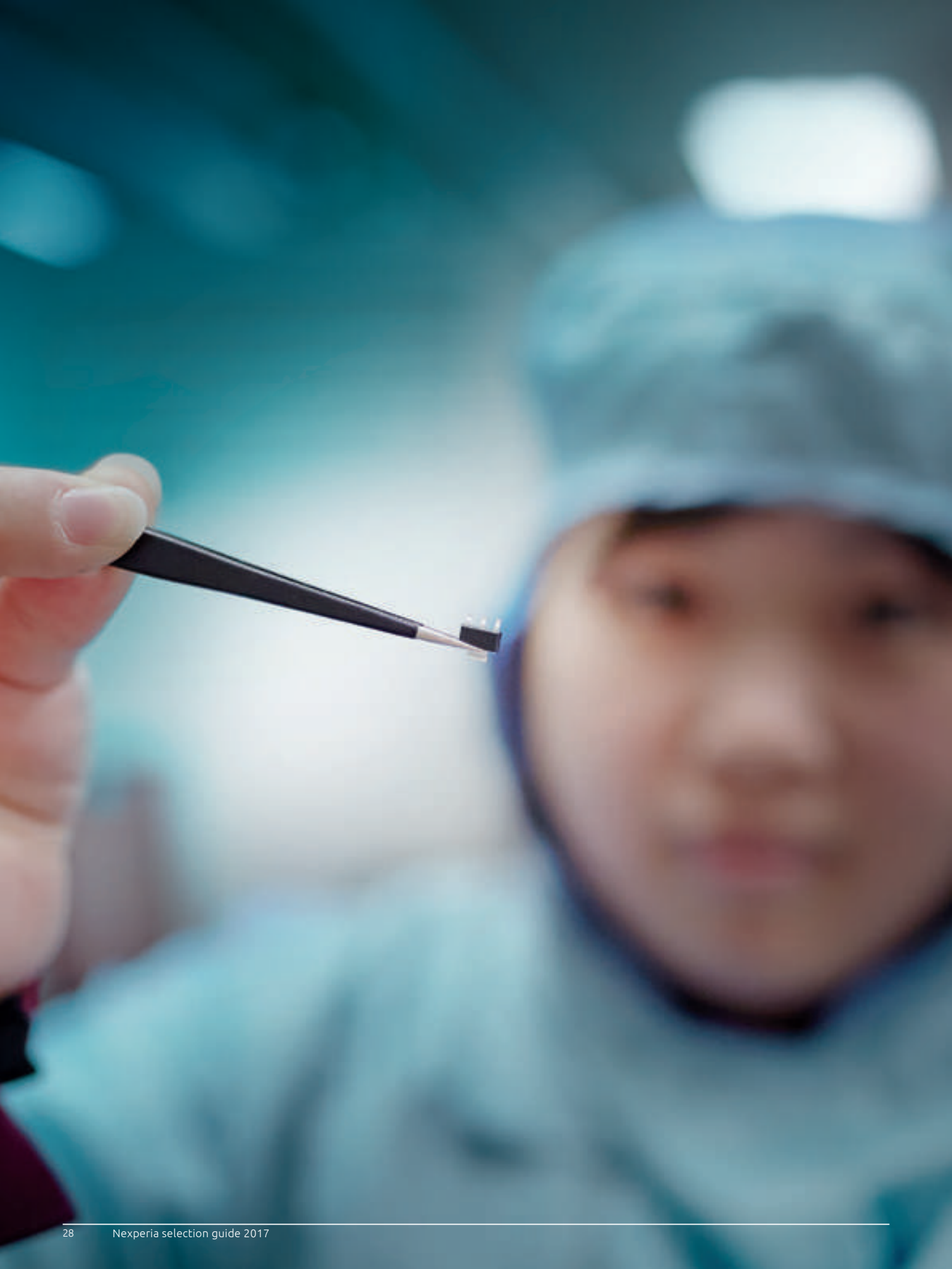
RETs 100 mA double

types in **bold** represent new products

Package					DFN1010B-6 (SOT1216)			DFN1412-6 (SOT1268)			SOT363 (SC-88)			SOT666		
																
Size (mm)					1.1 x 1.0 x 0.37			1.4 X 1.2 X 0.5			2.0 x 1.25 x 0.95			1.6 x 1.2 x 0.55		
P_{tot} (mW)					350			480			300			300		
V_{CEO} (V)	I_C (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN / NPN	NPN / PNP	PNP / PNP	NPN / NPN	NPN / PNP	PNP / PNP	NPN / NPN	NPN / PNP	PNP / PNP	NPN / NPN	NPN / PNP	PNP / PNP
50	100	R1 = R2	2.2	2.2							PUMH20	PUMD20	PUMB20	PEMH20	PEMD20	PEMB20
			4.7	4.7							PUMH15	PUMD15	PUMB15	PEMH15	PEMD15	PEMB15
			10	10	PQMH11	PQMD3	PQMB11	**PRMH11**	**PRMD3**	**PRMB11**	PUMH11	PUMD3	PUMB11	PEMH11	PEMD3	PEMB11
			22	22		PQMD2			**PRMD2**		PUMH1	PUMD2	PUMB1	PEMH1	PEMD2	PEMB1
			47	47	PQMH2	PQMD12		**PRMH2**	**PRMD12**		PUMH2	PUMD12	PUMB2	PEMH2	PEMD12	PEMB2
			100	100							PUMH24	PUMD24	PUMB24	PEMH24	PEMD24	PEMB24
		R1 ≠ R2	2.2	47	PQMH10	PQMD10		**PRMH10**	**PRMD10**		PUMH10	PUMD10	PUMB10	PEMH10	PEMD10	PEMB10
			4.7	10							PUMH18	PUMD18	PUMB18	PEMH18	PEMD18	PEMB18
			4.7	47	PQMH13	PQMD13		**PRMH13**	**PRMD13**		PUMH13	PUMD13	PUMB13	PEMH13	PEMD13	PEMB13
			10	47	PQMH9			**PRMH9**			PUMH9	PUMD9	PUMB9	PEMH9	PEMD9	PEMB9
			22	47		PQMD16			**PRMD16**		PUMH16	PUMD16	PUMB16	PEMH16	PEMD16	PEMB16
			47	22							PUMH17	PUMD17	PUMB17	PEMH17	PEMD17	PEMB17
			47 / 2.2	47 / 47								PUMD48			PEMD48	
		Only R1	2.2	-							PUMH30	PUMD30	PUMB30	PEMH30	PEMD30	PEMB30
			4.7	-							PUMH7	PUMD6	PUMB3	PEMH7	PEMD6	PEMB3
			10	-							PUMH4	PUMD4	PUMB4	PEMH4	PEMD4	PEMB4
			22	-							PUMH19	PUMD19	PUMB19	PEMH19	PEMD19	PEMB19
			47	-							PUMH14	PUMD14	PUMB14	PEMH14	PEMD14	PEMB14

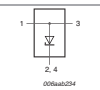
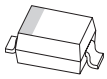
RETs 500mA single / double

Package					SOT457 (SC-74)		SOT23		SOT323 (SC-70)		SOT1215	
												
Size (mm)					2.9 x 1.5 x 1.0		2.9 x 1.3 x 1.0		2.0 x 1.25 x 0.95		1.1 x 1.0 x 0.37	
P_{tot} (mW)					750		250		200		750	
V_{CEO} (V)	I_C (mA)	Configuration	R1 (kΩ)	R2 (kΩ)	NPN / NPN	NPN / PNP	NPN	PNP	NPN	PNP	NPN	PNP
50	500	R1 = R2	1	1			PDTD113ET	PDTB113ET	PDTD113EU	PDTB113EU	PDTD113EQA	PDTB113EQA
			2.2	2.2			PDTD123ET	PDTB123ET	PDTD123EU	PDTB123EU	PDTD123EQA	PDTB123EQA
			4.7	4.7			PDTD143ET	PDTB143ET	PDTD143EU	PDTB143EU	PDTD143EQA	PDTB143EQA
			10	10			PDTD114ET	PDTB114ET	PDTD114EU	PDTB114EU	PDTD114EQA	PDTB114EQA
		R1 ≠ R2	1	10	PIMN31	PIMC31	PDTD113ZT	PDTB113ZT	PDTD113ZU	PDTB113ZU	PDTD113ZQA	PDTB113ZQA
			2.2	10			PDTD123YT	PDTB123YT	PDTD123YU	PDTB123YU	PDTD123YQA	PDTB123YQA
			4.7	10			PDTD143XT	PDTB143XT	PDTD143XU	PDTB143XU	PDTD143XQA	PDTB143XQA
		Only R1	2.2	-			PDTD123TT	PDTB123TT				



Diodes 2

General purpose Zener diodes

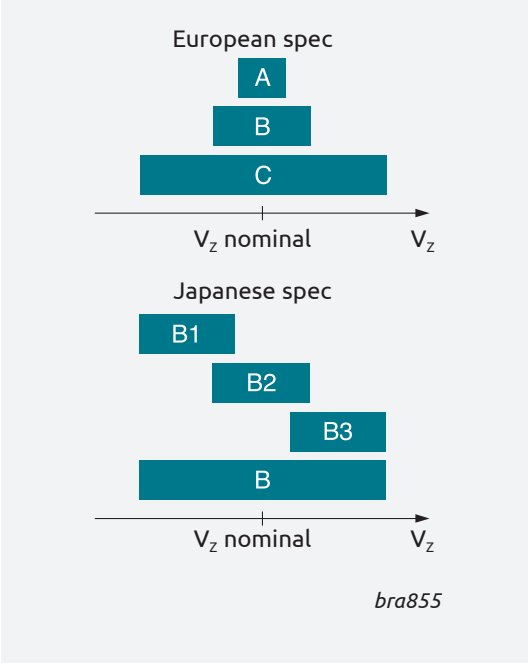
I_F max (mA)	P_{ZSM} (W)	V_Z nom (V)	V_Z tolerance	Note	Configuration		Series	Package	Size (mm)	P_{tot} (mW)
500	-	3.3~24	C	Europe	Single		1N47xxA series	SOD66 (DO-41) 	4.8 x 2.6 x 0.81	1000
	60	3.6~75					BZV85 series			
250	-	2.1~36	About 2%	Special	Single		NZX series	SOD27 (DO-35) 	4.25 x 1.85 x 0.56	400
	40	2.4~75	B, C	Europe			BZX79 series			
400	40	2.4~75	C	Europe	Single		BZV90 series	SOT223 (SC-73) 	6.5 x 3.5 x 1.65	1500
250	40	2.4~75	C	Europe	Single		BZV49 series	SOT89 (SC-62) 	4.5 x 2.5 x 1.5	1000
250	40	2.4~75	B, C	Europe	Single		BZV55 series	SOD80C (MiniMelf) 	3.5 x 1.5 x 1.5	400
200	40	2.4~75	B, C	Europe	Dual c.a.		BZB84 series	SOT23 	2.9 x 1.3 x 1.0	250
			A, B, C		Single		BZX84 series			
250	30	5~6.8	0.2 V	Ave			PLVA600A series			
250	40	2.4~75	C	Europe	Single		BZT52 series	SOD123 	2.7 x 1.6 x 1.2	550
200		2.4~36	B, C	Japan			PDZ-GW series			
250	-	3.0~30	About 2.5%	Special	Single		NZH series	SOD123F 	2.6 x 1.6 x 1.1	830
	40	2.4~75	B, C	Europe			BZT52H series			
200	40	10	B2	Japan	Dual isolated		PZU10DB2 series	SOT353 (SC-88A) 	2.0 x 1.25 x 0.95	300
200	40	2.4~15	C	Europe	Dual c.a.		BZB784 series	SOT323 (SC-70) 	2.0 x 1.25 x 0.95	350
200	30	100	C	Europe	Back-to-back		BZB100A	SOD323 (SC-76) 	1.7 x 1.25 x 0.95	300
	40	2.4~36	B2	Japan	Single		PDZ-B series			
250	40	2.4~75	B, C	Europe			BZX384 series			
200	40	2.4~36	B, B1, B2, B3	Japan			PZUxBA series			
200	60	100	C	Europe	Single		BZX100A	SOD323F (SC-90) 	1.7 x 1.25 x 0.7	550
200	40	2.4~36	B, B1, B2, B3	Japan			PZUxB series			
250	40	2.4~75	B, C	Europe			BZX84J series			
200	40	2.4~15	C	Europe	Dual c.a.		BZB984 series	SOT663 	1.6 x 1.2 x 0.55	350
200	40	2.4~75	B, C	Europe	Single		BZX585 series	SOD523 (SC-79) 	1.2 x 0.8 x 0.6	300
200	40	2.4~75	B, C	Europe	Single		BZX884 series	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.48	250
		2.4~36	B, B2	Japan			PZUxBL series			
250	40	2.4~30	B	Europe	Single		TDZxJ series	SOD323F 	1.7 x 1.25 x 0.7	500

Notes:
Japan: B selection: app. 5% Vz tolerance, B1, B2, B3 selections: app. 2% Vz tolerance in sequential intervals
Europe: A selection: app. 1% Vz tolerance, B selection: app. 2% Vz tolerance, C selection: app. 5% Vz tolerance; the selections are in overlapping intervals

Ave: low-voltage avalanche regulator diodes
Dual c.a.: dual common anode

Zener diodes specifications

Differences in Zener specifications



Japanese spec (PZU, PDZ)

y =	B-series	B1-series	B2-series	B3-series
	± 5%	± 2%	± 2%	± 2%
	V_z (V)	V_z (V)	V_z (V)	V_z (V)
PZU2.4y	2.3 - 2.6	-	-	-
PZU2.7y	2.5 - 2.9	2.5 - 2.75	2.65 - 2.9	-
PZU3.0y	2.8 - 3.2	2.8 - 3.05	2.95 - 3.2	-
PZU3.3y	3.1 - 3.5	3.1 - 3.35	3.25 - 3.5	-
PZU3.6y	3.4 - 3.8	3.4 - 3.65	3.55 - 3.8	-
PZU3.9y	3.7 - 4.1	3.7 - 3.97	3.87 - 4.1	-
PZU4.3y	4.01 - 4.48	4.01 - 4.21	4.15 - 4.34	4.28 - 4.48
PZU4.7y	4.42 - 4.9	4.42 - 4.61	4.55 - 4.75	4.69 - 4.9
PZU5.1y	4.84 - 5.37	4.84 - 5.04	4.98 - 5.2	5.14 - 5.37
PZU5.6y	5.31 - 5.92	5.31 - 5.55	5.49 - 5.73	5.67 - 5.92
PZU6.2y	5.86 - 6.53	5.86 - 6.12	6.06 - 6.33	6.26 - 6.53
PZU6.8y	6.47 - 7.14	6.47 - 6.73	6.65 - 6.93	6.86 - 7.14
PZU7.5y	7.06 - 7.84	7.06 - 7.36	7.28 - 7.6	7.52 - 7.84
PZU8.2y	7.76 - 8.64	7.76 - 8.1	8.02 - 8.36	8.28 - 8.64
PZU9.1y	8.56 - 9.55	8.56 - 8.93	8.85 - 9.23	9.15 - 9.55
PZU10y	9.45 - 10.55	9.45 - 9.87	9.77 - 10.21	10.11 - 10.55
PZU11y	10.44 - 11.56	10.44 - 10.88	10.76 - 11.22	11.1 - 11.56
PZU12y	11.42 - 12.6	11.42 - 11.9	11.74 - 12.24	12.08 - 12.6
PZU13y	12.47 - 13.96	12.47 - 13.03	12.91 - 13.49	13.37 - 13.96
PZU14y	-	-	13.7 - 14.3	-
PZU15y	13.84 - 15.52	13.84 - 14.46	14.34 - 14.98	14.85 - 15.52
PZU16y	15.37 - 17.09	15.37 - 16.01	15.85 - 16.51	16.35 - 17.09
PZU18y	16.94 - 19.03	16.94 - 17.7	17.56 - 18.35	18.21 - 19.03
PZU20y	18.86 - 21.08	18.86 - 19.7	19.52 - 20.39	20.21 - 21.08
PZU22y	20.88 - 23.17	20.88 - 21.77	21.54 - 22.47	22.23 - 23.17
PZU24y	22.93 - 25.57	22.93 - 23.96	23.72 - 24.78	24.54 - 25.57
PZU27y	25.1 - 28.9	-	-	-
PZU30y	28 - 32	-	-	-
PZU33y	31 - 35	-	-	-
PZU36y	34 - 38	-	-	-

European spec (BZV, BZX, BZB, 1N47)

y =	C-series	B-series	A-series
	±5%	±2%	±1%
	V_z (V)	V_z (V)	V_z (V)
BZX84-y2V4	2.2 - 2.6	2.35 - 2.45	2.37 - 2.43
BZX84-y2V7	2.5 - 2.9	2.65 - 2.75	2.67 - 2.73
BZX84-y3V0	2.8 - 3.2	2.94 - 3.06	2.97 - 3.03
BZX84-y3V3	3.1 - 3.5	3.23 - 3.37	3.26 - 3.34
BZX84-y3V6	3.4 - 3.8	3.53 - 3.67	3.56 - 3.64
BZX84-y3V9	3.7 - 4.1	3.82 - 3.98	3.86 - 3.94
BZX84-y4V3	4 - 4.6	4.21 - 4.39	4.25 - 4.35
BZX84-y4V7	4.4 - 5	4.61 - 4.79	4.65 - 4.75
BZX84-y5V1	4.8 - 5.4	5 - 5.2	5.04 - 5.16
BZX84-y5V6	5.2 - 6	5.49 - 5.71	5.54 - 5.66
BZX84-y6V2	5.8 - 6.6	6.08 - 6.32	6.13 - 6.27
BZX84-y6V8	6.4 - 7.2	6.66 - 6.94	6.73 - 6.87
BZX84-y7V5	7 - 7.9	7.35 - 7.65	7.42 - 7.58
BZX84-y8V2	7.7 - 8.7	8.04 - 8.36	8.11 - 8.29
BZX84-y9V1	8.5 - 9.6	8.92 - 9.28	9 - 9.2
BZX84-y10	9.4 - 10.6	9.8 - 10.2	9.9 - 10.1
BZX84-y11	10.4 - 11.6	10.8 - 11.2	10.8 - 11.11
BZX84-y12	11.4 - 12.7	11.8 - 12.2	11.88 - 12.12
BZX84-y13	12.4 - 14.1	12.7 - 13.3	12.87 - 13.13
BZX84-y15	13.8 - 15.6	14.7 - 15.3	14.85 - 15.15
BZX84-y16	15.3 - 17.1	15.7 - 16.3	15.84 - 16.16
BZX84-y18	16.8 - 19.1	17.6 - 18.4	17.82 - 18.18
BZX84-y20	18.8 - 21.2	19.6 - 20.4	19.8 - 20.2
BZX84-y22	20.8 - 23.3	21.6 - 22.4	21.78 - 22.22
BZX84-y24	22.8 - 25.6	23.5 - 24.5	23.76 - 24.24
BZX84-y27	25.1 - 28.9	26.5 - 27.5	26.73 - 27.27
BZX84-y30	28 - 32	29.4 - 30.6	29.70 - 30.30
BZX84-y33	31 - 35	32.3 - 33.7	32.67 - 33.33
BZX84-y36	34 - 38	35.3 - 36.7	35.64 - 36.36
BZX84-y39	37 - 41	38.2 - 39.8	38.61 - 39.39
BZX84-y43	40 - 46	42.1 - 43.9	42.57 - 43.43
BZX84-y47	44 - 50	46.1 - 47.9	-
BZX84-y51	48 - 54	50 - 52	50.49 - 51.51
BZX84-y56	52 - 60	54.9 - 57.1	-
BZX84-y62	58 - 66	60.8 - 63.2	-
BZX84-y68	64 - 72	66.6 - 69.4	-
BZX84-y75	70 - 79	73.5 - 76.5	74.25 - 75.75

NZX-series in SOD27

	V_z (V)		V_z (V)		V_z (V)
NZX2V1B	2.0 - 2.2	NZX6V2D	6.1 - 6.4	NZX14C	13.8 - 14.3
NZX2V4A	2.3 - 2.5	NZX6V2E	6.3 - 6.6	NZX15A	14.1 - 14.7
NZX2V4B	2.4 - 2.6	NZX6V8A	6.4 - 6.7	NZX15B	14.5 - 15.1
NZX2V7A	2.5 - 2.7	NZX6V8B	6.6 - 6.9	NZX15C	14.9 - 15.5
NZX2V7B	2.6 - 2.8	NZX6V8C	6.7 - 7	NZX15X	14.35 - 15.09
NZX2V7C	2.7 - 2.9	NZX6V8D	6.9 - 7.2	NZX16A	15.3 - 15.9
NZX3V0A	2.8 - 3	NZX7V5A	7 - 7.3	NZX16B	15.7 - 16.5
NZX3V0B	2.9 - 3.1	NZX7V5B	7.2 - 7.6	NZX16C	16.3 - 17.1
NZX3V0C	3 - 3.2	NZX7V5C	7.3 - 7.7	NZX18A	16.9 - 17.7
NZX3V3A	3.1 - 3.3	NZX7V5D	7.5 - 7.9	NZX18B	17.5 - 18.3
NZX3V3B	3.2 - 3.4	NZX7V5X	7.07 - 7.45	NZX18C	18.1 - 19
NZX3V3C	3.3 - 3.5	NZX8V2A	7.7 - 8.1	NZX20A	18.8 - 19.7
NZX3V6A	3.4 - 3.6	NZX8V2B	7.9 - 8.3	NZX20B	19.5 - 20.4
NZX3V6B	3.5 - 3.7	NZX8V2C	8.1 - 8.5	NZX20C	20.2 - 21.2
NZX3V6C	3.6 - 3.8	NZX8V2D	8.3 - 8.7	NZX22A	20.9 - 21.9
NZX3V9A	3.7 - 3.9	NZX9V1A	8.5 - 8.9	NZX22B	21.6 - 22.6
NZX3V9B	3.8 - 4	NZX9V1B	8.7 - 9.1	NZX22C	22.3 - 23.3
NZX3V9C	3.9 - 4.1	NZX9V1C	8.9 - 9.3	NZX24A	22.9 - 24
NZX4V3A	4 - 4.2	NZX9V1D	9.1 - 9.5	NZX24B	23.6 - 24.7
NZX4V3B	4.1 - 4.3	NZX9V1E	9.3 - 9.7	NZX24C	24.3 - 25.5
NZX4V3C	4.2 - 4.4	NZX10A	9.5 - 9.9	NZX24X	22.61 - 23.77
NZX4V3D	4.3 - 4.5	NZX10B	9.7 - 10.1	NZX27A	25.2 - 26.6
NZX4V7A	4.4 - 4.6	NZX10C	9.9 - 10.3	NZX27B	26.2 - 27.6
NZX4V7B	4.5 - 4.7	NZX10D	10.2 - 10.6	NZX27C	27.2 - 28.6
NZX4V7C	4.6 - 4.8	NZX11A	10.4 - 10.8	NZX27X	26.99 - 28.39
NZX4V7D	4.7 - 4.9	NZX11B	10.7 - 11.1	NZX30A	28.2 - 29.6
NZX5V1A	4.8 - 5	NZX11C	10.9 - 11.3	NZX30B	29.2 - 30.6
NZX5V1B	4.9 - 5.1	NZX11D	11.1 - 11.6	NZX30C	30.2 - 31.6
NZX5V1C	5 - 5.2	NZX12A	11.4 - 11.9	NZX30X	29.02 - 30.51
NZX5V1D	5.1 - 5.3	NZX12B	11.6 - 12.1	NZX33A	31.2 - 32.6
NZX5V6A	5.2 - 5.5	NZX12C	11.9 - 12.4	NZX33B	32.2 - 33.6
NZX5V6B	5.3 - 5.6	NZX12D	12.2 - 12.7	NZX33C	33.2 - 34.5
NZX5V6C	5.4 - 5.7	NZX12X	11.44 - 12.03	NZX36A	34.2 - 35.7
NZX5V6D	5.5 - 5.8	NZX13A	12.4 - 12.9	NZX36B	35.3 - 36.8
NZX5V6E	5.6 - 5.9	NZX13B	12.6 - 13.1	NZX36C	36.4 - 38
NZX6V2A	5.7 - 6	NZX13C	12.9 - 13.4	NZX36X	35.36 - 37.19
NZX6V2B	5.8 - 6.1	NZX14A	13.2 - 13.7		
NZX6V2C	6 - 6.3	NZX14B	13.5 - 14		

General purpose, high speed switching diodes <= 90V

types in **bold** represent new products

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA)	@ V_R (V)	t_{rr} max (ns)	Package	SOD80C (MiniMelf)	SOT23	SOT143B	SOT323 (SC-70)	SOT363 (SC-88)	DFN1412-6 (SOT1268)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)
						Size (mm)	3.5 x 1.5 x 1.5	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.4 x 1.2 x 0.5	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48
						P_{tot} (mW)	**400**	**250**	**250**	**200**	**350**	**480**	**325**	**250**
50	1	50	100	50	4			BAL74						
								BAV74						
70	1	50	1000	70	4			BAL99						
75	1	50	1000	75	4				BAS28					
		100	5000	75	4		BAS32L							
80	1	50	500	80	4					1PS300				
										1PS301				
										1PS302				
90	1	50	500	80	4			BAW56		BAW56W			BAW56QA	BAW56M
											BAW56S	BAW56SRA		
											BAV756S			

General purpose, high speed switching diodes 100V

types in **bold** represent new products

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA)	@ V_R (V)	t_{rr} max (ns)	Package	SOT23	SOD123	SOD123F	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOD323F (SC-90)	SOT666	DFN1412-6 (SOT1268)	SOD523 (SC-79)	DFN1010D-3 (SOT1215)	DFN1006-2 (SOD882)	DFN1006-3 (SOT883)	DFN1006D-2 (SOD882D)
						Size (mm)	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.6 x 1.2 x 0.55	1.4 x 1.2 x 0.5	1.2 x 0.8 x 0.6	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
						P_{tot} (mW)	**250**	**380**	**375**	**200**	**300**	**300**	**300**	**180**	**480**	**250**	**325**	**250**	**250**	**250**
100	1	50	500	80	4			**BAS16GW**	BAS16H			BAS316	BAS16J			BAS516		BAS16L		BAS16LD
							BAS16			BAS16W							BAS16QA			
											BAS-16VY			BAS-16VV						
							BAV70			BAV70W							BAV70QA		BAV70M	
											BAV70S				BAV70SRA					
							BAV99			BAV99W							BAV99QA			
											BAV99S									

General purpose, switching diodes >= 100V

types in **bold** represent new products

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA)	@ V_R (V)	t_{rr} max (ns)	Package	SOD80C (MiniMelf)	SOT457 (SC-74)	SOT23	SOT143B	SOD123	SOD123F	SOT323 (SC-70)	SOT353 (SC-88A)	SOT363 (SC-88)	SOD323 (SC-76)	SOD323F (SC-90)	SOD523 (SC-79)	DFN1006D-2 (SOD882(D))
																			
						Size (mm)	3.5 x 1.5 x 1.5	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.48 (1.0 x 0.6 x 0.37)
						P_{tot} (mW)	**400**	**250**	**250**	**250**	**380**	**375**	**200**	**255**	**300**	**300**	**300**	**250**	**250**
100	1	100	100	100	50				BAS19										
150	1	100	100	150	50		BAV102												
									BAS20										
≥200	1	100	100	150	50		BAV103				**BAS21GW**	BAS21H				BAS321			BAS21L(D)
				200					BAS21				BAS21W						
										BAV23									
														BAS21PG					
									BAV23A				BAS21AW						
									BAV23C										
									BAV23S				BAS21SW						
								BA-S21AVD											
								BAS21VD											
300	1.1	100	150	250	50												BAS21J	BAS521	
									BAS101										
									BAS101S										
										BAW101									
															BAW101S				

Controlled avalanche switching diodes

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA) @ V_R max	I_{FSM} max (A)	I_{FRM} max (mA)	C_d max (pF)	t_{rr} max (ns)	Package	SOT23	SOT143B
										
								Size (mm)	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0
								P_{tot} (mW)	250	250
60	1	200	100	9	600	2.5	6			BAS56
90	1	200	100	10	600	35	50		BAS29	
									BAS31	
									BAS35	

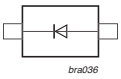
Low leakage current switching diodes

types in **bold** represent new products

V_R max (V)	V_F max (V)	@ I_F (mA)	I_R max (nA) @ V_R max	t_{rr} max (µs)	Package	SOD80C (MiniMelf)	SOD68 (DO-34)	SOT23	SOD123	SOD123F	SOT323 (SC-70)	SOD323 (SC-76)	SOD523 (SC-79)	DFN1010D-3 (SOT1215)	DFN1006-3 (SOT883)	DFN1006-2 (SOD882)
																
					Size (mm)	3.5 x 1.5 x 1.5	3.04 x 1.6 x 0.55	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.2 x 0.8 x 0.6	1.1 x 1.0 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.48
					P_{tot} (mW)	400	300	250	380	375	250	250	250	305	250	250
75	1	10	5	3					**BAS116GW**	BAS116H		BAS416	BAS716			BAS116L
								BAS116						BAS116QA		
								BAV199			BAV199W					
								BAW156								
								BAV170						BAV170QA	BAV170M	
125	1	100	1	1.5 typ		BAS45AL	BAS45A									

PN rectifiers

types in **bold** represent new products

V_R max (V)	V_F max (V)	(@ I_F (A)	I_R max (µA)	(@ V_R (V)	trr max (ns)	Package	CFP5 (SOD128)	CFP3 (SOD123W)
								
						Size (mm)	3.8 x 2.5 x 1.0	2.6 x 1.7 x 1.0
						P_{tot} (mW) @ 1cm²	1050	950
200	0.875	1	0.2	200	25	 bra036		**ES1DVR**
	0.93	1	0.2	200	25			**ES1DR**
	0.95	2	0.2	200	25			**ES2DVR**
	0.98	2	0.2	200	25			**ES2DR**
	0.95	2	0.2	200	25		**ES2DP**	
	0.98	3	0.2	200	30		**ES3DP**	
400	1.1	1	1	400	1800		PNS40010ER	PNS40010ER

PN rectifier nomenclature

ES 1 D V R

Recovery time indicator:
e.g. ES - hyperfast recovery time

Cont. forward current in A:
e.g. 1 = 1.0 A

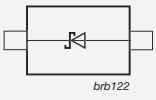
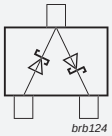
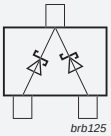
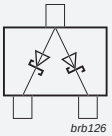
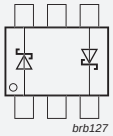
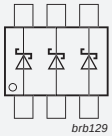
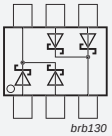
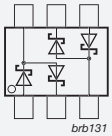
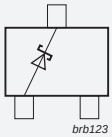
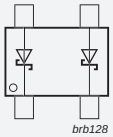
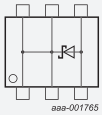
Max. reverse voltage:
e.g. D = 200 V

Variant letter (optional):
V = low V_F level

Package indicator:
P = SOD128
R = SOD123W

General purpose schottky diodes <= 250 mA

IF max (mA)	VR max (V)	VF max (mV)	@ IF (mA)	IR max (µA)	@ VR (V)	Package	SOD80C (MiniMelf)	SOD68 (DO-34)	SOT23	SOT143B	SOD123
						Size (mm)	3.5 x 1.5 x 1.5	3.04 x 1.6 x 0.55	2.9 x 1.3 x 1.0	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2
						P_{tot} (mW)	**300**	**500**	**250**	**250**	**357**
70	70	750	10	0.1	50	single			BAS70		
						dual series			BAS70-04		
						dual c.c.			BAS70-05		
						dual c.a.			BAS70-06		
						dual isolated				BAS70-07	
						triple isolated					
						quad 2x series					
120	40	370	1	0.5	30	single					
		500	10	1	30	single			BAS40		
						dual series			BAS40-04		
						dual c.c.			BAS40-05		
						dual c.a.			BAS40-06		
						dual isolated				BAS40-07	
						quad c.c./c.c.					
						quad 2x series					
200	30	300	10	30	10	single					
		340	10	2	25	single			BAT754		
						dual series			BAT754S		
						dual c.c.			BAT754C		
						dual c.a.			BAT754A		
						triple isolated					
		400	10	2	25	single	BAS85	BAT85	BAT54		**BAT54GW**
						dual series			BAT54S		
						dual c.c.			BAT54C		
						dual c.a.			BAT54A		
						dual isolated				BAT74	
						triple isolated					
						quad c.c./c.c.					
						quad 2x series					
		500	200	30	10	single					
		600	200	1	10	single					
	40	300	10	15	30	single			BAT721		
						dual series			BAT721S		
						dual c.c.			BAT721C		
						dual c.a.			BAT721A		
		360	10	0.5	25	single					
		420	30	0.5	25	single					
						dual series					
						dual c.c.					
						dual c.a.					
	50	450	10	5	40	single	BAS86	BAT86			
250	100	850	250	4	75	single					**BAT46GW**

Single	Dual series	Dual c.c.	Dual c.a.	Dual isolated	Triple isolated	Quad c.c./c.c.	Quad 2x series
 brb122	 brb124	 brb125	 brb126	 brb127	 brb129	 brb130	 brb131
 brb123				 brb128			
 aaa-001765							

types in **bold** represent new products

	SOD123F	SOT323 (SC-70)	SOT363 (SC-88)	SOD323F (SC-90)	SOD323 (SC-76)	SOT666	SOD523 (SC-79)	DFN1006-2 (SOD882)/ DFN1006-3 (SOT883)
								
	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.7 x 1.25 x 0.95	1.6 x 1.2 x 0.55	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.48
	375	**250**	**300**	**385**	**400**	**300**	**275**	**250**
	BAS70H	BAS70W			1PS76SB70		1PS79SB70	BAS70L
		BAS70-04W						
		BAS70-05W						
		BAS70-06W						
			BAS70-07S			BAS70-07V		
						BAS70VV		
			BAS70XY					
					RB751V40		RB751S40	RB751CS40
	BAS40H	BAS40W			1PS76SB40		1PS79SB40	BAS40L
		BAS40-04W						
		BAS40-05W						
		BAS40-06W						
						BAS40-07V		
			1PS88SB48			BAS40-05V		
			BAS40XY					
							1PS79SB31	
			BAT754L					
	BAT54H	BAT54W		BAT54J	1PS76SB10		1PS79SB10	BAT54L
		BAT54SW						
		BAT54CW						BAT54CM
		BAT54AW						
			BAT74S			BAT74V		
						BAT54VV		
						BAT54CV		
			BAT54XY					
							RB521S30	RB521CS30L
							RB520S30	RB520CS30L
					1PS76SB21			
							1PS79SB30	
		BAT854W						
		BAT854SW						
		BAT854CW						
		BAT854AW						
	BAT46WH			BAT46WJ				

Low capacitance schottky diodes

I_F max (mA)	V_R max (V)	V_F max (mV) @ I_F (mA)		C_d max (pF) @ V_R = 0 V	Package	SOT23	SOT323 (SC-70)	SOT363 (SC-88)	SOD323 (SC-76)	SOT666	SOD523 (SC-79)	DFN1006-2 (SOD882)
												
					Size (mm)	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.95	1.6 x 1.2 x 0.55	1.2 x 0.8 x 0.6	1.0 x 0.6 x 0.48
					P_{tot} (mW)	250	250	300	400	300	500	250
30	4	450	1	1	single	BAT17			1PS76SB17		1PS79SB17	
					triple isolated					1PS66SB17		
					dual series	PMBD353 PMBD354 [1]						
	15	340	1	1	single		1PS70SB82					1PS10SB82
					triple isolated			1PS88SB82		1PS66SB82		
					dual series		1PS70SB84					
					dual c.c.		1PS70SB85					
					dual c.a.		1PS70SB86					

[1] Diodes have matched capacitance

Medium power low VF schottky rectifiers single >= 200 mA - leadless DSN / DFN packages

I_F max (A)	V_R max (V)	V_F max (mV) @ IF max	I_R max (mA) @ V_R max	Package	DSN0603-2 (SOD962)	DSN1006-2 (SOD993)	DSN1006U-2 (SOD995)	
								
				Size (mm)	0.6 x 0.3 x 0.3	1.0 x 0.6 x 0.28	1.0 x 0.6 x 0.28	
				P_{tot} (mW) @ 1 cm²	525	1.000	1.190	
				Optimization				
0.2	20	420	0.045	Low V_F	PMEG2002AESF			
		490	0.0035	Low I_R	PMEG2002ESF			
	30	470	0.08	Low V_F	PMEG3002AESF			
		480	0.05	low V_F				
		535	0.009	Low I_R	PMEG3002ESF			
	40	525	0.08	Low V_F	PMEG4002AESF			
		600	0.0065	Low I_R	PMEG4002ESF			
		600	0.01	low I_R				
	60	600	0.1	low V_F				
0.5	20	390	0.2	low V_F				
		410	0.3	low V_F				
		440	1.5	low V_F				
		500	0.03	low I_R				
		550	0.045	Low V_F	PMEG2005AESF			
		620	0.0035	Low I_R	PMEG2005ESF			
	30	500	0.5	low V_F				
		630	0.08	Low V_F	PMEG3005AESF			
		720	0.009	Low I_R	PMEG3005ESF			
	40	590	0.01	low I_R				
		820	0.08	Low V_F	PMEG4005AESF			
		880	0.0065	Low I_R	PMEG4005ESF			
1	20	375	1.9	low V_F				
		415	0.6	low V_F				
		490	0.2	low V_F				
	30	480	1.25	Low V_F		PMEG3010AESB	PMEG3010AESA	
		565	0.045	Low I_R		PMEG3010ESF		
	40	505	0.115	Low V_F		PMEG4010AESB		
		600	0.02	low I_R				
		610	0.04	Low I_R		PMEG4010ESB		
	60	625	0.65	Low V_F		PMEG6010AESB		
		730	0.03	Low I_R		PMEG6010ESB		
1.5	20	420	0.9	low V_F				
	40	610	0.03	low I_R				
2	20	420	1.9	low V_F				
		450	0.9	low V_F				
	30	470	2.5	low V_F				
	40	535	0.1	low V_F				
	60	530	0.2	low V_F				
		575	0.25	low V_F				

	DFN2020-3 (SOT1061)	DFN2020-3S (SOT1061)	DFN1608D-2 (SOD1608)	DFN1006-2 (SOD882)	DFN1006D-2 (SOD882D)
					
	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.62	1.6 x 0.8 x 0.37	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
	960	960	780	565	660
				PMEG3002AEL	PMEG3002AELD
				PMEG4002EL	PMEG4002ELD
				PMEG6002EL	PMEG6002ELD
					PMEG2005BELD
			PMEG2005EPK		
				PMEG2005AEL	PMEG2005AELD
				PMEG2005EL	PMEG2005ELD
				PMEG3005EL	PMEG3005ELD
			PMEG4005EPK		
	PMEG2010EPA	PMEG2010EPAS			
			PMEG2010EPK		
					PMEG2010BELD
			PMEG4010EPK		
			PMEG2015EPK		
			PMEG4015EPK		
	PMEG2020EPA	PMEG2020EPAS			
			PMEG2020EPK		
	PMEG3020EPA	PMEG3020EPAS			
	PMEG4020EPA	PMEG4020EPAS			
			PMEG4020EPK		
	PMEG6020EPA	PMEG6020EPAS			

Medium power low VF schottky rectifiers single >= 200 mA

types in **bold** represent new products

I_F max (A)	V^R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Package	CFP15 (SOT1289)	CFP5 (SOD128)	CFP3 (SOD123W)
							
				Size (mm)	5.8 x 4.3 x 0.78	3.8 x 2.5 x 1.0	2.6 x 1.7 x 1.0
				P_{tot} (mW) @ 1 cm²	2150	1050	950
				Optimization			
1	20	340	1	Low V_F			PMEG2010ER
		450	0.05	Low I_R			PMEG2010BER
	30	360	1.5	Low V_F		PMEG3010EP	PMEG3010ER
		450	0.05	Low I_R		PMEG3010BEP	PMEG3010BER
	40	490	0.05	Low V_F		PMEG4010EP	PMEG4010ER
				Low V_F		PMEG4010ETP	PMEG4010ETR
		505	0.01	Low V_F/Low I_R			**PMEG40T10ER**
	60	530	0.06	Low V_F		PMEG6010EP	PMEG6010ER
				Low V_F			PMEG6010ETR
		660	0.0003	Low I_R			PMEG6010ELR
	100	770	0.00015	Low I_R			PMEG10010ELR
2	30	360	3	Low V_F		PMEG3020EP	
		420	1.5	Low V_F		PMEG3020CEP	PMEG3020ER
		450	0.1	Low I_R		PMEG3020BEP	
		520	0.05	Low I_R		PMEG3020DEP	PMEG3020BER
	40	490	0.1	Low V_F		PMEG4020EP	PMEG4020ER
				Low V_F		PMEG4020ETP	PMEG4020ETR
		535	0.014	Low V_F/Low I_R		**PMEG40T20EP**	**PMEG40T20ER**
	60	530	0.2	Low V_F		PMEG6020EP	PMEG6020ER
				Low V_F		PMEG6020ETP	PMEG6020ETR
		680	0.0007	Low I_R		PMEG6020AELP	PMEG6020AELR
		760	0.0003	Low I_R			PMEG6020ELR
	100	770	0.0003	Low I_R		PMEG10020AELP	PMEG10020AELR
		830	0.00015	Low I_R			PMEG10020ELR
3	30	360	5	Low V_F		PMEG3030EP	
		450	0.15	Low I_R	**PMEG030V030EPD**	PMEG3030BEP	
	40	490	0.12	Low V_F	**PMEG040V030EPD**		
			0.2	Low V_F		PMEG4030EP	
				Low V_F		PMEG4030ETP	
		535	0.02	Low V_F/Low I_R		**PMEG40T30EP**	**PMEG40T30ER**
		540	0.1	Low I_R			PMEG4030ER
	45	495	0.036	Low V_F/Low I_R	**PMEG045T030EPD**		
	50	530	0.1	Low V_F	**PMEG050V030EPD**		
	60	475	0.4	Low V_F		PMEG6030EVP	
		530	0.2	Low V_F	**PMEG060V030EPD**	PMEG6030EP	
				Low V_F		PMEG6030ETP	
		690	0.001	Low I_R		PMEG6030ELP	
	100	770	0.00045	Low I_R		PMEG10030ELP	
4.5	60	530	0.4	Low V_F		PMEG6045ETP	
5	30	360	8	Low V_F		PMEG3050EP	
		450	0.25	Low I_R		PMEG3050BEP	
		500	0.15	Low V_F	**PMEG030V050EPD**		
	40	490	0.3	Low V_F		PMEG4050EP	
			0.3	Low V_F		PMEG4050ETP	
		520	0.12	Low V_F	**PMEG040V050EPD**		
		545	0.032	Low V_F/Low I_R		**PMEG40T50EP**	
	45	490	0.3	Low V_F	PMEG045V050EPD		
		545	0.036	Low V_F/Low I_R	**PMEG045T050EPD**		
	60	560	0.4	Low V_F	PMEG060V050EPD		
6	100	840	0.00045	low leakage	**PMEG100V060ELPD**		
8	100	850	0.0005	low leakage	**PMEG100V080ELPD**		
10	45	490	0.6	Low V_F	PMEG045V1000EPD		
				Low V_F	PMEG45U10EPD		
		540	0.5	Low I_R	PMEG45A10EPD		
		565	0.061	Low V_F/Low I_R	**PMEG045T100EPD**		
	60	560	0.7	Low V_F	PMEG060V100EPD		
	100	850	0.0008	low leakage	**PMEG100V100ELPD**		
15	45	490	1	Low V_F	PMEG045V150EPD		
		550	0.1	Low V_F/Low I_R	PMEG045T150EPD		
		580		Low V_F/Low I_R	PMEG45T15EPD		
		590	76	Low V_F/Low I_R	**PMEG045T150EIPD**		
	50	500	1	Low V_F	PMEG050V150EPD		
		550	0.1	Low I_R	PMEG050T150EPD		

Medium power low VF schottky rectifiers single >= 200 mA - leaded packages

types in **bold** represent new products

I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Package	SOT457 (SC-74)	SOT23	SOD123	SOD123F	SOT323 (SC-70)	SOD323F (SC-90)	SOD323 (SC-76)	SOT666	SOD523 (SC-79)
				Size (mm)	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.7 x 1.6 x 1.2	2.6 x 1.6 x 1.1	2.0 x 1.25 x 0.95	1.7 x 1.25 x 0.7	1.7 x 1.25 x 0.95	1.6 x 1.2 x 0.55	1.2 x 0.8 x 0.6
				P_{tot} (mW) @ 1 cm²	540	420	660	830	400	830	570	570	500
				Optimization									
0.2	30	480	0.05	low V_F						PMEG3002EJ			PMEG3002AEB
	40	600	0.01	low I_R						PMEG4002EJ			PMEG4002EB
	60	600	0.1	low V_F						PMEG6002EJ			PMEG6002EB
0.5	20	390	0.2	low V_F		PMEG2005ET	**PMEG2005EGW**	PMEG2005EH		PMEG2005EJ	PMEG2005AEA	PMEG2005AEV	
		480	0.03	low I_R									PMEG2005EB
	30	430	0.15	low V_F		PMEG3005ET	**PMEG3005EGW**	PMEG3005EH		PMEG3005EJ	PMEG3005AEA	PMEG3005AEV	
		500	0.5	low V_F									PMEG3005EB
	40	470	0.1	low V_F		PMEG4005ET	**PMEG4005EGW**	PMEG4005EH		PMEG4005EJ	PMEG4005AEA	PMEG4005AEV	
		550	1.1	low V_F		BAT720			1PS70SB20				
		640	0.008	low I_R						**PMEG4005CEJ**	**PMEG4005CEA**		
0.75	40	740	0.008	low I_R							**BAT165A**		
1	20	430	0.2	low V_F		PMEG2010AET		PMEG2010AEH					
		500	0.2	low V_F		PMEG2010ET		PMEG2010EH		PMEG2010EJ	PMEG2010BEA	PMEG2010BEV	
		550	0.07	low I_R						PMEG2010AEJ	PMEG2010EA BAT760	PMEG2010EV BAT960	
		620	1.5	low V_F									PMEG2010AEB
	30	450	1	low V_F	1PS74SB23								
		520	0.1	low I_R				PMEG3010CEH		PMEG3010CEJ			
		560	0.15	low V_F		PMEG3010ET	**PMEG3010EGW**	PMEG3010EH		PMEG3010EJ	PMEG3010BEA	PMEG3010BEV	
		680	0.5	low V_F									PMEG3010EB
	40	570	0.05	low I_R			**PMEG4010CEGW**	PMEG4010CEH		PMEG4010CEJ			
		640	0.05	low V_F		PMEG4010ET	**PMEG4010EGW**	PMEG4010EH		PMEG4010EJ	PMEG4010BEA	PMEG4010BEV	
		840	0.008	low I_R							**PMEG4010CEA**		
	60	660	0.05	low I_R			**PMEG6010CEGW**	PMEG6010CEH		PMEG6010CEJ			
1.5	20	660	0.2	low I_R				PMEG2015EH		PMEG2015EJ	PMEG2015EA	PMEG2015EV	
	30	500	1	low V_F				PMEG3015EH		PMEG3015EJ		PMEG3015EV	
2	10	460	3	low V_F				PMEG1020EH		PMEG1020EJ	PMEG1020EA	PMEG1020EV	
	20	525	0.2	low V_F				PMEG2020EH		PMEG2020EJ	PMEG2020AEA		
	30	620	1	low V_F			**PMEG3020EGW**	PMEG3020EH		PMEG3020EJ			
3	10	530	3	low V_F				PMEG1030EH		PMEG1030EJ			

Medium power low VF schottky rectifiers dual >= 200 mA

I_F max (A)	V_R max (V)	V_F max (mV) @ I_F max	I_R max (mA) @ V_R max	Optimization	Package	SOT223 (SC-73)	SOT23	DFN2020-3 (SOT1061)	DFN2020D-3 (SOT1061D)	SOT666
										
					Size (mm)	6.5 x 3.5 x 1.65	2.9 x 1.3 x 1.0	2.0 x 2.0 x 0.62	2.0 x 2.0 x 0.63	1.6 x 1.2 x 0.55
					P_{tot} (mW) @ 1 cm²	1500	400	1000	1000	400
0.2	30	480	0.03	low V_F						PMEG3002TV
	60	600	0.1	low V_F						PMEG6002TV
0.5	20	390	0.2	low V_F			PMEG2005CT			
	30	430	0.15	low V_F			PMEG3005CT			
	40	470	0.1	low V_F			PMEG4005CT			
1.0	25	450	1.0	low V_F		BAT120S				
				low V_F		BAT120C				
				low V_F		BAT120A				
	40	500	0.05	low V_F				PMEG4010CPA	PMEG4010CPAS	
	60	540	0.06	low V_F				PMEG6010CPA	PMEG6010CPAS	
		650	0.35	low V_F		BAT160S				
				low V_F		BAT160C				
				low V_F		BAT160A				
2.0	20	420	1.0	low V_F				PMEG2020CPA	PMEG2020CPAS	
	30	440	2.0	low V_F				PMEG3020CPA	PMEG3020CPAS	

Nomenclature of low V_F (MEGA) schottky rectifiers

PMEG 40 10 A E T P

NEXPERIA MEGA
Schottky rectifier

Max. reverse voltage in V
e.g. 40 = 40 V

Cont. forward current in A
e.g. 10 = 1.0 A

Variant number (optional)

Variant letter (optional):
T = high temperature

Internal configuration:

A =	CA
B =	CC
E =	single
P =	double, parallel
R =	tripple, antiparallel
S =	series
V =	tripple
W =	CA and CC
X =	2 x series
Y =	2 x CC
Z =	2 x CA

Package indicator:

A	SOD323
B	SOD523
D	SOT457
GW	SOD123
H	SOD123F
L	SOD882
LD	SOD882D
ML	SOD923
P	SOD128
PA	SOT1061
PD	SOT1289
PK	SOD1608
R	SOD123W
T	SOT23
V	SOT666

Nomenclature of schottky rectifiers in SOT1289, AEC-Q101 qualified

PMEG 100 V 080 E L PD

NEXPERIA MEGA
Schottky rectifier

Max. reverse voltage in V
e.g. 100 = 100 V

Variant letter (design)
V = planar design
T = trench design

Cont. forward current in A
e.g. 080 = 8.0 A

Package indicator:
PD = SOT1289

Variant letter (optional):
L = low leakage current

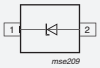
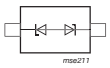
International configuration:
E = single die

3

ESD protection, TVS, filtering and signal conditioning

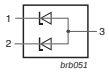
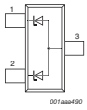
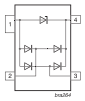
Low capacitance ESD protection for high-speed interfaces

types in **bold** represent new products

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	ESD rating max (kV) [1]	I_R max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional									
1	0	5	0.45	0.5	20			**PESD5V0C1USF**	DSN0603-2 (SOD962) 	0.6 x 0.3 x 0.3
		5	0.6	0.75	10			PESD5V0F1USF		
		5	0.95	1.15	8			PESD5V0X1ULD	DFN1006D-2 (SOD882D) 	1.0 x 0.6 x 0.37
			1.55	1.75	15			PESD5V0X1UALD		
		16	0.83	0.98	8			PESD16VX1UL	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.48
		5	0.95	1.15	8			PESD5V0X1UB	SOD523 (SC-79) 	1.2 x 0.8 x 0.6
			1.55	1.75	15			PESD5V0X1UAB		
		3.3	0.6	1.5	30	2		**PESD3V3U1UT**	SOT23 	2.9 x 1.3 x 1.0
		5	0.6	1.5	30	1		**PESD5V0U1UT**		
		12	0.6	1.5	30	0.05		**PESD12VU1UT**		
		15	0.6	1.5	30	0.05		**PESD15VU1UT**		
		24	0.6	1.5	23	0.05		**PESD24VU1UT**		
0	1	5	0.2	0.3	8			**PESD5V0F1BSH**	DSN0402-2 (SOD992) 	0.4 x 0.2 x 0.12
		3.3	0.2	0.25	20			**PESD3V3C1BSF**	DSN0603-2 (SOD962)	0.6 x 0.3 x 0.3
			0.28	0.35	20			**PESD3V3Z1BSF**		
		5	0.1	0.15	10			**PESD5V0R1BSF**		
			0.15	0.19	15			**PESD5V0H1BSF**		
			0.2	0.25	20			**PESD5V0C1BSF**		
		5	0.45	0.5	20			**PESD5V0C1USF** 		
		5.5	0.25	0.3	10			PESD5V0F1BSF		
								PESD5V0F1BRSF		
		3.3	–	1.1	20			**PESD3V3X1BCSF**		
		5.0	–	1.1				**PESD5V0X1BCSF**		
		18	0.28	0.45	10			**PESD18VF1BSF**		
		24	0.25	0.4				**PESD24VF1BSF**		
		5	0.4	0.55	10			PESD5V0F1BLD	DFN1006D-2 (SOD882D) 	1.0 x 0.6 x 0.37
								PESD5V0F1BRLD		
		3.3	1.3	1.6	9			PESD3V3X1BL	DFN1006-2 (SOD882)	1.0 x 0.6 x 0.48
		5.5	0.4	0.55	10			PESD5V0F1BL		
		5	0.49	0.6	8			PESD5V0X1BCL		
			0.85	0.95	15			PESD5V0X1BCAL		
			0.9	1.3	9			PESD5V0X1BL		
		18	0.35	0.5	10			PESD18VF1BL		
		24	0.3	0.45	10			PESD24VF1BL		

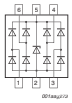
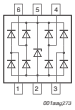
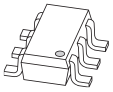
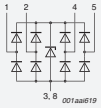
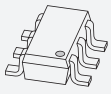
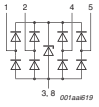
[1] according to IEC 61000-4-2 (contact discharge)

Low capacitance ESD protection for high-speed interfaces

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	ESD rating max (kV) [1]	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional								
2	1	5	0.5	0.65	10		PESD5V0X2UMB	DFN1006B-3 (SOT883B) 	1.0 x 0.6 x 0.37
							PESD5V0X2UM	DFN1006-3 (SOT883) 	1.0 x 0.6 x 0.48
			0.8	0.95	15		PESD5V0X2UAMB	DFN1006B-3 (SOT883B) 	1.0 x 0.6 x 0.37
							PESD5V0X2UAM	DFN1006-3 (SOT883) 	1.0 x 0.6 x 0.48
			0.9	1.3	9		PESD5V0X1BQ	SOT663 	1.6 x 1.2 x 0.55
							PESD5V0X1BT	SOT23 	2.9 x 1.3 x 1.0
	0	80	0.6	0.75	30		NUP1301U	SOT323 	2.0 x 1.25 x 0.95
							NUP1301	SOT23 	2.9 x 1.3 x 1.0
3	0	5.5	1	1.5	8		PRTR5V0U2X	SOT143B 	2.9 x 1.3 x 1.0
			1.8	-	12		PRTR5V0U2AX		
			1	1.5	8		PRTR5V0U2F	DFN1410-6 (SOT886) 	1.45 x 1.0 x 0.48

[1] according to IEC 61000-4-5 (contact discharge)

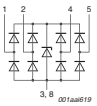
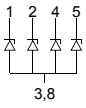
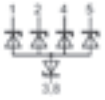
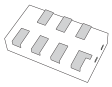
Low capacitance ESD protection for high-speed interfaces

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	ESD rating max (kV) [1]	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional								
4	0	5.5	1	-	8		IP4220CZ6	DFN1410-6 (SOT886) 	1.45 x 1.0 x 0.48
							IP4221CZ6-S	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
							PRTR5V0U4D	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
			0.7	0.85	12		PUSB2X4D	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
							PUSB2X4Y	SOT363 (SC-88) 	2.0 x 1.25 x 0.95
			0.6	-	8		IP4283CZ10-TBR	DFN2510A-10 (SOT1176) 	2.5 x 1.0 x 0.48

[1] according to IEC 61000-4-5 (contact discharge)

Low capacitance ESD protection for high-speed interfaces

types in **bold** represent new products

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	ESD rating [1] max (kV)	I_R max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional									
4	0	5.5	0.5	-	10	-		IP4294CZ10-TBR	DFN2510A-10 (SOT1176)	2.5 x 1.0 x 0.48
								PUSB3F96		
		3.3	0.27	-	15	0.1		**PUSB3FR4**		
0	4	3.3	0.17	0.2				**PUSB3AB4**		
6	0	3.3	0.25	-	15	-		**PUSB3FR6**	DFN2111-7 (SOT1358)	2.1 x 1.1 x 0.48
0	6	5.5	0.27	0.35	10	0.1		PUSB3TB6		
		3.3	0.15	0.2	15			**PUSB3AB6**		

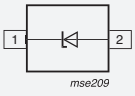
[1] according to IEC 61000-4-2 (contact discharge)

TrEOS protection devices

Unique combination of low capacitance, low clamping and high robustness for very fast, sensitive data lines

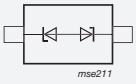
Type	device	V_{RWM} (V)	Uni- or bidirectional	C_d typ (pF)	ESD rating max (kV) (Ω)	R_{dyn} TLP (Ω)	Number of protected lines	Package	Size (mm)
PUSB3FR4	ESD protection	3.3	uni	0.29	15	0.27	4	DFN2510A-10	2.5 x 1.0 x 0.48
PUSB3FR6				0.35	15	0.29	6	DFN2111-7	2.1 x 1.1 x 0.48
PUSB3AB4			bi	0.17	15	0.4	4	DFN2510A-10	2.5 x 1.0 x 0.48
PUSB3AB6				0.15	15	0.4	6	DFN2111-7	2.1 x 1.1 x 0.48
PCMF1USB3S	Common Mode Filter with ESD protection	5	uni	0.3	15	0.14	2	WLCSP5	0.8 x 1.2 x 0.5
PCMF2USB3S							4	WLCSP10	1.6 x 1.2 x 0.5
PCMF3USB3S							6	WLCSP15	2.4 x 1.2 x 0.5
PESD3V3Z1BSF	ESD protection	3.3	bi	0.28	20	0.19	1	DSN0603-2	0.6 x 0.3 x 0.3
PESD3V3C1BSF				0.2	20	0.23			
PESD5V0R1BSF		5		0.1	10	0.45			
PESD5V0H1BSF				0.15	15	0.25			
PESD5V0C1BSF				0.2	20	0.23			
PESD5V0C1USF			uni	0.45	20	0.1			

General purpose ESD protection devices LP

Number of protected lines											
Unidirectional	Bidirectional	V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	P_{PP} max (W) [1]	ESD rating max (kV) [2]	I_R max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
1	0	5	35	42	40	30	0.1		PESD5V0S1USF	DSN0603-2 (SOD962) 	0.6 x 0.3 x 0.3
		5.5	12	15.4	10	30	0.1		PESD5V0L1USF		
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UL	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.5
			34	40	45	30	0.3		PESD3V3L1UL		
			207	300	150	30	2		PESD3V3S1UL		
		5	2	2.6	-	9	0.1		PESD5V0U1UL		
			25	30	42	26	0.1		PESD5V0L1UL		
		5	152	200	150	30	1		PESD5V0S1UL		
		12	38	75	150	30	0.05		PESD12VS1UL		
		15	32	70	150	30	0.05		PESD15VS1UL		
		24	23	50	150	23	0.05		PESD24VS1UL		
		36	18	30	150	30	0.01		PESD36VS1UL		
		5	25	30	42	26	0.1		PESD5V0L1ULD	DFN1006D-2 (SOD882D) 	1.0 x 0.6 x 0.4
			152	200	150	30	1		PESD5V0S1ULD		
		12	38	75	150	30	0.05		PESD12VS1ULD		
		15	32	70	150	30	0.05		PESD15VS1ULD		
		24	23	50	150	23	0.05		PESD24VS1ULD		
		2.5	229	300	260	30	6		PESD5Z2.5	SOD523 (SC-79) 	1.2 x 0.8 x 0.6
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UB		
			34	40	45	30	0.3		PESD3V3L1UB		
			172	200	260	30	0.05		PESD5Z3.3		
			207	300	330	30	2		PESD3V3S1UB		
		5	2	2.6	-	9	0.1		PESD5V0U1UB		
			25	30	42	26	0.1		PESD5V0L1UB		
			89	150	180	30	0.05		PESD5Z5.0		
			152	200	260	30	1		PESD5V0S1UB		
		6	78	150	180	30	0.01		PESD5Z6.0		
		7	69	150	180	30	0.01		PESD5Z7.0		
		12	35	75	200	30	0.01		PESD5Z12		
			38	75	180	30	0.05		PESD12VS1UB		
		15	32	70	160	30	0.05		PESD15VS1UB		
		24	23	50	160	23	0.05		PESD24VS1UB		
		3.3	2.6	3.1	-	9	0.1 (@ 3 V)		PESD3V3U1UA	SOD323 (SC-76) 	1.7 x 1.25 x 0.95
		5	2	2.6	-	9	0.1		PESD5V0U1UA		
			25	30	42	26	0.1		PESD5V0L1UA		
			480	530	890	30	4		PESD5V0S1UA		
		12	160	180	600	30	0.1		PESD12VS1UA		
		24	23	50	160	23	0.05		PESD24VS1UA		
		5	480	530	890	30	4		PESD5V0S1UJ	SOD323F (SC-90) 	1.7 x 1.25 x 0.7
		12	160	180	600	30	0.1		PESD12VS1UJ		

[1] 8 / 20 µs exponential decay waveform according to IEC 61000-4-5 [2] according to IEC 61000-4-5 (contact discharge)

General purpose ESD protection devices

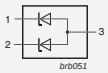
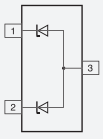
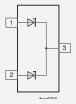
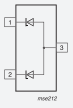
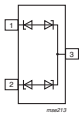
Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	P_{PP} max (W) [1]	ESD rating max (kV) [2]	I_R max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional										
		3.3	5.5	6	-	20	0.1		PESD3V3U1BCSF	DSN0603-2 (SOD962)	0.6 x 0.3 x 0.3
			8.5	10	-	30	0.1		PESD3V3V1BCSF		
		5.5	5.3	6	5.5	20	0.1		PESD5V0V1BCSF		
					20	20	0.1		PESD5V0V1BDSF		
				4.5	8	15	0.1		PESD5V0V1BSF		
					290	15	0.01		PESD12VV1BL		
			12	15.4	35	30	0.1		PESD5V0L1BSF		
			35	45	100	30	0.1		PESD5V0S1BSF		
		3.3	101	-	500	30	2		PESD3V3L1BA	SOD323 (SC-76)	1.7 x 1.25 x 0.95
		5	75	-	500	30	1		PESD5V0L1BA		
		12	19	-	200	30	0.05		PESD12VL1BA		
		15	16	-	200	30	0.05		PESD15VL1BA		
		24	11	-	200	23	0.05		PESD24VL1BA		
0	1	5	11	13	45	30	0.01	 mse211	PESD5V0V1BL	DFN1006-2 (SOD882)	
			35	45	130	30	0.1		PESD5V0S1BL		
			60	80	-	30	0.1		PESD5V0T1BLD		
			11	13	45	30	0.01		PESD5V0V1BLD	DFN1006D-2 (SOD882D)	
			35	45	130	30	0.1		PESD5V0S1BLD		
			11	13	45	30	0.01		PESD5V0V1BB	SOD523 (SC-79)	1.2 x 0.8 x 0.6
			35	45	130	30	0.1		PESD5V0S1BB		
			11	13	45	30	0.01		PESD5V0V1BA	SOD323 (SC-76)	1.7 x 1.25 x 0.95
			35	45		30	0.1		PESD5V0S1BA		
			2.9	3.5	-	10	0.1		PESD5V0U1BL	DFN1006-2 (SOD882)	
									PESD5V0U1BLD	DFN1006D-2 (SOD882D)	
									PESD5V0U1BB	SOD523 (SC-79)	
									PESD5V0U1BA	SOD323 (SC-76)	

[1] 8 / 20 µs exponential decay waveform according to IEC 61000-4-5

[2] according to IEC 61000-4-5 (contact discharge)

General purpose ESD protection devices

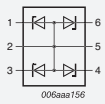
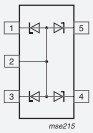
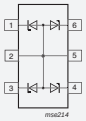
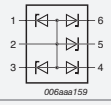
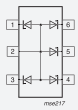
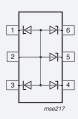
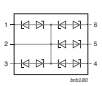
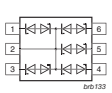
types in **bold** represent new products

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	P_{PP} max (W) [1]	ESD rating max (kV) [2]	I_R max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional										
2	1	3.3	22	28	30	15	0.3		PESD3V3L2UM	DFN1006-3 (SOT883) 	1.0 x 0.6 x 0.5
		5	16	19	30	15	0.025		PESD5V0L2UM		
					-	15	0.025		PESD5V0L2UMB	DFN1006B-3 (SOT883B) 	1 x 0.6 x 0.37
		3.3	200	275	150	30	3		PESD3V3S2UQ	SOT663 	1.6 x 1.2 x 0.55
		5	150	215	150	30	0.3		PESD5V0S2UQ		
		12	38	100	150	30	0.03		PESD12VS2UQ		
		15	32	70	150	30	0.05		PESD15VS2UQ		
		24	23	50	150	23	0.05		PESD24VS2UQ		
		3.3	207	300	330	30	2		PESD3V3S2UT	SOT23 	2.9 x 1.3 x 1
		5.2	152	200	260	30	1		PESD5V2S2UT		
		12	38	75	180	30	1		PESD12VS2UT		
		15	32	70	160	30	1		PESD15VS2UT		
		24	23	50	160	23	1		PESD24VS2UT		
		36	17	35	160	30	1 (@ 30 V)		PESD36VS2UT		
		3.3	207	300	330	30	2		PESD3V3S2UAT		
		5	152	200	260	30	1		PESD5VOS2UAT		
		15	32	70	160	30	0.05		PESD15VS2UAT		
		24	23	50	160	23	0.05		PESD24VS2UAT		
		5	38	46	70	30	0.09 (@ 4 V)		PESD5V0L2UU	SOT323 (SC-70) 	2 x 1.25 x 0.95
		6	34	40	60	30	0.018 (@ 4.3 V)		PESD6V0L2UU		
0	2	3.3	101	-	350	30	2		PESD3V3L2BT	SOT23 	2.9 x 1.3 x 1
		5	75	-		30	1		PESD5V0L2BT		
		12	19	-	200	30	0.05		PESD12VL2BT		
		15	16	-		30	0.05		PESD15VL2BT		
		24	11	-		23	0.05		PESD24VL2BT		
		5	35	45	130	30	0.1		PESD5V0S2BT		
			2.9	3.5	-	10	0.1		PESD5V0U2BT		
									PESD5V0U2BM	DFN1006-3 (SOT883) 	1.0 x 0.6 x 0.5
			18	20	110	30	0.01		**PESD5V0V2BM**		
			2.9	3.5	-	10	0.1		PESD5V0U2BMB	DFN1006B-3 (SOT883B) 	1 x 0.6 x 0.37
			18	20	110	30	0.01		**PESD5V0V2BMB**		
			35	45	130	30	0.1		**PESD5V0S2BQA**	DFN1010D-3 (SOT1215) 	1.1 x 1.0 x 0.37

[1] 8 / 20 µs exponential decay waveform according to IEC 61000-4-5

[2] according to IEC 61000-4-2 (contact discharge)

General purpose ESD protection devices

Number of protected lines		V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	P_{PP} max (W) [1]	ESD rating max (kV) [2]	I_R max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
Unidirectional	Bidirectional										
4	3	3.3	22	28	30	20	0.3		PESD3V3L4UF	DFN1410-6 (SOT886) 	1.45 x 1 x 0.5
			110	300	110	30	1 (@ 3 V)		PESD3V3S4UF		
		5	16	19	30	20	0.025		PESD5V0L4UF		
			85	220	110	30	0.1 (@ 4.3 V)		PESD5V0S4UF		
		3.3	22	28	30	20	0.3		PESD3V3L4UW	SOT665 	1.6 x 1.2 x 0.55
		5	16	19	30	20	0.025		PESD5V0L4UW		
		3.3	15	18	16	12	0.3		PESD3V3V4UW		
		5	12	15	16	12	0.025		PESD5V0V4UW		
		3	200	240	-	8	2		BZA856A	SOT353 (SC-88A) 	2 x 1.25 x 0.95
		3.3	22	28	30	20	0.3		PESD3V3L4UG		
		5	16	19	30	20	0.025		PESD5V0L4UG		
		3	200	240	-	8	2		BZA456A	SOT457 (SC-74) 	2.9 x 1.5 x 1
		3.3	215	300	200	30	0.8		PESD3V3S4UD		
		5	165	220	200	30	0.2		PESD5V0S4UD		
		15	37	48	-	8	0.1		BZA420A		
		24	40	70	200	23	0.01		PESD24VS4UD		
0	4	5	2.9	3.5	-	10	0.1		PESD5V0U4BF	DFN1410-6 (SOT886) 	1.45 x 1 x 0.5
			45	75	-	15	0.1		BZA408B	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
			2.9	3.5	-	10	0.1		PESD5V0U4BW	SOT665 	1.6 x 1.2 x 0.55
5	4	3.3	20	24	28	15	2		PESD3V3L5UK	DFN1010-6 (SOT891) 	1 x 1 x 0.5
		5	18.5	22	30	20	0.5		PESD5VOL5UK		
		3.3	22	28	25	20	0.3		PESD3V3L5UF	DFN1410-6 (SOT886) 	1.45 x 1 x 0.5
		5	16	19	25	20	0.025		PESD5V0L5UF		
		3.3	22	28	25	20	0.3		PESD3V3L5UV	SOT666 	1.6 x 1.2 x 0.55
		5	16	19	25	20	0.025		PESD5V0L5UV		
		3.3	22	28	25	20	0.3		PESD3V3L5UY	SOT363 (SC-88) 	2 x 1.25 x 0.95
		5	16	19	25	20	0.025		PESD5V0L5UY		
		3.3	215	300	200	30	0.8		PESD3V3S5UD	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
		5	165	220	200	30	0.2		PESD5V0S5UD		
		12	73	100	200	30	0.015		PESD12VS5UD		
		15	60	90	200	30	0.015		PESD15VS5UD		
		24	45	70	200	23	0.015		PESD24VS5UD		
0	5	5	2.9	3.5	-	10	0.1		PESD5V0U5BF	DFN1410-6 (SOT886) 	1.45 x 1 x 0.5
									PESD5V0U5BV	SOT666 	1.6 x 1.2 x 0.55

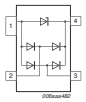
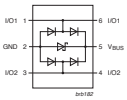
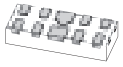
[1] 8 / 20 µs exponential decay waveform according to IEC 61000-4-5 [2] according to IEC 61000-4-5 (contact discharge)

Audio interface protection

Lines	V_{RWM}(V)	V_{BR} min (V)	V_{BR} max (V)	C_D typ (pF)	C_D max (pF)	I_{PPM} 8/20µs (A)	V_{CL} 8/20µs @ I_{ppm} (V)	V_{ESD} (hV)	Configuration	Type	Package
1	4.5	4.7 V		65	85	30	15	30	mse211 	**PTVS4V5D1BLD**	DFN1006D-2 (SOD882D) 
	5	5.5	9.5	70	90	28	11.5	30	brb178 	PESD5V0S2BQA	DFN1010D-3 (SOT1215) 
				60	80	22.5	14	30	mse211 	**PESD5V0T1BLD**	DFN1006D-2 (SOD882D) 
				35	45	12	14	30	mse211 	PESD5V0S1BL	DFN1006-2 (SOD882) 
				35	45	12	14	30	mse211 	PESD5V0S1BLD	DFN1006D-2 (SOD882D) 
		5.8	7.8	11	13	4.8	12.5	30	mse211 	PESD5V0V1BL	DFN1006-2 (SOD882) 
				11	13	4.8	12.5	30	mse211 	PESD5V0V1BLD	DFN1006D-2 (SOD882D) 
	12	14.6	16.8	17	25	7.8	38	30	mse211 	PESD12VV1BL	DFN1006-2 (SOD882) 
2	5	5.8	7.8	18	20	9	12.5	30	mse 213 	PESD5V0V2BM	DFN1006-3 (SOT883) 
				18	20	9	12.5	30	mse 213 	PESD5V0V2BMB	DFN1006B-3 (SOT883B) 

Automotive high-speed network protection

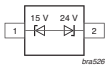
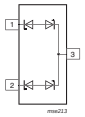
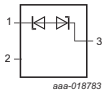
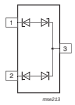
types in **bold** represent new products

Number of protected lines	V_{RWM} (V)	C_{line} typ (pF)	I_{RM} max (µA)	ESD rating max (kV) [1]	Configuration	Type	Package	Size (mm)
2	5 V	1	0.1	8		**PESD2ETH-X**	SOT143B 	2.9 x 1.3 x 1.0
		1.8	0.1	12		**PESD2ETH-AX**		
2	5 V	1	0.1	8		**PESD2ETH-D**	SOT457 	2.9 x 1.5 x 1.0
		1.8	0.1	12		**PESD2ETH-AD**		
4	5.5	0.6	1 @ 3 V	8		PESD1LVDS	DFN2510-10 (SOT1165) 	2.5 x 1.0 x 0.48
		0.6	1 @ 3 V	8		PRTR5V0U4D	SOT457 	2.9 x 1.5 x 1.0

(1) according to IEC 61000-4-2 (contact discharge)

Automotive in-vehicle network bus line protection

types in **bold** represent new products

Number of protected lines bidirectional	V_{RWM} (V)	C_{line} typ (pF)	C_{line} max (pF)	P_{PP} max (W) [1]	ESD rating max (kV) [2]	I_r max [µA] @ V_{RWM}	Configuration	Type	Package	Size (mm)
1	15 (diode 1) 24 (diode 2)	13	17	160	23	0.05		PESD1LIN	SOD323 (SC-76) 	1.7 x 1.25 x 0.95
2	24	11	17	200	23	0.05		PESD1CAN	SOT23 	2.9 x 1.3 x 1.0
		25	30	230	30	0.01		PESD2CAN		
		11	17	200	23	0.05		PESD1FLEX		
		9.3	12	150	23	0.05		PESD1CAN-U	SOT323 	2.0 x 1.25 x 0.95
1	26.5	9.3	11	150	23	0.05		**PESD1IVN-U**	SOT323 	2.0 x 1.25 x 0.95
2								**PESD2IVN-U**		

[1] 8 / 20 µs surge pulse according to IEC 61000-4-5

[2] according to IEC 61000-4-2 (contact discharge)

Battery and charger port protection

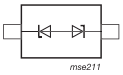
Number of protected lines	C_{line} (pF)	V_{RWM} (V)	I_{PPM} 8/20µs (A)	Type	Package	Size (mm)
1 x uni	160	12	22.5	PESD12VS1UJ	SOD323F (SC-90) 	1.7 x 1.25 x 0.7
	480	5	22.5	PESD5V0S1UJ		
	160	12	47	PESD12VS1UA	SOD323 (SC-76) 	1.7 x 1.25 x 0.95
	480	5	47	PESD5V0S1UA		
2 x bi	18	5	9	PESD5V0V2BM	DFN1006-3 (SOT883) 	1.0 x 0.6 x 0.48
	18	5	9	PESD5V0V2BMB	DFN1006-3 (SOT883) 	1.0 x 0.6 x 0.37
	35	5	15	PESD5V0S2BQA	DFN1010D-3 (SOT1215) 	1.1 x 1.0 x 0.37

HDMI and display port protection

types in **bold** represent new products

Interface	Number of protected lines	C_{line} (pF)	Remark	Type	Package	Size (mm)
Display port	4	0.6	ESD protection for ultra high-speed interfaces	IP4283CZ10-TBR	DFN2510A-10 (SOT1176) 	2.5 x 1.0 x 0.48
		0.55	ESD protection for ultra high-speed interfaces	IP4292CZ10-TBR		
		0.5	ESD protection for ultra high-speed interfaces	IP4294CZ10-TBR		
			ESD protection for ultra high-speed interfaces	PHDMI2F4		
HDMI	4	0.6	ESD protection for ultra high-speed interfaces	IP4283CZ10-TBR	DFN2510A-10 (SOT1176) 	2.5 x 1.0 x 0.48
		0.55	ESD protection for ultra high-speed interfaces	IP4292CZ10-TBR	DFN2510A-10 (SOT1176) 	2.5 x 1.0 x 0.48
		0.5	ESD protection for HDMI 2.0	PHDMI2F4		
			ESD protection for ultra high-speed interfaces	IP4294CZ10-TBR		
		0.27	ESD protection for ultra high-speed interfaces	**PUSB3FR4**	DFN2510A-10 (SOT1176) 	2.5 x 1.0 x 0.48
LVDS	4	0.8	Very low clamp ESD protection with 12 kV IEC rug-gedness	PUSB2X4D	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
		0.8	Very low clamp ESD protection with 12 kV IEC rug-gedness	PUSB2X4Y	SOT363 (SC-88) 	2.0 x 1.25 x 0.95

Antenna protection (NFC, WiFi,…)

Number of protected lines (Bidirectional)	V_{RWM} [V]	C_{line} typ [pF]	C_{line} max [pF]	ESD rating [1] max [kV]	Configuration	Type	Package	Size
1	18	0.28	0.45	10		PESD18VF1BSF	DSN0603-2 (SOD962) 	0.6 x 0.3 x 0.3
						PESD1NFC-SF		
		0.35	0.5	10		PESD18VF1BL	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.48
						PESD1NFC-L		
	24	0.25	0.4	10		PESD24VF1BSF	DSN0603-2 (SOD962) 	0.6 x 0.3 x 0.3
						PESD2NFC-SF		
		0.3	0.45	10		PESD24VF1BL	DFN1006-2 (SOD882) 	1.0 x 0.6 x 0.48
						PESD2NFC-L		

[1] according to IEC 61000-4-2 (contact discharge)

USB and SATA protection

Interface	Number of protected lines	R_{line}	C_{line} (pF)	Remark	Type	Package	Size (mm)
USB2.0 (Plastic package)	2	-	1.0	ESD protection for up to 2 ultra high-speed datalines	PRTR5V0U2X	SOT143B 	2.9 x 1.3 x 1.0
			1.8	ESD protection for up to 2 ultra high-speed datalines with 12 kV ESD robustness	PRTR5V0U2AX		
				ESD protection for up to 2 ultra high-speed datalines	PRTR5V0U2F	DFN1410-6 (SOT886) 	1.45 x 1.0 x 0.48
	3 + 1			USB protection for USB OTG with 5.5 V Vbat protection	PUSBM5V5X4-TL	DFN1616-6 (SOT1189) 	1.6 x 1.6 x 0.48
				USB protection for USB OTG with 12 V Vbat protection	PUSBM12VX4-TL		
				USB protection for USB OTG with 30 V Vbat protection	PUSBM30VX4-TL		
	4		0.8	Very low clamp ESD protection for USB2.0 high-speed with 12 kV IEC ESD protection	PUSB2X4Y	SOT363 (SC-88) 	2.0 x 1.25 x 0.95
			1	Very low clamp ESD protection for USB2.0 high-speed with 12 kV IEC ESD protection	PUSB2X4D	SOT457 (SC-74) 	2.9 x 1.5 x 1.0
				Dual ESD protection for USB2.0 high-speed, SD-card, SIM card	IP4220CZ6		
				Dual ESD protection for USB2.0 high-speed, SD-card, SIM card	PRTR5V0U4D		
				ESD protection for USB2.0 high-speed, SD-card, SIM card	IP4221CZ6-S	DFN1410-6 (SOT886) 	1.45 x 1.0 x 0.48

Common mode filter for USB 2.0

types in **bold** represent new products

Interface	Number of protected lines	C_{line} (pF)	ESD rating max (kV) [1]	Remark	Type	Package	Size (mm)
USB2.0	2	1.5	15	Common Mode filter with ESD protection for high-speed interfaces such as USB 2.0	**IP3319CX6**	WLCSP6 	1.34 x 0.95 x 0.57

[1] according to IEC 61000-4-2 (contact discharge)

Common mode filter for USB 3.x

types in **bold** represent new products

Interface	Number of protected line pairs	Type	Differential Mode 3dB frequency	Common Mode rejection 800 MHz - 10 GHz	C_d typical	V_{RWM}	ESD rating	Channel series resistance	Package	Size (mm)
USB3.x	1	**PCMF1USB3S**	6 GHz	>12	0.3	5	15	3	WLCSP5 	0.8 x 1.2 x 0.5
	2	**PCMF2USB3S**							WLCSP10 	1.6 x 1.2 x 0.5
	3	**PCMF3USB3S**							WLCSP15 	2.4 x 1.2 x 0.5
	1	**PESD1USB3S**	17 GHz	ESD protection only	0.5				WLCSP5 	0.8 x 1.2 x 0.5
	2	**PESD2USB3S**							WLCSP10 	1.6 x 1.2 x 0.5
	3	**PESD3USB3S**							WLCSP15 	2.4 x 1.2 x 0.5

[1] according to IEC 61000-4-2 (contact discharge)

Common mode filter for HDMI and MIPI

types in **bold** represent new products

Interface	Number of protected line pairs unidirectional	Number of protected line pairs bidirectional	Type	Differential Mode 3 dB frequency (typ.)	C_d pF typical	V_{rwm}	ESD rating [1] max (kV)	Channel series resistance	Package	Size (mm)
HDMI2.0	1	0	**PCMF1HDMI2S**	>6 GHz	0.3	5	15	3 Ω	WLCSP5 	0.8 x 1.2 x 0.5
	2		**PCMF2HDMI2S**						WLCSP10 	1.6 x 1.2 x 0.5
	3		**PCMF3HDMI2S**						WLCSP15 	2.4 x 1.2 x 0.5

[1] according to IEC 61000-4-2 (contact discharge)

HDMI signal conditioning

Interface	Number of protected lines	Buffer	Level shifer	C_{line} (pF)	Resistor (Ω)	LDO	Remark	Type	Package	Size (mm)
HDMI2.0 Tx	13			100 Ω differential impedance		CEC LDO. 5 V LDO	Fully integrated HDMI source solution with current limiter, buffer, and level shifter for DDC, CEC, and Hot Plug	IP4786CZ32	DFN5050-32 (SOT617) 	5.0 x 5.0 x 0.85
							Fully integrated HDMI sink solution with buffer, and level shifter for DDC, CEC, and Hot Plug			
							Fully integrated HDMI source solution with enhanced ESD protection, current limiter, buffer, and level shifter for DDC, CEC, and Hot Plug			
							Fully integrated HDMI source solution with small package, current limiter, buffer, and level shifter for DDC, CEC, and Hot Plug	IP4786CZ32S	DFN4040-32 (SOT1318-1) 	4.0 x 4.0 x 0.50
HDMI2.0 Tx	13	yes	yes	100 Ω differential impedance	integrated	-	Fully integrated HDMI source solution with current limiter, buffer, and level shifter for DDC, CEC, and Hot Plug	IP4786CZ32	DFN5050-32 (SOT617) 	5.0 x 5.0 x 0.85
							Fully integrated HDMI source solution with enhanced ESD protection, current limiter, buffer, and level shifter for DDC, CEC, and Hot Plug	IP4788CZ32		
HDMI2.0 Rx							Fully integrated HDMI source solution with current limiter, buffer, and level shifter for DDC, CEC, and Hot Plug	IP4787CZ32		
SD3.0	6	yes	yes	-	internal	-	SD 3.0-compliant memory card with integrated dual voltage- level translator with EMI filter and ESD protection	IP4856CX25/C	WLCSP25 	2.4 x 2.4 x 0.4
						1.8 V LDO	Fully integrated SD 3.0 card level shifter with buffer technology, LDO, and EMI filter	IP4855CX25	WLCSP25 	

LCD and camera RC filter with integrated protection

Number of protected lines	Line small-signal equivalents			Digital interface clock speed (MHz)	Insertion loss S21 ~ -3 dB (MHz)	Type	Package	Size (mm)
	R_{line} (Ω)	C_{line} (pF)	L_{line} (nH)					
4	40	18	-	~100	300	IP4252CZ8-4 -TTL	DFN1714-8 (SOT1166) 	1.7 x 1.35 x 0.52
	100	45	-	~40	130	IP4254CZ8-4-TTL		
8	40	18	-	~100	300	IP4252CZ16-8-TTL	DFN3314-16 (SOT1168) 	3.3 x 1.35 x 0.53
	100	45	-	~40	130	IP4254CZ16-8-TTL		
		15	-	~110	330	IP4251CZ16-8-TTL		

Memory and SIM card filter with integrated protection

types in **bold** represent new products

Interface	Number of protected lines	Line small-signal equivalents		Digital interface clock speed (MHz)	Remark	Type	Package	Size (mm)
		R_{line}	C_{line} (pF)					
SIM card	3	47 Ω / 100 Ω	20	~20	Integrated SIM-card EMI filter and ESD protection	IP4264CZ8-20-TTL	DFN1714-8 (SOT1166) 	1.7 x 1.35 x 0.52
	4	-	1	~240	Quad-channel, low-capacitance ESD protection	IP4221CZ6-S	DFN1410-6 (SOT886) 	1.0 x 1.0 x 0.48
SD 3.0	6	-	0.27	5000	6-line bidirectional ESD protection for ultra high-speed interfaces	PUSB3TB6	DFN2111-7 (SOT1358) 	2.1 x 1.1 x 0.5
			0.35			**PUSB3FR6**		
			0.15			**PUSB3AB6**		

USB 3.x and eSATA protection and filtering for high-speed and super-speed lines

types in **bold** represent new products

Baseband interface	Number of protected lines	C_d (pF)	ESD rating max (kV)	R_{dyn} (Ω)	Remark	Type	Package	Size (mm)
USB3.0 - 5 Gbps	4	0.55	8	0.3 / 0.4	ESD Protection for high-speed interfaces	IP4292CZ10-TBR	DFN2510A-10 (SOT1176) 	2.5 x. 1.0 x 0.48
		0.5	10			IP4294CZ10-TBR		
						PUSB3F96		
USB3.1 - 10 Gbps		0.29	15	0.27		**PUSB3FR4**		
		0.17	15	0.4	TrEOS Protection	**PUSB3AB4**		
	6	0.29	15	0.27		**PUSB3FR6**	DFN2111-7 (SOT1358) 	2.1 x 1.1 x 0.48
		0.27	15	0.5		**PUSB3TB6**		
		0.15	15	0.4		**PUSB3AB6**		
	1	0.1	10	0.45		**PESD5V0R1BSF**	DSN0603-2 (SOD962) 	0.6 x 0.3 x 0.3
		0.15	15	0.25		**PESD5V0H1BSF**		
		0.2	20	0.23		**PESD5V0C1BSF**		
		0.2	20	0.23		**PESD3V3C1BSF**		
		0.45	20	0.1		**PESD5V0C1USF**		
		0.28	20	0.19		**PESD3V3Z1BSF**		
	2	0.25	15	0.16		**PESD1USB3S**	WLCSP5 	1.2 x 0.8 x 0.6
		0.25	15	0.14	Common Mode Filter with TrEOS Protection for ultra high-speed interfaces	**PCMF1USB3S**		

TVS diodes for mobile applications

types in **bold** represent new products

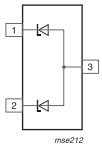
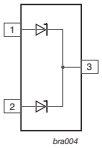
P_{PPM} 10/1000µs	V_{RWM}	V_{BR} min	V_{BR} max	I_{PPM} 8/20µs	V_{CL} 8/20µs	I_{PPM} 10/1000µs	V_{CL} 10/1000µs	Type	Package	Size
300	7.5	8.33	9.21	178	19.7	23.3	12.9	PTVS7V5U1UPA	DFN2020-3 (SOT1061) 	2.0 x 2.0 x 0.62
	10	11.1	12.3	148	23	17.6	17	PTVS10VU1UPA		
	12	13.3	14.7	131	25.2	15.1	19.9	PTVS12VU1UPA		
	15	16.7	18.5	111	28.8	12.3	24.4	PTVS15VU1UPA		
	18	20	22.1	97	32	10.3	29.2	PTVS18VU1UPA		
	20	22.2	24.5	95	35	10	32.6	**PTVS20VU1UPA**		
	22	24.4	26.9	87	37	9	36.1	**PTVS22VU1UPA**		
	24	26.7	29.5	80	40	8.1	40	**PTVS24VU1UPA**		
	26	28.9	31.9	69	43.5	7	43	PTVS26VU1UPA		

TVS diodes for mobile applications

types in **bold** represent new products

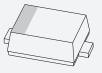
V_{RWM} (V)	V_{br} min (V)	V_{br} max (V)	8/20µs pulse		10/1000µs pulse		I_{rm} typ @ V_{rwm} (nA)	I_{rm} max @ V_{rwm} (nA)	R_{dyn} (TLP) - 8/20µs	Type	Package	Size
			V_{cl} @ I_{ppm} 8/20µs (V) max	I_{ppm} 8/20µs (A)	V_{cl} @ I_{ppm} 10/1000µs (V) max	I_{ppm} 10/1000µs (A)						
5	6.4	7.8	19,4	100	12	20	25	1000	0.1	**PTVS5V0Z1USKP**	DSN1608-2 (SOD964) 	**1.6 x 0.8 x 0.27**
			18	80	12	20	25	1000	0.06	**PTVS5V0Z1USK**		
7.5	8.33	9.65	22	100	13.5	17	1	200	0.08	**PTVS7V5Z1USK**		
10	11.1	12.9	27	75	18.2	12.5	0.1	200	0.11	**PTVS10VZ1USK**		
12	13.3	15.4	29	65	21.8	10.5	0.1	200	0.11	**PTVS12VZ1USK**		
15	16.7	19.4	36	52	27.4	7.5	0.1	200	0.13	**PTVS15VZ1USK**		
18	20	23.2	44	41	32.8	6.4	0.1	200	0.17	**PTVS18VZ1USK**		
20	22.2	25.4	48.3	41	36.9	6	1	200	0.2	**PTVS20VZ1USK**		
22	24.4	26.9	51	39	40	5	0.1	200	0.2	**PTVS22VZ1USK**		
26	28.9	33.4	57.5	32	46	4.5	0.1	200	0.15	**PTVS26VZ1USK**		

TVS diodes, 24 W/40 W (automotive)

Power (W) (10 / 1000 µs waveform) [1]	V_{RWM} (V)	V_{BR} min (V) @ I_R	V_{BR} typ (V) @ I_R	V_{BR} max (V) @ I_R	I_R (mA)	ESD rating max (kV) [1]	C_{line} typ (pF)	V_{CL} max (V) @ I_{PP} [1]	I_{PP} (A) [1]	I_{RM} max (µA) @ V_{RWM}	Configuration	Type	Package	Size (mm)
24	3	5.32	5.6	5.88	20	30	210	8	3	5	 mse212	MMBZ5V6AL	SOT23 	2.9 x 1.3 x 1.0
		5.89	6.2	6.51	1	30	175	8.7	2.76	0.2		MMBZ6V2AL		
	4.5	6.48	6.8	7.14	1	30	150	9.6	2.5	0.3		MMBZ6V8AL		
	6	8.65	9.1	9.56	1	30	155	14	1.7	0.1		MMBZ9V1AL		
	6.5	9.5	10	10.5	1	30	130	14.2	1.7	0.02		MMBZ10VAL		
40	8.5	11.4	12	12.6	1	30	110	17	2.35	0.005		MMBZ12VAL		
	12	14.25	15	15.75	1	30	85	21	1.9	0.005		MMBZ15VAL		
	14.5	17.1	18	18.9	1	30	70	25	1.6	0.005		MMBZ18VAL		
	17	19	20	21	1	30	65	28	1.4	0.005		MMBZ20VAL		
	22	25.65	27	28.35	1	30	48	40	1	0.005		MMBZ27VAL		
	26	31.35	33	34.65	1	30	45	46	0.87	0.005		MMBZ33VAL		
	8.5	11.4	12	12.6	1	30	110	17	2.35	0.005	 bra004	MMBZ12VDL		
	12.8	14.3	15	15.8	1	30	85	21.2	1.9	0.005		MMBZ15VDL		
	14.5	17.1	18	18.9	1	30	70	25	1.6	0.005		MMBZ18VCL		
	17	19	20	21	1	30	65	28	1.4	0.005		MMBZ20VCL		
	22	25.65	27	28.35	1	30	48	38	1	0.005		MMBZ27VCL		
	26	31.35	33	34.65	1	30	45	46	0.87	0.005		MMBZ33VCL		

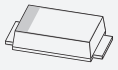
TVS diodes, 400 W

Power (W) (10/1000 µs waveform) [1]	V_{RWM} (V)	V_{BR} min (V) @ I_R	V_{BR} typ (V) @ I_R	V_{BR} max (V) @ I_R	I_R (mA)	V_{CL} max (V) @ I_{PP} [1]	I_{PP} (A) [1]	I_{RM} typ (µA) @ V_{RWM}	I_{RM} max (µA) @ V_{RWM}	Type (T_j max = 150 °C)	Type (T_j max = 185 °C)	Package	Size (mm)
350	3.5	5.20	5.60	6.00	10	8.0	43.8	5	600	PTVS3V3S1UR	PTVS3V3S1UTR	SOD123W	2.6 x 1.7 x 1.0
400	5.0	6.40	6.70	7.00	10	9.2	43.5	5	400	PTVS5V0S1UR	PTVS5V0S1UTR		
	6.0	6.67	7.02	7.37	10	10.3	38.8	5	400	PTVS6V0S1UR	PTVS6V0S1UTR		
	6.5	7.22	7.60	7.98	10	11.2	35.7	5	250	PTVS6V5S1UR	PTVS6V5S1UTR		
	7.0	7.78	8.20	8.60	10	12.0	33.3	3	100	PTVS7V0S1UR	PTVS7V0S1UTR		
	7.5	8.33	8.77	9.21	1	12.9	31.0	0.2	50	PTVS7V5S1UR	PTVS7V5S1UTR		
	8.0	8.89	9.36	9.83	1	13.6	29.4	0.03	25	PTVS8V0S1UR	PTVS8V0S1UTR		
	8.5	9.44	9.92	10.40	1	14.4	27.8	0.01	10	PTVS8V5S1UR	PTVS8V5S1UTR		
	9.0	10.00	10.55	11.10	1	15.4	26.0	0.005	5	PTVS9V0S1UR	PTVS9V0S1UTR		
	10	11.10	11.70	12.30	1	17.0	23.5	0.005	2.5	PTVS10VS1UR	PTVS10VS1UTR		
	11	12.20	12.85	13.50	1	18.2	22.0	0.005	2.5	PTVS11VS1UR	PTVS11VS1UTR		
	12	13.30	14.00	14.70	1	19.9	20.1	0.005	2.5	PTVS12VS1UR	PTVS12VS1UTR		
	13	14.40	15.15	15.90	1	21.5	18.6	0.001	0.1	PTVS13VS1UR	PTVS13VS1UTR		
	14	15.60	16.40	17.20	1	23.2	17.2	0.001	0.1	PTVS14VS1UR	PTVS14VS1UTR		
	15	16.70	17.60	18.50	1	24.4	16.4	0.001	0.1	PTVS15VS1UR	PTVS15VS1UTR		
	16	17.80	18.75	19.70	1	26.0	15.4	0.001	0.1	PTVS16VS1UR	PTVS16VS1UTR		
	17	18.90	19.90	20.90	1	27.6	14.5	0.001	0.1	PTVS17VS1UR	PTVS17VS1UTR		
	18	20.00	21.00	22.10	1	29.2	13.7	0.001	0.1	PTVS18VS1UR	PTVS18VS1UTR		
	20	22.20	23.35	24.50	1	32.4	12.3	0.001	0.1	PTVS20VS1UR	PTVS20VS1UTR		
	22	24.40	25.60	26.90	1	35.5	11.3	0.001	0.1	PTVS22VS1UR	PTVS22VS1UTR		
	24	26.70	28.10	29.50	1	38.9	10.3	0.001	0.1	PTVS24VS1UR	PTVS24VS1UTR		
	26	28.90	30.40	31.90	1	42.1	9.5	0.001	0.1	PTVS26VS1UR	PTVS26VS1UTR		
	28	31.10	32.80	34.40	1	45.4	8.8	0.001	0.1	PTVS28VS1UR	PTVS28VS1UTR		
	30	33.30	35.10	36.80	1	48.4	8.3	0.001	0.1	PTVS30VS1UR	PTVS30VS1UTR		
	33	36.70	38.70	40.60	1	53.3	7.5	0.001	0.1	PTVS33VS1UR	PTVS33VS1UTR		
	36	40.00	42.10	44.20	1	58.1	6.9	0.001	0.1	PTVS36VS1UR	PTVS36VS1UTR		
	40	44.40	46.80	49.10	1	64.5	6.2	0.001	0.1	PTVS40VS1UR	PTVS40VS1UTR		
	43	47.80	50.30	52.80	1	69.4	5.8	0.001	0.1	PTVS43VS1UR	PTVS43VS1UTR		
	45	50.00	52.65	55.30	1	72.7	5.5	0.001	0.1	PTVS45VS1UR	PTVS45VS1UTR		
	48	53.30	56.10	58.90	1	77.4	5.2	0.001	0.1	PTVS48VS1UR	PTVS48VS1UTR		
	51	56.70	59.70	62.70	1	82.4	4.9	0.001	0.1	PTVS51VS1UR	PTVS51VS1UTR		
	54	60.00	63.15	66.30	1	87.1	4.6	0.001	0.1	PTVS54VS1UR	PTVS54VS1UTR		
	58	64.40	67.80	71.20	1	93.6	4.3	0.001	0.1	PTVS58VS1UR	PTVS58VS1UTR		
	60	66.70	70.20	73.70	1	96.8	4.1	0.001	0.1	PTVS60VS1UR	PTVS60VS1UTR		
	64	71.10	74.85	78.60	1	103.0	3.9	0.001	0.1	PTVS64VS1UR	PTVS64VS1UTR		



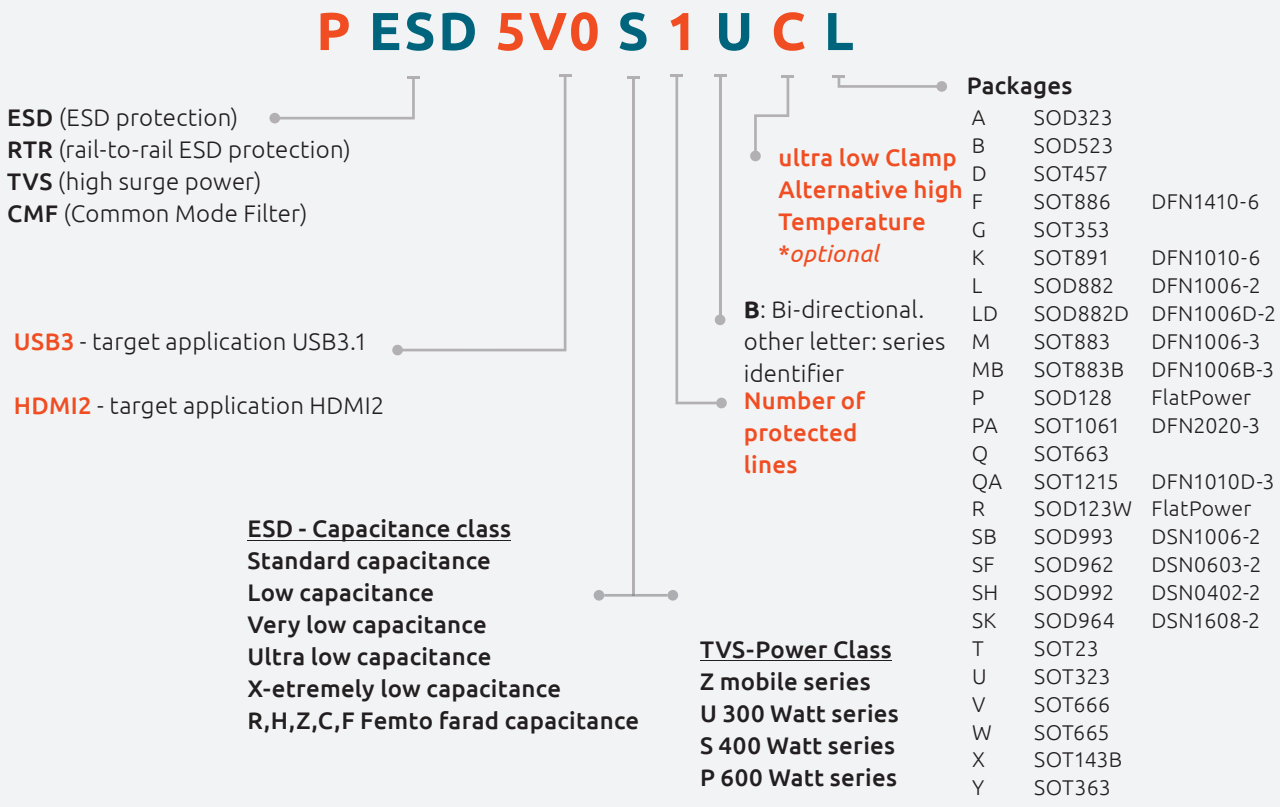
[1] 10 / 1000 µs according to IEC 61643-321

TVS diodes, 600W

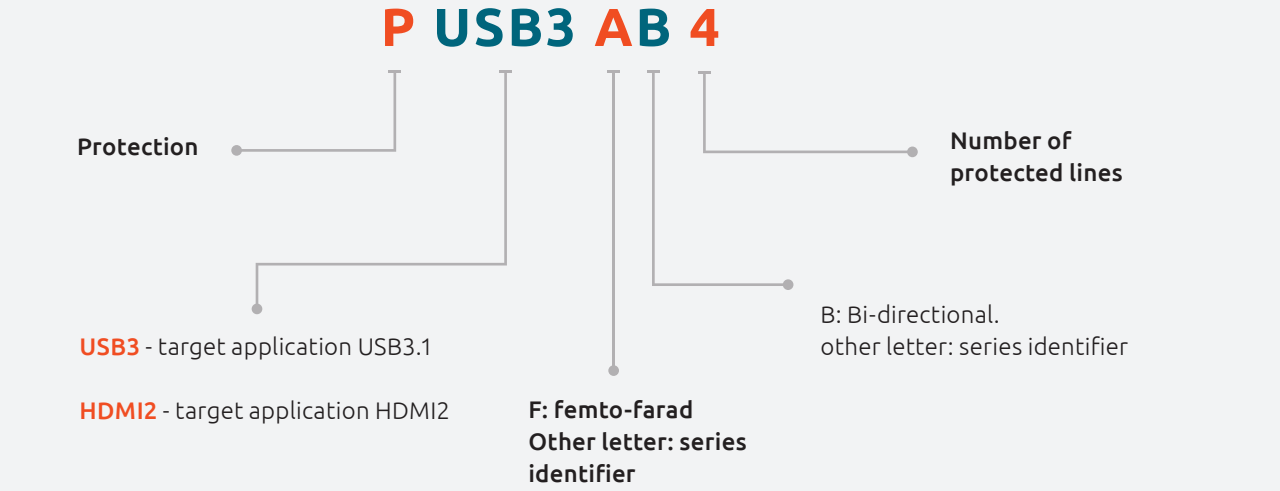
Power (W) (10 / 1000 µs waveform) [1]	V_{RWM} (V)	V_{BR} min (V) @ I_R	V_{BR} typ (V) @ I_R	V_{BR} max (V) @ I_R	I_R (mA)	V_{CL} max (V) @ I_{PP} [1]	I_{PP} (A) [1]	I_{RM} typ (µA) @ V_{RWM}	I_{RM} max (µA) @ V_{RWM}	Type (T_j max = 150 °C)	Type (T_j max = 185 °C)	Package	Size (mm)
600	3.5	5.20	5.60	6.00	10	8	75	5	600	PTVS3V3P1UP	PTVS3V3P1UTP	SOD128 	3.8 x 2.6 x 1.0
	5	6.40	6.70	7.00	10	9.2	65.2	5	400	PTVS5V0P1UP	PTVS5V0P1UTP		
	6	6.67	7.02	7.37	10	10.3	58.3	5	400	PTVS6V0P1UP	PTVS6V0P1UTP		
	6.5	7.22	7.60	7.98	10	11.2	53.6	5	250	PTVS6V5P1UP	PTVS6V5P1UTP		
	7	7.78	8.20	8.60	10	12	50	3	100	PTVS7V0P1UP	PTVS7V0P1UTP		
	7.5	8.33	8.77	9.21	1	12.9	46.5	0.2	50	PTVS7V5P1UP	PTVS7V5P1UTP		
	8	8.89	9.36	9.83	1	13.6	44.1	0.03	25	PTVS8V0P1UP	PTVS8V0P1UTP		
	8.5	9.44	9.92	10.40	1	14.4	41.7	0.01	10	PTVS8V5P1UP	PTVS8V5P1UTP		
	9	10.00	10.55	11.10	1	15.4	39	0.005	5	PTVS9V0P1UP	PTVS9V0P1UTP		
	10	11.10	11.70	12.30	1	17	35.3	0.005	2.5	PTVS10VP1UP	PTVS10VP1UTP		
	11	12.20	12.85	13.50	1	18.2	33	0.005	2.5	PTVS11VP1UP	PTVS11VP1UTP		
	12	13.30	14.00	14.70	1	19.9	30.2	0.005	2.5	PTVS12VP1UP	PTVS12VP1UTP		
	13	14.40	15.15	15.90	1	21.5	27.9	0.001	0.1	PTVS13VP1UP	PTVS13VP1UTP		
	14	15.60	16.40	17.20	1	23.2	25.9	0.001	0.1	PTVS14VP1UP	PTVS14VP1UTP		
	15	16.70	17.60	18.50	1	24.4	24.6	0.001	0.1	PTVS15VP1UP	PTVS15VP1UTP		
	16	17.80	18.75	19.70	1	26	23.1	0.001	0.1	PTVS16VP1UP	PTVS16VP1UTP		
	17	18.90	19.90	20.90	1	27.6	21.7	0.001	0.1	PTVS17VP1UP	PTVS17VP1UTP		
	18	20.00	21.00	22.10	1	29.2	20.5	0.001	0.1	PTVS18VP1UP	PTVS18VP1UTP		
	20	22.20	23.35	24.50	1	32.4	18.5	0.001	0.1	PTVS20VP1UP	PTVS20VP1UTP		
	22	24.40	25.60	26.90	1	35.5	16.9	0.001	0.1	PTVS22VP1UP	PTVS22VP1UTP		
	24	26.70	28.10	29.50	1	38.9	15.4	0.001	0.1	PTVS24VP1UP	PTVS24VP1UTP		
	26	28.90	30.40	31.90	1	42.1	14.2	0.001	0.1	PTVS26VP1UP	PTVS26VP1UTP		
	28	31.10	32.80	34.40	1	45.4	13.2	0.001	0.1	PTVS28VP1UP	PTVS28VP1UTP		
	30	33.30	35.10	36.80	1	48.4	12.4	0.001	0.1	PTVS30VP1UP	PTVS30VP1UTP		
	33	36.70	38.70	40.60	1	53.3	11.3	0.001	0.1	PTVS33VP1UP	PTVS33VP1UTP		
	36	40.00	42.10	44.20	1	58.1	10.3	0.001	0.1	PTVS36VP1UP	PTVS36VP1UTP		
	40	44.40	46.80	49.10	1	64.5	9.3	0.001	0.1	PTVS40VP1UP	PTVS40VP1UTP		
	43	47.80	50.30	52.80	1	69.4	8.6	0.001	0.1	PTVS43VP1UP	PTVS43VP1UTP		
	45	50.00	52.65	55.30	1	72.7	8.3	0.001	0.1	PTVS45VP1UP	PTVS45VP1UTP		
	48	53.30	56.10	58.90	1	77.4	7.8	0.001	0.1	PTVS48VP1UP	PTVS48VP1UTP		
	51	56.70	59.70	62.70	1	82.4	7.3	0.001	0.1	PTVS51VP1UP	PTVS51VP1UTP		
	54	60.00	63.15	66.30	1	87.1	6.9	0.001	0.1	PTVS54VP1UP	PTVS54VP1UTP		
	58	64.40	67.80	71.20	1	93.6	6.4	0.001	0.1	PTVS58VP1UP	PTVS58VP1UTP		
	60	66.70	70.20	73.70	1	96.8	6.2	0.001	0.1	PTVS60VP1UP	PTVS60VP1UTP		
	64	71.10	74.85	78.60	1	103	5.8	0.001	0.1	PTVS64VP1UP	PTVS64VP1UTP		

[1] 10 / 1000 µs according to IEC 61643-321

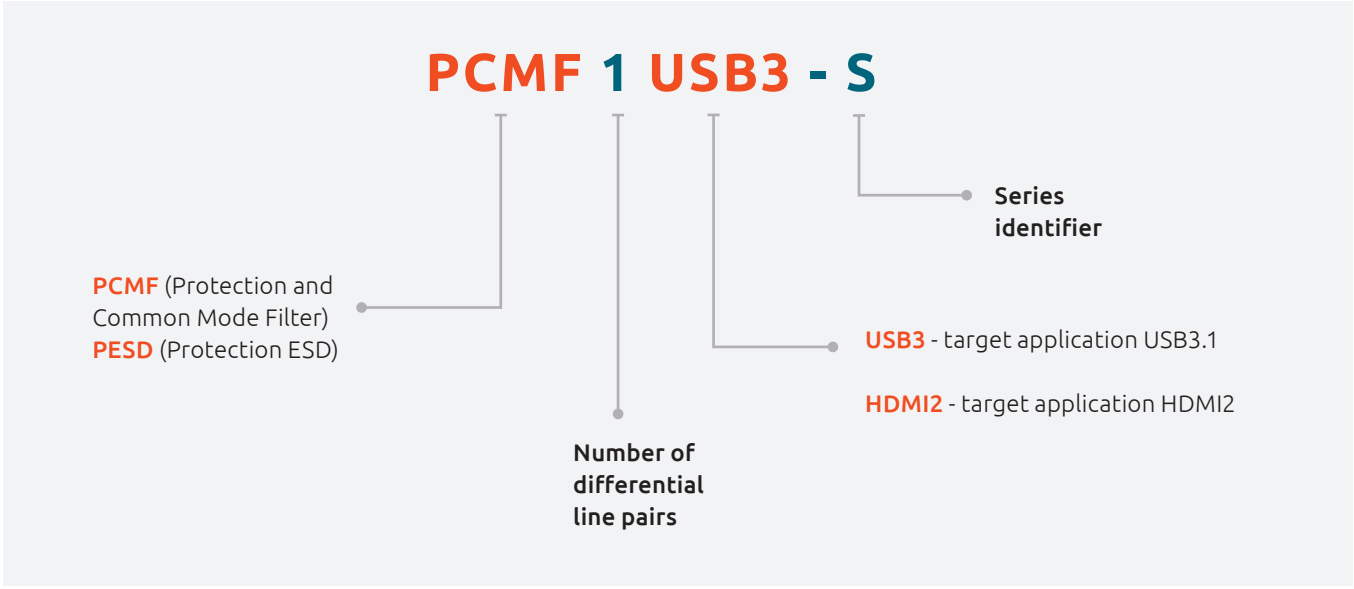
Nomenclature - protection devices



Nomenclature - application specific ESD protection



Nomenclature - common mode filter with ESD protection



MOSFETs 4

Automotive grade MOSFETs nomenclature

BUK 7 Y 3R5 - 40 E

Segment
'BUK' for automotive grade

Gate drive
7 = Standard level
6 = Intermediate level
9 = Logic level

Package
6 = D²PAK
2 = DPAK
E = I²PAK
5 = TO-220
M = LFPAK33
Y = LFPAK56
K = LFPAK56D

TrenchMOS technology
A = Generation 2
B = Generation 3
C = Generation 4
E = Generation 6

Voltage rating
BV_{DSS} rating

3R5 = $R_{DS(on)}$ <3.5mΩ max at 25°C

30V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
D²PAK (SOT404)	BUK962R8-30B	30	2.4	2.8	75	0.5
	BUK762R7-30B	30	2.7		75	0.5
	BUK763R4-30B	30	3.4		75	0.59
	BUK9607-30B	30	5	7	75	0.95
	BUK7607-30B	30	7		75	0.95
DPAK (SOT428)	BUK9207-30B	30	5	7	75	0.95
	BUK7207-30B	30	7		75	0.95
LFPAK56; Power-SO8 (SOT669)	BUK9Y07-30B	30	6	7	75	1.42
	BUK7Y07-30B	30	7		75	1.42
	BUK9Y11-30B	30	9	11	59	2
	BUK7Y10-30B	30	10		67	1.76
	BUK9Y22-30B	30	19	22	37.7	2.53
	BUK7Y20-30B	30	20		39.5	2.53
LFPAK56D (SOT1205)	BUK9K5R1-30E	30	4.4	5.3	40	2.21
	BUK9K5R6-30E	30	4.7	5.8	40	2.36
	BUK7K5R1-30E	30	5.1		40	2.21
	BUK7K5R6-30E	30	5.6		40	2.36
LFPAK33 (SOT1210)	BUK9M5R2-30E	30	4.1	5.2	70	1.89
	BUK9M6R6-30E	30	5.3	6.6	70	2
	BUK9M10-30E	30	7.8	10	54	2.75
	BUK9M17-30E	30	14	17	37	3.4

40V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
TO-220AB (SOT78) 	BUK751R8-40E	40	1.8		120	0.43
	BUK752R3-40E	40	2.3		120	0.51
	BUK753R1-40E	40	3.1		100	0.64
	BUK758R3-40E	40	7.4		75	1.56
D^2PAK (SOT404) 	BUK961R6-40E	40	1.4	1.6	120	0.43
	BUK761R6-40E	40	1.6		120	0.43
	BUK761R7-40E	40	1.6		120	0.46
	BUK762R0-40E	40	2		120	0.51
	BUK962R6-40E	40	2.4	2.8	100	0.57
	BUK762R6-40E	40	2.6		100	0.57
	BUK963R1-40E	40	2.7	3.1	100	0.64
	BUK762R9-40E	40	2.9		100	0.64
	BUK964R1-40E	40	3.5	4.1	75	0.82
	BUK764R0-40E	40	4		75	0.82
	BUK965R4-40E	40	4.4	5.4	75	1.09
	BUK765R3-40E	40	4.9		75	1.09
	BUK768R1-40E	40	7.2		75	1.56
DPAK (SOT428) 	BUK9209-40B	40	7	9	75	0.95
	BUK7208-40B	40	8		75	0.95
I^2PAK (SOT226) 	BUK7E1R8-40E	40	1.8		120	0.43
	BUK7E1R9-40E	40	1.9		120	0.46
	BUK7E2R3-40E	40	2.3		120	0.51
	BUK7E3R1-40E	40	3.1		100	0.64
	BUK7E8R3-40E	40	7.4		75	1.56
LFPAK56; Power-SO8 (SOT669) 	BUK9Y3R0-40E	40	2.5	3	100	0.77
	BUK7Y3R5-40E	40	3.5		100	0.9
	BUK9Y3R5-40E	40	3.6	3.8	100	0.9
	BUK9Y4R4-40E	40	3.7	4.4	100	1.02
	BUK7Y4R4-40E	40	4.4		100	1.02
	BUK9Y7R6-40E	40	6	7.6	79	1.58
	BUK7Y7R6-40E	40	7.6		79	1.58
	BUK9Y12-40E	40	10	12	52	2.31
	BUK7Y12-40E	40	12		52	2.31
	BUK9Y21-40E	40	17	21	33	3.33
	BUK7Y21-40E	40	21		33	3.33
	BUK9Y29-40E	40	25	29	25	4.03
	BUK7Y29-40E	40	29		26	4.03
LFPAK56D (SOT1205) 	BUK7K6R2-40E	40	5.8		40	2.21
	BUK9K6R2-40E	40	6	6.2	40	2.21
	BUK9K6R8-40E	40	6.1	7.2	40	2.36
	BUK7K6R8-40E	40	6.8			2.36
	BUK9K8R7-40E	40	8	9.4	30	2.84
	BUK7K8R7-40E	40	8.5			2.84
	BUK9K18-40E	40	16	20	30	3.96
	BUK7K18-40E	40	19		24.2	3.96
	BUK9K25-40E	40	24	29	18.2	4.68
	BUK7K25-40E	40	25			4.68

40V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK33 (SOT1210) 	BUK7M6R3-40E	40	6.3		70	1.89
	BUK7M8R0-40E	40	8		69	2
	BUK7M10-40E	40	10		56	2.43
	BUK7M12-40E	40	12		48	2.75
	BUK7M21-40E	40	21		33	3.4
	BUK7M45-40E	40	45		19	4.8
	BUK9M14-40E	40	11	14	44	2.75
	BUK9M24-40E	40	20	24	30	3.4
	BUK9M52-40E	40	40	52	17.6	4.8
	BUK9M7R2-40E	40	5.8	7.2	70	1.89
	BUK9M9R1-40E	40	7.3	9.1	64	2
	BUK9M11-40E	40	9	11	53	2.43

55V-60V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
TO-220AB (SOT78) 	BUK953R5-60E	60	3.4	3.7	120	0.51
	BUK954R8-60E	60	4.5	4.9	100	0.64
D^2PAK (SOT404) 	BUK7610-55AL	55	10		75	0.5
	BUK7610-55AL	55	10		75	0.5
	BUK9620-55A	55	18	20	54	1.2
	BUK7620-55A	55	20		54	1.2
	BUK9624-55A	55	22	24	46	1.4
	BUK7624-55A	55	24		47	1.4
	BUK9628-55A	55	25	28	42	1.5
	BUK7628-55A	55	28		42	1.5
	BUK9635-55A	55	32	35	34	1.8
	BUK7635-55A	55	35		35	1.7
	BUK9675-55A	55	68	75	20	2.4
	BUK7675-55A	55	75		20.3	2.4
D^2PAK (SOT404) 	BUK962R5-60E	60	2.3	2.5	120	0.43
	BUK762R4-60E	60	2.4		120	0.43
	BUK962R8-60E	60	2.5	2.8	120	0.46
	BUK762R6-60E	60	2.6		120	0.46
	BUK963R3-60E	60	3	3.3	120	0.51
	BUK763R1-60E	60	3.1		120	0.51
	BUK964R2-60E	60	3.9	4.2	100	0.57
	BUK763R9-60E	60	3.9		100	0.57
	BUK964R8-60E	60	4.4	4.8	100	0.64
	BUK764R4-60E	60	4.5		100	0.64
	BUK966R5-60E	60	5.9	6.5	75	0.82
	BUK766R0-60E	60	6		75	0.82
	BUK969R0-60E	60	8	9	75	1.09
	BUK768R3-60E	60	8.3		75	1.09
	BUK9614-60E	60	13	14	56	1.56
	BUK7613-60E	60	13		58	1.56

55V-60V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
DPAK (SOT428) 	BUK9212-55B	55	10	12	75	0.95
	BUK7210-55B	55	10		75	0.95
	BUK7212-55B	55	12		75	0.95
	BUK9215-55A	55	14	15	62	1.3
	BUK7215-55A	55	15		62	1.3
	BUK9219-55A	55	18	19	55	1.3
	BUK7219-55A	55	19		55	1.3
	BUK9222-55A	55	20	22	48	1.5
	BUK9225-55A	55	22	25	43	1.6
DPAK (SOT428) 	BUK7222-55A	55	22		48	1.5
	BUK7225-55A	55	25		43	1.6
	BUK9230-55A	55	27	30	38	1.7
	BUK7230-55A	55	30		38	1.7
	BUK9237-55A	55	33	37	32	1.94
	BUK7237-55A	55	37		32.3	1.9
	BUK9245-55A	55	40	45	28	2.1
	BUK9277-55A	55	69	77	18	2.93
	BUK9277-55A	55	69	77	18	2.93
	BUK7277-55A	55	77		18	2.9
	BUK92150-55A	55	125	140	11	4.1
	BUK92150-55A	55	125	140	11	4.1
	BUK72150-55A	55	150		11	4.1
I²PAK (SOT226) 	BUK7E2R6-60E	60	2.6		120	0.43
	BUK7E3R5-60E	60	3.5		120	0.51
	BUK7E4R6-60E	60	4.6		100	0.64
	BUK7E13-60E	60	13		58	1.56
LFPAK56; Power-SO8 (SOT669) 	BUK9Y4R8-60E	60	4.1	4.8	100	0.63
	BUK7Y4R8-60E	60	4.8		100	0.63
	BUK9Y6R0-60E	60	5.2	6	100	0.77
	BUK9Y7R2-60E	60	5.6	7.2	100	0.9
	BUK7Y6R0-60E	60	6		100	0.77
	BUK7Y7R2-60E	60	7.2		100	0.9
	BUK9Y8R7-60E	60	7.5	8.7	86	1.02
	BUK7Y8R7-60E	60	8.7		87	1.02
	BUK9Y15-60E	60	13	15	53	1.58
	BUK7Y15-60E	60	15		53	1.59
	BUK9Y25-60E	60	22	25	34	2.31
	BUK7Y25-60E	60	25		34	2.31
	BUK9Y43-60E	60	38	43	22	3.33
	BUK7Y43-60E	60	43		22	3.33
	BUK9Y59-60E	60	52	59	16.7	4.03
	BUK7Y59-60E	60	59		17	4.03

55V-60V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK56D (SOT1205) 	BUK7K12-60E	60	9.3			2.21
	BUK7K13-60E	60	10		40	2.36
	BUK9K12-60E	60	11	12	35	2.21
	BUK9K13-60E	60	12	13	40	2.36
	BUK7K17-60E	60	14		30	2.84
	BUK9K17-60E	60	16	17	26	2.84
	BUK7K35-60E	60	30		20.7	3.96
	BUK9K35-60E	60	32	35	22	3.96
	BUK9K35-60E	60	32	35	22	3.96
	BUK7K52-60E	60	45		15.4	4.68
	BUK9K52-60E	60	49	55	16	4.68
LFPAK33 (SOT1210) 	BUK7M9R9-60E	60	9.9		60	1.89
	BUK9M12-60E	60	11	12	54	1.89
	BUK7M12-60E	60	12		53	2
	BUK9M15-60E	60	13	15	47	2
	BUK7M15-60E	60	15		43	2.43
	BUK9M19-60E	60	17	19	38	2.43
	BUK7M19-60E	60	19		36	2.75
	BUK9M24-60E	60	21	24	32	2.75
	BUK7M33-60E	60	33			3.4
	BUK9M42-60E	60	37	42	22	3.4
	BUK7M42-60E	60	42		20	4.17
	BUK9M53-60E	60	46	53	17	4.17
	BUK7M67-60E	60	67		14	4.8
	BUK9M85-60E	60	73	85	12.8	4.8
SOT223 	BUK9832-55A/CU	55	29	32		
	BUK9880-55A/CU	55	73	80		
	BUK7880-55A/CU	55	80			
	BUK98150-55A/CU	55	137	150		
	BUK78150-55A/CU	55	150			

75V-80V N-channel automotive power MOSFETs

Types in **bold red** are in development

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
TO-220AB (SOT78) 	BUK753R8-80E	80	4		120	0.43
D²PAK (SOT404) 	BUK7613-75B	75	13		75	0.95
	BUK9616-75B	75	14	16	67	0.95
	BUK7623-75A	75	23		53	1.1
	BUK763R8-80E	80	3.8		120	0.43
	BUK964R2-80E	80	4	4.2	120	0.43
	BUK764R2-80E	80	4.2		120	0.46
	BUK964R7-80E	80	4.5	4.7	120	0.46
	BUK769R6-80E	80	9.6		75	0.82
	BUK9611-80E	80	10	11	75	0.82
DPAK (SOT428) 	BUK7214-75B	75	14		69	0.95
	BUK9217-75B	75	15	17	64	0.95
	BUK9226-75A	75	25	26	45	1.3
	BUK7226-75A	75	26		45	1
	BUK9214-80E	80	14		63	
	BUK9230-80E	80	30		32	
LFPAK56; Power-SO8 (SOT669) 	BUK7Y7R8-80E	80	7.8		100	0.63
	BUK9Y8R5-80E	80	8	8.5	100	0.63
	BUK7Y9R9-80E	80	9.9		89	0.77
	BUK7Y9R9-80E	80	9.9		89	0.77
	BUK9Y11-80E	80	10	11	84	0.77
	BUK9Y14-80E	80	14	15	62	1.02
	BUK7Y14-80E	80	14		65	1.02
	BUK9Y25-80E	80	25	27	37	1.58
	BUK7Y25-80E	80	25		39	1.58
	BUK9Y41-80E	80	41	45	24	2.33
	BUK7Y41-80E	80	41		25	2.31
	BUK9Y72-80E	80	72	78	15	3.33
	BUK7Y72-80E	80	72		16	3.33
	BUK9Y107-80E	80	98	107	11.8	4.03
	BUK7Y98-80E	80	98		12.3	4.03
LFPAK56D (SOT1205) 	**BUK9K19-80E**	**80**	**17**	**19**		**2.21**
	BUK9K21-80E	**80**	**19**	**21**		**2.36**
	BUK7K19-80E	**80**	**19**			**2.21**
	BUK9K29-80E	**80**	**21**	**29**		**2.84**
	BUK7K21-80E	**80**	**21**			**2.36**
	BUK7K29-80E	**80**	**29**			**2.84**
LFPAK33 (SOT1210 	BUK7M17-80E	80	17		43	1.89
	BUK9M23-80E	80	20	23	37	1.89
	BUK7M22-80E	80	22		37	2
	BUK7M27-80E	80	27		30	2.43
	BUK9M28-80E	80	28	28	33	2
	BUK9M35-80E	80	35	35	26	2.43

100V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
TO-220AB (SOT78) 	BUK755R4-100E	100	5.2		120	0.43
D²PAK (SOT404) 	BUK765R0-100E	100	5		120	0.43
	BUK965R8-100E	100	5.6	5.8	120	0.43
	BUK768R1-100E	100	8.1		100	0.57
	BUK969R3-100E	100	8.9	9.3	100	0.57
	BUK7613-100E	100	13		72	0.82
	BUK9615-100E	100	14	15	66	0.82
	BUK7631-100E	100	31		34	1.56
	BUK9637-100E	100	36	37	31	1.56
	BUK9660-100A	100	58	60	26	1.4
	BUK7660-100A	100	60		26	1.4
	BUK9675-100A	100	72	75	23	1.5
	BUK7675-100A	100	75		23	1.5
	BUK96180-100A	100	173	180	11	2.8
DPAK (SOT428) 	BUK7227-100B	100	27		48	0.95
	BUK9230-100B	100	28	30	47	0.95
	BUK9240-100A	100	39	40	33	1.3
	BUK7240-100A	100	40		34	1.3
	BUK9275-100A	100	72	75	21.7	1.7
	BUK7275-100A	100	75		21.7	1.7
I²PAK (SOT226) 	BUK7E5R2-100E	100	5.2		120	0.43
LFPAK56; Power-SO8 (SOT669) 	BUK9Y12-100E	100	12	12	85	0.63
	BUK7Y12-100E	100	12		85	0.63
	BUK9Y15-100E	100	15	15	69	0.77
	BUK7Y15-100E	100	15		68	0.77
	BUK9Y19-100E	100	18	19	56	0.9
LFPAK56; Power-SO8 (SOT669) 	BUK7Y19-100E	100	19		56	0.9
	BUK9Y22-100E	100	22	22	49	1.02
	BUK7Y22-100E	100	22		49	1.02
	BUK9Y38-100E	100	38	38	30	1.58
	BUK7Y38-100E	100	38		30	1.58
	BUK9Y65-100E	100	64	65	19	2.31
	BUK7Y65-100E	100	65		19	2.31
	BUK9Y113-100E	100	110	113	12	3.33
	BUK7Y113-100E	100	113		12	3.33
	BUK9Y153-100E	100	146	153	9.4	4.03
	BUK7Y153-100E	100	153		9.4	4.03

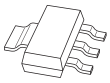
100V N-channel automotive power MOSFETs

Package name	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ 10 V (mΩ)	$R_{DS(on)}$ [max] @ 5 V (mΩ)	I_D [max] @ 25 °C (A)	$R_{th(j-mb)}$ [max] (K/W)
LFPAK56D (SOT1205) 	BUK7K29-100E	100	25		29.5	2.21
	BUK9K29-100E	100	27	29	30	2.21
	BUK7K32-100E	100	28		29	2.36
	BUK9K32-100E	100	31	33	26	2.36
	BUK7K45-100E	100	38		21.4	2.84
	BUK9K45-100E	100	42	45	21	2.84
	BUK7K89-100E	100	83		13	3.96
	BUK9K89-100E	100	85	89	12.5	3.96
	BUK7K134-100E	100	121		9.8	4.68
	BUK9K134-100E	100	154	159	8.5	4.68
LFPAK33 (SOT1210) 	BUK9M34-100E	100	34	34	29	1.89
	BUK9M43-100E	100	43	44	26	1.88
	BUK9M120-100E	100	119	120	11.5	3.4
	BUK9M156-100E	100	150	156	9.3	4.17
SOT223 	BUK98180-100A/CU	100	173	180	4.6	
	BUK9875-100A/CU	101	72	75	7	

Small-signal automotive MOSFETs – Low $R_{DS(on)}$

Package										
Size (mm)										
P_{tot} (mW)										
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =			
							10 V	4.5 V	2.5 V	1.8 V
N-channel	20	8	4.7	0.45	1	2	-	24	29	40
			2	0.45	1	2	-	57	64	78
			2.8	0.4	1	2	-	64	78	110
		12	12.9	0.4	0.9	2	-	10	12	16
			11.4	0.4	0.9	2	-	12	15	20
			6.3	0.75	1.25	2	-	16	24	-
	30	12	11.3	0.4	0.9	2	-	13	14	17
			5	0.4	0.9	2	-	28	32	37
			4	0.75	1.25	2	-	55	72	-
			0.9	0.75	1.25	2	-	212	269	-
		20	5.5	1	2.5	2	17	22	-	-
			3.9	1	2.5	2	30	39	-	-
			3.7	1	2.5	2	54	70	-	-
	40	15	7	1.4	2.1	0.5	-	18	22	-
		20	7	2.4	4	0.5	19	-	-	-
			2.7	1	2.5	1	64	79	-	-
			2.5	1	2.5	1	95	120	-	-
	60	20	5	1.3	2.7	0.5	32	38	-	-
			4	1.3	2.7	2	42	49	-	-
			3.1	1.3	2.7	2	46	52	-	-
			3	1.3	2.7	2	72	85	-	-
			2.1	1.3	2.7	2	96	108	-	-
			1.5	1.3	2.7	2	176	196	-	-
			0.8	1.3	2.7	2	300	332	-	-
	80	20	2.8	1.3	2.7	2	80	92	-	-
			1.9	1.3	2.7	2	175	195	-	-
			1.1	1.3	2.7	2	345	390	-	-
	100	20	1.5	1.3	2.7	2	285	301	-	-
			1.1	1.3	2.7	2	527	555	-	-
P-channel	12	12	11.8	0.47	0.9	-	-	15	17	21
	20	8	5.6	0.45	0.95	2	-	27	38	50
			6	0.45	0.95	2	-	37	45	59
			2	0.5	1.1	-	-	100	155	210
			2.3	0.45	0.95	-	-	120	150	200
		12	10.3	0.47	0.9	2	-	19	22	28
			5.7	0.75	1.25	2	-	27	39	-
			5.3	0.75	1.25	2	-	28	42	-
			5	0.47	0.9	2	-	39	45	56
			5.7	0.75	1.25	2	-	41	56	-
			3.5	0.75	1.25	-	-	48	71	-
			3.3	0.75	1.25	2	-	67	99	-
			4.1	0.75	1.25	2	-	70	101	-
			2.4	1	2.5	2	-	97	147	-
	30	20	4.2	1	3	2	35	47	-	-
	40	20	1.5	1	2.5	1	180	220	-	-
			5	1.5	3	1	32	42	-	-
	70	20	2.3	1	3	2	156	177	-	-

types in **bold** represent new products

	SOT223	SOT457 (SC-74)	SOT23	SOT323 (SC-70)	DFN2020MD-6 (SOT1220)	DFN2020D-6 (SOT1118D)	DFN1010D-3 (SOT1215)
							
	6.5 x 3.5 x 1.65	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 2.0 x 0.65	2.0 x 2.0 x 0.65	1.1 x 1.0 x 0.37
	1700	600	250	200	1250	1250	1000
		PMN28UNEA	PMV28UNEA				
				PMF63UNEA			
			PMV65UNEA				
					PMPB10XNEA		
					PMPB12UNEA		
			PMV20XNEA		PMPB20XNEA		
					PMPB13XNEA		
					PMPB29XNEA		
						PMDPB56XNEA	
				PMF250XNEA			
		PMN25ENEA	PMV25ENEA		**PMPB25ENEA**		
			PMV50ENEA		**PMPB50ENEA**		
			PMV100ENEA		**PMPB100ENEA**		
					PMPB20LNA		
					PMPB20SNA		
			PMV65ENEA				
			PMV130ENEA				
					PMPB40ENA		
					PMPB55ENEA		
		PMN55ENEA	PMV55ENEA				
					PMPB85ENEA		
		PMN120ENEA	PMV120ENEA				
		PMN230ENEA	PMV230ENEA				
			PMV450ENEA				
					PMPB95ENEA		
					PMPB215ENEA		
							PMXB360ENEA
	PMT280ENEA		**PMV280ENEA**				
	PMT560ENEA						
					PMPB15XPA		
			PMV27UPEA				
		PMN40UPEA					
			NX2301P				
			BSH205G2				
					PMPB20XPEA		
		PMN27XPEA					
		PMN30XPEA	PMV30XPEA		**PMPB30XPEA**		
					PMPB43XPEA		
		PMN42XPEA					
			PMV48XPA				
			PMV65XPEA				
		PMN70XPEA					
			PMV100XPEA		**PMPB100XPEA**		
		PMN50EPEA	PMV50EPEA		**PMPB50EPEA**		
			PMV250EPEA				
					PMPB45EPA		
	PMT200EPEA						

Small-signal automotive MOSFETs – High $R_{DS(on)}$

Package											
Size (mm)											
P_{tot} (mW)											
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =				
							10 V	4.5 V	2.5 V	1.8 V	
N	30	8	0.4	0.6	1.1	2	-	1000	1400	2000	
	60	20	0.36	0.9	1.5	-	900	1000	-	-	
			0.36	0.48	1.6	1.5	1000	1100	1400	-	
			0.3	1	2.5	2	1000	1300	-	-	
			0.3	1	2.5	3	1100	1300	-	-	
			0.2	0.8	1.5	yes	2700	3000	4000	-	
P	30	8	0.23	0.6	1.1	2		2800	5300	-	
	50	20	0.2	1.1	2.1	1	5300	6000	-	-	

Small-signal automotive MOSFETs – Dual

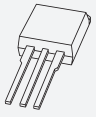
Package											
Size (mm)											
P_{tot} (mW)											
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =				
							10 V	4.5 V	2.5 V	1.8 V	
N	20	8	0.8	0.5	0.95	2	-	380	620	1100	
	30	12	4	0.75	1.25	2	-	55	72	-	
			0.95	0.75	1.25	2	-	211	267	-	
P	20	8	0.55	0.5	1.3	2	-	670	1200	1800	
N	20	8	0.73	0.5	0.95	2	-	290	420	600	
P			0.5	0.5	1.3	2	-	670	1200	1800	

	SOT23	SOT363 (SC-88)	SOT323 (SC-70)	SOT666	DFN1006 (SOT883)
					
	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.6 x 1.2 x 0.55	1.0 x 0.6 x 0.5
	250	300	200	300	250
	NX3008NBK	NX3008NBKS	NX3008NBKW	NX3008NBKV	
	BSS138P	BSS138PS	BSS138PW		
	BSS138BK	BSS138BKS	BSS138BKW		
	2N7002BK	2N7002BKS	2N7002BKW		2N7002BKM
	2N7002CK				
	BSS138AKA				
	NX3008PBK	NX3008PBKS	NX3008PBKW	NX3008PBKV	
	BSS84AK	BSS84AKS	BSS84AKW	BSS84AKV	BSS84AKM

types in **bold** represent new products

	SOT363 (SC-88)	SOT666	DFN2020D-6 (SOT1118D)
			
	2.0 x 1.25 x 0.95	1.6 x 1.2 x 0.55	2.0 x 2.0 x 0.65
	300	300	1250
		PMDT290UNE	
			PMDPB56XNEA
	PMGD175XNEA		
		PMDT670UPE	
	PMGD290UCEA		

N-channel 25V-30V MOSFETs

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
TO-220 (SOT78) 	PSMN1R1-30PL	30	1.3	1.6	120	118
	PSMN1R6-30PL	30	1.7	2.1	100	101
	PSMN1R8-30PL	30	1.8	2.3	100	83
	PSMN2R0-30PL	30	2.1	2.8	100	55
	PSMN2R7-30PL	30	2.7	3.6	100	32
	PSMN3R4-30PL	30	3.4	4.1	100	31
	PSMN4R3-30PL	30	4.3	6.2	100	19
	PSMN017-30PL	30	17	23	32	5.1
	PSMN022-30PL	30	22	34	30	4.4
D^2PAK (SOT404) 	PSMNR90-30BL	30	1	1.4	120	118
	PSMN1R5-30BLE	30	1.5	1.85	120	108
	PSMN1R8-30BL	30	1.8	2.1	100	83
	PSMN1R6-30BL	30	1.9	2.2	100	101
	PSMN2R0-30BL	30	2.1	2.9	100	55
	PSMN2R7-30BL	30	3	3.7	100	32
	PSMN3R4-30BL	30	3.3	3.8	100	31
	PSMN3R4-30BLE	30	3.4	5	120	37
	PSMN4R3-30BL	30	4.1	5.2	100	19
	PSMN017-30BL	30	17	23	32	5.1
	PSMN022-30BL	30	22	30	30	4.4
I^2PAK (SOT226) 	PSMN1R1-30EL	30	1.3	1.6	120	118
	PSMN017-30EL	30	17	23	32	5.1
SO8 (SOT96) 	PSMN006-20K	20	5	5	32	
	PHK31NQ03LT	30	4.4	5.6	30.4	33
	PSMN005-30K	30	5.5	8		34
	PHK18NQ03LT	30	8.9	13	20.3	10.6
	PHK12NQ03LT	30	11	14		
	PHKD13N03LT	30	20	26	10.4	
	PHK13N03LT	30	20	26	13.8	
LFPAK56 (Power-SO8) 	PSMN0R7-25YLD	25	0.74	0.92	300	50.9
	PSMN0R9-25YLD	25	0.86	1.2	300	41.5
	PSMN0R9-25YLC	25	0.99	1.3	100	51
	PSMN1R0-25YLD	25	1.02	1.4	100	33.2
	PSMN1R1-25YLC	25	1.15	1.5	100	39
	PSMN1R2-25YLD	25	1.15	1.7	100	28
	PSMN1R2-25YL	25	1.2	1.9	100	50.6
	PSMN1R2-25YLC	25	1.3	1.7	100	31
	PSMN1R5-25YL	25	1.5	2.2	100	36
	PSMN1R7-25YLD	25	1.68	2.4	100	21.5
	PSMN2R0-25YLD	25	2	2.9	100	15.7
	PSMN2R2-25YLC	25	2.4	3.1	100	18

N-channel 25V-30V MOSFETs

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
LFPAK56 (Power-SO8) 	PSMN2R9-25YLC	25	3.15	4.1	100	16
	PSMN4R0-25YLC	25	4.5	5.8	84	10.9
	PSMN5R4-25YLD	25	5.4	8.4	70	5.7
	PSMN6R0-25YLD	25	6.03	10	61	4.9
	PSMN6R0-25YLB	25	6.1	7.9	73	9
	PSMN6R5-25YLC	25	6.5	8.5	64	8.4
	PSMN0R9-30YLD	30	0.87	1.1	300	51
	PSMN1R0-30YLD	30	1.02	1.3	300	38.2
	PSMN1R0-30YLC	30	1.15	1.4	100	50
	PSMN1R2-30YLD	30	1.24	1.6	100	32
	PSMN1R2-30YLC	30	1.25	1.7	100	38
	PSMN1R3-30YL	30	1.3	2	100	46.6
	PSMN1R4-30YLD	30	1.42	1.9	100	27.6
	PSMN1R5-30YL	30	1.5	1.9	100	36.2
	PSMN1R5-30YLC	30	1.55	2.1	100	30
	PSMN1R7-30YL	30	1.7	2.1	100	36.2
	PSMN2R0-30YLD	30	2	2.5	100	21.8
	PSMN2R0-30YL	30	2	2.6	100	30
	PSMN2R0-30YLE	30	2	3.5	100	41
	PSMN2R2-30YLC	30	2.15	2.8	100	26
	PSMN2R4-30YLD	30	2.4	3.1	100	18
	PSMN2R5-30YL	30	2.4	3.2	100	27
	PSMN2R6-30YLC	30	2.8	3.7	100	18
	PSMN3R0-30YL	30	3	4	100	21
	PSMN3R0-30YLD	30	3	4	100	14.5
	PSMN3R5-30YL	30	3.5	4.6	100	19
	PSMN4R0-30YL	30	4	5.3	100	17.6
	PSMN4R0-30YLD	30	4	5.5	95	9.6
	PSMN4R1-30YLC	30	4.35	5.7	92	11
	PSMN5R0-30YL	30	5	6.7	91	14.1
	PSMN6R0-30YL	30	6	7.9	79	11
	PSMN6R0-30YLD	30	6	8.4	66	6.7
	PSMN6R1-30YLD	30	6.1	8.4	66	6.4
	PSMN6R0-30YLB	30	6.5	8.1	71	9
	PSMN7R0-30YL	30	7	9.1	76	10
	PSMN7R0-30YLC	30	7.1	8.9	61	7.9
	PSMN7R5-30YLD	30	7.5	10	51	5.8
	PSMN9R1-30YL	30	9.1	14	57	8.4
	PSMN9R5-30YLC	30	9.8	12	44	5
	PSMN013-30YLC	30	13	17	32	4
	PSMN011-30YLC	30	11.6	15	37	4.9
	PSMN3R2-30YLC	30	3.5	4.6	100	14.2
	PSMN4R5-30YLC	30	4.8	6.1	84	9.6

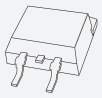
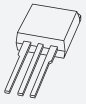
N-channel 25V-30V MOSFETs

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
LFPAK33 (SOT1210) 	PSMN2R0-25MLD	25	2	3.1	70	15.9
	PSMN2R8-25MLC	25	2.8	3.8	70	16.3
	PSMN3R5-25MLD	25	3.51	5.4	70	8.7
	PSMN3R9-25MLC	25	4.15	5.6	70	9.7
	PSMN5R3-25MLD	25	5.3	8.4	70	5.9
	PSMN6R1-25MLD	25	6.13	10	60	4.9
	PSMN9R0-25MLC	25	8.65	11	55	5.4
	PSMN2R4-30MLD	30	2.4	3.2	70	16
	PSMN2R9-30MLC	30	2.95	3.8	70	16.7
	PSMN3R0-30MLC	30	3.15	4.1	70	16.1
	PSMN4R2-30MLD	30	4.3	5.7	70	9.2
	PSMN4R4-30MLC	30	4.65	6	70	10.6
	PSMN6R4-30MLD	30	6.4	8.3	66	6.5
	PSMN6R5-30MLD	30	6.5	8.6	65	6.4
	PSMN7R0-30MLC	30	7	9	67	8.2
	PSMN7R5-30MLD	30	7.6	10	57	5.8
	PSMN9R8-30MLC	30	9.8	12	50	5
	PSMN013-30MLC	30	13	17	39	3.7
	PSMN020-30MLC	30	18	27	31.8	4.6

N-channel 40V-60V MOSFETs

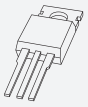
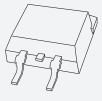
Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
TO-220 (SOT78) 	PSMN1R5-40PS	40	1.6		150	136
	PSMN1R9-40PL	40	1.7	1.9	150	230
	PSMN2R2-40PS	40	2.1		100	110
	PSMN2R1-40PL	40	2.2	2.6	150	168.9
	PSMN2R8-40PS	40	2.8		100	71
	PSMN4R5-40PS	40	4.6		100	35
	PSMN8R0-40PS	40	7.6		77	17
	PSMN2R0-60PSR	60	2		120	137
	PSMN2R0-60PS	60	2.2		120	137
	PSMN2R5-60PL	60	2.6	3.1	150	223
	PSMN2R6-60PS	60	2.6		150	140
	PSMN3R0-60PS	60	3		100	130
	PSMN3R3-60PL	60	3.4	3.8	130	175
	PSMN4R2-60PL	60	3.9	4.3	130	151
	PSMN3R9-60PS	60	3.9		130	103
	PSMN4R6-60PS	60	4.6		100	70.8
	PSMN7R6-60PS	60	7.8		92	38.7
	PSMN015-60PS	60	15		50	20.9

N-channel 40V-60V MOSFETs

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
D²PAK (SOT404) 	PSMN1R1-40BS	40	1.3		120	136
	PSMN2R2-40BS	40	2.2		100	130
	PSMN2R8-40BS	40	2.9		100	71
	PSMN4R5-40BS	40	4.5		100	35
	PSMN8R0-40BS	40	7.6		77	21
	PSMN1R7-60BS	60	2		120	137
	PSMN3R0-60BS	60	3.2		100	130
	PSMN4R6-60BS	60	4.4		100	70.8
	PSMN7R6-60BS	60	7.8		92	38.7
	PSMN015-60BS	60	15		50	20.9
I²PAK (SOT226) 	PSMN1R5-40ES	40	1.6		120	136
	PSMN2R0-60ES	60	2.2		120	137
	PSMN3R0-60ES	60	3		100	130
LFPAK56 (Power-SO8) 	PSMN1R0-40YLD	40	1.1	1.4	100	127
	PSMN1R4-40YLD	40	1.4	1.9	100	96
	PSMN1R6-40YLC	40	1.6	1.8	100	126
	PSMN1R8-40YLC	40	1.8	2.1	100	96
	PSMN2R6-40YS	40	2.8		100	63
	PSMN3R3-40YS	40	3.3		100	49
	PSMN4R0-40YS	40	4.2		100	38
	PSMN5R8-40YS	40	5.7		90	28.8
	PSMN8R3-40YS	40	8.6		70	20
	PSMN014-40YS	40	14		46	12
	PSMN4R0-60YS	60	4		100	56
	PSMN4R1-60YL	60	4.1	4.8	100	103
	PSMN5R2-60YL	60	5.2	6	100	78.4
	PSMN5R5-60YS	60	5.2		100	56
	PSMN5R6-60YL	60	5.6	7.2	100	66.8
	PSMN7R0-60YS	60	6.4		89	45
	PSMN7R5-60YL	60	7.5	8.7	86	60.6
	PSMN8R5-60YS	60	8		76	39
	PSMN012-60YS	60	11		59	28.4
	PSMN013-60YL	60	13	15	53	33.2
	PSMN030-60YS	60	15		29	13
	PSMN017-60YS	60	16		44	20
LFPAK33 (SOT1210) 	PSMN011-60ML	60	11	13	61	37.2
	PSMN011-60MS	60	11		61	23

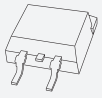
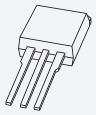
N-channel 75V-200V MOSFETs

Types in **bold red** are in development

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
TO-220 (SOT78) 	PSMN3R3-80PS	80	3.3		120	139
	PSMN3R5-80PS	80	3.5		120	139
	PSMN4R4-80PS	80	4.1		100	112
	PSMN4R3-80PS	80	4.3		120	111
	PSMN5R0-80PS	80	4.7		100	87
	PSMN6R5-80PS	80	6.9		100	71
	PSMN8R7-80PS	80	8.7		90	52
	PSMN012-80PS	80	11		74	36
	PSMN017-80PS	80	17		50	26
	PSMN3R3-100PSF	**100**	**3.3**			
	PSMN4R3-100PS	100	4.3		120	170
	PSMN4R5-100PSF	**100**	**4.5**			
	PSMN4R8-100PSE	100	4.8		120	196
	PSMN5R0-100PS	100	5		120	170
	PSMN5R6-100PS	100	5.6		100	141
	PSMN7R0-100PS	100	6.8		100	125
	PSMN7R0-100PSF	**100**	**7**			
	PSMN7R8-100PSE	100	7.8		100	128
	PSMN8R5-100PS	100	8.5		100	111
	PSMN8R5-100PSF	**100**	**8.5**			
	PSMN9R5-100PS	100	9.6		89	82
	PSMN013-100PS	100	13		68	59
	PSMN016-100PS	100	16		57	49
	PSMN018-100PSF	**100**	**18**			
	PSMN027-100PS	100	27		37	30
	PSMN034-100PS	100	35		32	23.8
	PSMN015-110P	110	15		75	90
	PHP27NQ11T	110	50		27.6	30
	PHP23NQ11T	110	70		23	22
	PHP18NQ11T	110	90		18	21
	PSMN6R3-120PS	120	6.7		70	207.1
	PSMN7R8-120PS	120	7.9		70	167
	PSMN030-150P	150	30		55.5	98
	PSMN035-150P	150	35		50	79
	PHP30NQ15T	150	63		29	55
	PHP28NQ15T	150	65		28.5	24
	PSMN057-200P	200	57		39	96
	PSMN070-200P	200	70		35	77
	PHP33NQ20T	200	77		32.7	32.2
	PHP20NQ20T	200	130		20	65
	PHP9NQ20T	200	400		8.7	24
D^2PAK (SOT404) 	PSMN2R8-80BS	80	3		120	139
	PSMN3R3-80BS	80	3.5		120	111
	PSMN4R4-80BS	80	4.5		100	125
	PSMN5R0-80BS	80	5.1		100	101

N-channel 75V-200V MOSFETs

Types in **bold red** are in development

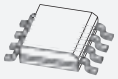
Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
D²PAK (SOT404) 	PSMN6R5-80BS	80	6.9		100	71
	PSMN8R7-80BS	80	8.7		90	52
	PSMN012-80BS	80	11		74	36
	PSMN017-80BS	80	17		50	26
	PSMN050-80BS	80	46		22	11
	PSMN3R3-100BSF	**100**	**3.3**			
	PSMN3R8-100BS	100	3.9		120	170
	PSMN4R5-100BSF	**100**	**4.5**			
	PSMN4R8-100BSE	100	4.8		120	196
	PSMN5R6-100BS	100	5.6		100	141
	PSMN7R0-100BS	100	6.8		100	125
	PSMN7R0-100BSF	**100**	**7**			
	PSMN7R6-100BSE	100	7.6		75	128
	PSMN8R5-100BSF	**100**	**8.5**			
	PSMN9R5-100BS	100	9.6		89	82
	PSMN013-100BS	100	14		68	59
	PSMN016-100BS	100	16		57	49
	PSMN018-100BSF	**100**	**18**			
	PSMN027-100BS	100	27		37	30
	PSMN034-100BS	100	35		32	23.8
	PSMN030-150B	150	30		55.5	98
	PSMN035-150B	150	35		50	79
	PHB45NQ15T	150	42		45.1	32
	PSMN057-200B	200	57		39	96
	PSMN070-200B	200	70		35	77
	PHB33NQ20T	200	77		32.7	32.2
	PHB20NQ20T	200	130		20	65
DPAK (SOT428) 	PSMN063-150D	150	63		29	55
	PSMN130-200D	200	130		20	65
	PHD9NQ20T	200	400		8.7	24
I²PAK (SOT226) 	PSMN3R3-80ES	80	3.3		120	139
	PSMN3R5-80ES	80	3.5		120	139
	PSMN4R3-80ES	80	4.3		120	111
	PSMN3R3-100ESF	**100**	**3.3**			
	PSMN4R3-100ES	100	4.3		120	170
	PSMN4R5-100ESF	**100**	**4.5**			
	PSMN5R0-100ES	100	5		120	170
	PSMN7R0-100ES	100	6.8		100	125
	PSMN7R0-100ESF	**100**	**7**			
	PSMN8R5-100ES	100	8.5		100	111
	PSMN8R5-100ESF	**100**	**8.5**			
	PSMN013-100ES	100	14		68	59
	PSMN018-100ESF	**100**	**18**			
	PSMN6R3-120ES	120	6.7		70	207.1
	PSMN7R8-120ES	120	7.9		70	167

N-channel 75V-200V MOSFETs

Types in **bold red** are in development

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V or 5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
SO8 (SOT96) 	PSMN038-100K	100	38			43
	PHK5NQ15T	150	75		5	29
	PSMN085-150K	150	85			40
	PSMN165-200K	200	165			40
LFPAK56 (Power-SO8) 	PSMN8R0-80YL	80	8	8.5	100	104
	PSMN8R2-80YS	80	8.5		82	55
	PSMN010-80YL	80	10	11	84	84.7
	PSMN011-80YS	80	11		67	45
	PSMN013-80YS	80	12.9		60	37
	PSMN014-80YL	80	14	15	62	56.9
	PSMN018-80YS	80	18		45	26
	PSMN025-80YL	80	25	27	37	34.3
	PSMN026-80YS	80	28		34	20
	PSMN041-80YL	80	41	45	25	21.9
	PSMN045-80YS	80	45		24	12.5
	PSMN5R6-100YSF	**100**	**5.6**		**158**	**63**
	PSMN6R9-100YSF	**100**	**6.9**		**128**	**51**
	PSMN8R7-100YSF	**100**	**8.7**		**100**	**39**
	PSMN012-100YL	100	12	12	85	118
	PSMN012-100YS	100	12		60	64
	PSMN013-100YSE	100	13		82	75
	PSMN015-100YL	100	15	15	69	86.3
	PSMN016-100YS	100	16		51	54
	PSMN019-100YL	100	19	19	56	72.4
	PSMN021-100YL	100	21	22	49	65.6
	PSMN020-100YS	100	21		43	41
	PSMN028-100YS	100	28		42	33
	PSMN038-100YL	100	38	38	30	39.2
	PSMN039-100YS	100	39		28.1	23
	PSMN069-100YS	100	72		17	14
	PSMN059-150Y	150	59		43	27.9
	PSMN102-200Y	200	102		21.5	30.7
LFPAK33 (SOT1210) 	PSMN040-100MSE	100	37		30	30
	PSMN075-100MSE	100	71		18	16.4
SOT873	PML260SN	200	294		8.8	13.3
	PML340SN	220	386		7.3	13.2

P-channel MOSFETs

Package	Type number	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
SO8 (SOT96-1) 	PMK30EP	-30	19	30	-14.9	50
	PMK35EP	-30	19	35	-14.9	42
	PHP225	-30	250	400	-	10
	PMK50XP	-20	-	50	-7.9	10
	PHK04P02T	-16	-	120	-4.66	7.2

Dual MOSFETs

Types in **bold red** are in development

Package	Type number	Channel	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	$R_{DS(on)}$ [max] @ V_{GS} = 4.5 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
DFN56AD (SOT1254) 	**PSMX3009-25LLD**	**N**	**25**	**2.6**	**3.5**	**50**	**12.6**
				0.72	**1**	**50**	**38.3**
	PSMX3510-30LLD	**N**	**30**	**3**	**4.5**	**50**	**13.7**
				0.82	**1.2**	**50**	**39.2**
SO8 (SOT96) 	PHKD3NQ10T	N	100	90		3	21
	PHKD6N02LT	N	20	20		10.9	
	PHN203	N	30	30	55	6.3	
	PHN210T	N	30	100	200	3.4	

Complementary MOSFETs

Package	Products	Channel	V_{DS} [max] (V)	$R_{DS(on)}$ [max] @ V_{GS} = 10 V (mΩ)	I_D [max] (A)	$Q_{G(tot)}$ [typ] (nC)
SO8 (SOT96) 	PHC2300	N	300	6000	0.34	6.24
		P	-300	17000	-0.235	2.14
SO8 (SOT96) 	PHC21025	N	30	100	3.5	10
		P	-30	250	-2.3	10

Power MOSFETs nomenclature

PSM N 4R0 - 30 Y L D

Segment
Power silicon max

Channel
N = N-channel
P = P-channel
X = Dual

$R_{DS(on)}$ in mΩ
4R0 means 4mΩ max at 25 °C

Voltage rating
BV_{DSS} rating

Package type
- B = D^2PAK
- D = DPAK
- E = I^2PAK
- K = SO8
- L = DFN56AD
- P = TO220
- Y = LFPAK56
- M = LFPAK33

Gate threshold voltage
- L = Logic level
- S = Standard level
- U = Ultra low gate
- X = Extremely low gate
- E = Enhanced logic

Technology family, e.g.
- C = NextPower
- D = NextPowerS3 (Super-fast Switching with Soft Recovery)
- E = NextPower Live (optimized for hot-swap applications)
- F = NextPower 80/100 V

Small-signal MOSFETs in DFN1006 and DFN1006B packages

Package																DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
																	
Size (mm)																1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
Ptot (mW)																250	250
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =							
										10 V	4.5 V	2.5 V	1.8 V	1.5 V	1.2 V		
N-channel	20	8	1.9	0.45	0.95	5.3	16	1.6	2	-	120	160	210	270	-	PMZ130UNE	
			1.6	0.45	0.95	5.3	16	1.6	2	-	170	200	240	300	-		PMZB150UNE
			1	0.5	0.95	6	86	0.45	2	-	270	360	470	600	-	PMZ290UNE2	PMZB290UNE2
			0.6	0.45	0.95	5.6	19	0.4	1	-	470	620	845	1125	2210	PMZ600UNE	PMZB600UNE
	30	8	1.5	0.45	0.95	5	17	1.6	2	-	210	240	270	300	-	PMZ200UNE	PMZB200UNE
			1	0.45	0.95	4	12	0.8	2	-	390	460	30	610	-	PMZ390UNE	PMZB390UNE
			0.59	0.45	0.95	4	12	0.6	2	-	550	660	770	890	-	PMZ550UNE	PMZB550UNE
	60	20	0.45	1.1	2.1	5	12	0.5	2	1000	1300	-	-	-	-	2N700BKM	2N7002BKMB
			0.35	1.1	2.1	4.7	6.9	1	2	2200	2500	-	-	-	-	NX7002BKM	NX7002BKMB
P-channel	20	8	1.4	0.45	0.95	4	26	1.3	1.8	-	330	420	520	-	-	PMZ350UPE	PMZB350UPE
			0.5	0.45	0.95	2.3	13.5	1.19	1	-	1020	1270	1700	2300	3500	PMZ950UPE	PMZB950UPE
	30	8	1	0.45	0.95	2.9	22	1.45	2	-	430	470	750	950	-	PMZ320UPE	PMZB320UPE
			0.41	0.45	0.95	3	14	0.7	2	-	1200	1700	2100	3000	-	PMZ1200UPE	PMZB1200UPE
	50	20	0.23	1.1	2.1	13	48	0.26	1	4500	5700	-	-	-	-	BSS84AKM	BSS84AKMB

Small-signal MOSFETs in DFN1010D-3 single and DFN1010B-3 dual packages

Package																	DFN1010D-3 (SOT1215)	DFN1010B-6 (SOT1216)
																		
Size (mm)																	1.1 x 1.0 x 0.37	1.1 x 1.0 x 0.37
P_{tot} (mW)																	1000	350
Configuration	Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =							
											10 V	4.5 V	2.5 V	1.8 V	1.5 V	1.2 V		
Single	N-channel	12	8	3.2	0.4	0.9	6	18	6.6	1	-	34	39	46	50	121	PMXB40UNE	
		20	8	3.2	0.5	0.9	6	17	5.7	1	-	42	48	56	64	-	PMXB43UNE	
		30	20	3.2	1	2	3	11	3.6	-	49	56	-	-	-	-	PMXB56EN	
				3.2	1	2.5	3	11	6	1	44	56	-	-	-	-	PMXB65ENE	
		80	20	1.1	1.3	2.7	2	9	3	2	345	390	-	-	-	-	PMXB360ENEA	
	P-channel	12	8	3.2	0.4	1	6.2	27	6.7	1.5	-	59	78	120	198	880	PMXB65UPE	
		20	8	2.9	0.4	1	6	29	6.8	1	-	69	86	130	205	950	PMXB75UPE	
				1.2	0.45	0.95	3	18	1.25	1.5	-	350	450	600	760	1200	PMXB350UPE	
		30	20	2.4	1	2.5	4	16	6.2	1	100	125	-	-	-	-	PMXB120EPE	
Dual	N-ch	20	8	0.6	0.45	0.95	5.6	19	0.4	1	-	470	620	845	1125	2210		PMDXB600UNE
		30	8	0.59	0.45	0.95	4	12	0.6	2	-	550	660	770	890	-		PMDXB550UNE
		60	20	0.26	1.1	2.1	4.7	6.9	1	2	2200	2500	-	-	-	-		NX7002BKXB
	P-ch	20	8	0.5	0.45	0.95	2.3	13.5	1.19	1	-	1020	1270	1700	2300	3500		PMDXB950UPE
		30	8	0.41	0.45	0.95	3	14	0.7	2	-	1200	1700	2100	3000	-		PMDXB1200UPE
Complementary	N	20	8	0.6	0.45	0.95	5.6	19	0.4	1	-	470	620	845	1125	2210		PMCXB900UE
	P	20	8	0.5	0.45	0.95	2.3	13.5	1.19	1	-	1020	1270	1700	2300	3500		
	N	30	8	0.59	0.45	0.95	4	12	0.6	2	-	550	660	770	890	-		PMCXB1000UE
	P	30	8	0.41	0.45	0.95	3	14	0.7	2	-	1200	1700	2100	3000	-		

Small-signal low-leakage MOSFETs

types in **bold** represent new products

Package															DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)	DFN1010B-6 (SOT1216)
																	
Size (mm)															1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37	1.1 x 1.0 x 0.37
Ptot (mW)															250	250	350
Config.	Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	I_{DSS} max (nA)	I_{GSS} max (nA)	ESD Protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =							
										4.5 V	2.5 V	1.8 V	1.5 V	1.2 V			
Single	N	20	8	0.6	0.45	0.95	25	50	1	470	620	845	1125	2210	**PMZ600UNEL**	**PMZB600UNEL**	
	P	20	8	0.5	0.45	0.95	25	50	1	1020	1270	1700	2300	3500	**PMZ950UPEL**	**PMZB950UPEL**	
Dual	N	20	8	0.6	0.45	0.95	25	50	1	470	620	845	1125	2210			**PMDXB600UNEL**
	P	20	8	0.5	0.45	0.95	25	50	1	1020	1270	1700	2300	3500			**PMDXB950UPEL**
Compl.	N	20	8	0.6	0.45	0.95	25	50	1	470	620	845	1125	2210			**PMCXB900UEL**
	P	20	8	0.5	0.45	0.95	25	50	1	1020	1270	1700	2300	3500			

Small-signal MOSFETs in DFN2020MD-6 single and DFN2020-6 dual packages

Package															DFN2020MD-6 (SOT1220)	DFN2020-6 (SOT1118)
																
Size (mm)															2.0 x 2.0 x 0.65	2.0 x 2.0 x 0.65
P_{tot} (mW)															1250	1250
Configuration	Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protec-tion (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =					
											10 V	4.5 V	2.5 V	1.8 V		
Single	N-channel	20	8	11.3	0.4	1	9	26	8.8	2	-	14	17	21	PMPB12UNE	
			12	12.9	0.4	0.9	13	54	23	2.2	-	10	12	16	PMPB10XNE	
				5.9	0.75	1.25	16	49	31	2	-	14	20	-	PMPB20XNEA	
				10.4	0.4	0.9	9	31	13.4	-	-	18	21	23	PMPB15XN	
				10.1	0.4	0.9	9	31	11.6	2.1	-	19	23	31	PMPB23XNE	
		30	12	11.3	0.4	0.9	12	54	24	2.2	-	13	14	17	PMPB13XNE	
				5	0.4	0.9	8	33	12.4	2.1	-	28	32	37	PMPB29XNE	
				5.5	0.45	1.2	6	21	5.1	-	-	37	55	-	PMPB33XN	
			20	13	1	2	9	17	13.7	-	12	14	-	-	PMPB11EN	
				10.4	1	2	9	9	7.2	-	16.5	20.5	-	-	PMPB20EN	
		60	20	4	1.3	2.7	4.5	13.5	7.5	1	42	48	-	-	PMPB55ENEA	
				3	1.3	2.7	4	10.5	6.2	2.7	72	85	-	-	PMPB85ENEA	
		80	20	2.8	1.3	2.7	5	15	9.9	2.8	80	92	-	-	PMPB95ENEA	
				1.9	1.3	2.7	3.5	9.5	4.8	2	175	195	-	-	PMPB215ENEA	
	P-channel	12	12	11.8	0.47	0.9	18	85	67	-	-	15	17	21	PMPB15XP	
		20	12	10.3	0.47	0.9	16	43	28.8	-	-	19	21	27	PMPB19XP	
				10.3	0.47	0.9	13	92	30	2.4	-	19	22	28	PMPB20XPE	
				5	0.47	0.9	12	91	30	2.3	-	28	31	36	PMPB29XPE	
				7.9	0.47	0.9	12	62	15	-	-	30	35	45	PMPB33XP	
				5	0.47	0.9	9	57	15.6	2.3	-	39	45	56	PMPB43XPE	
		30	12	5	0.47	0.9	15	28	14	-	-	47	54	74	PMPB47XP	
			20	8.8	1	2.5	10	28	30	-	24	32	-	-	PMPB27EP	
				6.8	1	2.5	7.4	27	17	-	40	55	-	-	PMPB48EP	
Dual	N-ch	20	12	5.3	0.4	0.9	4	40	14.4	-	-	32	40	60		PMDPB30XN
		30	12	3.1	0.75	1.25	9	19	2.9	2	-	55	72	-		PMDPB56XNEA
				3.1	0.5	1.5	6	18	1.65	1.8	-	95	130	-		PMDPB95XNE2
	P-channel	20	8	4.5	0.45	0.95	7	41	6.3	2	-	58	74	97		PMDPB58UPE
				3.7	0.45	0.95	6	47	5.4	2	-	82	107	142		PMDPB85UPE
			12	4.5	0.47	0.9	4	135	16.5	-	-	55	75	110		PMDPB55XP
				4.2	0.75	1.25	7	33	5	2	-	66	98			PMDPB70XPE
				3.7	0.4	1	6	120	5.7	-	-	80	95	120		PMDPB80XP
		30	12	3.8	0.45	1	3	112	5.2	-	-	70	89	-		PMDPB70XP
MOSFET-Schottky	P-channel	20	12	3.7	0.4	1	6	120	5.7	-	-	80	95	120		PMFPB8032XP
Pre-biased NPN	P	30	12	3.4	0.45	1	3	112	5.2	-	-	85	105	-		PMC85XP
Complementary	N	20	12	5.3	0.4	0.9	4	40	14.4	-	-	26	33	50		PMCPB5530X
	P	20	12	4.5	0.4	0.9	4	40	8.1	-	-	55	75	110		

Small-signal MOSFETs in WLCSP4 and WLCSP6 packages

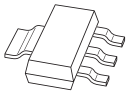
types in **bold** represent new products

Package											WLCSP4	WLCSP6
												
Size (mm)											0.78 x 0.78 x 0.35	1.48 x 0.98 x 0.35
P_{tot} (mW)											1300	1300
Configuration	Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =					
											4.5 V	2.5 V	1.8 V	1.5 V		
	N	12	8	6	0.4	0.9	6.3	30	6	2	36	46	60	86	PMCM4401VNE	
		20	8	4.3	0.4	0.9				2	42	47	67	82	**PMCM4401UNE**	
	P	12	8	4.9	0.4	0.9	4.8	25.1	6.8	2	55	77	110	-	PMCM4401VPE	
		20	8	4	0.4	0.9	4	31	5.9	2	75	95	130	-	**PMCM4401UPE**	
				3.6	0.4	0.9				2	65	85	120		**PMCM4402UPE**	
	N	12	8	9.6	0.4	0.9	10.8	97.5	16.1	2	15	18	22	30		PMCM6501VNE
		20	8	6.8	0.4	0.9				2	18	20	25	29		**PMCM6501UNE**
	P	12	8	8.2	0.4	0.9	8	72	19.6	2	19	25	37	-		PMCM6501VPE
		20	8	5.8	0.4	0.9				2	24	32	46	-		**PMCM6501UPE**
Common-drain	N	12	8	4.9	0.4	0.9				2	32	46	64	-		**PMCM6501CVNE**
		20	8	4.2	0.4	0.9				2	42	60	75	-		**PMCM6501CUNE**

Small-signal MOSFETs single (N-channel)

Package												
Size (mm)												
P_{tot} (mW)												
V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =			
									10 V	4.5 V	2.5 V	1.8 V
20	8	4.7	0.45	1	8.2	39.5	6.2	2	-	24	29	40
		1.9	0.4	1	8	31	2.2	2	-	63	77	114
		2.2	0.4	1	6	21	2.6	2	-	64	78	110
		1.9	0.45	0.95	5.3	16	1.6	2	-	120	155	195
		1.6	0.45	0.95	5.3	16	1.6	2	-	155	190	235
		1	0.5	0.95	6	86	0.45	2	-	270	360	470
		0.6	0.45	0.95	5.6	19	0.4	1	-	470	620	845
	12	6.3	0.75	1.25	16	44	9.9	2	-	16	24	-
		8.6	0.47	0.9	7	135	7.7	-	-	15	18	22
		9.1	0.4	0.9	9	31	12	1	-	15	19	22
		5.4	0.4	0.9	7	35	6.2	-	-	24	30	40
		6	0.4	0.9	5.5	22	5.1	1	-	28	38	42
30	8	1.5	0.45	0.95	5	17	1.6	2	-	210	240	270
		1	0.45	0.95	4	12	0.8	2	-	390	460	530
		0.59	0.45	0.95	4	12	0.6	2	-	550	660	770
		0.4	0.6	1.1	26	88	0.52	2	-	1000	1400	2000
	12	7.2	0.4	0.9	8	33	12.4	2	-	19	22	17
		5.7	0.4	0.9	9	34	7	-	-	33	42	54
		4.4	0.4	0.9	9	34	7	-	-	36	43	56
		0.9	0.5	1.5	8	11	0.74	2	-	234	324	-
	20	7.6	1	2	9	9	7.2	-	17	21	-	-
		5.5	1	2.5	8	33	12.6	2	17	22	-	-
		3.9	1	2.5	6.3	14.1	6	2	30	39	-	-
		3.1	1	2.5	18	78	6.5	-	28	37	-	-
		4.5	1	2.5	3	11	6	1	30	44	-	-
		5.1	1	2	3	11	3.6	-	35	43	-	-
		2.1	1	2.5	3	15	2.6	2	70	90	-	-
		0.18	0.8	1.5	10	51	0.34	-	2700	3000	4000	-
40	20	2.7	1	2.5	6	12	4.1	1	64	79	-	-
		2.5	1	2.5	14	14	2.4	1	95	120	-	-
55	10	0.3	0.4	1.3	4	11	1	3	-	2300	2400	3100
60	20	3.1	1.3	2.7	9	33	12.7	2	46	52		-
		2.1	1.3	2.7	6.4	15.9	5.9	2	96	108	-	-
		1.5	1.3	2.7	6.3	13	3.9	2	176	196	-	-
		0.8	1.3	2.7	5.3	10.2	2.4	2	300	332	-	-
		0.19	0.8	1.5	6	11	0.33	yes	2800	3500	4500	-
		0.27	0.5	1.5	7.9	12.5	0.49	2	2100	2200	2600	-
		0.1	0.6	1.4	2	5		2	2800	3800	-	-
		0.19	1.1	2.1	12	34	0.33	yes	3000	3700	-	-
		0.27	1.1	2.1	4.7	6.9	1	2	2200	2500	-	-
100	20	1.5	1.3	2.7	4.8	9.3	4.5	1	285	300	-	-
		1.1	1.3	2.7	5.7	10.2	2.9	1	527	555	-	-

types in **bold** represent new products

	SOT223	SOT457 (SC-74)	SOT23	SOT323 (SC-70)	DFN1006 (SOT883)	DFN1006B (SOT883B)
						
	6.5 x 3.5 x 1.65	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
	1700	600	250	200	250	250
		PMN28UNEA	PMV28UNEA			
				PMF63UNE		
			PMV65UNE			
					PMZ130UNE	
						PMZB150UNE
					PMZ290UNE2	PMZB290UNE2
					PMZ600UNE	PMZB600UNE
			PMV20XNEA			
			PMV16XN			
		PMN16XNE				
			PMV30UN2			
		PMN30UNE				
					PMZ200UNE	PMZB200UNE
					PMZ390UNE	PMZB390UNE
					PMZ550UNE	PMZB550UNE
			NX3008NBK	NX3008NBKW		
			PMV20XNE			
		PMN30UN				
			PMV40UN2			
				PMF250XNE		
			PMV20EN			
		PMN25ENEA	PMV25ENEA			
			PMV50ENEA			
			PMV37EN2			
		PMN40ENE	PMV42ENE			
			PMV45EN2			
			PMV90ENE			
			NX3020NAK	NX3020NAKW		
			PMV65ENEA			
			PMV130ENEA			
			BSH111BK			
		PMN55ENEA	PMV55ENEA			
		PMN120ENEA	PMV120ENEA			
		PMN230ENEA	PMV230ENEA			
			PMV450ENEA			
			NX138AK	NX138AKW		
			NX138BK	NX138BKW		
			BSN20BK			
			NX7002AK	NX7002AKW		
			NX7002BK	NX7002BKW	NX7002BKM	NX7002BKMB
	PMT280ENEA		**PMV280ENEA**			
	PMT560ENEA					

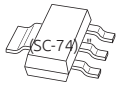
Small-signal MOSFETs single (P-channel)

Package												
Size (mm)												
P_{tot} (mW)												
V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =			
									10 V	4.5 V	2.5 V	1.8 V
20	8	5.6	0.45	0.95	11	83	14.7	2	-	27	38	50
		5.3	0.45	0.95	41	122	14.7	2	-	30	38	51
		5.4	0.45	0.95	34	128	15.5	-	-	34	42	57
		4	0.47	0.9	400	2180	10.5	3	-	50	57	70
		2	0.5	1.1	7	50	6	-	-	100	155	210
		1.2	0.45	0.95	33	52	3.3	-	-	170	210	280
		2.3	0.45	0.95	5	43	3.7	-	-	120	150	200
		1.4	0.45	0.95	9	35	1.3	1.8	-	330	420	520
		0.5	0.45	0.95	2.3	13.5	1.19	1	-	1020	1270	1700
	12	4.5	0.75	1.25	7.9	59	11	2	-	28	42	-
		6.8	0.47	0.9	12	62	15	-	-	30	35	48
		5.7	0.75	1.25	44	60	11.5	2	-	41	56	-
		4.1 / 3.5	0.75	1.25	24	84	8.5	-	-	48	71	-
		4.4	0.47	0.9	7	135	7.7	-	-	48	60	82
		4.7	0.47	0.9	5.1	141	8.5	-	-	50	64	88
		3.9	0.55	0.95	28	101	7.6	-	-	65	90	-
		3.3	0.75	1.25	7	36	5	2	-	67	99	-
		4.1	0.75	1.25	20	57	5.2	2	-	70	101	-
		3.9	0.47	0.9	6	120	5	-	-	72	88	110
		3.2	0.47	0.9	6	120	5	-	-	77	95	120
		2	0.65	1.15	48	64	4.8	-	-	90	125	-
		2.3	0.7	1.3	5.3	36	3.4	2	-	100	155	-
		1	0.65	1.15	26	44	2.6	-	-	175	240	-
30	8	1	0.45	0.95	2.9	22	1.45	2	-	400	480	600
		0.41	0.45	0.95	3	14	0.7	2	-	1200	1700	2100
		0.23	0.6	1.1	49	103	0.55	2	-	2800	5300	-
	20	5.3	1	3	6	36	12.8	2	35	49	-	-
		4.2	1	3	6	36	12.8	2	35	49	-	-
		4.4	1	3	5	19	6.5	2	60	96	-	-
40	20	1.8	1	2.5	10	40	4.7	1	180	220	-	-
50	20	0.2	1.1	2.1	24	73	0.26	1	5300	6000	-	-
70	20	2.4	1	3	6	42	10.6	2	130	150	-	-

Small-signal MOSFET–Schottky combination

Package														DFN2020-6 (SOT1118)
														
Size (mm)														2.0 x 2.0 x 0.65
P_{tot} (mW)														1250
Configuration	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	I_F (A)	V_R (V)	V_F typ. (mV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =			
												4.5 V	2.5 V	1.8 V	
Single + schottky	20	8	3.7	0.4	1	20	170	5.7	2	30	455	80	95	120	PMFPB8040XP

types in **bold** represent new products

	SOT223	SOT457 (SC-74)	SOT23	SOT363 (SC-88)	SOT323 (SC-70)	DFN1006-3 (SOT883)	DFN1006B-3 (SOT883B)
							
	6.5 x 3.5 x 1.65	2.9 x 1.5 x 1.0	2.9 x 1.3 x 1.0	2.0 x 1.25 x 0.95	2.0 x 1.25 x 0.95	1.0 x 0.6 x 0.48	1.0 x 0.6 x 0.37
	1700	600	250	300	200	250	250
			PMV27UPE				
			PMV33UPE				
			PMV32UP				
			PMV50UPE				
			NX2301P				
			PMV160UP				
			BSH205G2				
						PMZ350UPE	PMZB350UPE
						PMZ950UPE	PMZB950UPE
		PMN30XPEA	PMV30XPEA				
		PMN30XP					
		PMN48XP	PMV48XP				
			PMV50XP				
		PMN52XP					
			PMV65XP				
			PMV65XPE				
		PMN70XPE					
		PMN70XP					
			PMV75UP				
				PMG85XP			
			PMV100XPEA				
					PMF170XP		
						PMZ320UPE	PMZB320UPE
						PMZ1200UPE	PMZB1200UPE
			NX3008PBK		NX3008PBKW		
			PMV35EPE				
		PMN50EPEA					
		PMN70EPE					
			PMV250EPEA				
			BSS84AK		BSS84AKW	BSS84AKM	BSS84AKMB
	PMT200EPEA						

Small-signal MOSFETs dual

Package										
Size (mm)										
P_{tot} (mW)										
Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	$V_{GS(th)}$ min (V)	$V_{GS(th)}$ max (V)	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	
N-channel	20	8	0.8	0.5	0.95	10	117	0.45	2	
			0.6	0.45	0.95	5.6	19	0.4	1	
		12	5.3	0.4	0.9	4	40	14.4	-	
	30	8	0.59	0.45	0.95	4	12	0.6	2	
			0.35	0.6	1.1	26	88	0.52	2	
		12	3.1	0.75	1.25	9	19	2.9	2	
			3.1	0.5	1.5	6	18	1.65	1.8	
			1	0.5	1.5	6.5	14	0.7	2	
		20	0.18	0.8	1.5	10	51	0.34	yes	
	60	20	0.18	0.8	1.5	6	11	0.33	yes	
			0.26	0.5	1.5	7.9	12.5	0.49	2	
			0.17	1.1	2.1	12	34	0.33	yes	
			0.26	1.1	2.1	4.7	6.9	1	2	
P-channel	20	8	0.55	0.5	1.3	48	152	0.76	2	
			4.5	0.45	0.95	7	41	6.3	2	
			0.5	0.45	0.95	2.3	13.5	1.19	1	
			3.7	0.45	0.95	6	47	5.4	2	
		12	4.5	0.47	0.9	4	135	16.5	-	
			4.2	0.75	1	7	33	5	2	
			3.7	0.4	1	6	120	5.7	-	
	30	8	0.41	0.45	0.95	3	14	0.7	2	
			0.2	0.6	1.1	49	103	0.55	2	
		12	3.8	0.45	1	3	112	5.2	-	
	50	20	0.16	1.1	2.1	24	73	0.26	1	

Small-signal MOSFETs complementary

Package	Type	Polarity	V_{DS} (V)	V_{GS} (V)	I_D (A)	V_{GSth} min (V)	V_{GSth} max (V)	
 SOT666 (1.6 x 1.2 x 0.55)	NX1029X	N	60	20	0.33	1.1	2.1	
		P	50	20	0.17	1.1	2.1	
	NX3008CBKV	N	30	8	0.4	0.6	1.1	
		P	30	8	0.22	0.6	1.1	
	PMDT290UCE	N	20	8	0.8	0.5	0.95	
		P	20	8	0.55	0.5	1.3	
 SOT363 (SC-88) (2.0 x 1.25 x 0.95)	NX3008CBKS	N	30	8	0.35	0.6	1.1	
		P	30	8	0.2	0.6	1.1	
 DFN1010B-6 (1.1 x 1.0 x 0.37)	PMCXB900UE	N	20	8	0.6	0.45	0.95	
		P	20	8	0.5	0.45	0.95	
	PMCXB1000UE	N	30	8	0.59	0.45	0.95	
		P	30	8	0.41	0.45	0.95	
 DFN2020-6 (2.0 x 2.0 x 0.65)	PMCPB5530X	N	20	12	5.3	0.4	0.9	
		P	20	12	4.5	0.47	0.9	

types in **bold** represent new products

					SOT363 (SC-88)	SOT666	DFN2020-6 (SOT1118)	DFN1010B-6 (SOT1216)
								
					2.0 x 1.25 x 0.95	1.6 x 1.2 x 0.55	2.0 x 2.0 x 0.65	1.0 x 1.0 x 0.37
					300	300	1250	350
	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =							
	10 V	4.5 V	2.5 V	1.8 V				
	-	290	420	600		PMDT290UNE		
	-	470	620	845				PMDXB600UNE
	-	32	40	60			PMDPB30XN	
	-	550	660	770				PMDXB550UNE
	-	1000	1400	2000	NX3008NBKS	NX3008NBKV		
	-	55	72	-			PMDPB56XNEA	
	-	95	130	-			PMDPB95XNE2	
	-	170	240	-	PMGD175XNE			
	2700	3000	4000	-	NX3020NAKS	NX3020NAKV		
	2800	3500	4500	-	NX138AKS			
	2100	2200	2600	-	NX138BKS			
	3000	3700	-	-	NX7002AKS			
	2200	2500	-	-	NX7002BKS			NX7002BKXB
	-	670	1200	1800		PMDT670UPE		
	-	58	74	97			PMDPB58UPE	
	-	1020	1270	1700				PMDXB950UPE
	-	82	107	142			PMDPB85UPE	
	-	55	75	110			PMDPB55XP	
	-	66	98	-			PMDPB70XPE	
	-	80	95	120			PMDPB80XP	
	-	1200	1700	2100				PMDXB1200UPE
	-	2800	5300	-	NX3008PBKS	NX3008PBKV		
	-	70	89	-			PMDPB70XP	
	4500	5700	-	-	BSS84AKS	BSS84AKV		

types in **bold** represent new products

	t_{on} typ (ns)	t_{off} typ (ns)	Q_G typ (nC)	ESD protection (kV)	$R_{DS(on)}$ typ (mΩ) @ V_{GS} =					
					10 V	4.5 V	2.5 V	1.8 V	1.5 V	1.2 V
	11	19	0.5	2	1000	1300	-	-	-	-
	24	73	0.26	1	4500	5100	-	-	-	-
	26	88	0.52	2	-	1000	1400	2000	-	-
	49	103	0.55	2	-	2800	5300	-	-	-
	10	117	0.45	2	-	290	420	600	-	-
	48	152	0.76	2	-	670	1200	1800	-	-
	26	88	0.52	2	-	1000	1400	2000	-	-
	49	103	0.55	2	-	2800	5300	-	-	-
	5.6	19	0.4	1	-	470	620	845	1125	2210
	2.3	13.5	1.19	1	-	1020	1270	1700	2300	3500
	4	12	0.6	2	-	550	660	770	890	-
	3	14	0.7	2	-	1200	1700	2100	3000	-
	19	56	14.4	-	-	26	33	50	-	-
	18	56	16.5	-	-	55	75	110	-	-

Logic 5

Mini Buffers Inverters

Type number	Description	Features				Package (suffix)						
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT505-2 (DP)	SOT765-1 (DC)	SOT996-2 (GD)
74AHC1G17-Q100	Single buffer	2.0 - 5.5	± 8	3,1	-40~125	•						
74AHCT1G17-Q100	Single buffer; TTL-enabled	4.5 - 5.5	± 8	3,4	-40~125	•						
74LVC2G126-Q100	Dual buffer/line driver (3-state)	1.65 - 5.5	± 32	2,4	-40~125					•	•	

Mini Digital Decoders Demultiplexers

Type number	Description	Features				Package (suffix)	
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)
74LVC1G19-Q100	1-to-2 demultiplexer	1.65 - 5.5	± 32	1,8	-40~125	•	

Mini Flip-flops

Type number	Description	Features				Package (suffix)						
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT505-2 (DP)	SOT765-1 (DC)	SOT996-2 (GD)
74AUP1G74-Q100	Single D-type flip-flop with set and reset; positive-edge trigger	1.1 - 3.6	± 1.9	8,1	-40~125						•	
74LVC1G79-Q100	Single D-type flip-flop; positive-edge trigger	1.65 - 5.5	± 32	2,2	-40~125	•	•					

Mini Gates

Type number	Description	Features				Package (suffix)						
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT353-1 (GW)	SOT753 (GV)	SOT363 (GW)	SOT457 (GV)	SOT505-2 (DP)	SOT765-1 (DC)	SOT996-2 (GD)
74AHC2G08-Q100	Dual 2-input AND gate	2.0 - 5.5	± 8	3,2	-40~125					•	•	•
74AHCT2G08-Q100	Dual 2-Input AND gate; TTL-enabled	4.5 - 5.5	± 8	3,6	-40~125					•	•	•
74AHC2G32-Q100	Dual 2-input OR gate	2.0 - 5.5	± 8	3,2	-40~125					•	•	•
74AHCT2G32-Q100	Dual 2-input OR gate; TTL-enabled	4.5 - 5.5	± 8	3,3	-40~125					•	•	•
74LVC1G10-Q100	Single 2-input NAND gate	1.65 - 5.5	± 32	2,6	-40~125			•				
74LVC2G00-Q100	Dual 2-input NAND gate	1.65 - 5.5	± 32	2,2	-40~125						•	

Mini Level shifters/translators

Type number	Description	Features				Package (suffix)				
		V_{CC}(A) (V)	V_{CC}(B) (V)	I_O (mA)	T_{amb} (°C)	SOT353-1 (GW)	SOT363 (GW)	SOT505-2 (DP)	SOT765-1 (DC)	SOT996-2 (GD)
74AXP1T57-Q100	Dual-supply translating configurable multiple function gate	0.7 - 2.75	1.2 - 5.5	± 12	-40~125				•	
74AXP2T08-Q100	Dual-supply translating dual 2-input AND gate	0.7 - 2.75	1.2 - 5.5	± 12	-40~125			•		

Standard Analog switches

Type number	Description	Features					Package (suffix)								
		Configuration	V_{CC} (V)	R_{ON} (Ω)	R_{ON} (FLAT) (Ω)	T_{amb} (°C)	SOT108-1 (D)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT137-1 (D)	SOT355-1 (PW)	SOT815-1 (BQ)
74HC4067-Q100	Single-pole, 16-throw analog switch	SP16T-Z	2.0 - 10.0	200	25	-40~125							•	•	•
74HCT4067-Q100	Single-pole, 16-throw analog switch	SP16T-Z	4.5 - 5.5	225	25	-40~125							•	•	•

Standard Bus switches

Type number	Description	Features				Package (suffix)								
		V_{CC} (V)	V_{PASS} (V)	R_{ON} (Ω)	T_{amb} (°C)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT403-1 (PW)	SOT519-1 (DS)	SOT763-1 (BQ)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)
74CBTLV3245-Q100	Octal bus switch	2.3 - 3.6	3,3	7	-40~125								•	•
74CBTLVD3245-Q100	Octal bus switch level translator	3.0 - 3.6	1,8	7	-40~125								•	•

Standard Digital multiplexers

Type number	Description	Features				Package (suffix)			
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT109-1 (D)	SOT338-1 (DB)	SOT403-1 (PW)	SOT763-1 (BQ)
74HC257-Q100	Quad 2-input multiplexer (3-State)	2.0 - 6.0	± 7.8	11	-40~125	•		•	
74HCT257-Q100	Quad 2-input multiplexer; TTL-enabled (3-State)	4.5 - 5.5	± 6	13	-40~125	•		•	

Standard Flip-flops

Type number	Description	Features				Package (suffix)												
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT337-1 (DB)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT162-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT339-1 (DB)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT362-1 (DGG)	SOT815-1 (BQ)
74HC109-Q100	Dual J-K flip-flop with set and reset; positive-edge trigger	2.0 - 6.0	± 5.2	15	-40~125	•												
74HCT109-Q100	Dual J-K flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 - 5.5	± 4	17	-40~125	•												
74LVC823A-Q100	9-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 - 3.6	± 24	5,4	-40~125													•

Standard Gates

Type number	Description	Features				Package (suffix)			
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT337-1 (DB)	SOT402-1 (PW)	SOT762-1 (BQ)
HEF4082B-Q100	Dual 4-input AND gate	4.5 - 15.5	± 2.4	25	-40~85	•			

Standard Level Shifters-Translators

Type number	Description	Features				Package (suffix)								
		$V_{CC(A)}$ (V)	$V_{CC(B)}$ (V)	I_O (mA)	T_{amb} (°C)	SOT109-1 (D)	SOT403-1 (PW)	SOT763-1 (BQ)	SOT137-1 (D)	SOT355-1 (PW)	SOT815-1 (BQ)	SOT362-1 (DGG)	SOT480-1 (DGV)	SOT364-1 (DGG)
74AVC20T245-Q100	20-bit dual-supply voltage level translating transceiver (3-state)	0.8 - 3.6	0.8 - 3.6	± 12	-40~125									•

Standard Shift Registers

Type number	Description	Features				Package (suffix)								
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT108-1 (D)	SOT337-1 (DB)	SOT402-1 (PW)	SOT762-1 (BQ)	SOT109-1 (D)	SOT162-1 (D)	SOT403-1 (PW)	SOT163-1 (D)	SOT339-1 (DB)
74HC594-Q100	8-bit serial-in/parallel-out shift register with output storage register	2.0 - 6.0	± 7.8	14	-40~125				•		•			

Standard Transceivers

Type number	Description	Features				Package (suffix)				
		V_{CC} (V)	I_O (mA)	t_{pd} (ns)	T_{amb} (°C)	SOT163-1 (D)	SOT360-1 (PW)	SOT764-1 (BQ)	SOT362-1 (DGG)	SOT702-1 (EV)
74LVC162245A-Q100	16-bit transceiver with source termination (3-state)	1.2 - 3.6	± 12	3,3	-40~125				•	

Buffers/inverters/drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load $C_{L\ (Typ)}$	t_{pd} (ns)	f_{max} (MHz)	T_{amb} (°C)
74AHC04	Hex inverter	2.0 to 5.5	CMOS	±8	50 pF	3	60	-40 to +125
74AHCT04	Hex inverter; TTL-enabled	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74AHC125	Quad buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3	60	-40 to +125
74AHCT125	Quad buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74AHC126	Quad buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,3	60	-40 to +125
74AHCT126	Quad buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74AHC1G04	Single inverter	2.0 to 5.5	CMOS	±8	50 pF	3,1	60	-40 to +125
74AHCT14	Hex inverting Schmitt-trigger	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHCT1G04	Single inverter; TTL-enabled	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHC1G06	Single inverter; open drain	2.0 to 5.5	CMOS	8	50 pF	2,7	60	-40 to +125
74AHCT1G06	Single inverter; open drain; TTL-enabled	4.5 to 5.5	TTL	8	50 pF	3	60	-40 to +125
74AHC1G07	Single buffer; open drain	2.0 to 5.5	CMOS	8	50 pF	2,5	60	-40 to +125
74AHCT1G07	Single buffer; open drain; TTL-enabled	4.5 to 5.5	TTL	8	50 pF	2,8	60	-40 to +125
74AHC1G125	Single buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125
74AHCT1G125	Single buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHC1G126	Single buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125
74AHCT1G126	Single buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHC1G17	Single buffer with Schmitt-trigger inputs	2.0 to 5.5	CMOS	±8	50 pF	3,2	60	-40 to +125
74AHCT1G17	Single buffer with Schmitt-trigger inputs; TTL-enabled	4.5 to 5.5	TTL	±8	50 pF	4,1	60	-40 to +125
74AHC240	Octal inverter/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	2,8	60	-40 to +125
74AHCT240	Octal inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74AHC244	Octal buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,5	60	-40 to +125
74AHCT244	Octal buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,5	60	-40 to +125
74AHC2G125	Dual buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125
74AHCT2G125	Dual buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHC2G126	Dual buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125
74AHCT2G126	Dual buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHC2G241	Dual buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125
74AHCT2G241	Dual buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
74AHC3G04	Triple inverter	2.0 to 5.5	CMOS	±8	50 pF	3,1	60	-40 to +125
74AHCT3G04	Triple inverter; TTL-enabled	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74AHC541	Octal buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,5	60	-40 to +125
74AHCT541	Octal buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,5	60	-40 to +125
74AHC1GU04	Single inverter; unbuffered	2.0 to 5.5	CMOS	±8	50 pF	2,6	60	-40 to +125
74AHC3GU04	Triple inverter; unbuffered	2.0 to 5.5	CMOS	±8	50 pF	2,5	60	-40 to +125
74AHCU04	Hex inverter; unbuffered	2.0 to 5.5	CMOS	±8	50 pF	2,4	60	-40 to +125
74ALVC16244	16-bit buffer/line driver (3-state)	1.2 to 3.6	LVTTL	±24	50 pF	1,9	150	-40 to +85
74ALVCH16244	16-bit buffer/line driver with bus hold (3-state)	1.2 to 3.6	LVTTL	±24	30 pF	1,9	150	-40 to +85

Buffers/inverters/drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load $C_{L\ (Typ)}$	t_{pd} (ns)	f_{max} (MHz)	T_{amb} (°C)
74ALVC04	Hex inverter	1.65 to 3.6	LVTTL	±24	30 pF	2	150	-40 to +85
74ALVC125	Quad buffer/line driver (3-state)	1.65 to 3.6	LVTTL	±24	30 pF	1,8	145	-40 to +85
74ALVC244	Octal buffer/line driver (3-state)	1.65 to 3.6	LVTTL	±24	30 pF	2,9	130	-40 to +85
74ALVC541	Octal buffer/line driver (3-state)	1.65 to 3.6	LVTTL	±24	30 pF	2,3	130	-40 to +85
74ALVCH162244	16-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	LVTTL	±12	30 pF	2,7	150	-40 to +85
74ALVCH162827	20-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	LVTTL	±12	30 pF	2,9	150	-40 to +85
74ALVCH16825	18-bit buffer/line driver with bus hold (3-state)	2.3 to 3.6	LVTTL	±24	30 pF	2	150	-40 to +85
74ALVCH16827	20-bit buffer/line driver with bus hold (3-state)	2.3 to 3.6	LVTTL	±24	30 pF	2	150	-40 to +85
74ALVT162240	16-bit inverter/line driver with bus hold and 30 Ω termination (3-state)	2.3 to 3.6	LVTTL	±12	50 pF	2,6	75	-40 to +85
74ALVT162241	16-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	LVTTL	±12	50 pF	2,2	75	-40 to +85
74ALVT162244	16-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	LVTTL	±12	50 pF	2,2	75	-40 to +85
74ALVT16240	16-bit inverter/line driver with bus hold (3-state)	2.3 to 3.6	LVTTL	-0,5	50 pF	1,7	200	-40 to +85
74ALVT16241	16-bit buffer/line driver with bus hold (3-state)	2.3 to 3.6	LVTTL	-0,5	50 pF	1,3	200	-40 to +85
74ALVT16244	16-bit buffer/line driver with bus hold (3-state)	2.3 to 3.6	LVTTL	-0,5	50 pF	1,5	200	-40 to +85
74ALVT162827	20-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	LVTTL	±12	50 pF	2,2	75	-40 to +85
74ALVT16827	20-bit buffer/line driver with bus hold (3-state)	2.3 to 3.6	LVTTL	-0,5	50 pF	1,3	200	-40 to +85
74AUP1G04	Single inverter	1.1 to 3.6	CMOS	±1.9	30 pF	4	70	-40 to +125
74AUP1G06	Single inverter; open drain	1.1 to 3.6	CMOS	1,9	30 pF	4,5	70	-40 to +125
74AUP1G07	Single buffer; open drain	1.1 to 3.6	CMOS	1,9	30 pF	4,4	70	-40 to +125
74AUP1G125	Single buffer/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,3	70	-40 to +125
74AUP1G126	Single buffer/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,3	70	-40 to +125
74AUP1G14	Single inverter; Schmitt trigger	1.1 to 3.6	CMOS	±1.9	30 pF	4,7	70	-40 to +125
74AUP1G16	Single Buffer	1.1 to 3.6	CMOS	±1.9	30pF	4,7	70	-40 to +125
74AUP1G240	Single inverter/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,2	70	-40 to +125
74AUP1G34	Single buffer	1.1 to 3.6	CMOS	±1.9	30 pF	3,9	70	-40 to +125
74AUP1GU04	Single inverter; unbuffered	1.1 to 3.6	CMOS	±1.9	30 pF	2,3	70	-40 to +125
74AUP2G04	Dual inverter	1.1 to 3.6	CMOS	±1.9	30 pF	4	70	-40 to +125
74AUP2G06	Dual inverter; open drain	1.1 to 3.6	CMOS	1,9	30 pF	4,5	70	-40 to +125
74AUP2G07	Dual buffer; open drain	1.1 to 3.6	CMOS	1,9	30 pF	4,4	70	-40 to +125
74AUP2G125	Dual buffer/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,3	70	-40 to +125
74AUP2G126	Dual buffer/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,3	70	-40 to +125
74AUP2G14	Dual inverter; Schmitt trigger	1.1 to 3.6	CMOS	±1.9	30 pF	4,7	70	-40 to +125
74AUP2G16	Dual Buffer	1.1 to 3.6	CMOS	±1.9	30pF	4,7	70	-40 to +125
74AUP2G240	Dual inverter/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,2	70	-40 to +125
74AUP2G241	Dual buffer/line driver (3-state)	1.1 to 3.6	CMOS	±1.9	30 pF	4,3	70	-40 to +125
74AUP2G34	Dual buffer	1.1 to 3.6	CMOS	±1.9	30 pF	3,9	70	-40 to +125
74AUP2GU04	Dual inverter; unbuffered	1.1 to 3.6	CMOS	±1.9	30 pF	2,3	70	-40 to +125
74AUP3G04	Triple inverter	1.1 to 3.6	CMOS	±1.9	30 pF	4	70	-40 to +125
74AUP3G14	Triple inverter; Schmitt trigger	1.1 to 3.6	CMOS	±1.9	30pF	4,7	70	-40 to +125

Buffers/inverters/drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load $C_{L\ (Typ)}$	t_{pd} (ns)	f_{max} (MHz)	T_{amb} (°C)
74AUP3G16	Triple Buffer	1.1 to 3.6	CMOS	±1.9	30pF	4	70	-40 to +125
74AVC16244	16-bit buffer/line driver (3-state)	0.8 to 3.6	CMOS/LVTTL	±12	30 pF	2	200	-40 to +85
74AVCH16244	16-bit buffer/line driver with bus hold (3-state)	0.8 to 3.6	CMOS/LVTTL	±12	30 pF	2	200	-40 to +85
74AXP1G06	Single inverter; open drain	0.7 to 2.75	CMOS	4,5	5pF	3,5	70	-40 to +85
74AXP1G125	Single buffer/line driver (3-state)	0.7 to 2.75	CMOS	±4.5	5pF	2,7	70	-40 to +85
74HC04	Hex inverter	2.0 to 6.0	CMOS	±5.2	50 pF	7	36	-40 to +125
74HCT04	Hex inverter; TTL-enabled	4.5 to 5.5	TTL	±4.0	50 pF	8	36	-40 to +125
74HC125	Quad buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT125	Quad buffer/line driver (3-state)	4.5 to 5.5	TTL	±6	50 pF	12	36	-40 to +125
74HC126	Quad buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT126	Quad buffer/line driver (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC1G04	Single inverter	2.0 to 6.0	CMOS	±2.6	50 pF	7	36	-40 to +125
74HCT1G04	Single inverter; TTL-enabled	4.5 to 5.5	TTL	±2.0	50 pF	8	36	-40 to +125
74HC1G125	Single buffer/line driver (3-state)	2.0 to 6.0	CMOS	±2.6	50 pF	9	36	-40 to +125
74HCT1G125	Single buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±2.0	50 pF	10	36	-40 to +125
74HC1G126	Single buffer/line driver (3-state)	2.0 to 6.0	CMOS	±2.6	50 pF	9	36	-40 to +125
74HCT1G126	Single buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±2.0	50 pF	10	36	-40 to +125
74HC240	Octal inverter/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT240	Octal inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	9	36	-40 to +125
74HCT240	Octal inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	9	36	-40 to +125
74HCT240	Octal inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	9	36	-40 to +125
74HC241	Octal buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	7	36	-40 to +125
74HCT241	Octal buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC244	Octal buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT244	Octal buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC2G04	Dual inverter	2.0 to 6.0	CMOS	±5.2	50 pF	8	36	-40 to +125
74HCT2G04	Dual inverter; TTL-enabled	4.5 to 5.5	TTL	±4.0	50 pF	10	36	-40 to +125
74HC2G125	Dual buffer/line driver (3-state)	2.0 to 6.0	CMOS	±5.2	50 pF	10	36	-40 to +125
74HC2G16	Dual buffer gate	2.0 to 6.0	CMOS	±5.2	50pF	10	36	-40 to +125
74HCT2G16	Dual buffer gate; TTL enabled	4.5 to 5.5	TTL	±4.0	50pF	12	36	-40 to +125
74HCT2G125	Dual buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±4.0	50 pF	12	36	-40 to +125
74HC2G126	Dual buffer/line driver (3-state)	2.0 to 6.0	CMOS	±5.2	50 pF	10	36	-40 to +125
74HC2G34	Dual buffer	2.0 to 6.0	CMOS	±5.2	50 pF	9	36	-40 to +125
74HCT2G34	Dual buffer; TTL-enabled	4.5 to 5.5	TTL	±4	50 pF	10	32	-40 to +125
74HC365	Hex buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT365	Hex buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC366	Hex inverter/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	10	36	-40 to +125
74HCT366	Hex inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC367	Hex buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	8	36	-40 to +125

Buffers/inverters/drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load $C_{L\ (Typ)}$	t_{pd} (ns)	f_{max} (MHz)	T_{amb} (°C)
74HCT367	Hex buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC368	Hex inverter/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT368	Hex inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC3G04	Triple inverter	2.0 to 6.0	CMOS	±5.2	50 pF	8	36	-40 to +125
74HCT3G04	Triple inverter; TTL-enabled	4.5 to 5.5	TTL	±4.0	50 pF	10	36	-40 to +125
74HC3G06	Triple inverter; open drain	2.0 to 6.0	CMOS	5,2	50 pF	9	36	-40 to +125
74HCT3G06	Triple inverter; open drain; TTL-enabled	4.5 to 5.5	TTL	4	50 pF	9	36	-40 to +125
74HC3G07	Triple buffer; open drain	2.0 to 6.0	CMOS	5,2	50 pF	9	36	-40 to +125
74HCT3G07	Triple buffer; open drain; TTL-enabled	4.5 to 5.5	TTL	4	50 pF	9	36	-40 to +125
74HC3G34	Triple buffer	2.0 to 6.0	CMOS	±5.2	50 pF	9	36	-40 to +125
74HCT3G34	Triple buffer; TTL-enabled	4.5 to 5.5	TTL	±4.0	50 pF	10	36	-40 to +125
74HC540	Octal inverter/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	9	36	-40 to +125
74HCT540	Octal inverter/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	11	36	-40 to +125
74HC541	Octal buffer/line driver (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	10	36	-40 to +125
74HCT541	Octal buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	12	36	-40 to +125
74HC05	Hex inverter; open drain	2.0 to 6.0	CMOS	5,2	50 pF	11	36	-40 to +125
74HC1GU04	Single inverter; unbuffered	2.0 to 6.0	CMOS	±2.6	50 pF	5	36	-40 to +125
74HC2GU04	Single inverter; unbuffered	2.0 to 6.0	CMOS	±2.6	50 pF	5	36	-40 to +125
74HC3GU04	Triple inverter; unbuffered	2.0 to 6.0	CMOS	±5.2	50 pF	6	36	-40 to +125
74HC3GU04	Triple inverter; unbuffered	2.0 to 6.0	CMOS	±5.2	50 pF	6	36	-40 to +125
74HCU04	Hex inverter; unbuffered	2.0 to 6.0	CMOS	±5.2	50 pF	5	36	-40 to +125
74LV04	Hex inverter	1.0 to 5.5	CMOS	±12	50 pF	6	30	-40 to +125
74LV125	Quad buffer/line driver (3-state)	1.0 to 5.5	CMOS	±16	50 pF	9	30	-40 to +125
74LV241	Octal buffer/line driver (3-state)	1.0 to 5.5	CMOS	±8	50 pF	8	30	-40 to +125
74LV244	Octal buffer/line driver (3-state)	1.0 to 5.5	CMOS	±16	50 pF	8	30	-40 to +125
74LV365	Hex buffer/line driver (3-state)	1.0 to 3.6	CMOS	±8	50 pF	9	30	-40 to +125
74LV367	Hex buffer/line driver (3-state)	1.0 to 3.6	CMOS	±8	50 pF	8	30	-40 to +125
74LV540	Octal buffer/line driver (3-state)	1.0 to 3.6	CMOS	±8	50 pF	10	30	-40 to +125
74LV541	Octal buffer/line driver (3-state)	1.0 to 3.6	CMOS	±8	50 pF	10	30	-40 to +125
74LVC162244	16-bit buffer/line driver with 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,9	175	-40 to +125
74LVCH162244	16-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	50 pF	2,9	175	-40 to +125
74LVC16244	16-bit buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	3	175	-40 to +125
74LVCH16244	16-bit buffer/line driver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	3	175	-40 to +125
74LVC244	Octal buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,8	175	-40 to +125
74LVCH244	Octal buffer/line driver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,8	175	-40 to +125
74LVC04	Hex inverter	1.65 to 5.5	CMOS/LVTTL	±24	50 pF	2	175	-40 to +125
74LVC06	Hex inverter; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,2	175	-40 to +125
74LVC07	Hex buffer; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,2	175	-40 to +125
74LV540	Octal buffer/line driver (3-state)	1.65 to 5.5	CMOS/LVTTL	32	50pF	2,2	175	-40 to +125

Buffers/inverters/drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load $C_{L\ (Typ)}$	t_{pd} (ns)	f_{max} (MHz)	T_{amb} (°C)
74LVC125	Quad buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,4	175	-40 to +125
74LVC126	Quad buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,4	175	-40 to +125
74LVC16240	16-bit inverter/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,7	175	-40 to +125
74LVC16241	16-bit buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,9	175	-40 to +125
74LVC1G04	Single inverter	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2	175	-40 to +125
74LVC1G06	Single inverter; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,3	175	-40 to +125
74LVC1G07	Single buffer; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,2	175	-40 to +125
74LVC1G16	Single buffer	1.65 to 5.5	CMOS/LVTTL	±24	50pF	2	175	-40 to +125
74LVC1G125	Single buffer/line driver; TTL-enabled (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,1	175	-40 to +125
74LVC1G126	Single buffer/line driver; TTL-enabled (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2	175	-40 to +125
74LVC1G34	Single buffer	1.65 to 5.5	CMOS/LVTTL	±24	50 pF	2	175	-40 to +125
74LVC1GU04	Single inverter; unbuffered	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	1,6	175	-40 to +125
74LVC2244	Octal buffer/line driver with 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	50 pF	3,1	175	-40 to +125
74LVC240	Octal inverter/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	3,5	175	-40 to +125
74LVC241	Octal buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	3,2	175	-40 to +125
74LVC2G04	Dual inverter	1.65 to 5.5	CMOS/LVTTL	±24	50 pF	2,7	175	-40 to +125
74LVC2G06	Dual inverter; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,3	175	-40 to +125
74LVC2G07	Dual buffer; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,6	175	-40 to +125
74LVC2G16	Dual buffer	1.65 to 5.5	CMOS/LVTTL	±24	50pF	2	175	-40 to +125
74LVC2G125	Dual buffer/line driver; TTL-enabled (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,3	175	-40 to +125
74LVC2G126	Dual buffer/line driver; TTL-enabled (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,4	175	-40 to +125
74LVC2G240	Dual inverter/line driver (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,5	175	-40 to +125
74LVC2G241	Dual buffer/line driver (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,6	175	-40 to +125
74LVC2G34	Dual buffer	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,2	175	-40 to +125
74LVC2GU04	Dual inverter; unbuffered	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,3	175	-40 to +125
74LVC3G04	Triple inverter	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,7	175	-40 to +125
74LVC3G06	Triple inverter; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2	175	-40 to +125
74LVC3G07	Triple buffer; open drain	1.65 to 5.5	CMOS/LVTTL	32	50 pF	2,1	175	-40 to +125
74LVC3G16	Triple buffer	1.65 to 5.5	CMOS/LVTTL	±24	50pF	2	175	-40 to +125
74LVC3G34	Triple buffer	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,2	175	-40 to +125
74LVC3GU04	Triple inverter; unbuffered	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,3	175	-40 to +125
74LVC541	Octal buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	3,3	175	-40 to +125
74LVC827	10-bit buffer/line driver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	4	175	-40 to +125
74LVCH16541	16-bit buffer/line driver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,7	175	-40 to +125
74LVCH322244	32-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	50 pF	2	175	-40 to +125
74LVCH32244	32-bit buffer/line driver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	3	175	-40 to +125
74LVCU04	Hex inverter; unbuffered	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2	175	-40 to +125
74LVT125	Quad buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,9	150	-40 to +85
74LVTH125	Quad buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,9	150	-40 to +85

Buffers/inverters/drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load $C_{L\ (Typ)}$	t_{pd} (ns)	f_{max} (MHz)	T_{amb} (°C)
74LVT16244	16-bit buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	1,8	150	-40 to +85
74LVTH16244	16-bit buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	1,8	150	-40 to +85
74LVT244	Octal buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,6	150	-40 to +85
74LVTH244	Octal buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,6	150	-40 to +85
74LVT244	Octal buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2	150	-40 to +85
74LVTH244	Octal buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2	150	-40 to +85
74LVT04	Hex inverter	2.7 to 3.6	TTL	-0,625	50 pF	2,6	150	-40 to +85
74LVT126	Quad buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,4	150	-40 to +85
74LVT162240	16-bit inverter/line driver with bus hold and 30 Ω termination (3-state)	2.7 to 3.6	TTL	±12	50 pF	2,6	150	-40 to +85
74LVT162244	16-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	50 pF	2,8	150	-40 to +85
74LVT16240	16-bit inverter/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2	150	-40 to +85
74LVT2241	Octal buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	50 pF	3,3	150	-40 to +85
74LVT2244	Octal buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	50 pF	2,9	150	-40 to +85
74LVT240	Octal inverter/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,5	150	-40 to +85
74LVT241	Octal buffer/line driver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	2,8	150	-40 to +85
74LVTN16244	16-bit buffer/line driver (3-state)	2.7 to 3.6	TTL	-0,5	50 pF	1,8	150	-40 to +85
74LVU04	Hex inverter; unbuffered	1.0 to 5.5	CMOS	-1	50 pF	6	30	-40 to +125
74VHC125	Quad buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3	60	-40 to +125
74VHCT125	Quad buffer/line driver (3-state)	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74VHC126	Quad buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,3	60	-40 to +125
74VHCT126	Quad buffer/line driver (3-state)	4.5 to 5.5	TTL	±8	50 pF	3	60	-40 to +125
74VHC244	Octal inverter/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,5	60	-40 to +125
74VHCT244	Octal inverter/line driver (3-state)	4.5 to 5.5	TTL	±8	50 pF	5	60	-40 to +125
74VHC541	Octal buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,5	60	-40 to +125
74VHCT541	Octal buffer/line driver (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,5	60	-40 to +125
HEF40098	Hex inverter	3.0 to 15.0	CMOS	-0,5	50 pF	25	10	-40 to +125
HEF40240	Octal inverter/line driver (3-state)	3.0 to 15.0	CMOS	-1,111111111	50 pF	30	10	-40 to +125
HEF40244	Octal buffer/line driver (3-state)	3.0 to 15.0	CMOS	-1,377777778	50 pF	30	10	-40 to +125
HEF4049	Hex inverter/line driver	3.0 to 15.0	CMOS	-0,15	50 pF	20	10	-40 to +125
HEF4050	Hex buffer/line driver	3.0 to 15.0	CMOS	-0,15	50 pF	40	10	-40 to +125
HEF4069	Hex inverter; unbuffered	3.0 to 15.0	CMOS	±3.4	50 pF	15	10	-40 to +125
XC7SET04	Single inverter; TTL-enabled	4.5 to 5.5	TTL	±8	50 pF	3,5	60	-40 to +125
XC7SET125	Single buffer/line driver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,4	60	-40 to +125
XC7SH04	Single inverter	2.0 to 5.5	CMOS	±8	50 pF	3,5	60	-40 to +125
XC7SH125	Single buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125
XC7SHU04	Single inverter; unbuffered	2.0 to 5.5	CMOS	±8	50 pF	3,5	60	-40 to +125
XC7WH126	Dual buffer/line driver (3-state)	2.0 to 5.5	CMOS	±8	50 pF	3,4	60	-40 to +125

Transceivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Number of bits	f_{max} (MHz)	T_{amb} (°C)
74AHC245	Octal transceiver (3-state)	2.0 to 5.5	CMOS	±8	3,5	8	60	50 pF
74AHCT245	Octal transceiver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	5	8	60	50 pF
74ALVC16245	16-bit transceiver (3-state)	1.65 to 3.6	TTL	±24	1,9	16	150	50 pF
74ALVCH16245	16-bit transceiver with bus hold (3-state)	1.65 to 3.6	TTL	±24	1,9	16	150	50 pF
74ALVC245	Octal transceiver (3-state)	1.65 to 3.6	TTL	±24	2,3	8	130	50 pF
74ALVCH162245	16-bit transceiver with bus hold and 30 Ω termination resistors (3-state)	1.65 to 3.6	TTL	±12	2,4	16	150	50 pF
74ALVCH162601	18-bit universal bus transceiver with bus hold and 30 Ω termination resistors; positive-edge trigger (3-state)	1.65 to 3.6	TTL	±12	3,1	18	150	50 pF
74ALVCH16500	18-bit universal bus transceiver with bus hold; negative edge trigger (3-state)	1.65 to 3.6	TTL	±24	2,9	18	150	50 pF
74ALVCH16501	18-bit universal bus transceiver with bus hold; positive edge trigger (3-state)	1.65 to 3.6	TTL	±24	2,8	18	150	50 pF
74ALVCH16543	16-bit registered transceiver with bus hold (3-state)	1.65 to 3.6	TTL	±24	3,8	16	150	50 pF
74ALVCH16600	18-bit universal bus transceiver with bus hold; negative edge trigger (3-state)	1.65 to 3.6	TTL	±24	2,8	18	150	50 pF
74ALVCH16601	18-bit universal bus transceiver with bus hold; positive edge trigger (3-state)	1.65 to 3.6	TTL	±24	2,8	18	150	50 pF
74ALVCH16646	16-bit registered transceiver with bus hold (3-state)	1.65 to 3.6	TTL	±24	2,6	16	150	50 pF
74ALVCH16952	16-bit registered transceiver with bus hold (3-state)	1.65 to 3.6	TTL	±24	3,2	16	150	50 pF
74ALVT162245	16-bit transceiver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	TTL	±12	2,3	16	75	50 pF
74ALVT16245	16-bit transceiver with bus hold (3-state)	2.3 to 3.6	TTL	-0,5	1,5	16	200	50 pF
74ALVT16501	18-bit universal bus transceiver with bus hold; positive edge trigger (3-state)	2.3 to 3.6	TTL	-0,5	1,8	18	150	50 pF
74ALVT16543	16-bit registered transceiver with bus hold (3-state)	2.3 to 3.6	TTL	-0,5	1,8	16	200	50 pF
74ALVT16601	18-bit universal bus transceiver with bus hold; positive edge trigger (3-state)	2.3 to 3.6	TTL	-0,5	1,9	18	200	50 pF
74ALVT16652	16-bit registered transceiver with bus hold (3-state)	2.3 to 3.6	TTL	-0,5	2,4	16	150	50 pF
74AVC16245	16-bit transceiver (3-state)	1.2 to 3.6	CMOS	±12	2	16	200	30 pF
74AVCH16245	16-bit transceiver with bus hold (3-state)	1.2 to 3.6	CMOS	±12	2	16	200	30 pF
74HC245	Octal transceiver (3-state)	2.0 to 6.0	CMOS	±7.8	7	8	36	50 pF
74HCT245	Octal transceiver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	10	8	36	50 pF
74HC640	Octal transceiver; inverting (3-state)	2.0 to 6.0	CMOS	±7.8	9	8	36	50 pF
74HCT640	Octal transceiver; inverting; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	9	8	36	50 pF
74HC652	Octal registered transceiver (3-state)	2.0 to 6.0	CMOS	±7.8	13	8	36	50 pF
74HCT652	Octal registered transceiver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	13	8	36	50 pF
74LV245	Octal transceiver (3-state)	1.0 to 5.5	TTL	±16	7	8	30	50 pF
74LVC162245	16-bit transceiver with 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	3,3	16	175	50 pF
74LVCH162245	16-bit transceiver with bus hold and 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	3,3	16	175	50 pF
74LVC16245	16-bit transceiver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	3	16	175	50 pF
74LVCH16245	16-bit transceiver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	3	16	175	50 pF
74LVC245	Octal transceiver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	2,9	8	175	50 pF
74LVCH245	Octal transceiver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	2,9	8	175	50 pF
74LVC2245	Octal transceiver with 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	3,3	8	175	50 pF
74LVC2952	Octal registered transceiver with 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	4,3	8	175	50 pF
74LVC32245	32-bit transceiver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	2,2	32	175	50 pF

Transceivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Number of bits	f_{max} (MHz)	T_{amb} (°C)
74LVC543	Octal registered transceiver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	3,3	8	175	50 pF
74LVC544	Octal registered transceiver; inverting (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	4	8	175	50 pF
74LVC623	Octal transceiver with dual enable (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	3,3	8	175	50 pF
74LVC646	Octal registered transceiver (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	3,9	8	175	50 pF
74LVCH322245	32-bit transceiver with bus hold and 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS/LVTTL	±12	3,3	32	175	50 pF
74LVCH32245	32-bit transceiver with bus hold (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	3	32	175	50 pF
74LVT16245	16-bit transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	1,9	16	150	50 pF
74LVTH16245	16-bit transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	1,9	16	150	50 pF
74LVT2245	Octal transceiver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	3,2	8	150	50 pF
74LVTH2245	Octal transceiver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	3,2	8	150	50 pF
74LVT162245	16-bit transceiver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	2,5	16	150	50 pF
74LVT16500	18-bit universal bus transceiver with bus hold; negative-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	1,9	18	150	50 pF
74LVT16501	18-bit universal bus transceiver with bus hold; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	1,9	18	150	50 pF
74LVT16543	16-bit registered transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	2,2	16	150	50 pF
74LVT16646	16-bit registered transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	1,9	16	150	50 pF
74LVT16652	16-bit registered transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	1,9	16	150	50 pF
74LVT245	Octal transceiver (3-state)	2.7 to 3.6	TTL	-0,5	2,4	8	150	50 pF
74LVT2952	Octal registered transceiver with 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	-0,5	3,8	8	150	50 pF
74LVT543	Octal registered transceiver (3-state)	2.7 to 3.6	TTL	-0,5	3	8	150	50 pF
74LVT543	Octal registered transceiver (3-state)	2.7 to 3.6	TTL	-0,5	3	8	150	50 pF
74LVT640	Octal transceiver with bus hold; inverting (3-state)	2.7 to 3.6	TTL	-0,5	2,4	8	150	50 pF
74LVT646	Octal registered transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	3,8	8	150	50 pF
74LVT652	Octal registered transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	3,7	8	150	50 pF
74LVTH322245	32-bit transceiver with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	2,5	32	150	50 pF
74LVTH32245	32-bit transceiver with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	1,9	32	150	50 pF
74LVTN16245	16-bit transceiver (3-state)	2.7 to 3.6	TTL	-0,5	1,9	16	150	50 pF
74VHC245	Octal transceiver (3-state)	2.0 to 5.5	CMOS	±8	3,5	8	60	50 pF
74VHCT245	Octal transceiver; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	5	8	60	50 pF

Schmitt triggers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load CL (Typ)	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AHC132	Quad 2-input NAND gate Schmitt trigger	2.0 to 5.5	CMOS	±8	3,3	50 pF	60	4	-40 to +125
74AHCT132	Quad 2-input NAND gate Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	3,5	50 pF	60	4	-40 to +125
74AHC14	Hex inverter Schmitt trigger	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	6	-40 to +125
74AHCT14	Hex inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4	50 pF	60	6	-40 to +125
74AHC1G14	Single inverter Schmitt trigger	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125
74AHCT1G14	Single inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4,1	50 pF	60	1	-40 to +125
74AHC3G14	Triple inverter Schmitt trigger	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	3	-40 to +125
74AHCT3G14	Triple inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4,1	50 pF	60	3	-40 to +125
74ALVC14	Hex inverter Schmitt trigger	1.65 to 3.6	TTL	±24	2,4	50 pF	150	6	-40 to +85
74AUP1G17	Single buffer Schmitt trigger	1.1 to 3.6	CMOS	±1.9	7,8	30 pF	70	1	-40 to +125
74AUP2G132	dual 2-input NAND gate Schmitt trigger	1.1 to 3.6	CMOS	±1.9	10	30 pF	70	2	-40 to +125
74AUP2G14	dual inverter Schmitt trigger	1.1 to 3.6	CMOS	±1.9	4,7	30 pF	70	2	-40 to +125
74AUP2G17	dual buffer Schmitt trigger	1.1 to 3.6	CMOS	±1.9	7,8	30 pF	70	2	-40 to +125
74AUP3G14	Triple inverter Schmitt trigger	1.1 to 3.6	CMOS	±1.9	2,4	30pF	70	3	-40 to +125
74AUP3G17	Triple Schmitt trigger	1.1 to 3.6	CMOS	±1.9	2,4	30pF	70	3	-40 to +125
74HC132	Quad 2-input NAND gate Schmitt trigger	2.0 to 6.0	CMOS	±5.2	11	50 pF	36	4	-40 to +125
74HCT132	Quad 2-input NAND gate Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±4	17	50 pF	36	4	-40 to +125
74HC14	Hex inverter Schmitt trigger	2.0 to 6.0	CMOS	±5.2	12	50 pF	36	6	-40 to +125
74HCT14	Hex inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±4	17	50 pF	36	6	-40 to +125
74HC1G14	Single inverter Schmitt trigger	2.0 to 6.0	CMOS	±2.6	10	50 pF	36	1	-40 to +125
74HCT1G14	Single inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±2.0	15	50 pF	36	1	-40 to +125
74HC2G14	Dual inverter Schmitt trigger	2.0 to 6.0	CMOS	±5.2	16	50 pF	36	2	-40 to +125
74HCT2G14	Dual inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±4.0	21	50 pF	36	2	-40 to +125
74HC2G17	Dual buffer Schmitt trigger	2.0 to 6.0	CMOS	±5.2	12	50 pF	36	2	-40 to +125
74HCT2G17	Dual buffer Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±4.0	21	50 pF	36	2	-40 to +125
74HC3G14	Triple inverter Schmitt trigger	2.0 to 6.0	CMOS	±5.2	16	50 pF	36	3	-40 to +125
74HCT3G14	Triple inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±4.0	21	50 pF	36	3	-40 to +125
74HC7540	Octal inverter/line driver Schmitt trigger (3-state)	2.0 to 6.0	CMOS	±7.8	11	50 pF	36	8	-40 to +125
74HCT7540	Octal inverter/line driver Schmitt trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	16	50 pF	36	8	-40 to +125
74HC7541	Octal buffer/line driver Schmitt trigger (3-state)	2.0 to 6.0	CMOS	±7.8	11	50 pF	36	8	-40 to +125
74HCT7541	Octal buffer/line driver Schmitt trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	16	50 pF	36	8	-40 to +125
74HC9114	9-bit inverter Schmitt trigger; open drain (3-state)	2.0 to 6.0	CMOS	5,2	12	50 pF	36	9	-40 to +125
74HCT9114	9-bit inverter Schmitt trigger; open drain; TTL-enabled (3-state)	4.5 to 5.5	TTL	4	13	50 pF	36	9	-40 to +125
74HC9115	9-bit buffer Schmitt trigger; open drain (3-state)	2.0 to 6.0	CMOS	5,2	12	50 pF	36	9	-40 to +125
74HCT9115	9-bit buffer Schmitt trigger; open drain; TTL-enabled (3-state)	4.5 to 5.5	TTL	4	13	50 pF	36	9	-40 to +125
74HC7014	Hex buffer precision Schmitt trigger	2.0 to 6.0	CMOS	±5.2	27	50 pF	36	6	-40 to +125
74LV132	Quad 2-input NAND gate Schmitt trigger	1.0 to 5.5	TTL	±12	10	50 pF	30	4	-40 to +125

Schmitt triggers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load CL (Typ)	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74LV14	Hex inverter Schmitt trigger	1.0 to 5.5	TTL	±12	13	50 pF	30	6	-40 to +125
74LVC132	Quad 2-input NAND gate Schmitt trigger	1.2 to 3.6	CMOS/LVTTL	±24	3,4	50 pF	175	4	-40 to +125
74LVC14	Hex inverter Schmitt trigger	1.2 to 3.6	CMOS/LVTTL	±24	3,2	50 pF	175	6	-40 to +125
74LVC1G14	Single inverter Schmitt trigger	1.65 to 5.5	CMOS/LVTTL	±32	3	50 pF	175	1	-40 to +125
74LVC1G17	Single buffer Schmitt trigger	1.65 to 5.5	CMOS/LVTTL	±32	3	50 pF	175	1	-40 to +125
74LVC2G14	Dual inverter Schmitt trigger	1.65 to 5.5	CMOS/LVTTL	±32	3,9	50 pF	175	2	-40 to +125
74LVC2G17	Dual buffer Schmitt trigger	1.65 to 5.5	CMOS/LVTTL	±32	3,6	50 pF	175	2	-40 to +125
74LVC3G14	Triple inverter Schmitt trigger	1.65 to 5.5	CMOS/LVTTL	±32	3,2	50 pF	175	3	-40 to +125
74LVC3G17	Triple buffer Schmitt trigger	1.65 to 5.5	CMOS/LVTTL	±32	3,6	50 pF	175	3	-40 to +125
74LVT14	Hex inverter Schmitt trigger	2.7 to 3.6	TTL	-0,5	3,8	50 pF	150	6	-40 to +125
74VHCT14	Hex inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4,1	50 pF	60	6	-40 to +125
HEF40106	Hex inverter Schmitt trigger	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	6	-40 to +85
HEF4093	Quad 2-input NAND gate Schmitt trigger	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	4	-40 to +125
XC7SET14	Single inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4,1	50 pF	60	1	-40 to +125
XC7SH14	Single inverter Schmitt trigger	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125
XC7WH14	Triple inverter Schmitt trigger	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	3	-40 to +125
XC7WT14	Triple inverter Schmitt trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4,1	50 pF	60	3	-40 to +125

Counters/frequency dividers

Type number	Description	V_{CC} (V)	Output drive capability (mA)	Logic switching levels	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74AHC1G4210	10-stage divider and oscillator	2.0 to 5.5	±5.2	CMOS	7	50pF	125	-40 to +125
74AHC1G4212	12-stage divider and oscillator	2.0 to 5.5	±5.2	CMOS	7	50pF	125	-40 to +125
74AHC1G4214	14-stage divider and oscillator	2.0 to 5.5	±5.2	CMOS	7	50pF	125	-40 to +125
74HC160	Presettable synchronous BCD decade counter; asynchronous reset	2.0 to 6.0	±5.2	CMOS	18	50 pF	55	-40 to +125
74HCT160	Presettable synchronous BCD decade counter; asynchronous reset; TTL-enabled	4.5 to 5.5	±4.0	TTL	21	50 pF	28	-40 to +125
74HC161	Presettable synchronous 4-bit binary counter; asynchronous reset	2.0 to 6.0	±5.2	CMOS	19	50 pF	48	-40 to +125
74HCT161	Presettable synchronous 4-bit binary counter; asynchronous reset; TTL-enabled	4.5 to 5.5	±4.0	TTL	20	50 pF	41	-40 to +125
74HC163	Presettable synchronous 4-bit binary counter; synchronous reset	2.0 to 6.0	±5.2	CMOS	17	50 pF	50	-40 to +125
74HCT163	Presettable synchronous 4-bit binary counter; synchronous reset; TTL-enabled	4.5 to 5.5	±4.0	TTL	20	50 pF	50	-40 to +125
74HC191	Presettable synchronous 4-bit binary up/down counter	2.0 to 6.0	±5.2	CMOS	22	50 pF	36	-40 to +125
74HCT191	Presettable synchronous 4-bit binary up/down counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	22	50 pF	39	-40 to +125
74HC193	Presettable synchronous 4-bit binary up/down counter; separate up/down clocks	2.0 to 6.0	±5.2	CMOS	20	50 pF	49	-40 to +125
74HCT193	Presettable synchronous 4-bit binary up/down counter; separate up/down clocks; TTL-enabled	4.5 to 5.5	±4.0	TTL	20	50 pF	43	-40 to +125
74HC390	Dual decade ripple counter	2.0 to 6.0	±5.2	CMOS	14	50 pF	60	-40 to +125
74HCT390	Dual decade ripple counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	18	50 pF	55	-40 to +125
74HC393	Dual 4-bit binary ripple counter	2.0 to 6.0	±5.2	CMOS	12	50 pF	107	-40 to +125
74HCT393	Dual 4-bit binary ripple counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	20	50 pF	53	-40 to +125
74HC4017	Johnson decade counter with 10 decoded outputs	2.0 to 6.0	±5.2	CMOS	18	50 pF	77	-40 to +125
74HCT4017	Johnson decade counter with 10 decoded outputs; TTL-enabled	4.5 to 5.5	±4.0	TTL	21	50 pF	67	-40 to +125
74HC4020	14-stage binary ripple counter	2.0 to 6.0	±5.2	CMOS	11	50 pF	52	-40 to +125
74HCT4020	14-stage binary ripple counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	15	50 pF	52	-40 to +125
74HC4040	12-stage binary ripple counter	2.0 to 6.0	±5.2	CMOS	14	50 pF	90	-40 to +125
74HCT4040	12-stage binary ripple counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	16	50 pF	79	-40 to +125
74HC4059	Programmable divide-by-n counter	2.0 to 6.0	±5.2	CMOS	17	50 pF	43	-40 to +125
74HCT4059	Programmable divide-by-n counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	20	50 pF	40	-40 to +125
74HC4060	14-stage binary ripple counter with oscillator	2.0 to 6.0	±5.2	CMOS	31	50 pF	95	-40 to +125
74HCT4060	14-stage binary ripple counter with oscillator; TTL-enabled	4.5 to 5.5	±4.0	TTL	31	50 pF	88	-40 to +125
74HC4520	Dual 4-bit synchronous binary counter	2.0 to 6.0	±5.2	CMOS	24	50 pF	64	-40 to +125
74HCT4520	Dual 4-bit synchronous binary counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	24	50 pF	64	-40 to +125
74HC5555	Programmable delay timer with oscillator	2.0 to 6.0	-0,8	CMOS	89	50 pF	24	-40 to +125
74HCT5555	Programmable delay timer with oscillator; TTL-enabled	4.5 to 5.5	±20	TTL	75	50 pF	24	-40 to +125
74HC6323	Programmable ripple counter with oscillator (3-state)	2.0 to 6.0	±7.8	CMOS	17	50 pF	100	-40 to +125
74HCT6323	Programmable ripple counter with oscillator (3-state); TTL-enabled	4.5 to 5.5	±4.0	TTL	17	50 pF	85	-40 to +125
74HC93	4-bit binary ripple counter	2.0 to 6.0	±5.2	CMOS	12	50 pF	100	-40 to +125
74HCT93	4-bit binary ripple counter; TTL-enabled	4.5 to 5.5	±4.0	TTL	15	50 pF	77	-40 to +125
74HC40103	8-bit synchronous binary down counter	2.0 to 6.0	±5.2	CMOS	15	50 pF	14	-40 to +125
74HC4024	7-stage binary ripple counter	2.0 to 6.0	±5.2	CMOS	14	50 pF	90	-40 to +125

Counters/frequency dividers

Type number	Description	V_{CC} (V)	Output drive capability (mA)	Logic switching levels	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74HC590	8-bit binary counter with output register (3-state)	2.0 to 6.0	±5.2	CMOS	19	50 pF	61	-40 to +125
74LV393	Dual 4-bit binary ripple counter	1.0 to 3.6	±6	TTL	12	50 pF	90	-40 to +125
74LV4020	14-stage binary ripple counter	1.0 to 5.5	±6	TTL	16	50 pF	100	-40 to +125
74LV4060	14-stage binary ripple counter with oscillator	1.0 to 5.5	±6	TTL	29	50 pF	100	-40 to +125
74LVC161	Presettable synchronous 4-bit binary counter; asynchronous reset	1.2 to 3.6	±24	CMOS/ LVTTL	4,9	50 pF	200	-40 to +125
74LVC163	Presettable synchronous 4-bit binary counter; synchronous reset	1.2 to 3.6	±24	CMOS/ LVTTL	4,9	50 pF	200	-40 to +125
HEF4017	Johnson decade counter with 10 decoded outputs	4.5 to 15	±2.4	CMOS	40	50 pF	30	-40 to +85
HEF40193	Presettable synchronous 4-bit binary up/down counter; separate up/down clocks	4.5 to 15.5	±2.4	CMOS	60	50 pF	18	-40 to +85
HEF4020	14-stage binary ripple counter	4.5 to 15.5	±2.4	CMOS	35	50 pF	35	-40 to +85
HEF4024	7-stage binary ripple counter	4.5 to 15.5	±2.4	CMOS	30	50 pF	35	-40 to +85
HEF4040	12-stage binary ripple counter	4.5 to 15.5	±2.4	CMOS	35	50 pF	50	-40 to +85
HEF4059	Programmable divide-by-n counter	4.5 to 15.5	-0,35	CMOS	40	50 pF	20	-40 to +85
HEF4060	14-stage binary ripple counter with oscillator	4.5 to 15.5	±2.4	CMOS	50	50 pF	30	-40 to +85
HEF4516	Presettable synchronous 4-bit binary up/down counter	4.5 to 15.5	±2.4	CMOS	45	50 pF	18	-40 to +85
HEF4518	Dual BCD counter	4.5 to 15	±2.4	CMOS	40	50 pF	40	-40 to +85
HEF4520	Dual 4-bit synchronous binary counter	4.5 to 15.5	±2.4	CMOS	15	50 pF	40	-40 to +85
HEF4521	24-stage frequency divider and oscillator	4.5-15.5 V	±2.4	CMOS	220	50 pF	35	-40 to +85
HEF4526	Programmable 4-bit binary down counter	4.5 to 15.5	±2.4	CMOS	50	50 pF	32	-40 to +85
HEF4541	Programmable timer	4.5 to 15.5	- 4/ + 2.7	CMOS	38	50 pF	150	-40 to +85

FIFO registers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74HC40105	4-bit x 16-word FIFO register	2.0 to 6.0	CMOS	Low	15	50 pF	30	-40 to +125
74HCT40105	4-bit x 16-word FIFO register; TTL-enabled	4.5 to 5.5	TTL	±4 mA	18	50 pF	28	-40 to +125
74HC7030	9-bit x 64-word FIFO register (3-state)	2.0 to 6.0	CMOS	±5.2 mA	36	50 pF	33	-40 to +125
74HCT7030	9-bit x 64-word FIFO register; TTL-enabled (3-state)	4.5 to 5.5	TTL	±4 mA	26	50 pF	29	-40 to +125
74HC7403	4-bit x 16-word FIFO register (3-state)	2.0 to 6.0	CMOS	±5.2 mA	15	50 pF	30	-40 to +125
74HCT7403	4-bit x 16-word FIFO register; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8 mA	17	50 pF	30	-40 to +125

Flip-flops

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74AHC1G79	Single D-type flip-flop; positive-edge trigger	2.0 to 5.5	CMOS	±8	3,5	50 pF	90	-40 to +125
74AHCT1G79	Single D-type flip-flop; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±8	3,5	50 pF	90	-40 to +125
74AHC273	Octal D-type flip-flop with reset; positive-edge trigger	2.0 to 5.5	CMOS	±8	4,2	50 pF	165	-40 to +125
74AHCT273	Octal D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4	50 pF	120	-40 to +125
74AHC374	Octal D-type flip-flop; positive-edge trigger (3-state)	2.0 to 5.5	CMOS	±8	4,4	50 pF	185	-40 to +125
74AHCT374	Octal D-type flip-flop; positive-edge trigger (3-state)	4.5 to 5.5	TTL	±8	4,3	50 pF	140	-40 to +125
74AHC377	Octal D-type flip-flop with data enable; positive-edge trigger	2.0 to 5.5	CMOS	±8	3,9	50 pF	175	-40 to +125
74AHCT377	Octal D-type flip-flop with data enable; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±8	4	50 pF	140	-40 to +125
74AHC574	Octal D-type flip-flop; positive-edge trigger (3-state)	2.0 to 5.5	CMOS	±8	4,4	50 pF	130	-40 to +125
74AHCT574	Octal D-type flip-flop; positive-edge trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	4,4	50 pF	130	-40 to +125
74AHC74	Dual D-type flip-flop with set and reset; positive-edge trigger	2.0 to 5.5	CMOS	±8	3,7	50 pF	170	-40 to +125
74AHCT74	Dual D-type flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±8	3,3	50 pF	160	-40 to +125
74ALVC374	Octal D-type flip-flop; positive-edge trigger (3-state)	1.65 to 3.6	TTL	±24	2,5	50 pF	300	-40 to +85
74ALVC574	Octal D-type flip-flop; positive-edge trigger (3-state)	1.65 to 3.6	TTL	±24	2,5	50 pF	300	-40 to +85
74ALVC74	Dual D-type flip-flop with set and reset; positive-edge trigger	1.65 to 3.6	TTL	±24	2,3	50 pF	425	-40 to +85
74ALVCH16374	16-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	1.2 to 3.6	TTL	±24	2,3	50 pF	350	-40 to +85
74ALVCH16821	20-bit D-type flip-flop; positive-edge trigger (3-state)	2.3 to 3.6	TTL	±24	2,5	50 pF	350	-40 to +85
74ALVCH16823	18-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	1.2 to 3.6	TTL	±24	2,1	50 pF	350	-40 to +85
74ALVT162821	20-bit D-type flip-flop; positive-edge trigger (3-state)	2.3 to 3.6	TTL	±12	3,2	50 pF	150	-40 to +85
74ALVT162823	18-bit buffer/line driver with bus hold and 30 Ω termination resistors (3-state)	2.3 to 3.6	TTL	±12	3	50 pF	150	-40 to +85
74ALVT16374	16-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	2.3 to 3.6	TTL	-0,5	2,3	50 pF	250	-40 to +85
74ALVT16821	20-bit D-type flip-flop; positive-edge trigger (3-state)	2.3 to 3.6	TTL	-0,5	1,8	50 pF	150	-40 to +85
74ALVT16823	18-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	2.3 to 3.6	TTL	-0,5	1,9	50 pF	250	-40 to +85
74AUP1G175	Single D flip-flop with reset; positive-edge trigger	1.1 to 3.6	CMOS	±1.9	7,4	30 pF	70	-40 to +125
74AUP1G374	Single D-type flip-flop; positive-edge trigger (3-state)	1.1 to 3.6	CMOS	±1.9	7,9	30 pF	400	-40 to +125
74AUP1G74	Single D-type flip-flop with set and reset; positive-edge trigger	1.1 to 3.6	CMOS	±1.9	9,2	30 pF	400	-40 to +125
74AUP1G79	Single D-type flip-flop; positive-edge trigger	1.1 to 3.6	CMOS	±1.9	9,1	30 pF	400	-40 to +125

Flip-flops

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74AUP1G80	Single D-type flip-flop; positive-edge trigger	1.1 to 3.6	CMOS	±1.9	9,1	30 pF	400	-40 to +125
74AUP2G79	Dual D-type flip-flop; positive-edge trigger	1.1 to 3.6	CMOS	±1.9	8,5	30 pF	400	-40 to +125
74AUP2G80	Dual D-type flip-flop; positive-edge trigger	1.1 to 3.6	CMOS	±1.9	9,1	30 pF	400	-40 to +125
74AVC16374	16-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 to 3.6	CMOS	±12	1,5	30 pF	350	-40 to +85
74HC107	Dual JK-type flip-flop with reset; negative-edge trigger	2.0 to 6.0	CMOS	±5.2	16	50 pF	78	-40 to +125
74HCT107	Dual JK-type flip-flop with reset; negative-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	16	50 pF	73	-40 to +125
74HC109	Dual JK-type flip-flop with set and reset; positive-edge trigger	2.0 to 6.0	CMOS	±5.2	15	50 pF	75	-40 to +125
74HCT109	Dual JK-type flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	17	50 pF	61	-40 to +125
74HC112	Dual JK-type flip-flop with set and reset; negative-edge trigger	2.0 to 6.0	CMOS	±5.2	15	50 pF	66	-40 to +125
74HCT112	Dual JK-type flip-flop with set and reset; negative-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	19	50 pF	70	-40 to +125
74HC173	Quad D-type flip-flop; positive-edge trigger (3-state)	2.0 to 6.0	CMOS	±7.8	17	50 pF	88	-40 to +125
74HCT173	Quad D-type flip-flop; positive-edge trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	17	50 pF	88	-40 to +125
74HC174	Hex D-type flip-flop with reset; positive-edge trigger	2.0 to 6.0	CMOS	±5.2	17	50 pF	99	-40 to +125
74HCT174	Hex D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	18	50 pF	69	-40 to +125
74HC175	Quad D-type flip-flop with reset; positive-edge trigger	2.0 to 6.0	CMOS	±5.2	17	50 pF	83	-40 to +125
74HCT175	Quad D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	16	50 pF	54	-40 to +125
74HC273	Octal D-type flip-flop with reset; positive-edge trigger	2.0 to 6.0	CMOS	±5.2	15	50 pF	122	-40 to +125
74HCT273	Octal D-type flip-flop with reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	15	50 pF	36	-40 to +125
74HC374	Octal D-type flip-flop; positive-edge trigger (3-state)	2.0 to 6.0	CMOS	±7.8	14	50 pF	83	-40 to +125
74HCT374	Octal D-type flip-flop; positive-edge trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	13	50 pF	48	-40 to +125
74HC377	Octal D-type flip-flop with data enable; positive-edge trigger	2.0 to 6.0	CMOS	±7.8	13	50 pF	83	-40 to +125
74HCT377	Octal D-type flip-flop with data enable; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±6	14	50 pF	53	-40 to +125
74HC574	Octal D-type flip-flop; positive-edge trigger (3-state)	2.0 to 6.0	CMOS	±7.8	14	50 pF	133	-40 to +125
74HCT574	Octal D-type flip-flop; positive-edge trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	15	50 pF	76	-40 to +125
74HC74	Dual D-type flip-flop with set and reset; positive-edge trigger	2.0 to 6.0	CMOS	±5.2	14	50 pF	82	-40 to +125
74HCT74	Dual D-type flip-flop with set and reset; positive-edge trigger; TTL-enabled	4.5 to 5.5	TTL	±4	15	50 pF	59	-40 to +125
74HC73	Dual JK-type flip-flop with reset; negative-edge trigger	2.0 to 6.0	CMOS	±5.2	16	50 pF	77	-40 to +125
74HCT534	Octal D-type flip-flop; inverting; positive-edge trigger; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	13	50 pF	40	-40 to +125
74HCT7273	Octal D-type flip-flop with reset; positive edge-trigger; open drain outputs; TTL-enabled	4.5 to 5.5	TTL	4	16	50 pF	56	-40 to +125
74LV174	Hex D-type flip-flop with reset; positive-edge trigger	1.0 to 5.5	TTL	±12	16	50 pF	77	-40 to +125
74LV273	Octal D-type flip-flop with reset; positive-edge trigger	1.0 to 5.5	TTL	±12	12	50 pF	110	-40 to +125
74LV374	Octal D-type flip-flop; positive-edge trigger (3-state)	1.0 to 5.5	TTL	±16	14	50 pF	77	-40 to +125
74LV377	Octal D-type flip-flop with data enable; positive-edge trigger	1.0 to 3.6	TTL	±6	13	50 pF	77	-40 to +125
74LV574	Octal D-type flip-flop; positive-edge trigger (3-state)	1.0 to 5.5	TTL	±16	13	50 pF	77	-40 to +125
74LV74	Dual D-type flip-flop with set and reset; positive-edge trigger	1.0 to 5.5	TTL	±12	11	50 pF	75	-40 to +125
74LVC16374	16-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	3,8	50 pF	150	-40 to +125
74LVCH16374	16-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	3,8	50 pF	150	-40 to +125

Flip-flops

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74LVC109	Dual JK-type flip-flop with set and reset; positive-edge trigger	1.2 to 3.6	CMOS/ LVTTL	±24	4	50 pF	330	-40 to +125
74LVC1G175	Single D flip-flop with reset; positive-edge trigger	1.65 to 5.5	CMOS/ LVTTL	±32	3,1	50 pF	300	-40 to +125
74LVC1G74	Single D-type flip-flop with set and reset; positive-edge trigger	1.65 to 5.5	CMOS/ LVTTL	±32	3,5	50 pF	280	-40 to +125
74LVC1G79	Single D-type flip-flop; positive-edge trigger	1.65 to 5.5	CMOS/ LVTTL	±32	2,2	50 pF	450	-40 to +125
74LVC1G80	Single D-type flip-flop; positive-edge trigger	1.65 to 5.5	CMOS/ LVTTL	±32	2,4	50 pF	450	-40 to +125
74LVC273	Octal D-type flip-flop with reset; positive-edge trigger	1.2 to 3.6	CMOS/ LVTTL	±24	6	50 pF	230	-40 to +125
74LVC2G74	Single D-type flip-flop with set and reset; positive-edge trigger	1.65 to 5.5	CMOS/ LVTTL	±32	3,5	50 pF	280	-40 to +125
74LVC374	Octal D-type flip-flop; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	2,7	50 pF	100	-40 to +125
74LVC377	Octal D-type flip-flop with data enable; positive-edge trigger	1.2 to 3.6	CMOS/ LVTTL	±24	6	50 pF	230	-40 to +125
74LVC574	Octal D-type flip-flop; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	3,2	50 pF	150	-40 to +125
74LVC74	Dual D-type flip-flop with set and reset; positive-edge trigger	1.2 to 3.6	CMOS/ LVTTL	±24	2,5	50 pF	250	-40 to +125
74LVC821	10-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	5,4	50 pF	150	-40 to +125
74LVC823	9-bit D-type flip-flop; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	5,4	50 pF	150	-40 to +125
74LVCH162374	16-bit D-type flip-flop with bus hold and 30 Ω termination resistors; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	3,8	50 pF	150	-40 to +125
74LVCH32374	32-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	1.2 to 3.6	CMOS/ LVTTL	±24	3,8	50 pF	150	-40 to +125
74LVT16374	16-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	3	50 pF	150	-40 to +85
74LVTH16374	16-bit D-type flip-flop with bus hold; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	3	50 pF	150	-40 to +85
74LVT574	Octal D-type flip-flop; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	4,3	50 pF	150	-40 to +85
74LVTH57	Octal D-type flip-flop; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	4,3	50 pF	150	-40 to +85
74LVTH574	Octal D-type flip-flop; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	4,3	50 pF	150	-40 to +85
74LVT162374	16-bit D-type flip-flop with bus hold and 30 Ω termination resistors; positive-edge trigger (3-state)	2.7 to 3.6	TTL	±12	3	50 pF	150	-40 to +85
74LVT273	Octal D-type flip-flop with reset; positive-edge trigger	2.7 to 3.6	TTL	-0,5	3,5	50 pF	150	-40 to +85
74LVT32374	32-bit D-type flip-flop with bus hold and 30 Ω termination resistors; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	3	50 pF	150	-40 to +85
74LVT373	Octal D-type transparent latch (3-state)	2.7 to 3.6	TTL	-0,5	3	50 pF		-40 to +85
74LVT374	Octal D-type flip-flop; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	3,5	50 pF	200	-40 to +85
74LVT534	Octal D-type flip-flop; inverting; positive-edge trigger (3-state)	2.7 to 3.6	TTL	-0,5	3,5	50 pF	150	-40 to +85
74LVT74	Dual D-type flip-flop with set and reset; positive-edge trigger	2.7 to 3.6	TTL	-0,625	3,6	50 pF	345	-40 to +85
HEF4013	Dual D-type flip-flop with set and reset; positive-edge trigger	4.5 to 15.5	CMOS	±2.4	30	50 pF	40	-40 to +85
HEF40174	Hex D-type flip-flop with reset; positive-edge trigger	4.5 to 15.5	CMOS	±2.4	20	50 pF	45	-40 to +85
HEF40175	Quad D-type flip-flop with reset; positive-edge trigger	4.5 to 15.5	CMOS	±2.4	25	50 pF	45	-40 to +85
HEF4027	Dual JK-type flip-flop	4.5 to 15.5	CMOS	±2.4	30	50 pF	30	-40 to +85
HEF40374	Octal D-type flip-flop; positive-edge trigger (3-state)	4.5 to 15.5	CMOS	-50/62	40	50 pF	17	-40 to +85

Latches/registered drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	Number of bits	T_{amb} (°C)
74AHC259	8-bit addressable latch	2.0 to 5.5	CMOS	±8	4,1	50 pF	8	-40 to +125
74AHCT259	8-bit addressable latch; TTL-enabled	4.5 to 5.5	TTL	±8	4,1	50 pF	8	-40 to +125
74AHC373	Octal D-type transparent latch (3-state)	2.0 to 5.5	CMOS	±8	4,3	50 pF	8	-40 to +125
74AHCT373	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	4,3	50 pF	8	-40 to +125
74AHC573	Octal D-type transparent latch (3-state)	2.0 to 5.5	CMOS	±8	4,2	50 pF	8	-40 to +125
74AHCT573	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	3,9	50 pF	8	-40 to +125
74ALVC162334	16-bit registered driver with 30 Ω termination resistors (3-state)	1.65 to 3.6	LVTTL	±24	6	50 pF	16	-40 to +85
74ALVC162834	18-bit registered driver with 30 Ω termination resistors (3-state)	1.65 to 3.6	LVTTL	±24	6	50 pF	18	-40 to +85
74ALVC162835	18-bit registered driver with 30 Ω termination resistors (3-state)	1.65 to 3.6	LVTTL	±24	6	50 pF	18	-40 to +85
74ALVC162836	20-bit registered driver with 30 Ω termination resistors (3-state)	1.65 to 3.6	LVTTL	±24	6	50 pF	20	-40 to +85
74ALVC16834	18-bit registered driver (3-state)	1.65 to 3.6	LVTTL	±24	4	50 pF	18	-40 to +85
74ALVC16835	18-bit registered driver (3-state)	1.65 to 3.6	LVTTL	±24	4	50 pF	18	-40 to +85
74ALVC16836	20-bit registered driver (3-state)	1.65 to 3.6	LVTTL	±24	4	50 pF	20	-40 to +85
74ALVC373	Octal D-type transparent latch (3-state)	1.65 to 3.6	LVTTL	±24	2,2	50 pF	8	-40 to +85
74ALVC573	Octal D-type transparent latch (3-state)	1.65 to 3.6	LVTTL	±24	2,2	50 pF	8	-40 to +85
74ALVCH16373	16-bit D-type transparent latch with bus hold (3-state)	2.3 to 3.6	LVTTL	±24	2,1	50 pF	16	-40 to +85
74ALVCH16832	7-bit to 28-bit address register/driver (3-state)	2.3 to 3.6	LVTTL	±24	4	50 pF	7	-40 to +85
74ALVCH16841	20-bit D-type transparent latch with bus hold (3-state)	2.3 to 3.6	LVTTL	±24	2,4	50 pF	20	-40 to +85
74ALVCH16843	18-bit D-type transparent latch with bus hold (3-state)	2.3 to 3.6	LVTTL	±24	2,1	50 pF	18	-40 to +85
74ALVCH32973	16-bit transceiver and transparent D-type latch with 8 independent buffers	1.8 to 3.6	LVTTL	±24	2,5	50 pF	16	-40 to +85
74ALVT16260	12-bit to 24-bit multiplexed D-type latch with bus hold (3-state)	2.3 to 3.6	TTL	-0,5	2,8	50 pF	12	-40 to +85
74ALVT16373	16-bit D-type transparent latch with bus hold (3-state)	2.3 to 3.6	TTL	-0,5	1,8	50 pF	16	-40 to +85
74AUP1G373	Single D-type transparent latch (3-state)	1.1 to 3.6	CMOS	1.9 / -1.9	8,5	30 pF	1	-40 to +125
74AVC16334	16-bit registered driver (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	16	-40 to +85
74AVC16373	16-bit D-type transparent latch (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	16	-40 to +85
74AVC16834	18-bit registered driver (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	18	-40 to +85
74AVC16835	18-bit registered driver (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	18	-40 to +85
74AVC16836	20-bit registered driver (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	20	-40 to +85
74AVCM162834	18-bit registered driver with 30 Ω termination resistors (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	18	-40 to +85
74AVCM162835	18-bit registered driver with 15 Ω termination resistors (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	18	-40 to +85
74AVCM162836	20-bit registered driver with 15 Ω termination resistors (3-state)	1.2 to 3.6	CMOS	±12	2	30 pF	20	-40 to +85
74HC259	8-bit addressable latch	2.0 to 6.0	CMOS	±5.2	18	50 pF	8	-40 to +125
74HCT259	8-bit addressable latch; TTL-enabled	4.5 to 5.5	TTL	±4	20	50 pF	8	-40 to +125
74HC373	Octal D-type transparent latch (3-state)	2.0 to 6.0	CMOS	±7.8	12	50 pF	8	-40 to +125
74HCT373	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	14	50 pF	8	-40 to +125
74HCT563	Octal D-type transparent latch; inverting; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	16	50 pF	8	-40 to +125
74HC573	Octal D-type transparent latch (3-state)	2.0 to 6.0	CMOS	±7.8	14	50 pF	8	-40 to +125

Latches/registered drivers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	Number of bits	T_{amb} (°C)
74HCT573	Octal D-type transparent latch; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	17	50 pF	8	-40 to +125
74HC670	4-bit x 4-word register (3-state)	2.0 to 6.0	CMOS	±7.8	17	50 pF	4	-40 to +125
74HCT670	4-bit x 4-word register; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	23	50 pF	4	-40 to +125
74HC75	Quad bistable transparent latch	2.0 to 6.0	CMOS	±5.2	11	50 pF	4	-40 to +125
74HC75	Quad bistable transparent latch	2.0 to 6.0	CMOS	±5.2	11	50 pF	4	-40 to +125
74LV259	8-bit addressable latch	1.0 to 3.6	CMOS	±6	17	50 pF	8	-40 to +125
74LV373	Octal D-type transparent latch (3-state)	1.0 to 5.5	CMOS	±16	10	50 pF	8	-40 to +125
74LV573	Octal D-type transparent latch (3-state)	1.0 to 5.5	CMOS	±16	12	50 pF	8	-40 to +125
74LVC162373	16-bit D-type transparent latch with 30 Ω termination resistors (3-state)	1.2 to 3.6	TTL	±12	3,2	50 pF	16	-40 to +125
74LVCH162373	16-bit D-type transparent latch with bus hold and 30 Ω termination resistors (3-state)	1.2 to 3.6	TTL	±24	3,2	50 pF	16	-40 to +125
74LVC16373	16-bit D-type transparent latch (3-state)	1.2 to 3.6	TTL	±24	3	50 pF	16	-40 to +125
74LVCH16373	16-bit D-type transparent latch with bus hold (3-state)	1.2 to 3.6	TTL	±24	3	50 pF	16	-40 to +125
74LVC373	Octal D-type transparent latch (3-state)	1.2 to 3.6	TTL	±24	3	50 pF	8	-40 to +125
74LVC573	Octal D-type transparent latch (3-state)	1.2 to 3.6	TTL	±24	3,4	50 pF	8	-40 to +125
74LVC841	10-bit D-type transparent latch (3-state)	1.2 to 3.6	TTL	±24	4,5	50 pF	10	-40 to +125
74LVCH32373	32-bit D-type transparent latch (3-state)	1.2 to 3.6	TTL	±24	3	50 pF	32	-40 to +125
74LVT162373	16-bit D-type transparent latch with bus hold and 30 Ω termination resistors (3-state)	2.7 to 3.6	TTL	±12	2,5	50 pF	16	-40 to +85
74LVT16373	16-bit D-type transparent latch with bus hold (3-state)	2.7 to 3.6	TTL	-0,5	1,9	50 pF	16	-40 to +85
74LVT573	Octal D-type transparent latch (3-state)	2.7 to 3.6	TTL	-0,5	2,7	50 pF	8	-40 to +85
HEF40373	Octal D-type transparent latch (3-state)	4.5 to 15.5	CMOS	-50 / 62	40	50 pF	8	-40 to +85
HEF4043	Quad R/S latch with set and reset (3-state)	4.5 to 15	CMOS	±2.4	25	50 pF	4	-40 to +85
HEF4044	Quad R/S latch with set and reset (3-state)	4.5 to 15	CMOS	±2.4	30	50 pF	4	-40 to +85

AND Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AHC08	Quad 2-input AND gate	2.0 to 5.5	CMOS	±8	3,5	50 pF	60	4	-40 to +125
74AHC1G08	Single 2-input AND gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125
74AHC1G09	Single 2-input AND gate; open drain	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125
74AHC2G08	Dual 2-input AND gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	2	-40 to +125
74AHCT08	Quad 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±8	5	50 pF	60	4	-40 to +125
74AHCT1G08	Single 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,6	50 pF	60	1	-40 to +125
74AHCT2G08	Dual 2-Input AND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,6	50 pF	60	2	-40 to +125
74ALVC08	Quad 2-input AND gate	1.65 to 3.6	TTL	±24	2	50 pF	145	4	-40 to +85
74AUP1G08	Single 2-input AND gate	1.1 to 3.6	CMOS	±1.9	8,2	30 pF	70	1	-40 to +125
74AUP1G09	Single 2-input AND gate; open drain	1.1 to 3.6	CMOS	1,9	8,5	30 pF	70	1	-40 to +125
74AUP1G11	Single 3-input AND gate	1.1 to 3.6	CMOS	±1.9	6,9	30 pF	70	1	-40 to +125
74AUP2G08	Dual 2-input AND gate	1.1 to 3.6	CMOS	±1.9	8,2	30 pF	70	2	-40 to +125
74AXP1G08	Single 2-input AND gate	0.7 to 2.75	CMOS	±4.5	2,6	5pF	70	1	-40 to +85
74HC08	Quad 2-input AND gate	2.0 to 6.0	CMOS	±5.2	7	50 pF	36	4	-40 to +125
74HC11	Triple 3-input AND gate	2.0 to 6.0	CMOS	±5.2	10	50 pF	36	3	-40 to +125
74HC1G08	Single 2-input AND gate	2.0 to 6.0	CMOS	±5.2	7	50 pF	36	1	-40 to +125
74HC21	Dual 4-input AND gate	2.0 to 6.0	CMOS	±5.2	10	50 pF	36	2	-40 to +125
74HC2G08	Dual 2-input AND gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	2	-40 to +125
74HCT08	Quad 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±4	11	50 pF	36	4	-40 to +125
74HCT11	Triple 3-input AND gate	4.5 to 5.5	TTL	±4	11	50 pF	36	3	-40 to +125
74HCT1G08	Single 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±2	11	50 pF	36	1	-40 to +125
74HCT1G08	Single 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±2	11	50 pF	36	1	-40 to +125
74HCT2G08	Dual 2-Input AND gate; TTL-enabled	4.5 to 5.5	TTL	±4	14	50 pF	36	2	-40 to +125
74LV08	Quad 2-input AND gate	1.0 to 5.5	TTL	±12	7	50 pF	30	4	-40 to +125
74LVC08	Quad 2-input AND gate	1.2 to 3.6	TTL	±24	2,1	50 pF	150	4	-40 to +125
74LVC11	Triple 3-input AND gate	1.2 to 3.6	TTL	±24	3,7	50 pF	150	3	-40 to +125
74LVC1G08	Single 2-input AND gate	1.65 to 5.5	CMOS / LVTTL	±24	2,1	50 pF	150	1	-40 to +125
74LVC1G11	Single 3-input AND gate	1.65 to 5.5	CMOS / LVTTL	±24	2,6	50 pF	150	1	-40 to +125
74LVC2G08	Dual 2-input AND gate	1.65 to 5.5	CMOS / LVTTL	±24	2,1	50 pF	150	2	-40 to +125
74LVT08	Quad 2-input AND gate	2.7 to 3.6	TTL	-0,5	3,4	50 pF	150	4	-40 to +85
74VHC08	Quad 2-input AND gate	2.0 to 5.5	CMOS	±8	3,5	50 pF	60	4	-40 to +125
74VHCT08	Quad 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±8	5	50 pF	60	4	-40 to +125
HEF4073	Triple 3-input AND gate	4.5 to 15.5	CMOS	±2.4	20	50 pF	10	3	-40 to +85
HEF4081	Quad 2-input AND gate	4.5 to 15.5	CMOS	±2.4	20	50 pF	10	4	-40 to +85
HEF4082	Dual 4-input AND gate	4.5 to 15.5	CMOS	±2.4	25	50 pF	10	2	-40 to +85
XC7SET08	Single 2-input AND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,6	50 pF	60	1	-40 to +125
XC7SH08	Single 2-input AND gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125

Combination Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AUP1G0832	Single 3-input AND-OR gate	1.1 to 3.6	CMOS	±1.9	6,7	30 pF	70	1	-40 to +125
74AUP1G3208	Single 3-input OR-AND gate	1.1 to 3.6	CMOS	±1.9	7,4	30 pF	70	1	-40 to +125
74AUP1G885	Dual function gate	1.1 to 3.6	CMOS	±1.9	7,6	30 pF	70	1	-40 to +125
74AUP1Z04	Crystal driver with enable and internal resistor	1.1 to 3.6	CMOS	±1.9	5,6	30 pF	70	1	-40 to +125
74AUP1Z125	Crystal driver with enable and internal resistor (3-state)	1.1 to 3.6	CMOS	±1.9	4,7	30 pF	70	1	-40 to +125
74AUP2G0604	Inverter with open drain and inverter	1.1 to 3.6	CMOS	±1.9	4	30 pF	70	2	-40 to +125
74AUP2G3404	Buffer and inverter	1.1 to 3.6	CMOS	±1.9	4	30 pF	70	2	-40 to +125
74AUP2G3407	Buffer and buffer with open drain	1.1 to 3.6	CMOS	±1.9	4,1	30 pF	70	2	-40 to +125
74AUP2T1326	Dual supply buffer/line driver; 3-state	1.1 to 3.6	CMOS	±1.9	3,8	30 pF	70	2	-40 to +125
74AUP3G0434	Dual inverter and single buffer	1.1 to 3.6	CMOS	±1.9	4	30 pF	70	3	-40 to +125
74AUP3G3404	Dual buffer and single inverter	1.1 to 3.6	CMOS	±1.9	4	30 pF	70	3	-40 to +125
74HC58	Dual AND-OR gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	2	-40 to +125
74LVC1GX04	Crystal driver	1.65 to 5.5	CMOS / LVTTL	±24	2,8	50 pF	150	1	-40 to +125
HEF4000	Dual 3-input NOR gate	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	2	-40 to +85
HEF4007	Dual complementary pair and inverter	4.5 to 15.5	CMOS	±3.4	15	50 pF	10	2	-40 to +85

Configurable Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AUP1G57	Configurable gate; Schmitt trigger	1.1 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP1G58	Configurable gate; Schmitt trigger	1.1 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP1G97	Configurable gate; Schmitt trigger	1.1 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP1G98	Configurable gate; Schmitt trigger	1.1 to 3.6	CMOS	1.9 / -1.9	8,9	30 pF	70	1	-40 to +125
74AUP1G3208	Configurable multiple function gate	0.8 to 3.6	CMOS	4 / -4	6,6	30 pF	70	1	-40 to +125
74AUP1T57	Configurable gate with voltage-level translation	2.3 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP1T58	Configurable gate with voltage-level translation	2.3 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP1T97	Configurable gate with voltage-level translation	2.3 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP1T98	Configurable gate with voltage-level translation	2.3 to 3.6	CMOS	1.9 / -1.9	8,7	30 pF	70	1	-40 to +125
74AUP2G57	Configurable multiple function gate	0.8 to 3.6	CMOS	4 / -4	6,6	30pF	70	1	-40 to +125
74AUP2G58	Configurable multiple function gate	0.8 to 3.6	CMOS	4 / -4	6,6	30pF	70	1	-40 to +125
74AUP2G97	Configurable multiple function gate	0.8 to 3.6	CMOS	4 /-4	6,6	30pF	70	1	-40 to +125
74AUP2G98	Configurable multiple function gate	0.8 to 3.6	CMOS	4 / -4	6,6	30pF	70	1	-40 to +125
74AXP1G57	Configurable gate; Schmitt trigger	0.7 to 2.75	CMOS	4.5 / -4.5	4,6	5pF	70	1	-40 to +85
74AXP1G58	Configurable gate; Schmitt trigger	0.7 to 2.75	CMOS	4.5 / -4.5	4,5	5pF	70	1	-40 to +85
74AXP1G97	Configurable gate; Schmitt trigger	0.7 to 2.75	CMOS	4.5 / -4.5	4,5	5pF	70	1	-40 to +85
74AXP1G98	Configurable gate; Schmitt trigger	0.7 to 2.75	CMOS	4.5 / -4.5	4,5	5pF	70	1	-40 to +85
74LVC1G57	Configurable gate; Schmitt trigger	1.65 to 5.5	TTL	±32	6,3	50 pF	150	1	-40 to +125
74LVC1G58	Configurable gate; Schmitt trigger	1.65 to 5.5	TTL	±32	6,3	50 pF	150	1	-40 to +125
74LVC1G97	Configurable gate; Schmitt trigger	1.65 to 5.5	TTL	±32	6,3	50 pF	150	1	-40 to +125
74LVC1G98	Configurable gate; Schmitt trigger	1.65 to 5.5	TTL	±32	6,3	50 pF	150	1	-40 to +125
74LVC1G99	Configurable gate; Schmitt trigger	1.65 to 5.5	TTL	±32	8,4	50 pF	150	1	-40 to +125

EXCLUSIVE-NOR Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	T_{amb} (°C)
74HC7266	Quad 2-input EXCLUSIVE-NOR gate	2.0 to 6.0	CMOS	±5.2	11	50 pF	36	-40 to +125
HEF4077	Quad 2-input EXCLUSIVE-NOR gate	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	-40 to +85

EXCLUSIVE-OR Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AHC1G86	2-input EXCLUSIVE-OR gate	2.0 to 5.5	CMOS	±8	3,4	50 pF	60	1	-40 to +125
74AHCT1G86	2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,5	50 pF	60	1	-40 to +125
74AHC86	Quad 2-input EXCLUSIVE-OR gate	2.0 to 5.5	CMOS	±8	3,4	50 pF	60	4	-40 to +125
74AHCT86	Quad 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,4	50 pF	60	4	-40 to +125
74AUP1G386	Single 3-input EXCLUSIVE-OR gate	1.1 to 3.6	CMOS	1.9/-1.9	8,6	30 pF	70	1	-40 to +125
74AUP2G86	Dual 2-input EXCLUSIVE-OR gate	1.1 to 3.6	CMOS	1.9/-1.9	9	30 pF	70	2	-40 to +125
74HC1G86	Single 2-input EXCLUSIVE-OR gate	2.0 to 6.0	CMOS	±2.6	9	50 pF	36	1	-40 to +125
74HCT1G86	Single 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 to 5.5	TTL	±2.0	10	50 pF	36	1	-40 to +125
74HC2G86	Dual 2-input EXCLUSIVE-OR gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	2	-40 to +125
74HCT2G86	Dual 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 to 5.5	TTL	±4.0	11	50 pF	36	2	-40 to +125
74HC86	Quad 2-input EXCLUSIVE-OR gate	2.0 to 6.0	CMOS	±5.2	11	50 pF	36	4	-40 to +125
74HCT86	Quad 2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 to 5.5	TTL	±4	14	50 pF	36	4	-40 to +125
74LV86	Quad 2-input EXCLUSIVE-OR gate	1.0 to 5.5	TTL	±12	11	50 pF	30	4	-40 to +125
74LVC1G386	Single 3-Input EXCLUSIVE-OR gate	1.65 to 5.5	CMOS/ LVTTL	±32	4,5	50 pF	150	1	-40 to +125
74LVC1G86	Single 2-input EXCLUSIVE-OR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,4	50 pF	150	1	-40 to +125
74LVC2G86	Dual 2-input EXCLUSIVE-OR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,3	50 pF	150	2	-40 to +125
74LVC86	Quad 2-input EXCLUSIVE-OR gate	1.2 to 3.6	CMOS/ LVTTL	±24	3	50 pF	150	4	-40 to +125
HEF4030	Quad 2-input EXCLUSIVE-OR gate	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	4	-40 to +85
HEF4070	Quad 2-input EXCLUSIVE-OR gate	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	4	-40 to +85
XC7SET86	2-input EXCLUSIVE-OR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,5	50 pF	60	1	-40 to +125
XC7SH86	2-input EXCLUSIVE-OR gate	2.0 to 5.5	CMOS	±8	3,4	50 pF	60	1	-40 to +125

NAND Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AHC00	Quad 2-input NAND gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	4	-40 to +125
74AHCT00	Quad 2-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,3	50 pF	60	4	-40 to +125
74AHC1G00	Single 2-input NAND gate	2.0 to 5.5	CMOS	±8	3,5	50 pF	60	1	-40 to +125
74AHCT1G00	Single 2-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,6	50 pF	60	1	-40 to +125
74AHC2G00	Dual 2-input NAND gate	2.0 to 5.5	CMOS	±8	3,5	50 pF	60	2	-40 to +125
74AHCT2G00	Dual 2-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,6	50 pF	60	2	-40 to +125

NAND Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AHC30	8-input NAND gate	2.0 to 5.5	CMOS	±8	3,6	50 pF	60	1	-40 to +125
74AHCT30	8-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,3	50 pF	60	1	-40 to +125
74ALVC00	Quad 2-input NAND gate	1.65-3.6	TTL	±24	2,1	50 pF	145	4	-40 to +85
74AUP1G00	Single 2-input NAND gate	1.1 to 3.6	CMOS	1.9/-1.9	8,3	30 pF	70	1	-40 to +125
74AUP1G132	Single 2-input NAND gate Schmitt trigger	1.1 to 3.6	CMOS	1.9/-1.9	10	30 pF	70	1	-40 to +125
74AUP1G38	Single 2-input NAND gate; open drain	1.1 to 3.6	CMOS	1,9	8,5	30 pF	70	1	-40 to +125
74AUP2G00	Dual 2-input NAND gate	1.1 to 3.6	CMOS	1.9/-1.9	8,3	30 pF	70	2	-40 to +125
74AUP2G38	Dual 2-input NAND gate; open drain	1.1 to 3.6	CMOS	1,9	8,5	30 pF	70	2	-40 to +125
74HC00	Quad 2-input NAND gate	2.0 to 6.0	CMOS	±5.2	7	50 pF	36	4	-40 to +125
74HCT00	Quad 2-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±4	10	50 pF	36	4	-40 to +125
74HC03	Quad 2-input NAND gate; open drain	2.0 to 6.0	CMOS	5,2	8	50 pF	36	4	-40 to +125
74HCT03	Quad 2-input NAND gate; open drain; TTL-enabled	4.5 to 5.5	TTL	±4	10	50 pF	36	4	-40 to +125
74HC10	Triple 3-input NAND gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	3	-40 to +125
74HCT10	Triple 3-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±4	11	50 pF	36	3	-40 to +125
74HC1G00	Single 2-input NAND gate	2.0 to 6.0	CMOS	±2.6	7	50 pF	36	1	-40 to +125
74HCT1G00	Single 2-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±2	10	50 pF	36	1	-40 to +125
74HC20	Dual 4-input NAND gate	2.0 to 6.0	CMOS	±5.2	8	50 pF	36	2	-40 to +125
74HCT20	Dual 4-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±4	13	50 pF	36	2	-40 to +125
74HC2G00	Dual 2-input NAND gate	2.0 to 6.0	CMOS	±5.6	9	50 pF	36	2	-40 to +125
74HCT2G00	Dual 2-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±4	12	50 pF	36	2	-40 to +125
74HC30	8-input NAND gate	2.0 to 6.0	CMOS	±5.2	12	50 pF	36	1	-40 to +125
74HCT30	8-input NAND gate; TTL-enabled	4.5 to 5.5	TTL	±4	12	50 pF	36	1	-40 to +125
74LV00	Quad 2-input NAND gate	1.0 to 5.5	TTL	±12	7	50 pF	30	4	-40 to +125
74LV03	Quad 2-input NAND gate; open drain	1.0 to 5.5	TTL	±12	8	50 pF	30	4	-40 to +125
74LVC00	Quad 2-input NAND gate	1.2 to 3.6	CMOS/ LVTTL	±24	2,1	50 pF	150	4	-40 to +125
74LVC10	Triple 3-input NAND gate	1.2 to 3.6	CMOS/ LVTTL	±24	3,9	50 pF	150	3	-40 to +125
74LVC1G00	Single 2-input NAND gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,2	50 pF	175	1	-40 to +125
74LVC1G10	Single 3-input NAND gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,6	50 pF	175	1	-40 to +125
74LVC1G38	Single 2-input NAND gate; open drain	1.65 to 5.5	CMOS/ LVTTL	32	2,3	50 pF	175	1	-40 to +125
74LVC2G00	Dual 2-input NAND gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,2	50 pF	175	2	-40 to +125
74LVC2G38	Dual 2-input NAND gate; open drain	1.65 to 5.5	CMOS/ LVTTL	32	2,1	50 pF	175	2	-40 to +125
74LVC30	8-input NAND gate	1.65 to 5.6	CMOS/ LVTTL	24	3,6	50 pF	175	1	-40 to +125
74LVC38	Quad 2-input NAND gate; open drain	1.2 to 3.6	CMOS/ LVTTL	24	2,2	50 pF	175	4	-40 to +125
74LVT00	Quad 2-input NAND gate	2.7 to 3.6	TTL	-0,5	2,7	50 pF	150	4	-40 to +85
74LVT10	Triple 3-input NAND gate	2.7 to 3.6	TTL	-0,5	3,8	50 pF	150	3	-40 to +85
HEF4011	Quad 2-input NAND gate	4.5 to 15.5	CMOS	±2.4	20	50 pF	10	4	-40 to +85
HEF4023	Triple 3-input NAND gate	4.5 to 15.5	CMOS	±2.4	25	50 pF	10	3	-40 to +85
HEF4068	8-input NAND gate	4.5 to 15.5	CMOS	±2.4	30	50 pF	10	1	-40 to +85

NOR Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	T_{amb} (°C)
74AHCT02	Quad 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,8	50 pF	60	4	-40 to +125
74AHC1G02	Single 2-input NOR gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125
74AHCT1G02	Single 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,5	50 pF	60	1	-40 to +125
74ALVC02	Quad 2-input NOR gate	1.65 to 3.6	TTL	±24	2,2	50 pF	150	4	-40 to +85
74AUP1G02	Single 2-input NOR gate	1.1 to 3.6	CMOS	1.9/-1.9	8,3	30 pF	70	1	-40 to +125
74AUP2G02	Dual 2-input NOR gate	1.1 to 3.6	CMOS	1.9/-1.9	8,3	30 pF	70	2	-40 to +125
74HC02	Quad 2-input NOR gate	2.0 to 6.0	CMOS	±5.2	7	50 pF	36	4	-40 to +125
74HCT02	Quad 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±4	9	50 pF	36	4	-40 to +125
74HC1G02	Single 2-input NOR gate	2.0 to 6.0	CMOS	±2.6	7	50 pF	36	1	-40 to +125
74HCT1G02	Single 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±2.0	9	50 pF	36	1	-40 to +125
74HC27	Triple 3-input NOR gate	2.0 to 6.0	CMOS	±5.2	8	50 pF	36	3	-40 to +125
74HCT27	Triple 3-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±4	10	50 pF	36	3	-40 to +125
74HC2G02	Dual 2-input NOR gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	2	-40 to +125
74HCT2G02	Dual 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±4	12	50 pF	36	2	-40 to +125
74HC4002	Dual 4-input NOR gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	2	-40 to +125
74HCT4002	Dual 4-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±4	11	50 pF	36	2	-40 to +125
74HCT2G02	Dual 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±4	12	50 pF	36	2	-40 to +125
74LV02	Quad 2-input NOR gate	1.0 to 5.5	TTL	±12	6	50 pF	30	4	-40 to +125
74LV27	Triple 3-input NOR gate	1.0 to 5.5	TTL	±12	8	50 pF	30	3	-40 to +125
74LVC02	Quad 2-input NOR gate	1.2 to 3.6	TTL	±24	2,1	50 pF	150	4	-40 to +125
74LVC1G02	Single 2-input NOR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,1	50 pF	150	1	-40 to +125
74LVC1G27	Single 3-input NOR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,6	50 pF	150	1	-40 to +125
74LVC27	Triple 3-input NOR gate	1.2 to 3.6	TTL	±24	3,4	50 pF	150	3	-40 to +125
74LVC2G02	Dual 2-input NOR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,4	50 pF	150	2	-40 to +125
74LVT02	Quad 2-input NOR gate	2.7 to 3.6	TTL	-0,5	2,8	50 pF		4	-40 to +85
74VHC02	Quad 2-input NOR gate	2.0 to 5.5	CMOS	±8	2,9	50 pF	60	4	-40 to +125
74VHCT02	Quad 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,8	50 pF	60	4	-40 to +125
HEF4001	Quad 2-input NOR gate	4.5 to 15.5	CMOS	±2.4	20	50 pF	10	4	-40 to +85
HEF4002	Dual 4-input NOR gate	4.5 to 15.5	CMOS	±2.4	20	50 pF	10	4	-40 to +85
HEF4025	Triple 3-input NOR gate	4.5 to 15.5	CMOS	±2.4	40	50 pF	10	3	-40 to +85
XC7SET02	Single 2-input NOR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,5	50 pF	60	1	-40 to +125
XC7SH02	Single 2-input NOR gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	-40 to +125

OR Gates

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	f_{max} (MHz)	Number of bits	Power dissipation considerations	T_{amb} (°C)
74AHC1G32	Single 2-input OR gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	*low*	-40 to +125
74AHCT1G32	Single 2-input OR gate	4.5 to 5.5	TTL	±8	3,3	50 pF	60	1	*low*	-40 to +125
74AHC2G32	Dual 2-input OR gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	2	*low*	-40 to +125
74AHCT2G32	Dual 2-input OR gate	4.5 to 5.5	TTL	±8	3,3	50 pF	60	2	*low*	-40 to +125
74AHC32	Quad 2-input OR gate	2.0 to 5.5	CMOS	±8	3,5	50 pF	60	4	*low*	-40 to +125
74AHCT32	Quad 2-input OR gate; TTL-enabled	4.5 to 5.5	TTL	±8	5	50 pF	60	4	*low*	-40 to +125
74ALVC32	Quad 2-input OR gate	1.65 to 3.6	TTL	±24	2	50 pF	150	4	*low*	-40 to +125
74AUP1G32	Single 2-input OR gate	1.1 to 3.6	CMOS	1.9/-1.9	7,9	30 pF	70	1	*ultra low*	-40 to +125
74AUP1G332	Single 3-input OR gate	1.1 to 3.6	CMOS	1.9/-1.9	6,8	30 pF	70	1	*ultra low*	-40 to +125
74AUP2G32	Dual 2-input OR gate	1.1 to 3.6	CMOS	1.9/-1.9	7,9	30 pF	70	2	*ultra low*	-40 to +125
74HC1G32	Single 2-input OR gate	2.0 to 6.0	CMOS	±2.6	8	50 pF	36	1	*low*	-40 to +125
74HCT1G32	Single 2-input OR gate; TTL-enabled	4.5 to 5.5	TTL	±2.0	10	50 pF	36	1	*low*	-40 to +125
74HC2G32	Dual 2-input OR gate	2.0 to 6.0	CMOS	±5.2	9	50 pF	36	2	*low*	-40 to +125
74HCT2G32	Dual 2-input OR gate; TTL-enabled	4.5 to 5.5	TTL	±4.0	13	50 pF	36	2	*low*	-40 to +125
74HC32	Quad 2-input OR gate	2.0 to 6.0	CMOS	±5.2	6	50 pF	36	4	*low*	-40 to +125
74HCT32	Quad 2-input OR gate	4.5 to 5.5	TTL	±4.0	9	50 pF	36	4	*low*	-40 to +125
74HC4075	Triple 3-input OR gate	2.0 to 6.0	CMOS	±5.2	8	50 pF	36	3	*low*	-40 to +125
74HCT4075	Triple 3-input OR gate; TTL-enabled	4.5 to 5.5	TTL	±4	10	50 pF	36	3	*low*	-40 to +125
74LV32	Quad 2-input OR gate	1.0 to 5.5	TTL	±12	6	50 pF	30	4	*low*	-40 to +125
74LVC1G32	Single 2-input OR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,1	50 pF	150	1	*low*	-40 to +125
74LVC1G332	Single 3-input OR gate	1.65 to 5.5	CMOS/ LVTTL	±32		50 pF	150	1	*low*	-40 to +125
74LVC2G32	Dual 2-input OR gate	1.65 to 5.5	CMOS/ LVTTL	±32	2,2	50 pF	150	2	*low*	-40 to +125
74LVC32	Quad 2-input OR gate	1.2 to 3.6	CMOS/ LVTTL	±24	2,1	50 pF	150	4	*low*	-40 to +125
74LVC332	Triple 3-input OR gate	1.2 to 3.6	CMOS/ LVTTL	±24	2,4	50 pF	150	3	*low*	-40 to +125
74LVT32	Quad 2-input OR gate	2.7 to 3.6	TTL	-0,625	3,2	50 pF		4	*medium*	-40 to +125
74VHC32	Quad 2-input OR gate	2.0 to 5.5	CMOS	±8	3,5	50 pF	60	4	*low*	-40 to +125
74VHCT32	Quad 2-input OR gate; TTL-enabled	4.5 to 5.5	TTL	±8	5	50 pF	60	4	*low*	-40 to +125
HEF4071	Quad 2-input OR gate	4.5 to 15.5	CMOS	±2.4	20	50 pF	10	4	*low*	-40 to +125
HEF4072	Dual 4-input OR gate	4.5 to 15.5	CMOS	±2.4	25	50 pF	10	2	*low*	-40 to +85
HEF4075	Triple 3-input OR gate	4.5 to 15.5	CMOS	±2.4	25	50 pF	10	3	*low*	-40 to +85
XC7SET32	Single 2-input OR gate; TTL-enabled	4.5 to 5.5	TTL	±8	3,3	50 pF	60	1	*low*	-40 to +125
XC7SH32	Single 2-input OR gate	2.0 to 5.5	CMOS	±8	3,2	50 pF	60	1	*low*	-40 to +125

Level shifters/translators

Type number	Description	V_{CC} (V)	$V_{CC(B)}$ (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	Number of bits	T_{amb} (°C)
74ALVC164245	16-bit dual-supply voltage-translating transceiver (3-state)	1.5 to 5.5	1.5 to 3.6	CMOS/ LVTTL	±24	2,9	50	16	-40 to +85
74AUP1T34	Single dual-supply translating buffer	1.1 to 3.6	1.1 to 3.6	CMOS	±1.9	15,2	30	1	-40 to +125
74AUP1T45	Single dual-supply voltage-translating transceiver (3-state)	1.1 to 3.6	1.1 to 3.6	CMOS	±1.9	15,6	30	1	-40 to +125
74AVC16T245	16-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	16	-40 to +125
74AVC1T45	Single dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	1	-40 to +125
74AVC1T1022	1-to-4 fan out buffer	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30pF	1	-40 to +125
74AVC20T245	20-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	3,5	30	20	-40 to +125
74AVC2T45	Dual-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	2	-40 to +125
74AVC2T245	2-bit dual-supply voltage-translating transceiver	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	2	-40 to +125
74AVC32T245	32-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	32	-40 to +125
74AVC4T245	4-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	4	-40 to +125
74AVC4TD245	4-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	4	-40 to +125
74AVC8T245	8-bit dual-supply voltage-translating transceiver (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	8	-40 to +125
74AVCH16T245	16-bit dual-supply voltage-translating transceiver with bus hold (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	16	-40 to +125
74AVCH1T45	Single dual-supply voltage-translating transceiver with bus hold (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	1	-40 to +125
74AVCH20T245	20-bit dual-supply voltage-translating transceiver with bus hold (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	3,5	30	20	-40 to +125
74AVCH2T45	Dual-bit dual-supply voltage-translating transceiver with bus hold (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	2	-40 to +125
74AVCH4T245	4-bit dual-supply voltage-translating transceiver with bus hold (3-state)	0.8 to 3.6	0.8 to 3.6	CMOS/ LVTTL	±12	2,1	30	4	-40 to +125
74HC4049	Hex inverter with 15 V-tolerant inputs	2.0 to 6.0	N/A	CMOS	±5.2	8	50	6	-40 to +125
74HC4050	Hex buffer with 15 V-tolerant inputs	2.0 to 6.0	N/A	CMOS	±5.2	7	50	6	-40 to +125
74LVC1T45	Single dual-supply voltage-translating transceiver (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	2,5	50	1	-40 to +125
74LVCH1T45	Single dual-supply voltage-translating transceiver with bus hold (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	2,5	50	1	-40 to +125
74LVC2T45	Dual-bit dual-supply voltage-translating transceiver (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	2,5	50	2	-40 to +125
74LVCH2T45	Dual-bit dual-supply voltage-translating transceiver with bus hold (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	2,5	50	2	-40 to +125
74LVC8T245	8-bit dual-supply voltage-translating transceiver (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	3,5	50	8	-40 to +125
74LVCH8T245	8-bit dual-supply voltage-translating transceiver with bus hold (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	3,5	50	8	-40 to +125
74LVC4245	8-bit dual-supply voltage-translating transceiver (3-state)	1.2 to 5.5	1.2 to 5.5	CMOS/ LVTTL	±24	3,5	50	8	-40 to +125
HEF4104	Quad low-to-high voltage translator (3-state)	3.0 to 15.0	3.0 to 15.0	CMOS	±2.4	3,4	50	16	-40 to +85
74AXP1T14	Dual-supply schmitt-trigger inverter	0.7 to 2.75	1.2 to 5.5	CMOS	±12	3,4	50	1	-40 to +125
74AXP1T32	Dual-supply 2-input or gate	0.7 to 2.75	1.2 to 5.5	CMOS	±12	3,4	50	1	-40 to +125
74AXP1T34	Single dual-supply voltage-translating buffer	0.7 to 2.75	1.2 to 5.5	CMOS	±12	3,4	50	1	-40 to +125
74AXP1T57	Schmitt-trigger inputs, Dual supply configurable multiple function gate	0.7 to 2.75	1.2 to 5.5	CMOS	±12	4,8	50	1	-40 to +85
74AXP1T125	Dual-supply buffer/line driver (3-state)	0.7 to 2.75	1.2 to 5.5	CMOS	±12	4,8	50	1	-40 to +125
74AXP2T08	Dual-supply 2-input AND gate	0.7 to 2.75	1.2 to 5.5	CMOS	±12	4,8	50	1	-40 to +125
74AXP2T3407	Dual-supply single buffer and single buffer with open drain	0.7 to 2.75	1.2 to 5.5	CMOS	±12	4,8	50	1	-40 to +125

Digital comparators

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	Number of bits	T_{amb} (°C)
74HC688	8-bit magnitude comparator	2.0 to 6.0	CMOS	±5.2	17	50 pF	8	-40 to +125
74HCT688	8-bit magnitude comparator; TTL-enabled	4.5 to 5.5	TTL	±4.0	17	50 pF	8	-40 to +125
74HC85	4-bit magnitude comparator	2.0 to 6.0	CMOS	±5.2	23	50 pF	4	-40 to +125
74HCT85	4-bit magnitude comparator; TTL-enabled	4.5 to 5.5	TTL	±4.0	26	50 pF	4	-40 to +125
HEF4585	4-bit magnitude comparator	4.5 to 15.5	CMOS	±2.4	65	50 pF	4	-40 to +85

Multivibrators

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	T_{amb} (°C)
74AHC123	Dual retriggerable monostable multivibrator with reset	2.0 to 5.5	CMOS	±8	5,1	50 pF	-40 to +125
74AHCT123	Dual retriggerable monostable multivibrator with reset; TTL-enabled	4.5 to 5.5	TTL	±8	5	50 pF	-40 to +125
74HC123	Dual retriggerable monostable multivibrator with reset	2.0 to 6.0	CMOS	±7.8	9	50 pF	-40 to +125
74HCT123	Dual retriggerable monostable multivibrator with reset; TTL-enabled	4.5 to 5.5	TTL	±4	26	50 pF	-40 to +125
74HC221	dual non-retriggerable monostable multivibrator with reset	2.0 to 6.0	CMOS	±5.2	29	50 pF	-40 to +125
74HCT221	dual non-retriggerable monostable multivibrator with reset; TTL-enabled	4.5 to 5.5	TTL	±4	32	50 pF	-40 to +125
74HC423	Dual retriggerable monostable multivibrator with reset	2.0 to 6.0	CMOS	±5.2	23	50 pF	-40 to +125
74HCT423	Dual retriggerable monostable multivibrator with reset; TTL-enabled	4.5 to 5.5	TTL	±4	26	50 pF	-40 to +125
74HC4538	Dual retriggerable precision monostable multivibrator	2.0 to 6.0	CMOS	±5.2	27	50 pF	-40 to +125
74HCT4538	Dual retriggerable precision monostable multivibrator; TTL-enabled	4.5 to 5.5	TTL	±4	30	50 pF	-40 to +125
74LV123	Dual retriggerable monostable multivibrator with reset	1.0 to 5.5	TTL	±12	20	50 pF	-40 to +125
74LVC1G123	Single retriggerable monostable multivibrator	1.65 to 5.5	CMOS/LVTTL	±32	3,5	50 pF	-40 to +125
HEF4047	Monostable/astable multivibrator	4.5 to 15.5	CMOS	±2.4	50	50 pF	-40 to +85
HEF4528	Dual retriggerable monostable multivibrator with reset	4.5 to 15.5	CMOS	±2.4	40	50 pF	-40 to +85

Parity generators-checkers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	T_{amb} (°C)
74HC280	9-bit odd/even parity generator/checker	2.0 to 6.0	CMOS	±5.2	17	50 pF	-40 to +125
74HCT280	9-bit odd/even parity generator/checker; TTL-enabled	4.5 to 5.5	TTL	±4	18	50 pF	-40 to +125

Phase-locked loops

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	T_{amb} (°C)
74HC4046	Phase-locked loop with VCO	3.0 to 6.0	CMOS	±5.2	18	50 pF	21
74HCT4046	Phase-locked loop with VCO; TTL-enabled	4.5 to 5.5	TTL	±4	23	50 pF	19
74HC7046	Phase-locked loop with lock detector	3.0 to 6.0	CMOS	±5.2	17	50 pF	19
74HCT7046	Phase-locked loop with lock detector; TTL-enabled	4.5 to 5.5	TTL	±4	21	50 pF	19
74HCT9046	Phase-locked loop with bandgap controlled VCO; TTL-enabled	4.5 to 5.5	TTL	±4	23	50 pF	19
HEF4046	Phase-locked loop with VCO	4.5 to 15.5	CMOS	±2.4		50 pF	2,7

Printer interfaces

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	T_{amb} (°C)
PDI1284P11	Parallel interface transceiver/buffer	3.0 to 3.6	LVTTL	- 14 / 14	13,9	50 pF	0 to +70

CBT Bus switches

Type number	Description	V_{CC} (V)	$V_{PAS}S$ (V)	Logic switching levels	R_{ON}(Ω)	f(-3dB) (MHz)	Number of bits	t_{pd} (ns)	T_{amb} (°C)
74CBTLV16211	24-bit bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	10	0,2	-40 to +125
74CBTLV1G125	Single bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	1	0,2	-40 to +125
74CBTLV3125	Quad bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	4	0,2	-40 to +125
74CBTLV3126	Quad bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	4	0,2	-40 to +125
74CBTLV3244	Octal bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	8	0,2	-40 to +125
74CBTLV3245	Octal bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	8	0,2	-40 to +125
74CBTLV3253	Dual 4:1 mux/demux	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	2	0,2	-40 to +125
74CBTLV3257	Quad 2:1 mux/demux	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	4	0,2	-40 to +125
74CBTLV3306	2-bit bus switch	2.3 to 3.6	3,3	CMOS/LVTTL	7	400	2	0,2	-40 to +125
74CBTLV3384	10-bit bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	10	0,2	-40 to +125
74CBTLV3861	10-bit bus switch	2.3 to 3.6	3,3	CMOS / LVTTL	7	400	10	0,2	-40 to +125
74CBTLVD3244	Octal bus switch level translator	3.0 to 3.6	1,8	CMOS / LVTTL	7	400	8	0,2	-40 to +125
74CBTLVD3245	Octal bus switch level translator	3.0 to 3.6	1,8	CMOS / LVTTL	7	400	8	0,2	-40 to +125
74CBTLVD3384	10-bit bus switch level translator	3.0 to 3.6	1,8	CMOS / LVTTL	7	400	10	0,2	-40 to +125
74CBTLVD3861	10-bit bus switch level translator	3.0 to 3.6	1,8	CMOS / LVTTL	7	400	10	0,2	-40 to +125
CBT16210	20-bit bus switch	4.5 to 5.5	3,9	TTL	7	300	20	0,25	-40 to +85
CBT16211	24-bit bus switch	4.5 to 5.5	3,9	TTL	7	300	24	0,25	-40 to +85
CBT16212	24-bit bus exchange switch	4.5 to 5.5	3,9	TTL	7	300	24	0,25	-40 to +85
CBT16292	12-bit 2:1 mux/demux	4.5 to 5.5	3,9	TTL	8	300	12	0,4	-40 to +85
CBT3125	Quad bus switch	4.5 to 5.5	3,9	TTL	7	300	4	0,25	-40 to +85
CBT3126	Quad bus switch	4.5 to 5.5	3,9	TTL	7	300	4	0,25	-40 to +85
CBT3244	Octal bus switch	4.5 to 5.5	3,9	TTL	7	300	8	0,25	-40 to +85
CBT3245	Octal bus switch	4.5 to 5.5	3,9	TTL	7	300	8	0,25	-40 to +85
CBT3251	8:1 mux/demux	4.5 to 5.5	3,9	TTL	7	300	8	0,25	-40 to +85
CBT3253	Dual 4:1 mux/demux	4.5 to 5.5	3,9	TTL	7	300	2	0,25	-40 to +85
CBT3257	Quad 2:1 mux/demux	4.5 to 5.5	3,9	TTL	7	300	4	0,25	-40 to +85
CBT3306	Dual bus switch	4.5 to 5.5	3,9	TTL	7	300	2	0,25	-40 to +85
CBT3384	10-bit bus switch	4.5 to 5.5	3,9	TTL	7	300	10	0,25	-40 to +85
CBT3861	10-bit bus switch	4.5 to 5.5	3,9	TTL	7	300	10	0,25	-40 to +85
CBTD16210	20-bit bus switch level translator	4.5 to 5.5	3,3	TTL	7	300	20	0,25	-40 to +85
CBTD16211	24-bit bus switch level translator	4.5 to 5.5	3,3	TTL	7	300	24	0,25	-40 to +85
CBTD3306	Dual bus switch level translator	4.5 to 5.5	3,3	TTL	7	300	2	0,25	-40 to +85
CBTD3384	10-bit bus switch level translator	4.5 to 5.5	3,3	TTL	7	300	10	0,25	-40 to +85
CBTD3861	10-bit bus switch level translator	4.5 to 5.5	3,3	TTL	7	300	10	0,25	-40 to +85

Decoders demultiplexers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	t_{pd} (ns)	Output Load $C_{L\ (Typ)}$	T_{amb} (°C)
74AHC138	3-to-8 line decoder/demultiplexer; inverting	2.0 to 5.5	CMOS	±8	4,4	50 pF	-40 to +125
74AHCT138	3-to-8 line decoder/demultiplexer; inverting; TTL-enabled	4.5 to 5.5	TTL	±8	4,4	50 pF	-40 to +125
74AHC139	Dual 2-to-4 line decoder/demultiplexer	2.0 to 5.5	CMOS	±8	3,9	50 pF	-40 to +125
74AHCT139	Dual 2-to-4 line decoder/demultiplexer; TTL-enabled	4.5 to 5.5	TTL	±8	3,6	50 pF	-40 to +125
74AUP1G18	1-to-2 demultiplexer (3-state)	1.1 to 3.6	CMOS	1.9/-1.9	3,2	30 pF	-40 to +125
74AUP1G19	1-to-2 decoder/demultiplexer	1.1 to 3.6	CMOS	1.9/-1.9	3	30 pF	-40 to +125
74HC138	3-to-8 line decoder/demultiplexer; inverting	2.0 to 6.0	CMOS	±5.2	12	50 pF	-40 to +125
74HCT138	3-to-8 line decoder/demultiplexer; inverting; TTL-enabled	4.5 to 5.5	TTL	±4	19	50 pF	-40 to +125
74HC139	Dual 2-to-4 line decoder/demultiplexer	2.0 to 6.0	CMOS	±5.2	14	50 pF	-40 to +125
74HCT139	Dual 2-to-4 line decoder/demultiplexer; TTL-enabled	4.5 to 5.5	TTL	±4	16	50 pF	-40 to +125
74HC154	4-to-16 line decoder/demultiplexer	2.0 to 6.0	CMOS	±5.2	11	50 pF	-40 to +125
74HCT154	4-to-16 line decoder/demultiplexer; TTL-enabled	4.5 to 5.5	TTL	±4	13	50 pF	-40 to +125
74HC238	3-to-8 decoder/demultiplexer	2.0 to 6.0	CMOS	±5.2	14	50 pF	-40 to +125
74HCT238	3-to-8 decoder/demultiplexer; TTL-enabled	4.5 to 5.5	TTL	±4	18	50 pF	-40 to +125
74HC42	BCD to decimal decoder (1-of-10)	2.0 to 6.0	CMOS	±5.2	17	50 pF	-40 to +125
74HCT42	BCD to decimal decoder (1-of-10); TTL-enabled	4.5 to 5.5	TTL	±4	20	50 pF	-40 to +125
74HC4511	BCD to 7-segment latch/decoder/driver with lamp test input	2.0 to 6.0	CMOS	-10	28	50 pF	-40 to +125
74HCT4511	BCD to 7-segment latch/decoder/driver with lamp test input; TTL-enabled	4.5 to 5.5	TTL	-10	28	50 pF	-40 to +125
74HC4514	4-to-16 decoder/demultiplexer with address latches	2.0 to 6.0	CMOS	±5.2	27	50 pF	-40 to +125
74HCT4514	4-to-16 decoder/demultiplexer with address latches; TTL-enabled	4.5 to 5.5	TTL	±4	30	50 pF	-40 to +125
74HC4515	4-to-16 decoder/demultiplexer with address latches; inverting	2.0 to 6.0	CMOS	±5.2	29	50 pF	-40 to +125
74HCT4515	4-to-16 decoder/demultiplexer with address latches; inverting; TTL-enabled	4.5 to 5.5	TTL	±4	30	50 pF	-40 to +125
74HC137	3-to-8 line decoder/demultiplexer with address latches; inverting	2.0 to 6.0	CMOS	±5.2	18	50 pF	-40 to +125
74HC237	3-to-8 decoder/demultiplexer with address latches	2.0 to 6.0	CMOS	±5.2	18	50 pF	-40 to +125
74LV138	3-to-8 line decoder/demultiplexer; inverting	1.0 to 5.5	TTL	±12	12	50 pF	-40 to +125
74LVC138	3-to-8 line decoder/demultiplexer; inverting	1.2 to 3.6	CMOS/LVTTL	±24	2,7	50 pF	-40 to +125
74LV139	Dual 2-to-4 line decoder/demultiplexer	1.0 to 5.5	TTL	±12	11	50 pF	-40 to +125
74LVC139	Dual 2-to-4 line decoder/demultiplexer	1.2 to 3.6	CMOS/LVTTL	±24	2,5	50 pF	-40 to +125
74LVC1G18	1-to-2 demultiplexer (3-state)	1.65 to 5.5	CMOS/LVTTL	±32	2,3	50 pF	-40 to +125
HEF4028	1-of-10 decoder	4.5 to 15	CMOS	±2.4	30	50 pF	-40 to +85
HEF4511	BCD to 7-segment latch/decoder/driver with lamp test input	4.5 to 15	CMOS	-25/2.4	40	50 pF	-40 to +85
HEF4514	4-to-16 decoder/demultiplexer with address latches	4.5 to 15	CMOS	±2.4	65	50 pF	-40 to +85
HEF4543	BCD to 7-segment latch/decoder/driver with phase input	4.5 to 15	CMOS	±2.4	55	50 pF	-40 to +85
HEF4555	Dual 1-to-4 line decoder/demultiplexer	4.5 to 15	CMOS	±2.4	30	50 pF	-40 to +85

Digital multiplexers

Type number	Description	V_{CC} (V)	Logic switching levels	Output drive capability (mA)	Output Load CL (Typ)	t_{pd} (ns)	T_{amb} (°C)
74AHC157	Quad 2-input multiplexer	2.0 to 5.5	CMOS	±8	50 pF	3,2	
74AHCT157	Quad 2-input multiplexer; TTL-enabled	4.5 to 5.5	TTL	±8	50 pF	3,2	-40 to +125
74AHC257	Quad 2-input multiplexer (3-state)	2.0 to 5.5	CMOS	±8	50 pF	2,9	-40 to +125
74AHCT257	Quad 2-input multiplexer; TTL-enabled (3-state)	4.5 to 5.5	TTL	±8	50 pF	3,7	-40 to +125
74AUP1G157	Single 2-input multiplexer	1.1 to 3.6	CMOS	1.9/-1.9	30 pF	3,2	-40 to +125
74AUP1G158	Single 2-input multiplexer; inverting	1.1 to 3.6	CMOS	1.9/-1.9	30 pF	3,2	-40 to +125
74AUP2G157	Single 2-input multiplexer	1.1 to 3.6	CMOS	1.9/-1.9	30 pF	3,4	-40 to +125
74HC151	8-input multiplexer	2.0 to 6.0	CMOS	±5.2	50 pF	17	-40 to +125
74HCT151	8-input multiplexer; TTL-enabled	4.5 to 5.5	TTL	±4	50 pF	19	-40 to +125
74HC153	Dual 4-input multiplexer	2.0 to 6.0	CMOS	±5.2	50 pF	17	-40 to +125
74HCT153	Dual 4-input multiplexer; TTL-enabled	4.5 to 5.5	TTL	±4	50 pF	19	-40 to +125
74HC157	Quad 2-input multiplexer	2.0 to 6.0	CMOS	±5.2	50 pF	11	-40 to +125
74HCT157	Quad 2-input multiplexer; TTL-enabled	4.5 to 5.5	TTL	±4	50 pF	13	-40 to +125
74HC251	8-input multiplexer (3-state)	2.0 to 6.0	CMOS	±5.2	50 pF	18	-40 to +125
74HCT251	8-input multiplexer; TTL-enabled (3-state)	4.5 to 5.5	TTL	±4	50 pF	22	-40 to +125
74HC253	Dual 4-input multiplexer (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	17	-40 to +125
74HCT253	Dual 4-input multiplexer; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	17	-40 to +125
74HC257	Quad 2-input multiplexer (3-state)	2.0 to 6.0	CMOS	±7.8	50 pF	11	-40 to +125
74HCT257	Quad 2-input multiplexer; TTL-enabled (3-state)	4.5 to 5.5	TTL	±6	50 pF	13	-40 to +125
74HC158	Quad 2-input multiplexer; inverting	2.0 to 6.0	CMOS	±5.2	50 pF	12	-40 to +125
74LV153	Dual 4-input multiplexer	1.0 to 3.6	TTL	±6	50 pF	14	-40 to +125
74LV251	8-input multiplexer (3-state)	1.0 to 3.6	TTL	±6	50 pF	17	-40 to +125
74LVC157	Quad 2-input multiplexer	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,5	-40 to +125
74LVC1G157	Single 2-input multiplexer	1.65 to 5.5	CMOS/LVTTL	±32	50 pF	2,2	-40 to +125
74LVC257	Quad 2-input multiplexer (3-state)	1.2 to 3.6	CMOS/LVTTL	±24	50 pF	2,4	-40 to +125

Digital switches

Type number	Description	V_{CC} (V)	Logic switching levels	R_{ON} (Ω)	R_{ON}(FLAT) (Ω)	f(-3dB) (MHz)	T_{HD} (%)	X_{talk} (dB)	T_{amb} (°C)
74AHC1G66	Single-pole, single-throw analog switch	2.0 to 5.5	CMOS	40	14	280	0,015		-40 to +125
74AHCT1G66	Single-pole, single-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	40	14	280	0,015		-40 to +125
74HC1G66	Single-pole, single-throw analog switch	2.0 to 9.0	CMOS	105	23	200	0,02		-40 to +125
74HCT1G66	Single-pole, single-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	118	23	180	0,04		-40 to +125
74HC2G66	Dual single-pole, single-throw analog switch	2.0 to 9.0	CMOS	105	23	200	0,02	-60	-40 to +125
74HCT2G66	Dual single-pole, single-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	118	23	180	0,04	-60	-40 to +125
74HC4016	Quad single-pole, single-throw analog switch	2.0 to 10.0	CMOS	300	80	160	0,4	-60	-40 to +125
74HCT4016	Quad single-pole, single-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	400	50	150	0,8	-60	-40 to +125
74HC4051	Single-pole, octal-throw analog switch	2.0 to 10.0	CMOS	200	20	180	0,02		-40 to +125
74HCT4051	Single-pole, octal-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	225	20	170	0,04		-40 to +125
74HC4052	Dual single-pole, quad-throw analog switch	2.0 to 10.0	CMOS	200	20	180	0,02	-60	-40 to +125
74HCT4052	Dual single-pole, quad-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	225	20	170	0,04	-60	-40 to +125
74HC4053	Triple single-pole, double-throw analog switch	2.0 to 10.0	CMOS	200	20	170	0,02		-40 to +125
74HCT4053	Triple single-pole, double-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	225	20	160	0,04		-40 to +125
74HC4066	Quad single-pole, single-throw analog switch	2.0 to 10.0	CMOS	105	23	200	0,02	-60	-40 to +125
74HCT4066	Quad single-pole, single-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	118	23	180	0,04	-60	-40 to +125
74HC4067	Single-pole, 16-throw analog switch	2.0 to 10.0	CMOS	200	25	100	0,02		-40 to +125
74HCT4067	Single-pole, 16-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	225	25	90	0,04		-40 to +125
74HC4316	Quad single-pole, single-throw analog switch with translation	2.0 to 10.0	CMOS	300	80	160	0,4	-60	-40 to +125
74HCT4316	Quad single-pole, single-throw analog switch with translation; TTL-enabled	4.5 to 5.5	TTL	400	50	150	0,8	-60	-40 to +125
74HC4351	Single-pole, octal-throw analog switch with latch	2.0 to 10.0	CMOS	200	20	180	0,02		-40 to +125
74HCT4351	Single-pole, octal-throw analog switch with latch; TTL-enabled	4.5 to 5.5	TTL	225	20	170	0,04		-40 to +125
74HC4353	Triple single-pole, double-throw analog switch with latch	4.5 to 5.5	TTL	225	20	160	0,04	-60	-40 to +125
74HCT4353	Triple single-pole, double-throw analog switch with latch; TTL-enabled	4.5 to 5.5	TTL	225	20	160	0,04	-60	-40 to +125
74HC4851	Single-pole, octal-throw analog switch	2.0 to 10.0	CMOS	220					-40 to +125
74HCT4851	Single-pole, octal-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	240					-40 to +125
74HC4852	Dual single-pole, quad-throw analog switch; TTL-enabled	2.0 to 10.0	CMOS	220					-40 to +125
74HCT4852	Dual single-pole, quad-throw analog switch; TTL-enabled	4.5 to 5.5	TTL	240					-40 to +125
74LV4051	Single-pole, octal-throw analog switch	1.0 to 6.0	TTL	135	35	200	0,4	-60	-40 to +125
74LV4052	Dual single-pole, quad-throw analog switch	1.0 to 6.0	TTL	125	15	180	0,4	-60	-40 to +125
74LV4053	Triple single-pole, double-throw analog switch	1.0 to 6.0	TTL	150	30	180	0,4	-60	-40 to +125
74LV4066	Quad single-pole, single-throw analog switch	1.0 to 6.0	TTL	50	3	180	0,02	-60	-40 to +125
74LVC1G3157	Single-pole, double-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	300	0,078		-40 to +125
74LVC1G384	Single-pole, single-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	440	0,001		-40 to +125
74LVC1G53	Single-pole, double-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	300	0,078		-40 to +125
74LVC1G66	Single-pole, single-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	440	0,001		-40 to +125
74LVC2G53	Single-pole, double-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	300	0,078		-40 to +125
74LVC2G66	Dual single-pole, single-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	440	0,005		-40 to +125
74LVC2G3157	Double-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	440	0,005		-40 to +125
74LVC4066	Quad single-pole, single-throw analog switch	1.65 to 5.5	CMOS/ LVTTL	15	1,5	440	0,005		-40 to +125
74LVCV2G66	Dual single-pole, single-throw analog switch; overvoltage tolerant	2.3 to 5.5	CMOS/ LVTTL	15	3	210	0,01		-40 to +125
HEF4016	Quad single-pole, single-throw analog switch	4.5 to 15.5	CMOS	350	65	90	0,04	-50	-40 to +85
HEF4051	Single-pole, octal-throw analog switch	4.5 to 15.5	CMOS	175	30	70	0,04	-50	-40 to +85
HEF4052	Dual single-pole, quad-throw analog switch	4.5 to 15.5	CMOS	175	30	70	0,04	-50	-40 to +85
HEF4053	Triple single-pole, double-throw analog switch	4.5 to 15.5	CMOS	175	30	70	0,04	-50	-40 to +85
HEC4066	Quad single-pole, single-throw analog switch	4.5 to 15.5	CMOS	175	20	90	0,04	-50	-40 to +85
HEF4067	Single-pole, 16-throw analog switch	4.5 to 15.5	CMOS	175	20	13	0,04	-50	-40 to +85

Standard logic functions

74 XXX XXX XXX

Logic family	Function number	Package type	
AHC(T)		BQ	DQFN
ALVC		BX	DQFN
ALVT		D	SO
AUP		DB	SSOP
AVC(M)		DC	VSSOP
CBT(D)		DG	TSSOP
CBTLV(D)		DGG	TSSOP
HC(T)		DL	SSOP
HEF4000B		DP	TSSOP
LV		FC	BGA
LVC		EV	BGA
LVT		GU	DQFN
NPIC		P	TSSOP
VHC(T)		T	SO
XC7		TS	SSOP
		TT	TSSOP

Mini logic functions

74 XXX XG / XT XXX XXX

Logic family	Gate format	Function number	Package type	
AHC(T)	1G Single-gate		DC	PicoGate
AUP	2G Dual-gate		DP	PicoGate
AVC(M)	3G Triple-gate		GD	MicroPak
AXP			GF	MicroPak
CBT(D)	**Translator format**		GM	MicroPak
CBTLV(D)	1T Single-translator		GN	MicroPak
HC(T)	2T Dual-translator		GS	MicroPak
LVC	3T Triple-translator		GT	MicroPak
XC7	4T Quad-translator		GV	PicoGate
			GW	PicoGate
			GX	MicroPak

Packages 6

Package details and packing methods SMD – Part 1

Package details					Packing methods																	
Pins/ Terminals	Package	Package size (l x w x h) (mm)	Lead pitch (mm)	Package	Packing method and tape dimension	Reel dimension (d x w) (mm)	Packing quantity and ordering code (12NC ending)															
							500	800	1000	1400	1500	2000	2500	3000	3500	4000	4500	5000	6000	8000	9000	10000
2	DSN0402-2 (SOD992)	0.4 x 0.2 x 0.12	0.25		2 mm pitch, 8 mm tape and reel	180 x 8																-315
	DSN0603-2 (SOD962)	0.6 x 0.3 x 0.3	0.4		2 mm pitch. 8 mm tape and reel	180 x 8															-315	
	DSN1006U-2 (SOD995)	1.0 x 0.6 x 0.3	0.55		2 mm pitch, 8 mm tape and reel	180 x 8																-315
	DSN1006-2 (SOD993)	1.0 x 0.6 x 0.3	0.65		2 mm pitch, 8 mm tape and reel	180 x 8																-315
	DFN1006D-2 (SOD882D)	1.0 x 0.6 x 0.37	0.65		2 mm pitch. 8 mm tape and reel	180 x 8																-315
	DFN1006-2 (SOD882)	1.0 x 0.6 x 0.48	0.65		2 mm pitch. 8 mm tape and reel	180 x 8																-315
	SOD523 (SC-79)	1.2 x 0.8 x 0.6			2 mm pitch. 8 mm tape and reel	180 x 8														-315		
					4 mm pitch. 8 mm tape and reel	180 x 8								-115								
					4 mm pitch. 8 mm tape and reel	286 x 8																-135
	DFN1608-2 (SOD963)	1.6 x 0.8 x 0.25	0.885		2 mm pitch. 8 mm tape and reel	180 x 8														-315		
	DFN1608D-2 (SOD 1608)	1.6 x 0.8 x 0.37	0.94		2 mm pitch. 8 mm tape and reel	180 x 8														-315		
	DSN1608-2 (SOD964)	1.6 x 0.8 x 0.37	0.94		2 mm pitch. 8 mm tape and reel	180 x 8														-315		
	SOD323F (SC-90)	1.7 x 1.25 x 0.7			4 mm pitch. 8 mm tape and reel	180 x 8								-115								
						286 x 8																-135
	SOD323 (SC-76)	1.7 x 1.25 x 0.95			4 mm pitch. 8 mm tape and reel	180 x 8								-115								
					4 mm pitch. 8 mm tape and reel	286 x 8																-135
					10 reels in one box	286 x 8																-135
	SOD123F	2.6 x 1.6 x 1.1			4 mm pitch. 8 mm tape and reel	180 x 8								-115								
	CFP3 (SOD123W)	2.6 x 1.7 x 1.0			4 mm pitch. 8 mm tape and reel	180 x 8								-115								
	SOD123	2.7 x 1.6 x 1.2			4 mm pitch. 8 mm tape and reel	180 x 8								-115								
						286 x 8																-118
	SOD80C (MiniMelf)	3.5 x 1.5 x 1.5			4 mm pitch. 8 mm tape and reel	180 x 8							-115									
					4 mm pitch. 8 mm tape and reel	330 x 8																-135
	CFP5 (SOD128)	3.8 x 2.5 x 1.0			4 mm pitch. 12 mm tape and reel	180 x 12								-115								
3	DFN1006B-3 (SOT883B)	1.0 x 0.6 x 0.37	0.65		2 mm pitch. 8 mm tape and reel	180 x 8																-315
	DFN1006-3 (SOT883)	1.0 x 0.6 x 0.48	0.65		2 mm pitch. 8 mm tape and reel	180 x 8																-315
	DFN1010D-3 (SOT1215)	1.1 x 1.0 x 0.37	0.75		4 mm pitch. 8 mm tape and reel	180 x 8												-115				
	SOT663	1.2 x 1.6 x 0.55	0.5		4 mm pitch. 8 mm tape and reel	180 x 8										-115						
	SOT323 (SC-70)	2.0 x 1.25 x 0.95	0.65		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
					4 mm pitch. 8 mm tape and reel	286 x 8																-135
	DFN2020-3 (SOT1061)	2.0 x 2.0 x 0.62	1.3		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
	DFN2020D-3 (SOT1061D)	2.0 x 2.0 x 0.62	1.3		4 mm pitch, 8 mm tape and reel	180 x 8								-115								
	SOT23	2.9 x 1.3 x 1.0	0.95		4 mm pitch. 8 mm tape and reel	180 x 8								-215								
						286 x 8																-235
					10 reels in one box	180 x 8								-185								

Package details and packing methods SMD – Part 2

Package details					Packing methods																	
Pins/ Terminals	Package	Package size (l x w x h) (mm)	Lead pitch (mm)	Package	Packing method and tape dimension	Reel dimension (d x w) (mm)	Packing quantity and ordering code (12NC ending)															
							500	800	1000	1400	1500	2000	2500	3000	3500	4000	4500	5000	6000	8000	9000	10000
3	SOT89 (SC-62)	4.5 x 2.5 x 1.5	1.5		8 mm pitch. 12 mm tape and reel	180 x 12			-115													
					8 mm pitch. 12 mm tape and reel	330 x 12										-135						
					8 mm pitch. 12 mm tape and reel	180 x 12			-146													
					8 mm pitch. 12 mm tape and reel	180 x 12			-147													
	CFP15 (SOT1289)	5.8 x 4.3 x 0.78	2.13		8 mm pitch. 12 mm tape and reel	330 x 12					-146							-139				
	DPAK (SOT428)	6.6 x 6.1 x 2.3	4.57		8 mm pitch. 16 mm tape and reel	330 x 16							-118									
	D2PAK (SOT404)	10 x 9.6 x 4.3	5.08		16 mm pitch. 24 mm tape and reel	330 x 24		118														
4	SOT143B	2.9 x 1.3 x 1.0	1.9		4 mm pitch. 8 mm tape and reel	180 x 8								-215								
					4 mm pitch. 8 mm tape and reel	286 x 8																-235
	LFPAK56 (SOT669)	4.9 x 4.45 x 1.0	1.27		8 mm pitch. 12 mm tape and reel	180 x 12					-115											
	SOT223 (SC-73)	6.5 x 3.5 x 1.65	2.3		8 mm pitch. 12 mm tape and reel	180 x 12			-115													
					8 mm pitch. 12 mm tape and reel	330 x 12										-135						
5	X2SON5 (SOT1226)	0.8 x 0.8 x 0.35	0.48		2mm pitch, 8mm tape and reel	180 x 8																-125
	SOT665	1.6 x 1.2 x 0.55	0.5		2 mm pitch. 8 mm tape and reel	180 x 8														-315		
					4 mm pitch. 8 mm tape and reel	180 x 8										-115						
	SOT353 (SC-88 A)	2.0 x 1.25 x 0.95	0.65		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
					4 mm pitch. 8 mm tape and reel	286 x 8																-135
					4 mm pitch. 8 mm tape and reel	180 x 8								-125								
					4 mm pitch. 8 mm tape and reel	286 x 8																-165
	TSOP5 (SOT753)	2.9 x 1.5 x 1.1	0.95		4mm pitch, 8mm tape and reel	180 x 8								-125								
6	X2SON6 (SOT1255)	0.8 x 1 x 0.35	0.48		2mm pitch, 8mm tape and reel	180 x 8																-147
	XSON6 (SOT1115)	0.9 x 1 x 0.35	0.3		4mm pitch, 8mm tape and reel	180 x 8												-132				
	XSON6 (SOT1202)	1 x 1 x 0.35	0.35		4mm pitch, 8mm tape and reel	180 x 8												-132				
	DFN1010-6 (SOT891)	1.0 x 1.0 x 0.48	0.35		4 mm pitch. 8 mm tape and reel	180 x 8												-132				
	XSON6 (SOT886)	1 x 1.45 x 0.5	0.5		4mm pitch, 8mm tape and reel	180 x 8												-132				
	DFN1010B-6 (SOT1216)	1.1 x 1.0 x 0.37	0.35		4 mm pitch. 8 mm tape and reel	180 x 8												-147				
	DFN1412-6 (SOT1268)	1.4 x 1.2 x 0.5	0.5		4 mm pitch. 8 mm tape and reel	180 x 8												-147				
	DFN1412-6 (SOT1268)	1.4 x 1.2 x 0.5	0.5		4 mm pitch. 8 mm tape and reel	180x8												147				
	DFN1410-6 (SOT886)	1.45 x 1.0 x 0.48	0.5		4 mm pitch. 8 mm tape and reel	180 x 8												-115				
					4 mm pitch. 8 mm tape and reel	180 x 8												-132				
	SOT666	1.6 x 1.2 x 0.55	0.5		2 mm pitch. 8 mm tape and reel	180 x 8														-315		
					4 mm pitch. 8 mm tape and reel	180 x 8										-115						
	DFN1616-6 (SOT 1189)	1.6 x 1.6 x 0.48	0.5		4 mm pitch. 8 mm tape and reel	180 x 8										-115						
	SOT363 (SC-88)	2.0 x 1.25 x 0.95	0.65		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
					4 mm pitch. 8 mm tape and reel	286 x 8																-135
					4 mm pitch. 8 mm tape and reel	180 x 8								-125								
					4 mm pitch. 8 mm tape and reel	286 x 8																-165

Package details and packing methods SMD – Part 3

Package details					Packing methods																	
Pins/ Terminals	Package	Package size (l x w x h) (mm)	Lead pitch (mm)	Package	Packing method and tape dimension	Reel dimension (d x w) (mm)	Packing quantity and ordering code (12NC ending)															
							500	800	1000	1400	1500	2000	2500	3000	3500	4000	4500	5000	6000	8000	9000	10000
6	DFN2020-6 (SOT 1118)	2.0 x 2.0 x 0.62	0.65		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
														-184								
	DFN2020D-6 (SOT1118D)	2.0 x 2.0 x 0.62	0.65		4 mm pitch, 8 mm tape and reel	180 x 8								-115								
	DFN2020MD-6 (SOT1220)	2.0 x 2.0 x 0.62	0.65		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
														-125								
	SOT457 (SC-74)	2.9 x 1.5 x 1.0	0.95		4 mm pitch. 8 mm tape and reel	180 x 8								-115								
					4 mm pitch. 8 mm tape and reel	286 x 8																-135
					4 mm pitch. 8 mm tape and reel	180 x 8								-125								
					4 mm pitch. 8 mm tape and reel	286 x 8																-165
7	DFN2111-7 (SOT1358)	2.1 x 1.1 x 0.5	1.3		4 mm pitch, 8 mm tape and reel	180 x 9								471								
	D2PAK-7 (SOT428)	10 x 15.3 x 4.3	-		16 mm pitch, 24 mm tape and reel	330 x 24		118														
8	XSON8 (SOT1116)	1.2 x 1 x 0.35	0.55		4mm pitch, 8mm tape and reel	180 x 8												-115				
	XSON8 (SOT1089)	1.35 x 1 x 0.5	0.55		4mm pitch, 8mm tape and reel	180 x 8												-115				
	X2SON8 (SOT1233)	1.45 x 1.05 x 0.4	0.35		2mm pitch, 8mm tape and reel	180 x 8																-115
	XSON8 (SOT1203)	1.5 x 1.05 x 0.5	0.35		4mm pitch, 8mm tape and reel	180 x 8												-115				
	XQFN8 (SOT902-2)	1.6 x 1.6 x 0.5	0.5		4mm pitch, 8mm tape and reel	180 x 8										-125						
	DFN1714-8 (SOT1166)	1.7 x 1.35 x 0.52	0.4		4 mm pitch. 8 mm tape and reel	180 x 8										-115						
					4 mm pitch. 8 mm tape and reel	180 x 8										-132						
	DFN1714U-8 (SOT983)	1.7 x 1.35 x 0.48	0.4		4 mm pitch. 8 mm tape and reel	180 x 8										-118						
	XSON8 (SOT833-1)	1.95 x 1.05 x 0.5	0.5		4mm pitch, 8mm tape and reel	180 x 8												-115				
	VSSOP8 (SOT765-1)	2 x 2.3 x 0.85	0.5		4mm pitch, 8mm tape and reel	180 x 8								-125								
	XSON8 (SOT996-2)	2 x 3 x 0.5	0.5		4mm pitch, 8mm tape and reel	180 x 8								-125								
	TSSOP8 (SOT505-2)	3 x 3 x 0.95	0.65		4mm pitch, 12mm tape and reel	180 x 12								-125								
	LFPAK33 (SOT1210)	3.3 x 3.3 x 0.85	-		8 mm pitch, 12 mm tape and reel	180 x 12					-115											
	SOT96 (S08)	4.9 x 3.9 x 1.75	1.27		8 mm pitch. 12 mm tape and reel	180 x 12			-115													
					8 mm pitch. 12 mm tape and reel	330 x 12							-518									
					8 mm pitch. 12 mm tape and reel	331 x 12							-118									
	LFPAK56D (SOT1205)	4.9 x 4.45 x 1.0	1.27		8 mm pitch. 12 mm tape and reel	180 x 12					-115											
10	XQFN10 (SOT1337-1)	1.4 x 1.8 x 0.5	0.4																			
	XQFN10 (SOT1049-3)	1.55 x 2 x 0.5	0.5		4mm pitch, 8mm tape and reel	180 x 8												-115				
	XSON10 (SOT1081-2)	1.7 x 1 x 0.4	0.35																			
	DFN2510-10 (SOT1165)	2.5 x 1.0 x 0.48	0.5		4 mm pitch. 8 mm tape and reel	180 x 8												-115				
	DFN2510A-10 (SOT1176)	2.5 x 1.0 x 0.48	0.5		4 mm pitch. 8 mm tape and reel	180 x 8												-115 -471				
	HVSON10 (SOT650)	3 x 3 x 0.85	0.5		8mm pitch, 12mm tape and reel	330 x 12													-118			
12	DFN2514-12 (SOT1167)	2.5 x 1.35 x 0.53	0.4		4 mm pitch. 8 mm tape and reel	180 x 8										-132						
	DFN2521-12 (SOT 1156)	2.5 x 2.1 x 0.48	0.4		4 mm pitch. 8 mm tape and reel	180 x 8										-132						
12	XQFN12 (SOT1174-1)	1.7 x 2 x 0.5	0.4		4mm pitch, 8mm tape and reel	180 x 8										-115						

Package details and packing methods SMD – Part 4

Package details					Packing methods																	
Pins/ Terminals	Package	Package size (l x w x h) (mm)	Lead pitch (mm)	Package	Packing method and tape dimension	Reel dimension (d x w) (mm)	Packing quantity and ordering code (12NC ending)															
							500	800	1000	1400	1500	2000	2500	3000	3500	4000	4500	5000	6000	8000	9000	10000
14	TSSOP14 (SOT402-1)	5 x 4.4 x 0.95	0.65		8mm pitch, 12mm tape and reel	330 x 12							-623									
	SO14 (SOT108-1)	8.65 x 3.9 x 1.45	1.27		8mm pitch, 16mm tape and reel	330 x 16							-431									
16	XQFN16 (SOT1161-1)	1.8 x 2.6 x 0.5	0.4		4mm pitch, 8mm tape and reel	180 x 8										-115						
	DFN3312-16 (SOT 1159)	3.3 x 1.2 x 0.48	0.4		4 mm pitch. 12 mm tape and reel	180 x 12										-132						
16	DFN3314-16 (SOT1168)	3.3 x 1.35 x 0.53	0.4		4 mm pitch. 8 mm tape and reel	180 x 8										-132						
	TSSOP16 (SOT403-1)	5 x 4.4 x 0.95	0.65		8mm pitch, 12mm tape and reel	330 x 12							-623									
	SSOP16 (SOT338-1)	6.2 x 5.3 x 1.8	0.65		12mm pitch, 16mm tape and reel	330 x 16						-431										
20	DHVQFN20 (SOT764-1)	4.5 x 2.5 x 1	0.5		4mm pitch, 12mm tape and reel	180 x 12								-115								
	DHXQFN20 (SOT1045-2)	4.6 x 2.6 x 0.5	0.5		4mm pitch, 12mm tape and reel	180x12								-115								
	SSOP20 (SOT339-1)	7.2 x 5.3 x 1.8	0.65		12mm pitch, 16mm tape and reel	330 x 16			-118													
	SSOP20 (SOT724)	8.7 x 3.9 x 1.73	0.635		12mm pitch, 16mm tape and reel	330 x 16							-118									
	SO20 (SOT163-1)	12.8 x 7.5 x 2.45	1.27		12mm pitch, 24mm tape and reel	330 x 24						-518										
24	DHVQFN24 (SOT815-1)	5.5 x 3.5 x 0.85	0.5		8mm pitch, 12mm tape and reel	330 x 12								-118								
	TSSOP24 (SOT355-1)	7.8 x 4.4 x 0.95	0.65		8mm pitch, 16mm tape and reel	330 x 16							-128									
	SSOP24 (SOT340-1)	8.2 x 5.3 x 1.8	0.65		12mm pitch, 16mm tape and reel	330 x 16			-118													
	SSOP24 (SOT556-1)	8.7 x 3.9 x 1.47	0.635		12mm pitch, 16mm tape and reel	330 x 16			-118													
	SO24 (SOT137-1)	15.3 x 7.5 x 2.45	1.27		12mm pitch, 24mm tape and reel	330 x 24			-118													
32	DFN5050-32 (SOT617)	5.0 x 5.0 x 1.0	0.5		8 mm pitch. 12 mm tape and reel	330 x 12													-118			
					8 mm pitch. 12 mm tape and reel	330 x 12													-128			

Package details and packing methods WLCSP

Basic Type	Length x width x height	# of balls	Pitch	Package	Package name
IP4369CX4	0.76 x 0.76 x 0.5	4	0.4		WLCSP4
PMCM440VNE	0.78 x 0.78 x 0.35	4	0.4		WLCSP4
PMCM4401VNE	0.78 x 0.78 x 0.35	4	0.4		WLCSP4
PMCM440VPE	0.78 x 0.78 x 0.35	4	0.4		WLCSP4
PMCM4401VPE	0.78 x 0.78 x 0.35	4	0.4		WLCSP4
PCMF1USB3S	1.17 x 0.77 x 0.57	5	0.4		WLCSP5
PESD1USB3S	1.17 x 0.77 x 0.57	5	0.4		WLCSP5
PCMF2USB3S	1.17 x 1.57 x 0.57	10	0.4		WLCSP10
PESD2USB3S	1.17 x 1.57 x 0.57	10	0.4		WLCSP10
PCMF3USB3S	1.17 x 2.37 x 0.57	15	0.4		WLCSP15
PESD3USB3S	1.17 x 2.37 x 0.57	15	0.4		WLCSP15
IP3319CX6	1.34 x 0.95 x 0.57	6	0.4		WLCSP6
PMCM650VNE	1.48 x 0.98 x 0.35	6	0.5		WLCSP6
PMCM650VPE	1.48 x 0.98 x 0.35	6	0.5		WLCSP6
IP4340CX15	1.56 x 1.56 x 0.47	15	0.4		WLCSP15

Packing details glass diodes, single ended and through hole packages

Pins/ leads	Package	Packing method and tape/reel/tube dimensions	Package	Ordering code (12 NC ending)	Packing quantity
2	SOD27	26 mm tape ammo pack, axial		-143	5000 pcs
		52 mm tape ammo pack, axial		-133	10000 pcs
		52 mm reel pack, axial		-113	10000 pcs
	SOD66	52 mm tape ammo pack, axial		-133	10000 pcs
		52 mm reel pack, axial		-113	10000 pcs
	SOD68	26 mm tape ammo pack, axial		-143	5000 pcs
		52 mm reel pack, axial		-113	10000 pcs
		52 mm tape ammo pack, axial		-133	10000 pcs
3	SOT78 (TO-220)	Rail packing, 50 pcs/tube, tube length = 520 mm		-127	20 tubes x 50 pcs
	I2PAK (SOT226)	Rail packing, 50 pcs/tube, tube length = 520 mm		-127	20 tubes x 50 pcs
5	SOT263B-1	Rail packing		-127	20 tubes x 50 pcs

Package cross reference list – Part 1

Type	Competitor	Nexperia	Pins/ Leads
µQFN-10L	ST	DFN2510A-10 (SOT1176)	10
µQFN-2L	ST	DFN1006-2 (SOD882)	2
6 Lead DFN	ON Semi	DFN2020-6 (SOT1118)	6
CL2	Toshiba	DSN0402-2 (SOD992)	2
CLP0603	Vishay	DSN0603-2 (SOD962)	2
CMAK/ CMPAK	Renesas	SOT323	3
CMPAK-5(T)	Renesas	SOT353	5
CMPAK-6	Renesas	SOT363	6
CMPAK/ CMAK	Renesas	SOT323	3
CP4	Toshiba	SOT143B	4
CPT3	Rohm	DPAK (SOT428)	3
CS6	Toshiba	DFN1010-6 (SOT891)	6
CST3	Toshiba	DFN1006-3 (SOT883)	3
CST3	Toshiba	DFN1006B-3 (SOT883B)	3
CTS2 (fSC)	Toshiba	DFN1006-2 (SOD882)	2
CTS2 (fSC)	Toshiba	DFN1006D-2 (SOD882D)	2
D2PAK	ON Semi	D2PAK (SOT404)	3
D2PAK	Vishay	D2PAK (SOT404)	3
D2PAK	Toshiba	D2PAK (SOT404)	3
D2PAK	Infineon	D2PAK (SOT404)	3
D2PAK	ST	D2PAK (SOT404)	3
D2PAK 3	ON Semi	D2PAK (SOT404)	3
D2PAK-3	OnSemi	D2PAK (SOT404)	3
D2PAK-7	ST	D2PAK-7 (SOT427)	7
D2PAK*	Diodes Inc.	D2PAK (SOT404)	3
D2PAK7P	Infineon	D2PAK-7 (SOT427)	7
DFN-5	OnSemi	LFPAK56 (SOT669)	4
DFN-8	OnSemi	LFPAK56D (SOT1205)	8
DFN1006-3	Diodes Inc.	DFN1006-3 (SOT883)	3
DFN1006H4-3	Diodes Inc.	DFN1006-3 (SOT883)	3
DFN1411*	Diodes Inc.	DFN1010D-3 (SOT1215)	3
DFN2	ST	DSN0603-2 (SOD962)	2
DPAK	ON Semi	DPAK (SOT428)	3
DPAK	Toshiba	DPAK (SOT428)	3
DPAK	OnSemi	DPAK (SOT428)	3
DPAK	Infineon	DPAK (SOT428)	3
DPAK	ST	DPAK (SOT428)	3
DPAK(S)	Renesas	DPAK (SOT428)	3
DSN2, 0.4 x 0.2	ON Semi	DSN0402-2 (SOD992)	2
DSN2, 0.6 x 0.3	ON Semi	DSN0603-2 (SOD962)	2
DSN2, 1.0 x 0.6	ON Semi	DSN1006-2 (SOD993)	2
DSN2, 1.0 x 0.6	ON Semi	DFN1006D-2 (SOD882D)	2
DSN2, 1.6 x 0.8	ON Semi	DFN1608D-2 (SOD1608)	2
DSN2, 1.6 x 0.8	ON Semi	DFN1608D-2 (SOD1608)	2
EMD2	Rohm	SOD523	2
EMD3/EMT3	Rohm	DFN1006-3 (SOT883)	3
EMD5/EMT5	Rohm	SOT665	5
EMD6/EMT6/WEMT6	Rohm	SOT666	6
EMT3	Rohm	DFN1006-3 (SOT883)	3

Type	Competitor	Nexperia	Pins/ Leads
EMT3/EMD3	Rohm	DFN1006-3 (SOT883)	3
EMT3F*	Rohm	DFN1006-3 (SOT883)	3
EMT5*	Rohm	SOT666	6
EMT5/EMD5	Rohm	SOT665	5
EMT6	Rohm	SOT666	6
EMT6/EMD6/WEMT6	Rohm	SOT666	6
ES6	Toshiba	SOT666	6
ES6 ESV	Toshiba	SOT666	6
ESC/TESC	Toshiba	SOD523	2
ESM	Toshiba	DFN1006-3 (SOT883)	3
ESV	Toshiba	SOT665	5
ESV	Toshiba	SOT666	6
FM8	Toshiba	SOT96	8
FS6*	Toshiba	DFN1010B-6 (SOT1216)	6
GMD2	Rohm	DSN0603-2 (SOD962)	2
H2PAK-2	ST	D2PAK (SOT404)	3
H2PAK-6	ST	D2PAK-7 (SOT427)	7
HSMT8	Rohm	LFPAK33 (SOT1210)	8
HSON-8	Renesas	LFPAK56 (SOT669)	4
HSON-8 Dual	Renesas	LFPAK56D (SOT1205)	8
HSOP8 (Dual)	Rohm	LFPAK56D (SOT1205)	8
HSOP8 (Single)	Rohm	LFPAK56 (SOT669)	4
HUML2020L8 (Dual)	Rohm	DFN2020-6 (SOT1118)	6
HUML2020L8 (Single)	Rohm	DFN2020MD-6 (SOT1220)	6
I2PAK	OnSemi	I2PAK (SOT226)	3
I2PAK	ST	I2PAK (SOT226)	3
KMD2	Rohm	DFN1608D-2 (SOD1608)	2
LDPAK(S)-(1)	Renesas	D2PAK (SOT404)	3
LFPAK	Renesas	LFPAK (SOT669)	5
LG A 1.0 x 0.6mm	Texas Instruments	DFN1006B-3 (SOT883B)	3
LLD	Renesas	SOD80C	2
LLDS	Rohm	SOD80C	2
LLP1006-2L	Vishay	DFN1006-2 (SOD882)	2
LLP1006-2L	Vishay	DFN1006D-2 (SOD882D)	2
LLP1006-2M	Vishay	DFN1006-2 (SOD882)	2
LLP1006-2M	Vishay	DFN1006D-2 (SOD882D)	2
LLP75-7L	Vishay	DFN1616-6 (SOT1189)	6
LPDS/LPTS	Rohm	D2PAK (SOT404)	3
LPTS	Rohm	D2PAK (SOT404)	3
LPTS/LPDS	Rohm	D2PAK (SOT404)	3
M-Flat	Toshiba	SOD128	2
Micro 3	Int. Rectifier	SOT23	3
Micro 6	Int. Rectifier	SOT457	6
MiCRO FOOT 0.8 x 0.8*	Vishay	DFN1010D-3 (SOT1215)	3
MiCRO FOOT 1 x 1.2*	Vishay	DFN1010D-3 (SOT1215)	3
MICRO FOOT 1 x 1.5*	Vishay	DFN1010D-3 (SOT1215)	3
MiCRO FOOT 1 x 1*	Vishay	DFN1010D-3 (SOT1215)	3
MiCRO FOOT 1.6 x 1.6*	Vishay	DFN2020MD-6 (SOT1220)	6
MICRO FOOT*	Vishay	DFN2020MD-6 (SOT1220)	6

Types with * show footprint compability only

Package cross reference list – Part 2

Type	Competitor	Nexperia	Pins/ Leads
MicroFET	Fairchild	DFN2020MD-6 (SOT1220)	6
MicroFET 1.6 x 1.6*	Fairchild	DFN2020MD-6 (SOT1220)	6
MiniMelf	Diodes Inc.	SOD80C	2
MiniMelf	ST	SOD80C	2
MiniMelf	Vishay	SOD80C	2
MP-25(K)	Renesas	TO-220 (SOT78)	3
MP-25SK	Renesas	I2PAK (SOT226)	3
MP-25ZT	Renesas	D2PAK-7 (SOT427)	7
MP-25ZT	Renesas	D2PAK (SOT404)	3
MP-3Z	Renesas	DPAK (SOT428)	3
MP6	Renesas	DSN0603-2 (SOD962)	2
MPAK	Renesas	SOT23	3
MPAK	Renesas	SOT23	3
MPAK-4R	Renesas	SOT143B	4
MPT3	Rohm	SOT89	3
PG-TD SON-8	Infineon	LFPAK (SOT669)	5
PG-TDSON-8	Infineon	LFPAK56D (SOT1205)	8
PG-TDSON-8	Infineon	LFPAK56 (SOT669)	4
PG-TO220-3	Infineon	TO-220 (SOT78)	3
PG-TO252-3	Infineon	DPAK (SOT428)	3
PG-TO262-3	Infineon	I2PAK (SOT226)	3
PG-TO263-3	Infineon	D2PAK (SOT404)	3
PG-TO263-7	Infineon	D2PAK-7 (SOT427)	7
PG-TSDSON-8	Infineon	LFPAK33 (SOT1210)	8
PMDT	Rohm	SOD128	2
PMDU	Rohm	SOD123W	2
Power DI3333-8	Diodes Inc.	LFPAK33 (SOT1210)	8
Power DI5060-8	Diodes Inc.	LFPAK56D (SOT1205)	8
Power DI5060-8	Diodes Inc.	LFPAK56 (SOT669)	4
Power FLAT 3.3 x 3.3	ST	LFPAK33 (SOT1210)	8
Power FLAT 5x6 Dual	ST	LFPAK56D (SOT1205)	8
Power FLAT 5x6 Dual	ST	LFPAK56 (SOT669)	4
PowerDI123	Diodes Inc.	SOD123F	2
PowerDI123	Diodes Inc.	SOD123W	2
PowerDI323	Diodes Inc.	SOD323F	2
PowerDi5	Diodes Inc.	CFP15 (SOT1289)	3
PowerFLAT (6 x 5)	ST	LFPAK (SOT669)	5
PowerFLAT (6 x 5)	ST	LFPAK56D (SOT1205)	5
PowerPAK 1212-8	Vishay	LFPAK33 (SOT1210)	8
PowerPAK SC-70	Vishay	DFN2020-6 (SOT1118)	6
PowerPAK SC-70	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPAK SC-70	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPak SC-70-6L	Vishay	DFN2020-6 (SOT1118)	6
PowerPak SC-75-6L*	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPAK SC-75*	Vishay	DFN2020MD-6 (SOT1220)	6
PowerPAK SC706L	Vishay	DFN2020-3 (SOT1061)	3
PowerPAK SO-8	Vishay	LFPAK (SOT669)	5
PowerPAK SO-8(L)	Vishay	LFPAK56 (SOT669)	4
PowerPAK SO-8L Dual	Vishay	LFPAK56D (SOT1205)	8

Type	Competitor	Nexperia	Pins/ Leads
PW-Mini	Toshiba	SOT89	3
S-Flat	Toshiba	SOD123F	2
S-Flat	Toshiba	SOD123W	2
S-Mini	Toshiba	SOT23	3
S-Mini TSM	Toshiba	SOT23	3
S08	Vishay	SOT96	8
SC-70	ON Semi	SOT323	3
SC-70, 3 leads	Vishay	SOT323	3
SC-74 TSOP-6	ON Semi	SOT457	6
SC-75	ON Semi	DFN1006-3 (SOT883)	3
SC-75	Semtech	DFN1006-3 (SOT883)	3
SC-75A	Vishay	DFN1006-3 (SOT883)	3
SC-88	ON Semi	SOT363	6
SC-88A	ON Semi	SOT353	5
SC-89	Semtech	SOT666	6
SC2	Toshiba	DSN0603-2 (SOD962)	2
SC59	Diodes Inc.	SOT23	3
SC70	ON Semi	SOT323	3
SC70-3	Vishay	SOT323	3
SC70-3	AOS	SOT323	3
SC70-5L	Semtech	SOT353	5
SC70-6	Vishay	SOT363	6
SC70-6	AOS	SOT363	6
SC70-6	Fairchild	SOT363	6
SC70-6L	Semtech	SOT363	6
SC74 TSOP6	Infineon	SOT457	6
SC75	Infineon	DFN1006-3 (SOT883)	3
SC75	ON Semi	DFN1006-3 (SOT883)	3
SC75A	Vishay	DFN1006-3 (SOT883)	3
SC79	Infineon	SOD523	2
SC88/SC 7 0-6/SOT 363 6 LEAD	ON Semi	SOT363	6
SC89	Fairchild	SOT666	6
SC89-3	Vishay	DFN1006-3 (SOT883)	3
SC89-3	ON Semi	DFN1006-3 (SOT883)	3
SC89-3	Fairchild	DFN1006-3 (SOT883)	3
SC89-6	Vishay	SOT666	6
SC89-6	AOS	SOT666	6
SC89-6	Fairchild	SOT666	6
SC89-6lead	Vishay	SOT666	6
SLP0402P2X3	Semtech	DSN0402-2 (SOD992)	2
SLP1006P2	Semtech	DFN1006-2 (SOD882)	2
SLP1006P2T	Semtech	DFN1006D-2 (SOD882D)	2
SLP1006P3	Semtech	DFN1006-3 (SOT883)	3
SLP1006P3T	Semtech	DFN1006B-3 (SOT883B)	3
SLP1510N6	Semtech	DFN1410-6 (SOT886)	6
SLP1610N2	Semtech	DFN1608D-2 (SOD1608)	2
SLP1610P4	Semtech	DFN2510A-10 (SOT1176)	10
SLP1616P6	Semtech	DFN1616-6 (SOT1189)	6
SLP1713P8	Semtech	DFN1714-8 (SOT1166)	8

Types with * show footprint compability only

Package cross reference list – Part 3

Type	Competitor	Nexperia	Pins/ Leads
SLP1713P8	Semtech	DFN1714U-8 (SOT983)	8
SLP2513P12	Semtech	DFN2514-12 (SOT1167)	12
SLP3313P16	Semtech	DFN3314-16 (SOT1168)	16
SM6 VS-6	Toshiba	SOT457	6
SMA flat	ST	SOD128	2
SMD TO-263	Renesas	D2PAK (SOT404)	3
SMD0402	Rohm	DSN0402-2 (SOD992)	2
SMD6/SMT6	Rohm	SOT457	6
SMD6/SMZ6	Rohm	SOT457	6
SMFPAK-6	Renesas	SOT666	6
SMPAK	Renesas	DFN1006-3 (SOT883)	3
SMPC TO-277A	Vishay	CFP15 (SOT1289)	3
SMT3	Rohm	SOT23	3
SMT5*	Rohm	SOT457	6
SMT6	Rohm	SOT457	6
SMZ6/SMD6	Rohm	SOT457	6
SO-8 FL	ON Semi	LFPAK (SOT669)	5
SO-8FL Dual	OnSemi	LFPAK56D (SOT1205)	8
SO-8FL Dual	OnSemi	LFPAK56 (SOT669)	4
SOD-123	ST	SOD123F	2
SOD-123-FL	ON Semi	SOD123F	2
SOD-123-FL	ON Semi	SOD123W	2
SOD-323	ON Semi	SOD323	2
SOD-323	Diodes Inc.	SOD323	2
SOD-323	ST	SOD323	2
SOD-523	ON Semi	SOD523	2
SOD-523	ST	SOD523	2
SOD323	Infineon	SOD323	2
SOD323	Vishay	SOD323	2
SOD323	Semtech	SOD323	2
SOD523	Diodes Inc.	SOD523	2
SOD523	Vishay	SOD523	2
SOD523	Semtech	SOD523	2
SOD882	ST	DFN1006-2 (SOD882)	2
SOD882T	ST	DFN1006D-2 (SOD882D)	2
SOD923-2*	ON Semi	DFN1006-2 (SOD882)	2
SOIC-8 NB	ON Semi	SOT96	8
SON 2x2	Texas Instruments	DFN2020MD-6 (SOT1220)	6
SON 3x3*	Texas Instruments	DFN2020MD-6 (SOT1220)	6
SOP-8	Renesas	SOT96	8
SOP/DSOP Advance	Toshiba	LFPAK56 (SOT669)	4
SOP8	Rohm	SOT96	8
SOT 143	Infineon	SOT143B	4
SOT-143	Semtech	SOT143B	4
SOT-143	Diodes Inc.	SOT143B	4
SOT-223	ON Semi	SOT223	4
SOT-223	Diodes Inc.	SOT223	4
SOT-223	OnSemi	SOT223	3
SOT-223	Infineon	SOT223	3

Type	Competitor	Nexperia	Pins/ Leads
SOT-223	ST	SOT223	3
SOT-23	ON Semi	SOT23	3
SOT-23	Diodes Inc.	SOT23	3
SOT-323	Diodes Inc.	SOT323	3
SOT-323	ST	SOT323	3
SOT-363	Diodes Inc.	SOT363	6
SOT-553	ON Semi	SOT665	5
SOT-563	ON Semi	SOT666	6
SOT-89	ON Semi	SOT89	3
SOT063*	ON Semi	DFN101 OB-6 (SOT1216)	6
SOT223	Vishay	SOT223	4
SOT223	Infineon	SOT223	4
SOT223	Fairchild	SOT223	4
SOT223	ON Semi	SOT223	4
SOT223	Diodes Inc.	SOT223	4
SOT223	Diodes Inc.	SOT223	3
SOT23	Infineon	SOT23	3
SOT23	ST	SOT23	3
SOT23	Vishay	SOT23	3
SOT23	Semtech	SOT23	3
SOT23	Diodes Inc.	SOT23	3
SOT23	AOS	SOT23	3
SOT23	ON Semi	SOT23	3
SOT23-3	Diodes Inc.	SOT23	3
SOT23-3	AOS	SOT23	3
SOT23-3	ON Semi	SOT23	3
SOT23-5	AOS	SOT457	6
SOT23-5	Diodes Inc.	SOT457	6
SOT23-6	Diodes Inc.	SOT457	6
SOT23-6	ST	SOT457	6
SOT23-6	Diodes Inc.	SOT457	6
SOT23-6L	Semtech	SOT457	6
SOT23F	Toshiba	SOT23	3
SOT23F	Diodes Inc.	SOT23	3
SOT26	Diodes Inc.	SOT457	6
SOT323	Infineon	SOT323	3
SOT323	Diodes Inc.	SOT323	3
SOT323	Fairchild	SOT323	3
SOT353	Diodes Inc.	SOT353	5
SOT353	Vishay	SOT353	5
SOT353	Diodes Inc.	SOT363	6
SOT363	Infineon	SOT363	6
SOT363	Diodes Inc.	SOT363	6
SOT523	Diodes Inc.	DFN1006-3 (SOT883)	3
SOT523F	Fairchild	DFN1006-3 (SOT883)	3
SOT563	Diodes Inc.	SOT666	6
SOT563-6	ON Semi	SOT666	6
SOT563F	Fairchild	SOT666	6
SOT666	Infineon	SOT666	6

Types with * show footprint compability only

Package cross reference list – Part 4

Type	Competitor	Nexperia	Pins/ Leads
SOT723-3*	ON Semi	DFN1010D-3 (SOT1215)	3
SOT723*	ON Semi	DFN1010D-3 (SOT1215)	3
SOT89	Infineon	SOT89	3
SOT89	Diodes Inc.	SOT89	3
SOT89-3L	Diodes Inc.	SOT89	3
SOT963	ON Semi	DFN1010-6 (SOT891)	6
SOT963*	Diodes Inc.	DFN1010B-6 (SOT1216)	6
SRP-F	Renesas	SOD123W	2
SS CSP2	Toshiba	DFN1006-3 (SOT883)	3
SSD3/SST3	Rohm	SOT23	3
SSM	Toshiba	DFN1006-3 (SOT883)	3
SSOT3	Fairchild	SOT23	3
SSOT6	Fairchild	SOT457	6
SSOT6 FLMP	Fairchild	SOT457	6
SST3	Rohm	SOT23	3
SST3/SSD3	Rohm	SOT23	3
ST01005	STM	DSN0402-2 (SOD992)	2
Stmite flat	ST	SOD123W	2
T0263	Diodes Inc.	D2PAK(SOT404)	3
T0263-3	Infineon	D2PAK (SOT404)	3
Thin PowerPAK SC-70	Vishay	DFN2020-6 (SOT1118)	6
Thin PowerPAK SC-70	Vishay	DFN2020MD-6 (SOT1220)	6
Thin PowerPAK SC70	Vishay	DFN2020MD-6 (SOT1220)	6
Thin PowerPAK SC75*	Vishay	DFN2020MD-6 (SOT1220)	6
TO-220	ST	TO-220 (SOT78)	3
TO-220	Vishay	TO-220 (SOT78)	3
TO-220	Toshiba	TO-220 (SOT78)	3
TO-220-3	OnSemi	TO-220 (SOT78)	3
TO-220-3L	OnSemi	TO-220 (SOT78)	3
TO-220AB	Vishay	TO-220 (SOT78)	3
TO-220F-3FS	OnSemi	TO-220 (SOT78)	3
TO-220FM	Rohm	TO-220 (SOT78)	3
TO-220S	Renesas	D2PAK (SOT404)	3
TO-220SM	Toshiba	D2PAK (SOT404)	3
TO-252	Renesas	DPAK (SOT428)	3
TO-252	Vishay	DPAK (SOT428)	3
TO-252 (MP-3ZK)	Renesas	DPAK (SOT428)	3
TO-252 reverse, TO-252	Vishay	DPAK (SOT428)	3
TO-252-3/-3-23	Infineon	DPAK (SOT428)	3
TO-252, TO-252 reverse	Vishay	DPAK (SOT428)	3
TO-262	Renesas	I2PAK (SOT226)	3
TO-262	Vishay	I2PAK (SOT226)	3
TO-262-2L	OnSemi	I2PAK (SOT226)	3
TO-262-3L	OnSemi	I2PAK (SOT226)	3
TO-263	Renesas	D2PAK-7 (SOT427)	7
TO-263	Renesas	D2PAK (SOT404)	3
TO-263	Vishay	D2PAK (SOT404)	3
TO-263 3-lead	Vishay	D2PAK (SOT404)	3
TO-263-2L	OnSemi	D2PAK (SOT404)	3

Type	Competitor	Nexperia	Pins/ Leads
TO-263-7L	Vishay	D2PAK-7 (SOT427)	7
TO-263AB	Vishay	D2PAK (SOT404)	3
TO220	Infineon	TO-220 (SOT78)	3
TO220-3	Diodes Inc.	TO-220 (SOT78)	3
TO252	Diodes Inc.	DPAK (SOT428)	3
TO262	Infineon	I2PAK (SOT226)	3
TO263	Diodes Inc.	D2PAK (SOT404)	3
TP-FA	OnSemi	DPAK (SOT428)	3
TSLP-2-1	Infineon	DFN1006-2 (SOD882)	2
TSLP-2-7/-17	Infineon	DFN1006D-2 (SOD882D)	2
TSLP-3-1, -15	Infineon	DFN1006B-3 (SOT883B)	3
TSLP-3-4	Infineon	DFN1006-3 (SOT883)	3
TSLP-9-1	Infineon	DFN2510A-10 (SOT 1176)	10
TSMT5*	Rohm	SOT457	6
TSMT6	Rohm	SOT457	6
TSNP-2-2	Infineon	DFN1608D-2 (SOD 1608)	2
TSON Advance	Toshiba	LFPAK33 (SOT1210)	8
TSOP-6	Renesas	SOT457	6
TSOP-6/ TSOP6	Vishay	SOT457	6
TSOP6	Vishay	SOT457	6
TSOP6	AOS	SOT457	6
TSOP6	ON Semi	SOT457	6
TSSLP-2-1	Infineon	DSN0603-2 (SOD962)	2
TSST8*	Rohm	DFN2020MD-6 (SOT1220)	6
TUMT3	Rohm	SOT323	3
TUMT5*	Rohm	DFN2020-6 (SOT1118)	6
TUMT6*	Rohm	DFN2020-6 (SOT1118)	6
U-DFN2020-3 Type B 2.0 x 2.0 x 0.6	Diodes Inc.	DFN2020-3 (SOT1061)	3
U-DFN2020-6	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
U-DFN2523-6*	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
UDFN 1.6 x 1.6	ON Semi	DFN1616-6 (SOT1189)	6
UDFN 1.7 x 1.35, 0.4P	ON Semi	DFN1714U-8 (SOT983)	8
UDFN-6 WDFN6	ON Semi	DFN2020MD-6 (SOT1220)	6
UDFN10 2.5 x 1, 0.5P	ON Semi	DFN2510A-10 (SOT1176)	10
UDFN12 2.5 x 1.35, 0.4P	ON Semi	DFN2514-12 (SOT1167)	12
UDFN2020-6 Type B	Diodes Inc.	DFN2020-6 (SOT1118)	6
UDFN2020-6 Type E	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
UDFN6	Toshiba	DFN2020-6 (SOT1118)	6
UDFN6	ON Semi	DFN2020MD-6 (SOT1220)	6
UDFN6B	Toshiba	DFN2020MD-6 (SOT1220)	6
UF6	Toshiba	SOT363	6
UF6/ USV/ US6	Toshiba	SOT363	6
UFP	Renesas	SOD523	2
UMD2	Rohm	SOD323F	2
UMD3/UMT3	Rohm	SOT323	3
UMD5/UMT5	Rohm	SOT353	5
UMD6/ UMT6	Rohm	SOT363	6
UMLP 1.6 x 1.6*	Fairchild	DFN2020MD-6 (SOT1220)	6
UMT3	Rohm	SOT323	3

Types with * show footprint compability only

Package cross reference list – Part 5

Type	Competitor	Nexperia	Pins/ Leads
UMT3F*	Rohm	SOT323	3
UMT5/ UMD5	Rohm	SOT353	5
UMT6	Rohm	SOT363	6
UMT6/ UMD6	Rohm	SOT363	6
UPAK (SOT89)	Renesas	SOT89	3
URP	Renesas	SOD323	2
US-Flat	Toshiba	SOD323F	2
US6	Toshiba	SOT363	6
US6/ UF6/ USV	Toshiba	SOT363	6
use	Toshiba	SOD323	2
USM	Toshiba	SOT323	3
USV	Toshiba	SOT353	5
USV	Toshiba	SOT363	6
USV/ US6/ UF6/	Toshiba	SOT363	6
VESM*	Toshiba	DFN1010D-3 (SOT1215)	3
VML0806*	Rohm	DFN1006B-3 (SOT883B)	3
VML1006	Rohm	DFN1006-3 (SOT883)	3
VMN2*	Rohm	DFN1006-2 (SOD882)	2
VMN2*	Rohm	DFN1006D-2 (SOD882D)	2
VMN3*	Rohm	DFN1006-3 (SOT883)	3
VMT3*	Rohm	DFN1010D-3 (SOT1215)	3
VMT6*	Rohm	DFN101 OB-6 (SOT1216)	6
VS6	Toshiba	SOT457	6
VSON-5	Renesas	SOT665	5
W-DFN3020-8*	Diodes Inc.	DFN2020-6 (SOT1118)	6
WDFN-8	OnSemi	LFPAK33 (SOT1210)	8
WDFN3	ON Semi	DFN2020-3 (SOT1061)	3
WDFN6	ON Semi	DFN2020-6 (SOT1118)	6
WDFN6	ON Semi	DFN2020MD-6 (SOT1220)	6
WEMT6	Rohm	SOT666	6
WEMT6/ EMT6/ EMD6	Rohm	SOT666	6
WLCSP 1 x 1*	Fairchild	WLCSP4	3
WLCSP-4*	Fairchild	WLCSP4	3
WLCSP-4*	ON Semi	WLCSP4	3
WLCSP1.6 x 1.6*	AOS	WLCSP6	6
WLCSP2	ON Semi	DSN0603-2 (SOD962)	2
WLL-2-2	Infineon	DSN0402-2 (SOD992)	2
WLP1.5x 1.5*	Texas Instruments	DFN2020MD-6 (SOT1220)	6
WLPI.Ox 1.0*	Texas Instruments	DFN1010D-3 (SOT1215)	3
WLPI.Ox 1.5*	Texas Instruments	DFN2020MD-6 (SOT1220)	6
X1 -DFN 1006-3	Diodes Inc.	DFN1006-3 (SOT883)	3
X1-DFN1212-3*	Diodes Inc.	DFN1010D-3 (SOT1215)	3
X1-DFN1616-6*	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
X2-DFN0806-3	Diodes Inc.	DFN1006-3 (SOT883)	3
X2-DFN1006-2	Diodes Inc.	DFN1006D-2 (SOD882D)	2
X2-DFN1006-3	Diodes Inc.	DFN1006B-3 (SOT883B)	3
X2-DFN1010-3	Diodes Inc.	DFN1010D-3 (SOT1215)	3
X2-DFN1310-6*	Diodes Inc.	DFN1010B-6 (SOT1216)	6
X2-DFN2015-3*	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
X2-DFN2020-6	Diodes Inc.	DFN2020MD-6 (SOT1220)	6
X3-DFN0603-2	Diodes Inc.	DSN0603-2 (SOD962)	2
X3DFN-2	ON Semi	DSN0603-2 (SOD962)	2
XDFN3	ON Semi	DFN1006-3 (SOT883)	3
XI-DFN1006-2	Diodes Inc.	DFN1006-2 (SOD882)	2
µ8FL	OnSemi	LFPAK33 (SOT1210)	8

Types with * show footprint compability only

Package cross reference matrix – Part 1

Pins/ leads	Nexperia	Industry standard names	Size (l x w x h) (mm)	P_{tot} (mW)	Package	Competitor synonyms								
						Rohm	Toshiba	ON Semi	Renesas	Infineon	Diodes Inc	ST	Vishay	Semtech
2	DSN0402-2 (SOD992)		0.4 x 0.2 x 0.12			SMD0402	CL2	DSN2 0.4 x 0.2		WLL-2-2		ST01005		SLP-0402P2X3
	DSN1006-2 (SOD993)		1.0 x 0.6 x 0.3					DSN2 1.0 x 0.6						
	DSN1006U-2 (SOD995)		1.0 x 0.6 x 0.3					DSN2 1.0 x 0.6						
	DFN1006-2 (SOD882)		1.0 x 0.6 x 0.48	250		(VMN2)	CTS2 (fSC)	(SOD923-2)		TSLP-2-1	XI-DFN1006-2	SOD 882 uQFN-2L	LLP1006-2M LLP1006-2L	SLP1006P2
	DFN1006D-2 (SOD882D)		1.0 x 0.6 x 0.37	250		(VMN2)	CTS2 (fSC)	DSN2 1.0 x 0.6		TSLP-2-7/ -17	X2-DFN1006-2	SOD882T	LLP1006-2L LLP1006-2M	SLP1006P2T
	DFN1608D-2 (SOD1608)		1.6 x 0.8 x 0.37	780		KMD2		DSN2 1.6 x 0.8		TSNP-2-2				SLP1610N2
	DSN0603-2 (SOD962)		0.6 x 0.3 x 0.3	525		GMD2	SC2	DSN2, X3DFN-2 WLCSP2	MP6	TSSLP-2-1	X3-DFN0603-2	DFN2	CLP0603	SLP-0603P2X3
	SOD80C	Mini-Melf	3.5 x 1.5 x 1.5	300		LLDS			LLD		MiniMelf	MiniMelf	MiniMelf	
	SOD123F		2.6 x 1.6 x 1.1	830			S-Flat	SOD-123-FL			PowerDI123	SOD-123		
	SOD123W		2.6 x 1.7 x 1.0	900		PMDU	S-Flat	SOD-123-FL	SRP-F		PowerDI123	Stmite flat		
	SOD128		3.8 x 2.5 x 1.0	1000		PMDT	M-Flat					SMA flat		
	SOD323	SC-76	1.7 x 1.25 x 0.95	400			USC	SOD-323	URP	SOD323	SOD-323	SOD-323	SOD323	SOD323
	SOD323F	SC-90	1.7 x 1.25 x 0.7	830		UMD2	US-Flat				PowerDI323			
	SOD523	SC-79	1.2 x 0.8 x 0.6	500		EMD2	ESC/ TESC	SOD-523	UFP	SC79	SOD523	SOD-523	SOD523	SOD523
3	CFP15 (SOT1289)		5.8 x 4.3 x 0.78	1200							PowerDi5		SMPC TO-277A	
	DFN1006-3 (SOT883)	SC-101	1.0 x 0.6 x 0.48	250		VML1006	SS CSP2	XDFN3		TSLP-3-4	X1 -DFN 1006-3			SLP1006P3
	DFN1006B-3 (SOT883B)		1.0 x 0.6 x 0.37	250		VML1006	CST3	XDFN3		TSLP-3-1, -15	X2-DFN1006-3			SLP1006P3T
	DFN1010D-3 (SOT1215)		1.1 x 1.0 x 0.37	325		(VMT3)	(VESM)	(SOT723)			X2-DFN1010-3			
	DFN2020-3 (SOT1061)	HU-SON3	2.0 x 2.0 x 0.62	1300				WDFN3			U-DFN2020-3 Type B 2.0 x 2.0 x 0.6		PowerPAK SC706L	
	DFN2020D-3 (SOT1061D)		2.0 x 2.0 x 0.62	1300				WDFN3			U-DFN2020-3 Type B 2.0 x 2.0 x 0.6		PowerPAK SC706L	
	DPAK (SOT428)		6.6 x 6.1 x 2.3			CPT3	DPAK	DPAK, TP-FA	TO-252 (MP-3ZK) DPAK(S)	TO-252-3/-3-2 3 DPAK, PG-TO252-3	TO252	DPAK	TO-252,TO-252 reverse	
	D2PAK (SOT404)		11.0 x 11.0 x 4.3			LPDS/ LPTS	TO-220SM D2PAK	D2PAK D2PAK 3 TO-263-2L	TO-220S / SMD TO-263 LDPAK(S)-(1) MP-25Z	D2PAK, PG-T0263-3	T0263 (D2PAK)	D2PAK, H2PAK-2	TO-263 3-lead TO-263AB / D2PAK TO-263	
	SOT23		2.9 x 1.3 x 1.0	250		SSD3/ SST3	S-Mini TSM	SOT-23	MPAK	SOT23	SOT-23	SOT23	SOT23	SOT23
	SOT89	SC-62	4.5 x 2.5 x 1.5	1300		MPT3	PW-Mini	SOT-89	UPAK (SOT89)	SOT89	SOT89			
	SOT323	SC-70	2.0 x 1.25 x 0.95	200		UMD3/ UMT3 TUMT3	USM	SC-70	CMAK/ CMPAK	SOT323	SOT-323	SOT-323	SC-70 3 leads	SOT-323

Types in brackets (…) show footprint compatibility only

Package cross reference matrix – Part 2

Pins/ leads	Nexperia	Industry standard names	Size (l x w x h) (mm)	P_{tot} (mW)	Package	Competitor synonyms								
						Rohm	Toshiba	ON Semi	Renesas	Infineon	Diodes Inc	ST	Vishay	Semtech
3	TO-220 (SOT78)		15.6 x 10 x 4.4			TO-220FM	TO-220	TO-220-3L, TO-220F-3FS, TO-220-3	MP-25(K)	PG-TO220-3, TO220	TO220-3	TO-220	TO-220, TO-220AB	
	I2PAK (SOT226)		11 x 10 x 4.3					I2PAK, TO-262-2L, TO-262-3L	MP-25SK, TO-262	PG-TO262-3, TO262		I2PAK	TO-262	
	SOT223		6.5 x 3.5 x 1.65					SOT-223		SOT-223	SOT223	SOT-223		
4	LFPAK56 (SOT669)	Power-S08	4.9 x 4.45 x 1.0	3000		HSOP8 (Single)	SOP / DSOP Advance	SO-8 FL, DFN-5	LFPAK, HSON-8	PG-TD-SON-8	Power-Di5060-8	Power-FLAT (6x5)	PowerPAK SO-8(L)	
	SOT143B		2.9 x 1.3 x 1.0	250			CP4		MPAK-4R	SOT143	SOT-143			SOT-143
	SOT223	SC-73	6.5 x 3.5 x 1.65	1700				SOT-223		SOT223	SOT-223		SOT223	
5	SOT353	SC-88 A	2.0 x 1.25 x 0.95	300		UMD5/ UMT5	USV	SC-88 A	CMPAK-5C0		SOT353		SOT353	SC70-5L
	SOT665		1.6 x 1.2 x 0.55	300		EMD5/ EMT5	ESV	SOT-553	VSON-5					
6	DFN1010-6 (SOT891)	x SON6	1.0 x 1.0 x 0.48				CS6	SOT963						
	DFN1010B-6 (SOT1216)		1.1 x 1.0 x 0.37	350		(VMT6)	(FS6)	(SOT063)			(SOT963)			
	DFN1410-6 (SOT886)	x SON6	1.45 x 1.0 x 0.48	250										SLP1510N6
	DFN1616-6 (SOT1189)	H x SON6	1.6 x 1.6 x 0.48					UDFN 1.6 x 1.6					LLP75-/L	SLP1616P6
	DFN2020-6 (SOT1118)		2.0 x 2.0 x 0.62	1300		HU-ML2020L8 (Dual)	UDFN6	6 Lead DFN WDFN6			UDFN2020-6 Type B		PowerPAK SC-70 Thin PowerPAK SC-70	
	DFN2020D-6 (SOT1118D)		2.0 x 2.0 x 0.62	1300		HU-ML2020L8 (Dual)	UDFN6	6 Lead DFN WDFN6			UDFN2020-6 Type B		PowerPAK SC-70 Thin PowerPAK SC-70	
	DFN-2020MD-6 (SOT1220)		2.0 x 2.0 x 0.62	1250		HU-ML2020L8 (Single)	UDFN6B	UDFN-6 WDFN6			UDFN2020-6 Type E		PowerPAK SC-70 Thin PowerPAK SC-70	
	SOT363	SC-88	2.0 x 1.25 x 0.95	300		UMD6/ UMT6	US6 UF6 USV	SC-88	CMPAK-6	SOT363	SOT-363		SC70-6	SC70-6L
	SOT457	SC-74	2.9 x 1.5 x 1.0	750		SMD6/ SMT6	SM6 VS-6	SC-74 TSOP-6	TSOP-6	SC74 TSOP6	SOT23-6 SOT26		TSOP6 TSOP-6	SOT23-6L
	SOT666		1.6 x 1.2 x 0.55	300		EMD6/ EMT6 WEMT6	ES6 ESV	SOT-563	SMFPAK-6	SOT666	SOT563		SC89-6lead	SC-89
7	D2PAK-7 (SOT427)		11 x 10 x 4.3						MP-25ZT, 7pin TO-263	D2PAK7P, PG-TO263-7		D2PAK-7, H2PAK-6	TO-263-7L	
8	LFPAK33 (SOT1210)		3.3 x 3.3 x 0.85			HSMT8	TSON Advance	µ8FL, WDFN-8		PG-TSD-SON-8	Power DI3333-8	Power FLAT 3.3 x 3.3	PowerPAK 1212-8	
	LFPAK56D (SOT1205)		4.9 x 4.45 x 1.0	3000		HSOP8 (Dual)		SO-8FL Dual, DFN-8	HSON-8 dual	PG-TD-SON-8	Power DI5060-8	Power FLAT 5x6 Dual	PowerPAK SO-8L Dual	
	SOT96	S08	4.9 x 3.9 x 1.75	1500		SOP8	FM8	SOIC-8 NB	SOP-8				S08	
	DFN1714-8 (SOT 1166)	HUSON8	1.7 x 1.35 x 0.52											SLP1713P8
	DFN1714U-8 (SOT983)	H x SON8	1.7 x 1.35 x 0.48					UDFN 1.7 x 1.35, 0.4P						SLP1713P8
10	DFN2510-10 (SOT 1165)	x SON10	2.5 x 1.0 x 0.48					UDFN10 2.5 x 1, 0.5P		TSLP-9-1		pQFN-10L		SLP1610P4

Types in brackets (…) show footprint compatibility only

Package cross reference matrix – Part 3

Pins/ leads	Nexperia	Industry standard names	Size (l x w x h) (mm)	P_{tot} (mW)	Package	Competitor synonyms								
						Rohm	Toshiba	ON Semi	Renesas	Infineon	Diodes Inc	ST	Vishay	Semtech
10	DF-N2510A-10 (SOT1176)	x SON10	2.5 x 1.0 x 0.48					UDFN10 2.5 x 1, 0.5P		TSLP-9-1		pQFN-10L		SLP1610P4
	DFN2626-10 (SOT 1197)		2.6 x 2.6 x 0.48					UDFN10 2.6 x 2.6, 0.5P						SLP2626P10
12	DFN2512-12 (SOT 1158)	H x - SON12	2.5 x 1.2 x 0.48					UDFN12, 2.5 x 1.2, 0.4P						
	DFN2514-12 (SOT 1167)	HU-SON12	2.5 x 1.35 x 0.53					UDFN12, 2.5 x 1.35, 0.4P						SLP2513P12
16	DFN3312-16 (SOT 1159)	H x - SON16	3.3 x 1.2 x 0.48					UDFN 16, 3.5 x 1.2, 0.4P						
	DFN3314-16 (SOT 1168)	HU-SON16	3.3 x 1.35 x 0.53											SLP3313P16

Types in brackets (…) show footprint compatibility only

Competitive cross reference - Logic

This cross reference allows you to match a competitor's part number to a Nexperia part number. Once you have the equivalent part number, check the Nexperia website www.nexperia.com/logic to confirm that the particular configuration is released.

On semiconductor low pin count logic

NL 1 7 SZ 08 DTF

Prefix		Prefix		Gate count		Function	Package	
ON	Nexperia	ON	Nexperia	ON	Nexperia		ON	Nexperia
NL7	74	n	nG	SV	AUP		DFT	GW
				SZ	LVC		DTT	GV
				WZ	LVC		US	DC
				WB	LVC		AMX	GM
							CMX	GS

74 LVC 1G 08 GW

Fairchild semiconductor tiny logic

NC7 S Z 157 P6

Prefix		Gate count		Logic Family		Function	Package	
FSC	Nexperia	FSC	Nexperia	FSC	Nexperia		FSC	Nexperia
NC7	74	S	1G	-	HC		P5	GW
		W	2G	B	LVC		M5	GV
		n	3G	P	AUP		P6	GW
				T	HCT		K8	DC
				V	AUP		L6	GM
				Z	LVC		L8	GM

74 LVC 1G 157 GW

On semiconductors logic

MC74 VHC 1GT 08 DTT

Prefix		logic Family		Gate count		Function	Package	
ON	Nexperia	ON	Nexperia	ON	Nexperia		ON	Nexperia
-	-	HC	HC(T)	-	-		N, C	N, P
MC74	74	LCX	LVC	nG	nG		D	D
		LVX	LV	nGT*	nG		DT	PW
		MC1	HEF	* Indicates TTL variant of the family			DFT	GW
		VCX	ALVC				DTT	GV
		VHC	AHC(T)				US	DC
							QZ	DS
							MN	BQ
							AMX	GM
							CMX	GS

74 AHCT 1G 08 GW

Toshiba one gate

TC7 S Z 157 FU

Prefix		Gate count		logic Family		Function	Package	
Tosh	Nexperia	Tosh	Nexperia	Tosh	Nexperia		Tosh	Nexperia
TC7	74	S	1G	-	HC		FK	GV
		W	1,2 or 3G	A	LVC		FU	GW, DP
		P	1 or 2G	G	AUP			
				T	HCT			
				H	AHC			
				ET	AHCT			
				Z	LVC			

74 LVC 1G 157 GW

Fairchild semiconductor standard logic

MM74 LCX 157 MTD

Prefix		logic Family		Function	Package	
FSC	Nexperia	FSC	Nexperia		FSC	Nexperia
MM74	74	ABT	ABT		N	N
74	74	F	F		M, SC	D
		HC(T)	HC(T)		MSA	DB
		LCX	LVC		MEA	DL
		LVX	LV		MTC	PW
		VCX	ALVC		MTD	DGG
		VHC(T)	AHC(T)		BQ	BQ
		LVT	LVT			

74 LVC 157 PW

Toshiba standard logic

TC74 LCX 125 FT

Prefix		logic Family		Function	Package	
Tosh	Nexperia	Tosh	Nexperia		Tosh	Nexperia
-	-	HC(T)	HC(T)		P	N
TC74	74	LCX	LVC		FW	D
		LVX	LV		FN	D
		TC	HEF		FT	PW
		VCX	ALVC		FS	DB
		VHC(T)	VHC(T)			

74 LVC 125 PW

Texas instruments logic

SN74 LVC 1G 08 DCK

Prefix		Logic Family		Gate count		Function	Package	
TI	Nexperia	TI	Nexperia	TI	Nexperia		TI	Nexperia
-	-	ABT	ABT	-	-		E	P
SN74	74	AHC(T)	AHC(T)	nG	nG		M	T
SN54	74	ALVC	ALVC	nT	nT		D	D
		ALVT	ALVT				PW	PW, TT
		AUP	AUP				DB	DB
		AVC	AVC				DL	DL
		CBT	CBT				DGG	DGG
		CBT LV	CBT LV				DGV	DGV
		CD	HEF				GKE	EV
		F	F				ZKE	EC
		HC(T)	HC(T)				DCK	GW
		LV	LV				DBV	GV
		LVC	LVC				DCU	DC
		LVT	LVT				DCT	DP
		TPIC6C	NPIC6C				DRY	GM
							YZP	GM

74 LVC 1G 08 GW

IDT logic

74 FCT 244 PY

Prefix		logic Family		Function	Package	
Tosh	Nexperia	IDT	Nexperia		IDT	Nexperia
TC7	74	ALVC	ALVC		BF	EC
54	74	CBTLV	CBTLV		CD	N
		FCT	ABT		DC, PS	D
		LVC	LVC		DJ, PF	DGV
		QS	CBT		PA	DGG
					PC	DS, DK
					PG	PW
					PV	DL
					PY	DB

74 ABT 244 DB

Diodes Inc. logic

74 LVC 1G 08 FW4

Prefix		logic Family		Gate count		Function	Packages	
Diodes	Nexperia	Diodes	Nexperia	Diodes	Nexperia		Diodes	Nexperia
74	74	AHC(T)	AHC(T)	-	-		T14	PW
		LVC	LVC	nG	nG		S14	D
							SE	GW
							DW	GW
							W5	GV
							FZ4	GM
							FW4	GF

74 LVC 1G 08 GW

Renesas logic

HD74 HC 1G 08 CM

Prefix		logic Family		Gate count		Function	package	
Ren.	Nexperia	Ren.	Nexperia	Ren.	Nexperia		Ren.	Nexperia
HD74	74	ALVC	ALVC	-	-		CM	GW
		BC, LS	ABT	nG	nG		FP	DC
		CBT	CBT				P	N
		HC(T)	HC(T)				T	PW
		LV	LV				US	DC
		LVC	LVC					
		LVT	LVT					

74 HC 1G 08 GW

Product orientation (tape and reel pack)

2 pin packages

Orientation in tape	Package	Packing 12NC ending
	DFN1006-2 (SOD882)	315
	DFN1006D-2 (SOD882D)	315
	DFN1608D-2 (SOD1608)	315
	DSN0603-2 (SOD962)	315
	DSN0402-2 (SOD992)	315
	DSN1006-2 (SOD993)	315
	DSN1006U-2 (SOD995)	315
	DSN1608-2 (SOD963&964)	315
	SOD80	115, 135
	SOD123F	115
	CFP3 (SOD123W)	115
	SOD123	115,118
	CFP5 (SOD128)	115
	SOD323	115, 135
	SOD323F	115
	SOD523	115, 135, 315, 335

3 pin packages

Orientation in tape	Package	Packing 12NC ending
	SOT89	146
Orientation in tape	Package	Packing 12NC ending
	DFN1006-3 (SOT883)	315
	DFN1006B-3 (SOT883B)	315
	SOT23	185, 215, 235
	SOT323	115, 135
	SOT416	115, 135

Orientation in tape	Package	Packing 12NC ending
	DFN1010D-3 (SOT1215)	147
	DFN2020-3 (SOT1061)	115, 135
	DFN2020D-3 (SOT1061D)	115,135
	SOT89	115,135
	SOT663	115
	CFP15 (SOT1289)	139, 146
	DPAK (SOT428)	118
	D2PAK (SOT404)	118
Orientation in tape		
	SOT89	147

4 pin packages

Orientation in tape	Package	Packing 12NC ending
	WLCSP4 (0808)	084
Orientation in tape	Package	Packing 12NC ending
	SOT143B	215, 235
	SOT223	115, 135
	DFN1010-4 (SOT1194)	115

Orientation in tape	Package	Packing 12NC ending
	SOT89	115, 135
Orientation in tape	Package	Packing 12NC ending
		

5 pin packages

Orientation in tape	Package	Packing 12NC ending
	LFPAK (SOT669)	115
	WLCSP5 (1208)	087

Orientation in tape	Package	Packing 12NC ending
	SOT353	115, 135
	SOT665	115

Orientation in tape	Package	Packing 12NC ending
	SOT753	125

Orientation in tape	Package	Packing 12NC ending
		

6 pin packages

Orientation in tape	Package	Packing 12NC ending
	DFN1410-6 (SOT886)	115
	DFN1616-6 (SOT1189)	115
	DFN2020MD-6 (SOT1220)	184
	LFPAK33 (SOT1210)	115
	LFPAK56D (SOT1205)	115
	WLCSP6 (1510)	023

Orientation in tape	Package	Packing 12NC ending
	DFN1412-6 (SOT1268)	147
	DFN2020-6 (SOT1118)	115
	DFN2020D-6 (SOT1118D)	115
	DFN2020MD-6 (SOT1220)	115
	SOT363	115, 135
	SOT457	115, 135
	SOT666	115, 315

Orientation in tape	Package	Packing 12NC ending
	DFN1010-6 (SOT891)	132
	DFN1010E-6 (SOT1202)	132
	DFN1410-6 (SOT886)	132
	DFN2020MD-6 (SOT1220)	125
	SOT363	125, 165
	SOT457	125, 165

Orientation in tape	Package	Packing 12NC ending
		

multi I/O pin packages

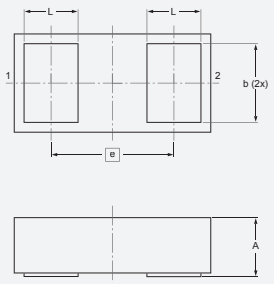
Orientation in tape	Package	Packing 12NC ending
	DFN2110-9 (SOT1178)	115
	DFN2111-7 (SOT1358)	471
	DFN2510A-10 (SOT1176)	115
	DFN2520-9 (SOT1333)	
	DFN2520-9 (SOT1333)	
	DFN2520-9 (SOT1333)	
	DFN2520-9 (SOT1333)	
	DFN5050-32 (SOT617-3)	

Orientation in tape	Package	Packing 12NC ending
		

Orientation in tape	Package	Packing 12NC ending
		

Orientation in tape	Package	Packing 12NC ending
		

2-pin SMD packages



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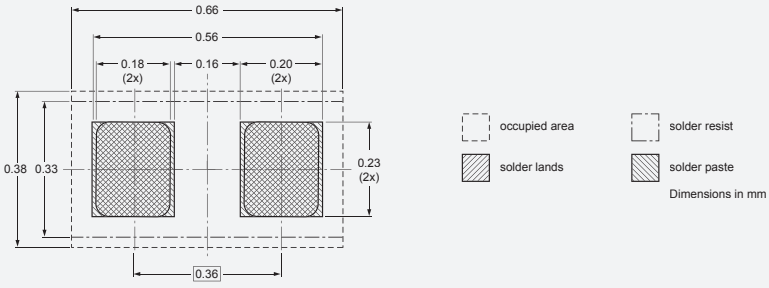

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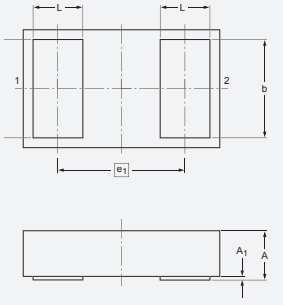

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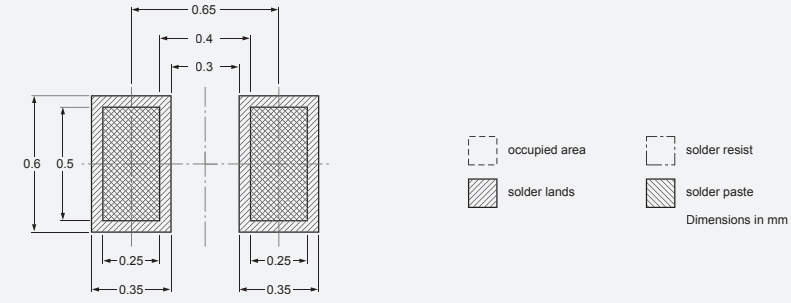

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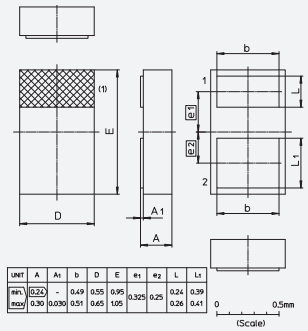

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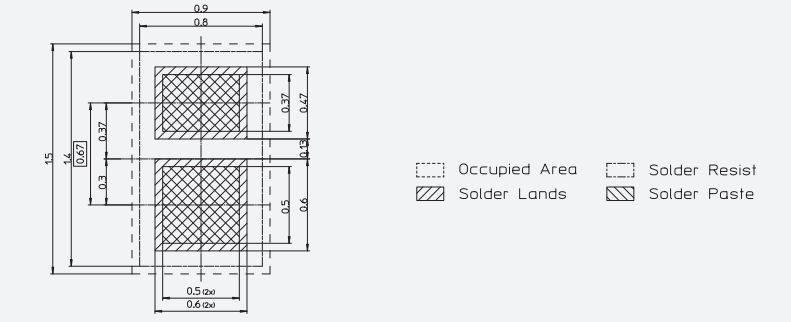

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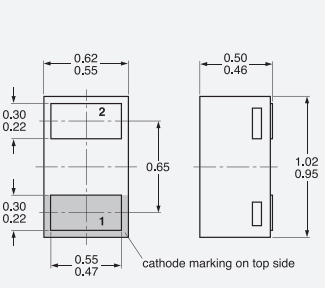

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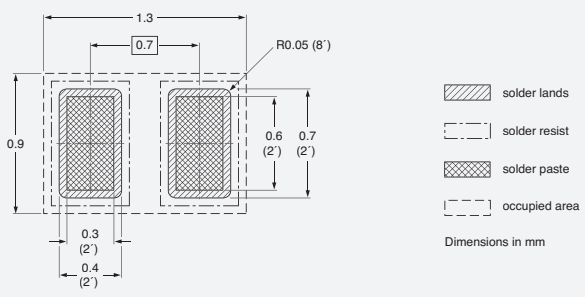
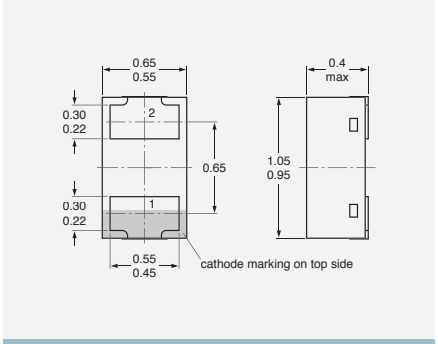


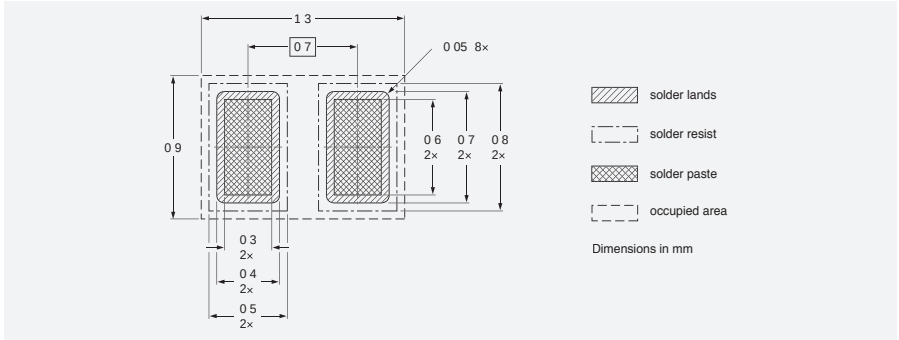
DFN1006-2 (SOD882)

Dimensions in mm

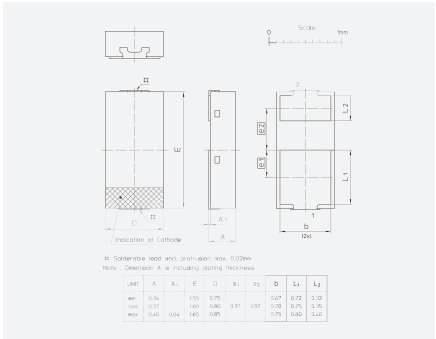
2-pin SMD packages



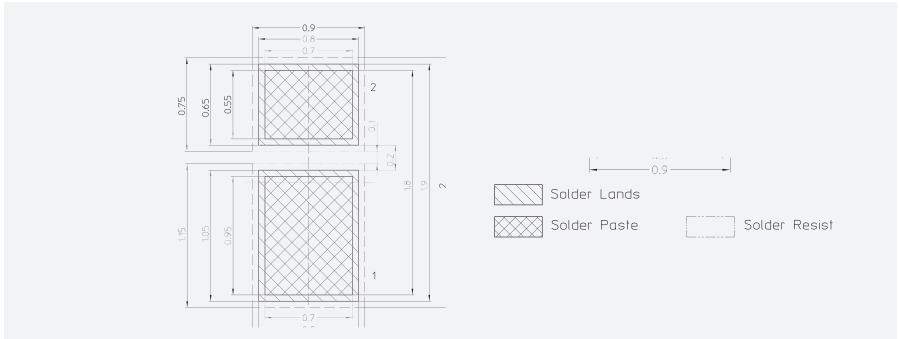
DFN1006D-2 (SOD882D)



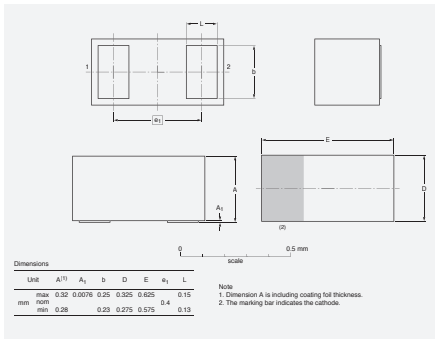
DFN1006D-2 (SOD882D)



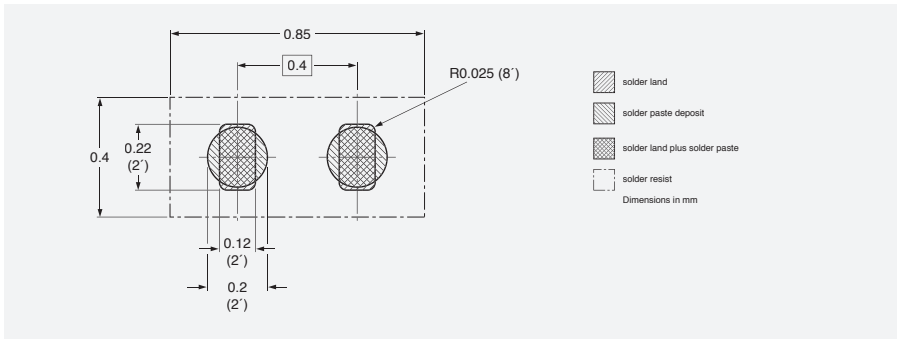
DFN1608D-2 (SOD1608)



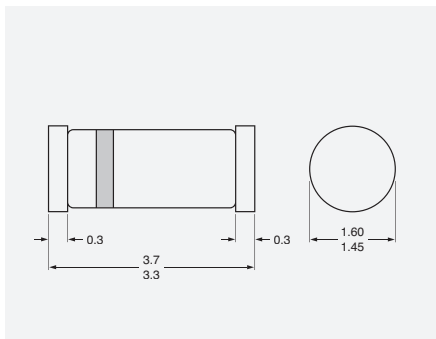
DFN1608D-2 (SOD1608)



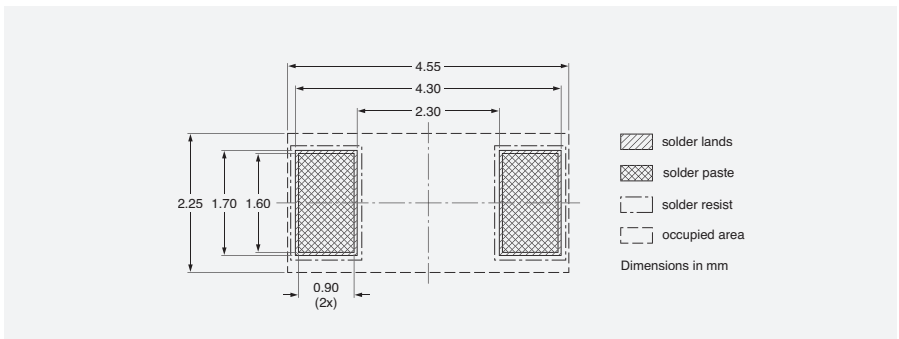
DSN0603-2 (SOD962)



DSN0603-2 (SOD962) and DSN0603B-2 (SOD962B)



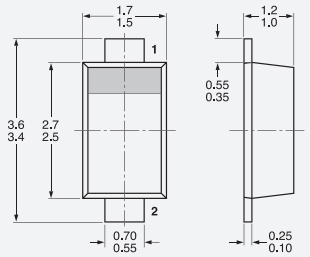
SOD80C



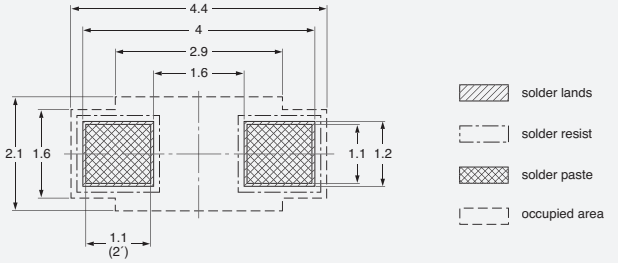
SOD80C

Dimensions in mm

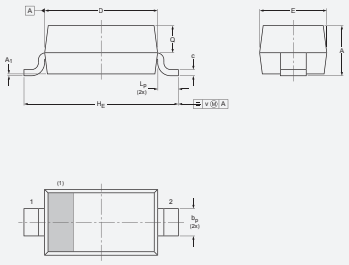
2-pin SMD packages



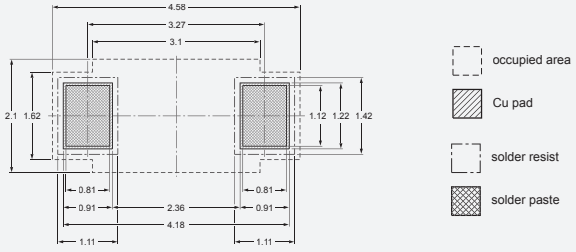
SOD123F



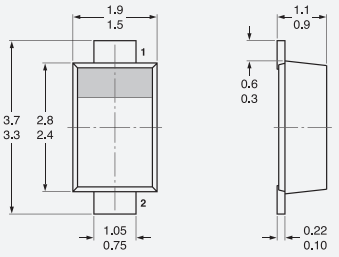
SOD123F



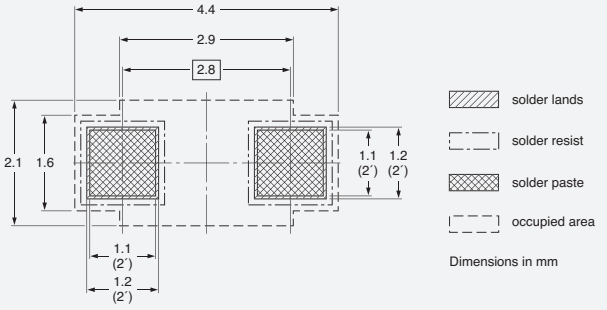
SOD123



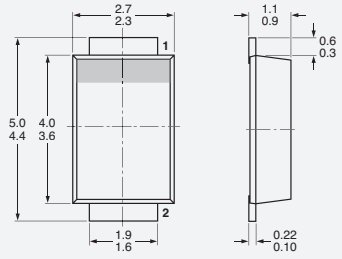
SOD123



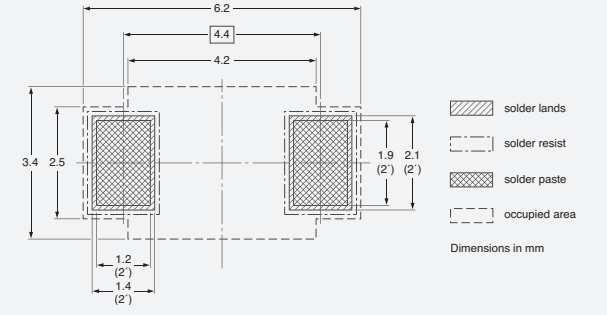
SOD123W



SOD123W



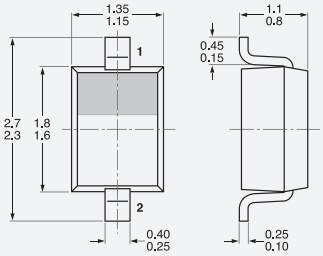
SOD128



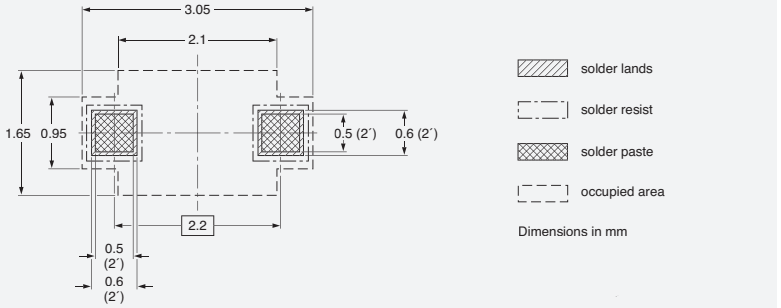
SOD128

Dimensions in mm

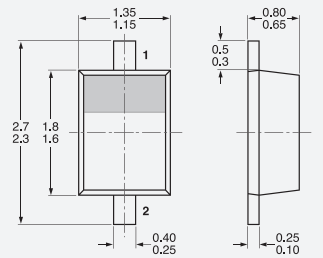
2-pin SMD packages



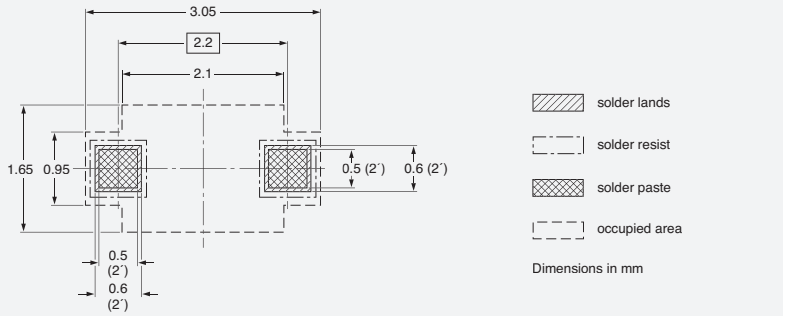
SOD323 (SC-76)



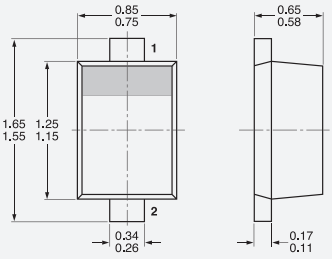
SOD323 (SC-76)



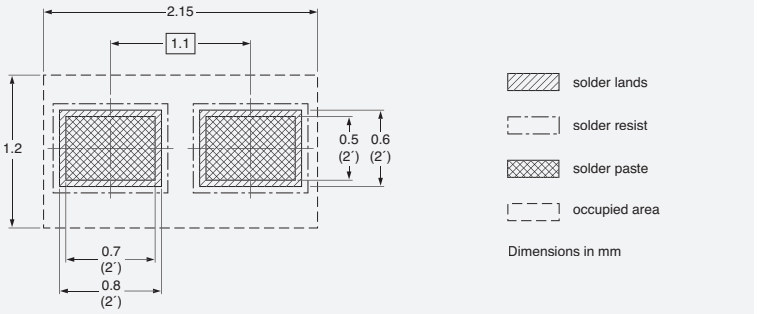
SOD323F (SC-90)



SOD323F (SC-90)

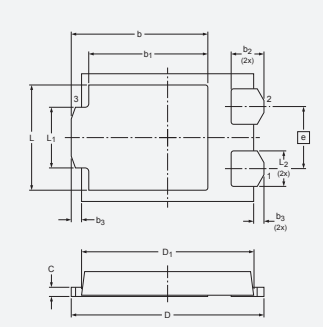


SOD523 (SC-79)

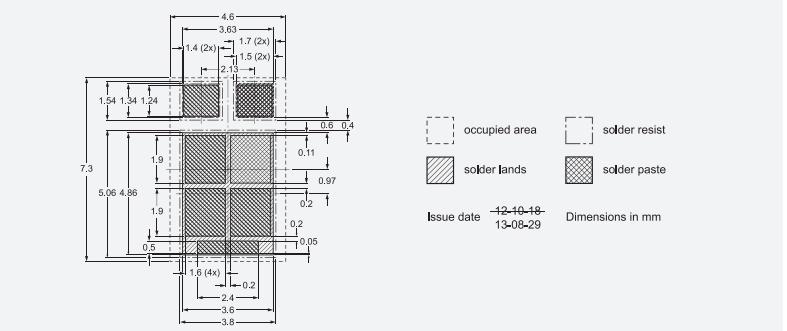


SOD523 (SC-79)

3-pin SMD packages



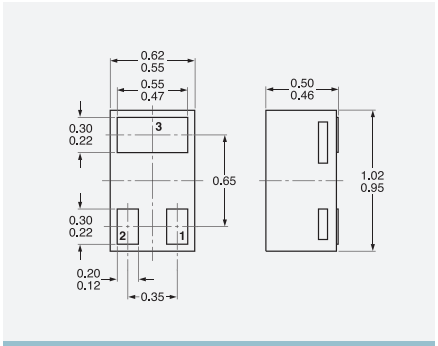
CFP15 (SOT1289)



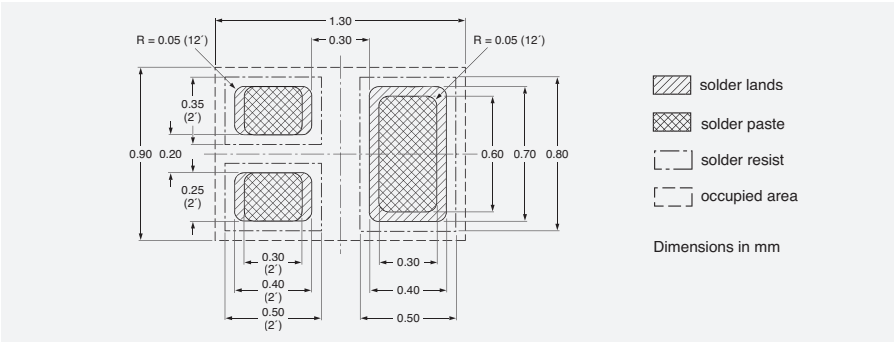
CFP15 (SOT1289)

Dimensions in mm

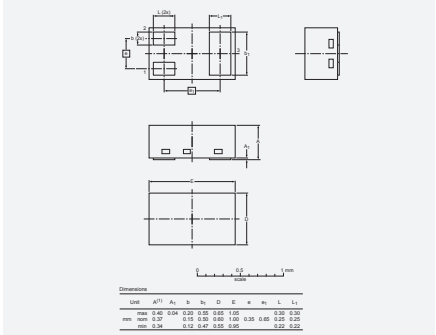
3-pin SMD packages



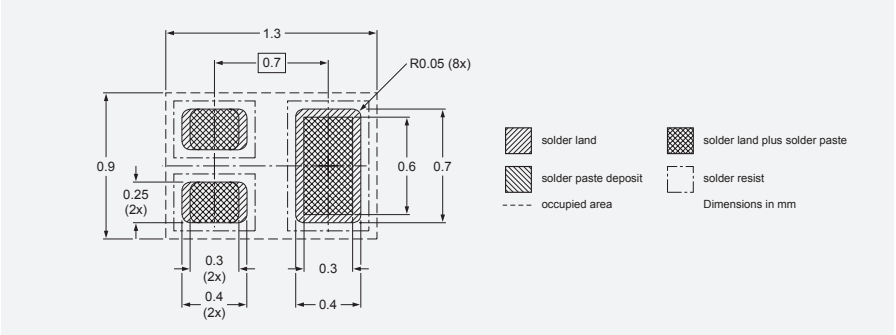
DFN1006-3 (SOT883)



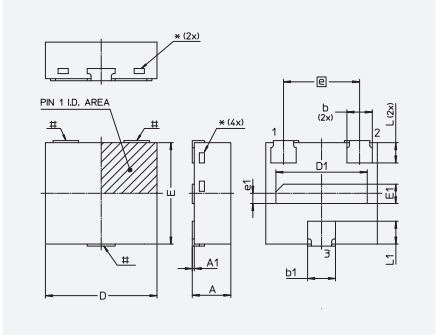
DFN1006-3 (SOT883)



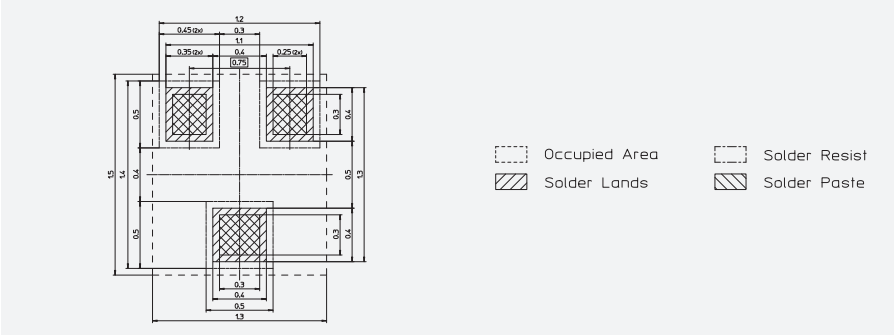
DFN1006B-3 (SOT883B)



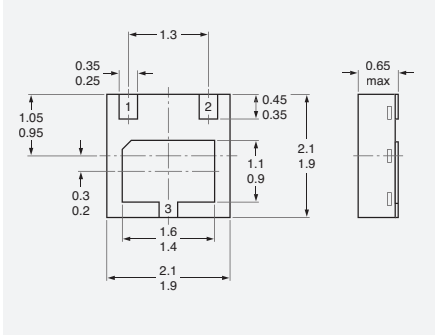
DFN1006B-3 (SOT883B)



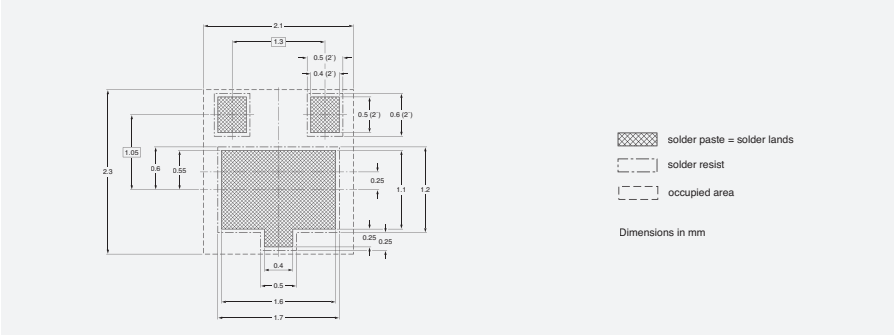
DFN1010D-3 (SOT1215)



DFN1010D-3 (SOT1215)



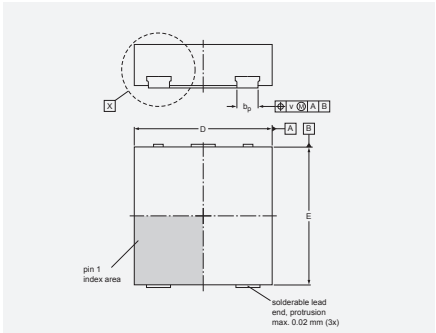
DFN2020-3 (SOT1061)



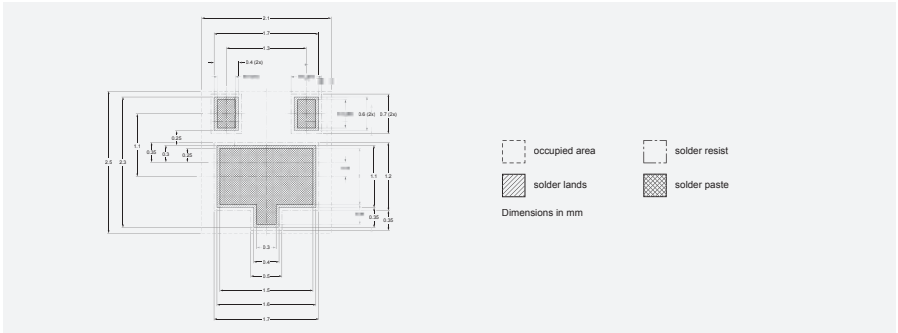
DFN2020-3 (SOT1061)

Dimensions in mm

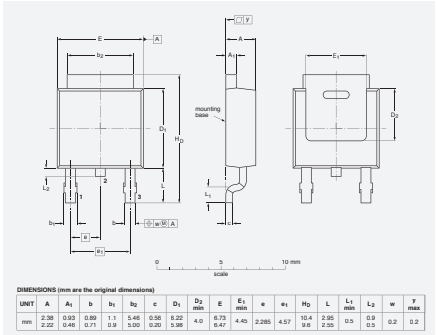
3-pin SMD packages



DFN2020D-3 (SOT1061D)

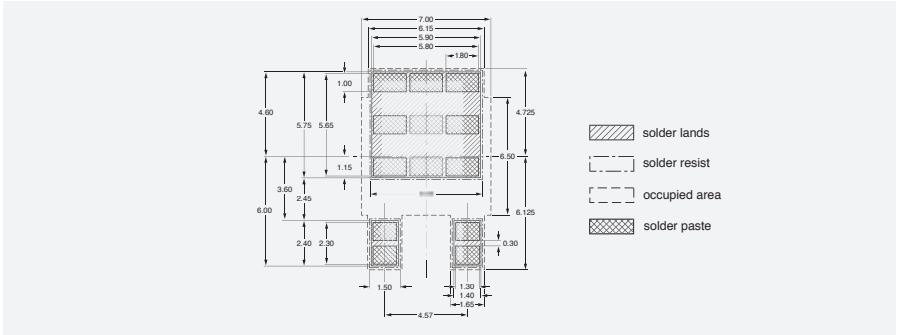


DFN2020D-3 (SOT1061D)

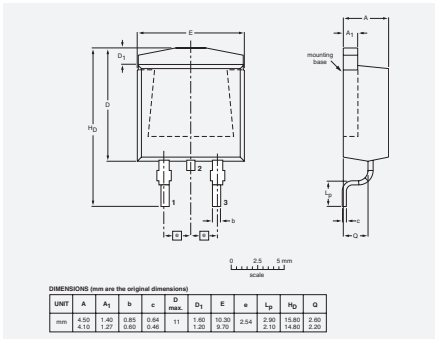


UNIT	A	A_1	b	b_1	b_2	c	D_1	D_2 min	E	E_1 min	e	e_1	H_D	L	L_1 min	L_2	w	y max
mm	2.38 2.22	0.93 0.46	0.89 0.71	1.1 0.9	5.46 5.00	0.56 0.20	6.22 5.98	4.0	6.73 6.47	4.45	2.285	4.57	10.4 9.6	2.95 2.55	0.5	0.9 0.5	0.2	0.2

DPAK (SOT428)

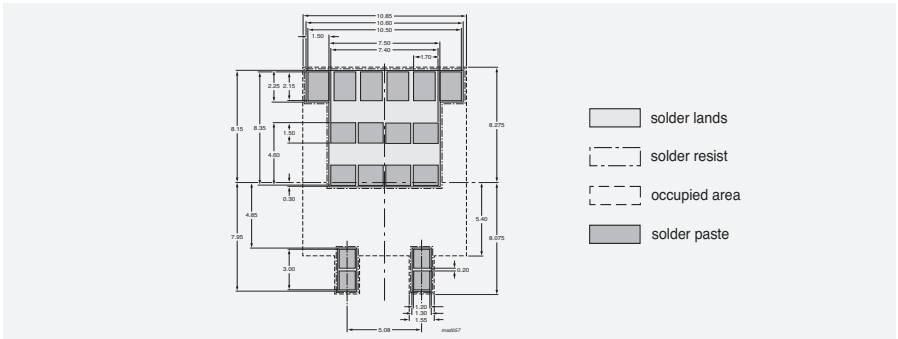


DPAK (SOT428)

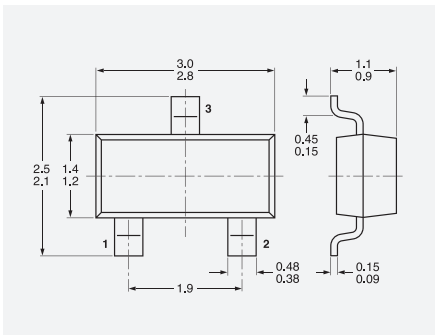


UNIT	A	A_1	b	c	D max.	D_1	E	e	L_p	H_D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

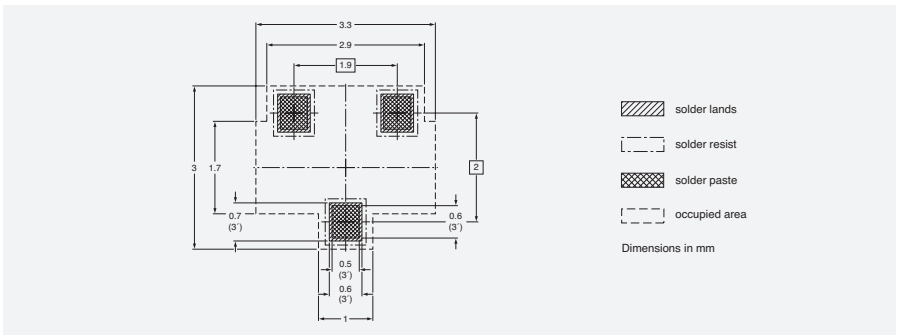
D²PAK (SOT404)



D²PAK (SOT404)



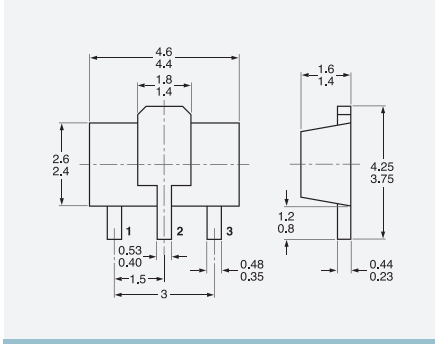
SOT23



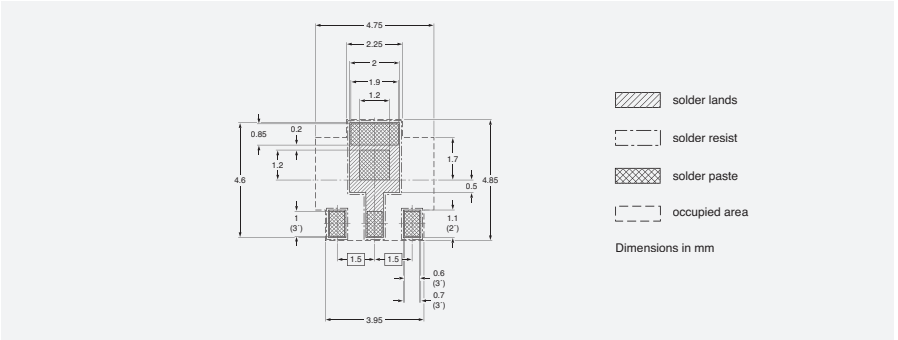
SOT23

Dimensions in mm

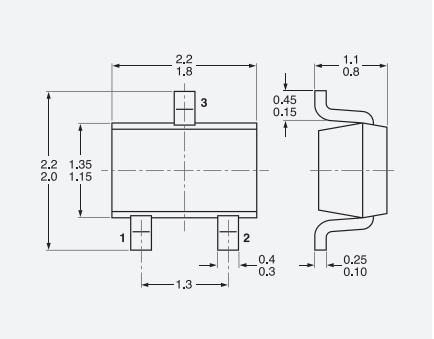
3-pin SMD packages



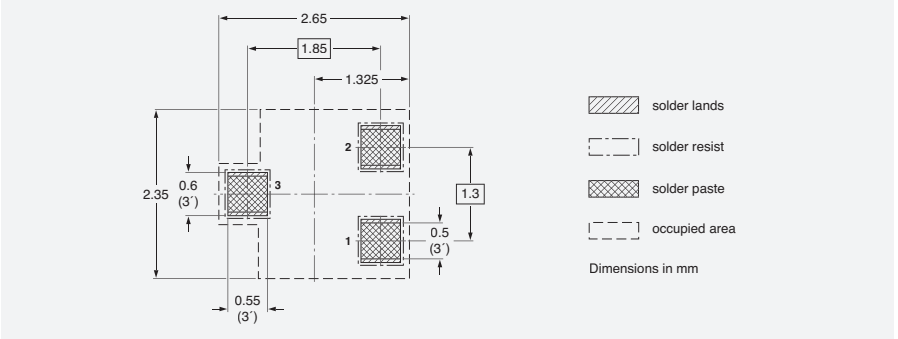
SOT89 (SC-62)



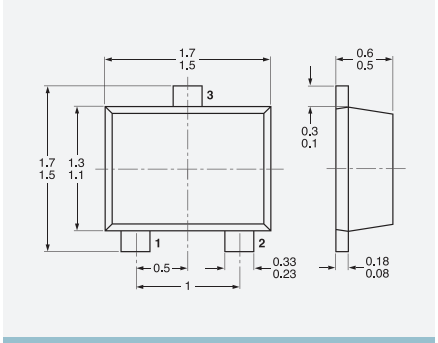
SOT89 (SC-62)



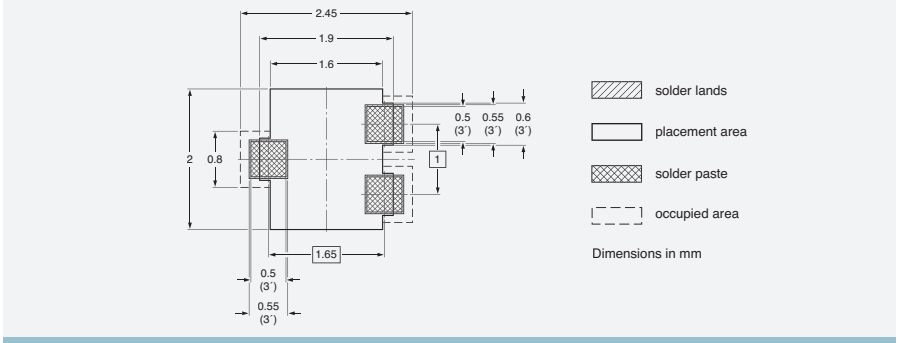
SOT323 (SC-70)



SOT323 (SC-70)

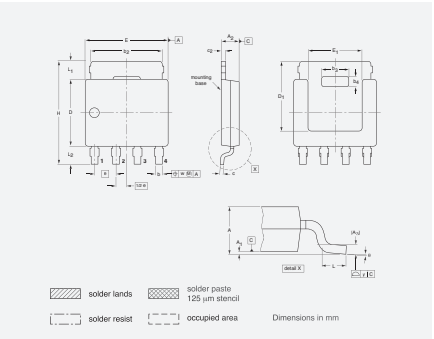


SOT663

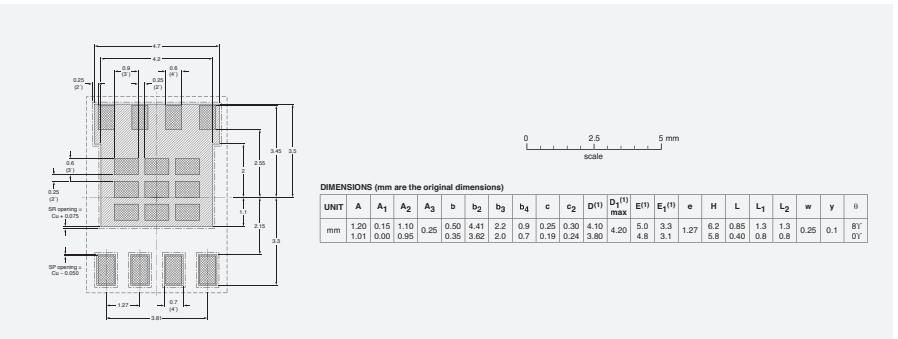


SOT663

4-pin SMD packages



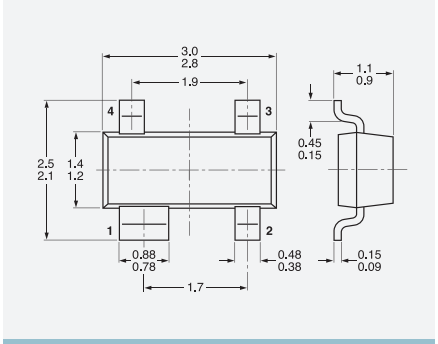
LFPAK56 (SOT669)



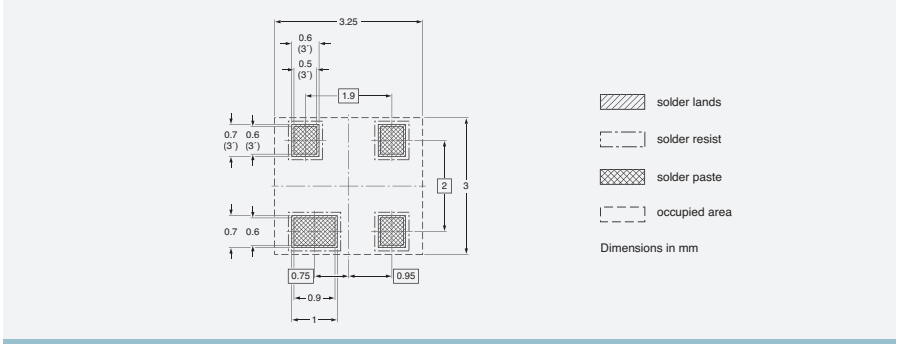
LFPAK56 (SOT669)

Dimensions in mm

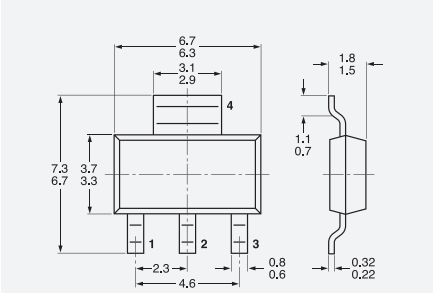
4-pin SMD packages



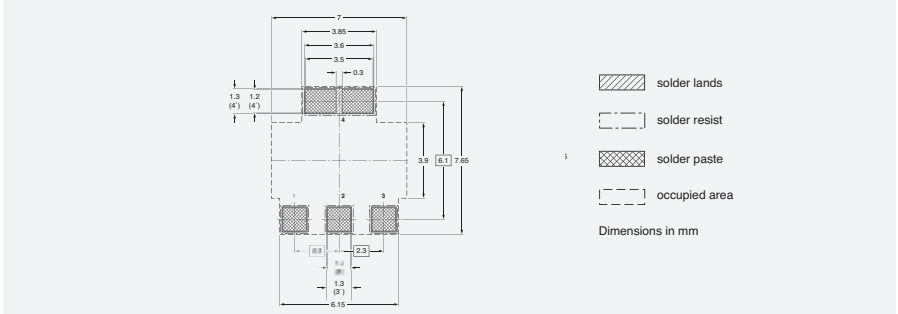
SOT143B



SOT143B

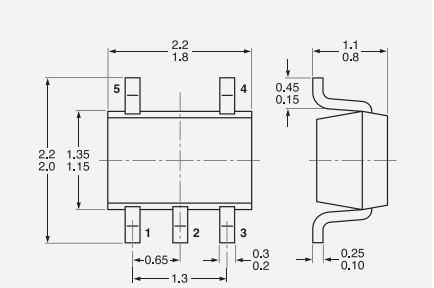


SOT223 (SC-73)

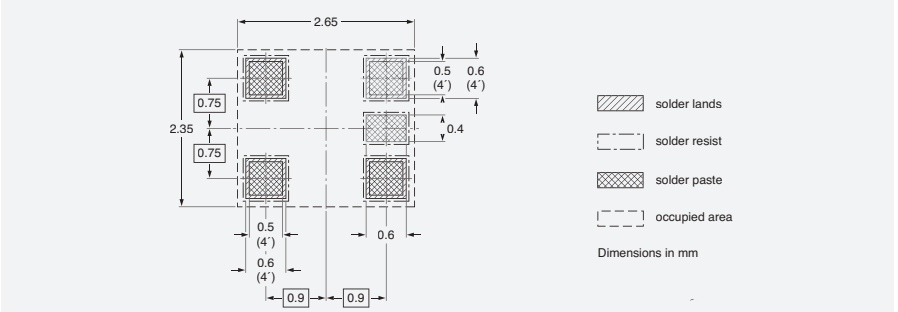


SOT223 (SC-73)

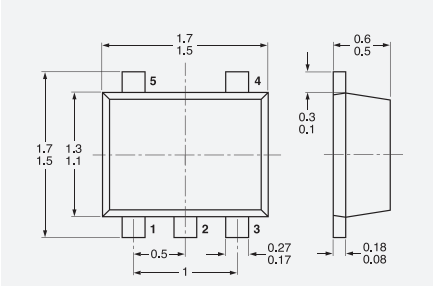
5-pin SMD packages



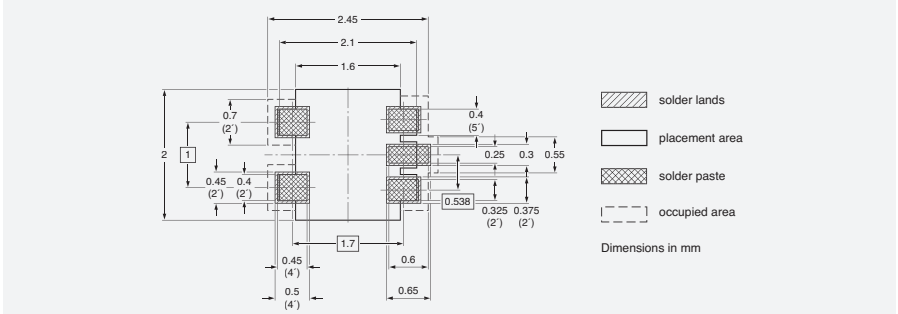
SOT353 (SC-88A)



SOT353 (SC-88A)



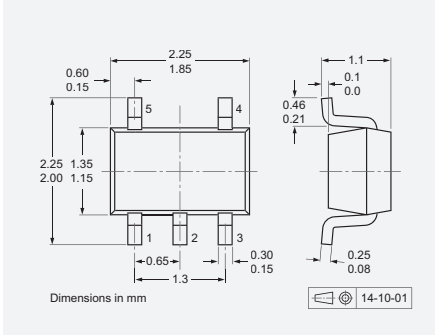
SOT665



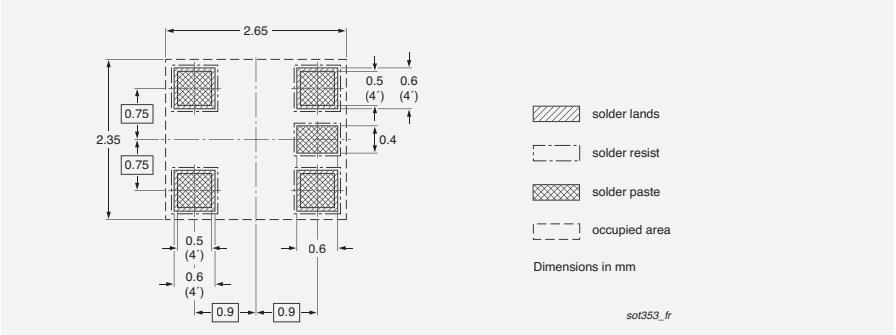
SOT665

Dimensions in mm

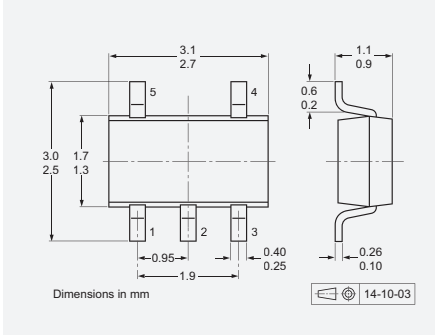
5-pin SMD packages



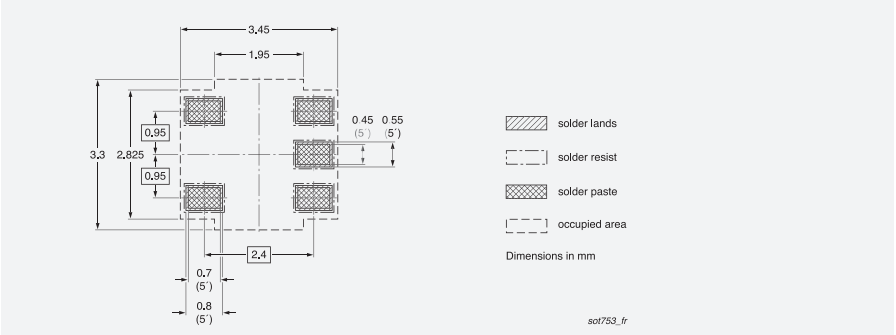
SOT353 GW



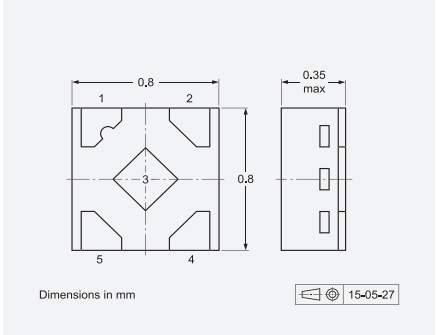
SOT353 GW



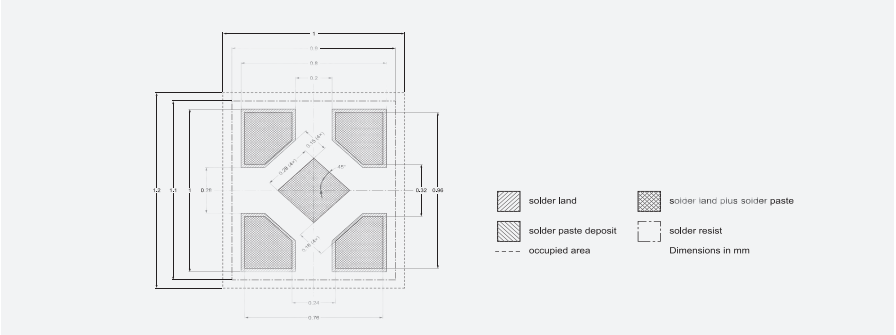
SOT753-1 GV



SOT753-1 GV

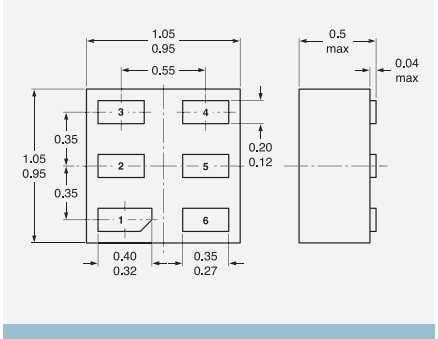


SOT1226 GX

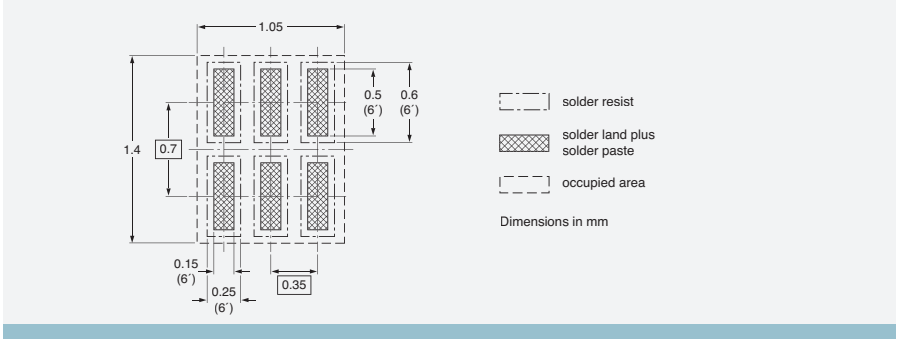


SOT1226 GX

6-pin SMD packages



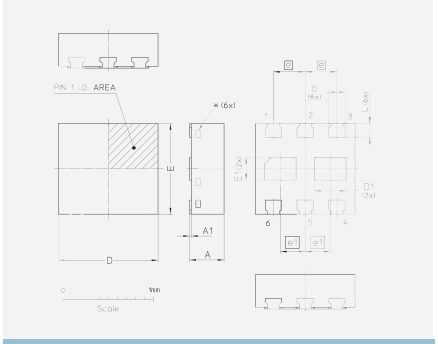
DFN1010-6 (SOT891)



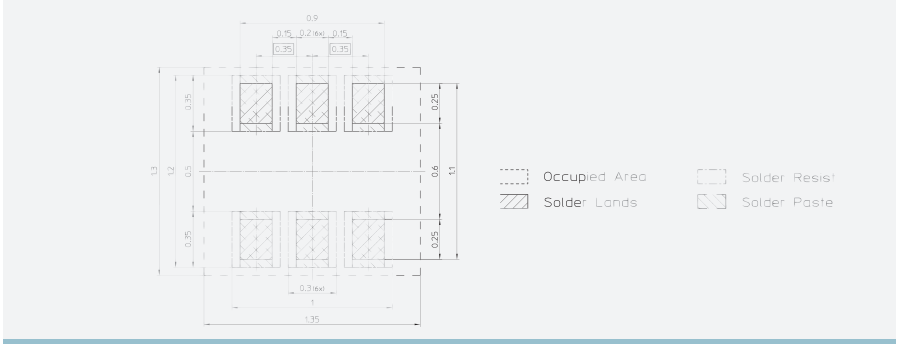
DFN1010-6 (SOT891)

Dimensions in mm

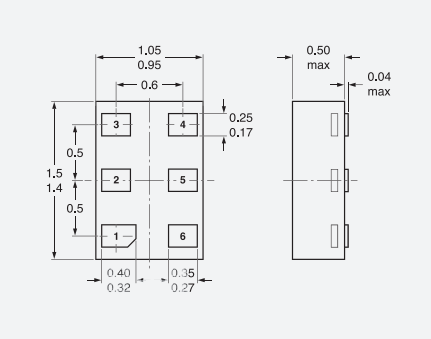
6-pin SMD packages



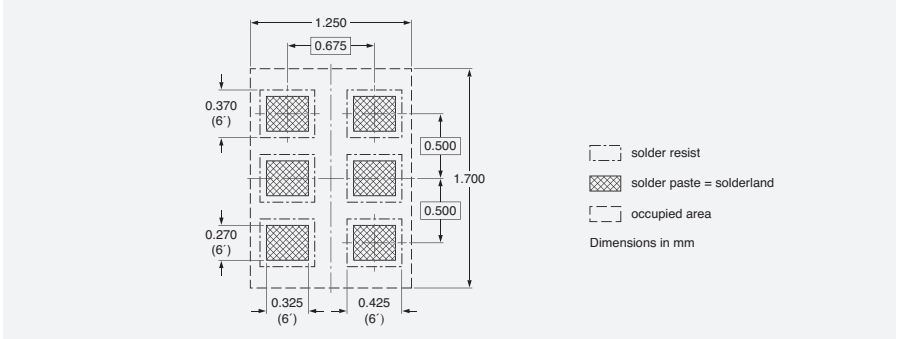
DFN1010B-6 (SOT1216)



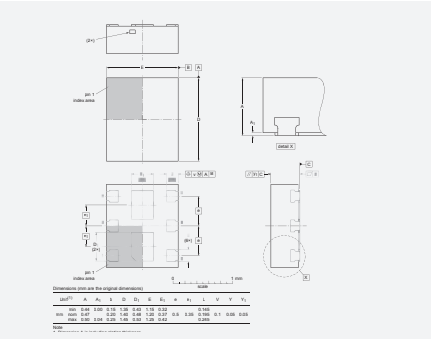
DFN1010B-6 (SOT1216)



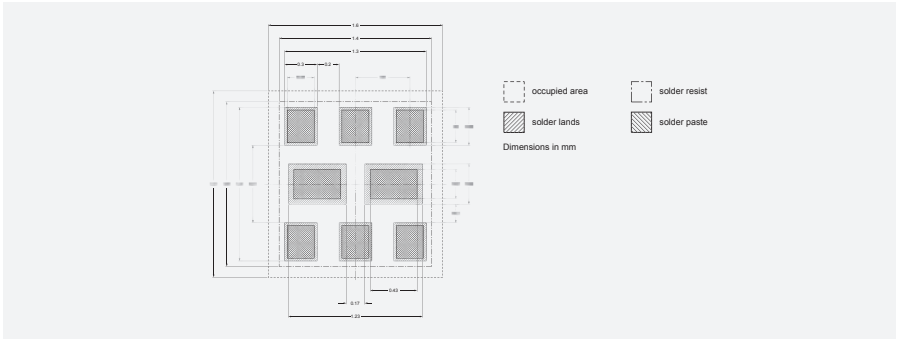
DFN1410-6 (SOT886)



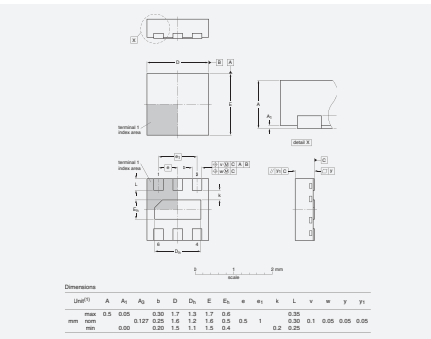
DFN1410-6 (SOT886)



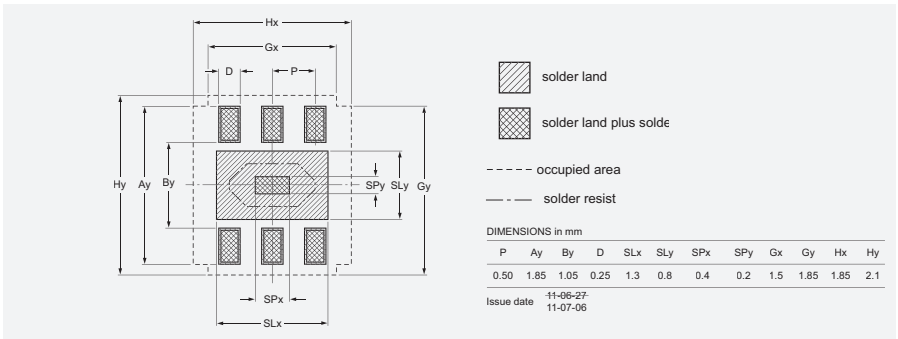
DFN1412-6 (SOT1268)



DFN1412-6 (SOT1268)



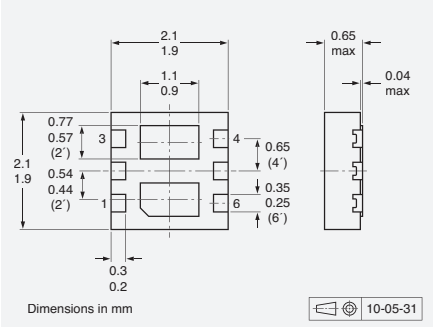
DFN1616-6 (SOT1189)



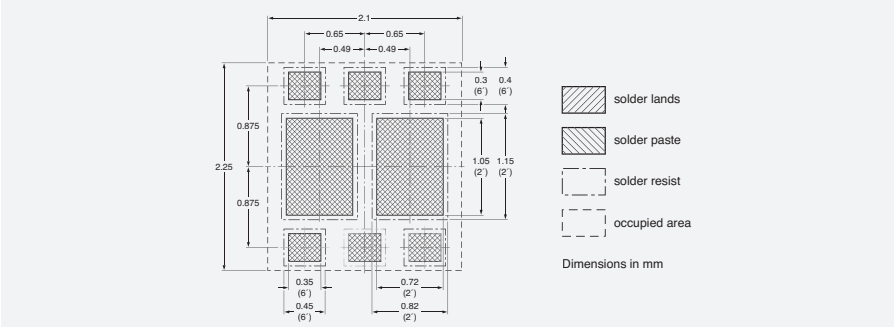
DFN1616-6 (SOT1189)

Dimensions in mm

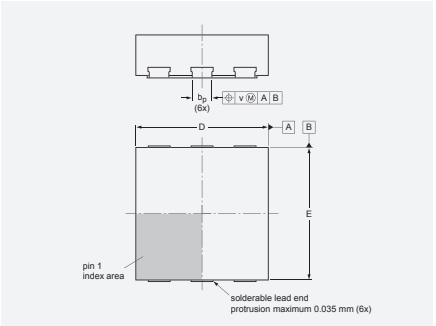
6-pin SMD packages



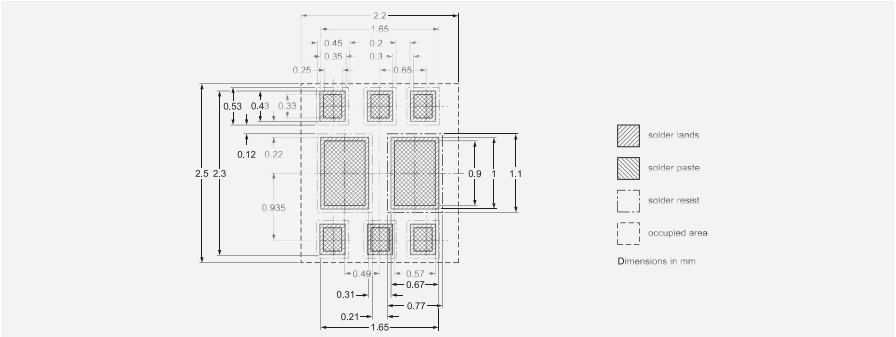
DFN2020-6 (SOT1118)



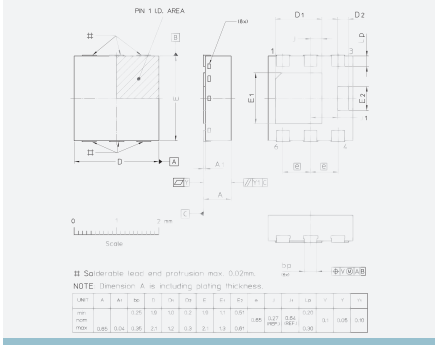
DFN2020-6 (SOT1118)



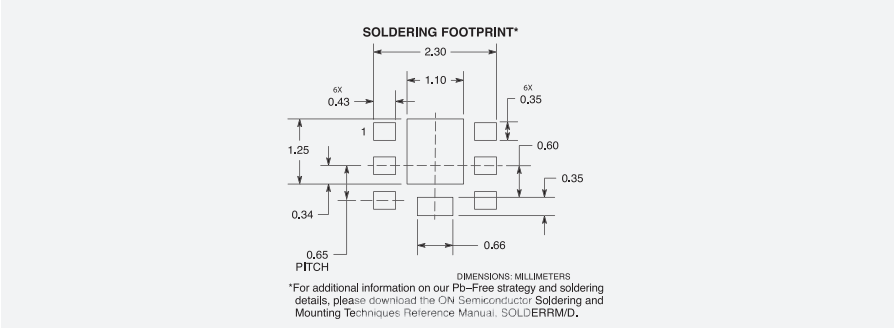
DFN2020D-6 (SOT1118D)



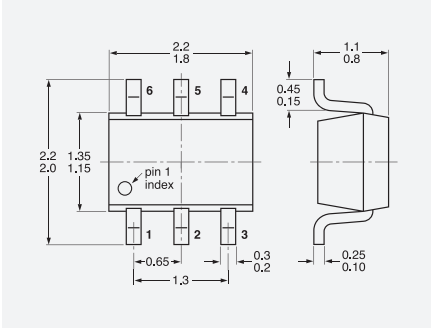
DFN2020D-6 (SOT1118D)



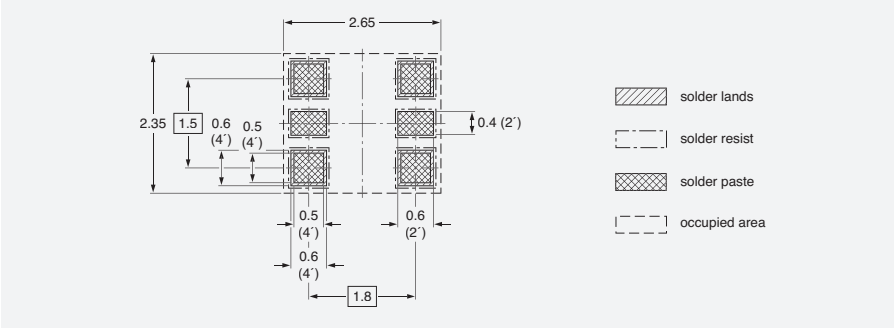
DFN2020MD-6 (SOT1220)



DFN2020MD-6 (SOT1220)



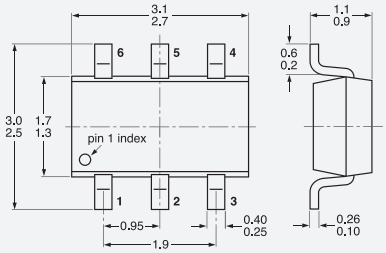
SOT363 (SC-88)



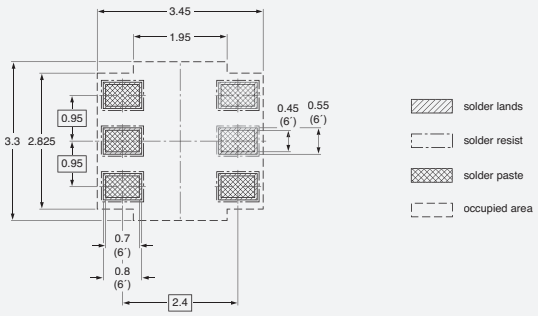
SOT363 (SC-88)

Dimensions in mm

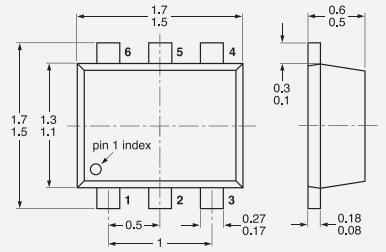
6-pin SMD packages



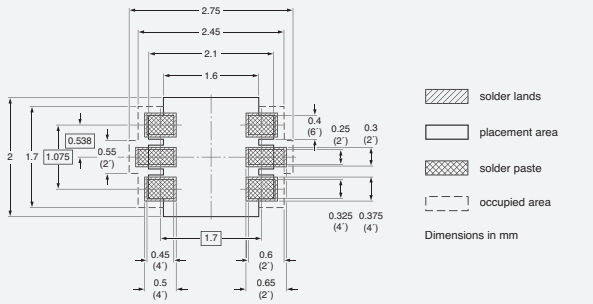
SOT457 (SC-74)



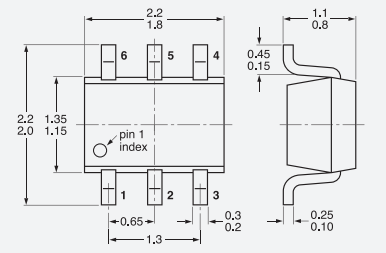
SOT457 (SC-74)



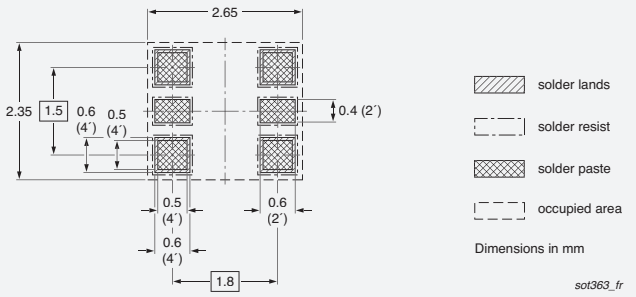
SOT666



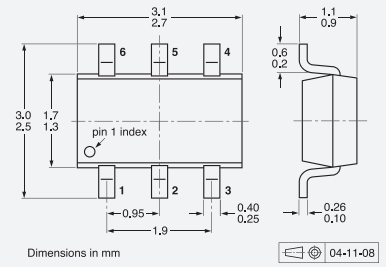
SOT666



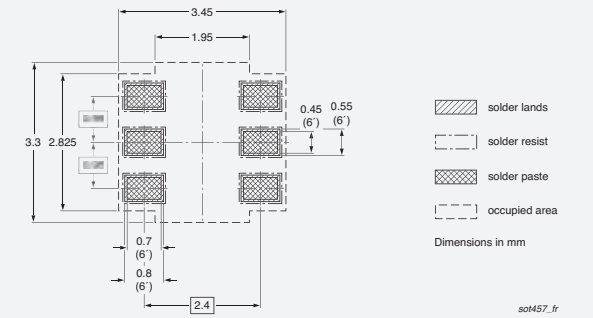
SOT363 GW



SOT363 GW



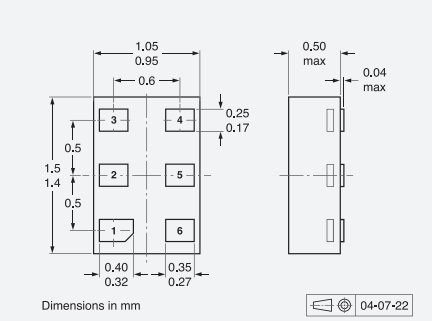
SOT457 GV



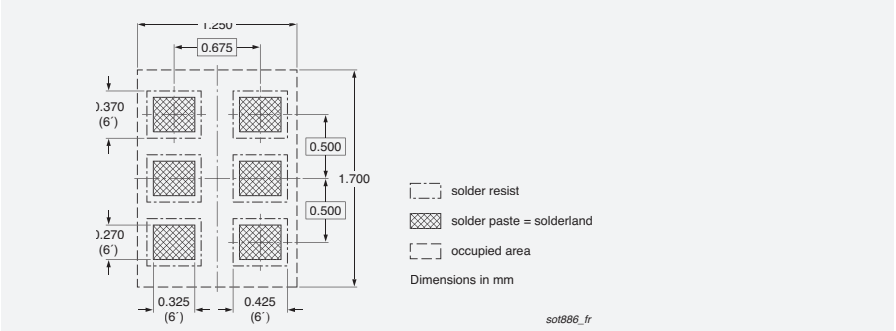
SOT457 GV

Dimensions in mm

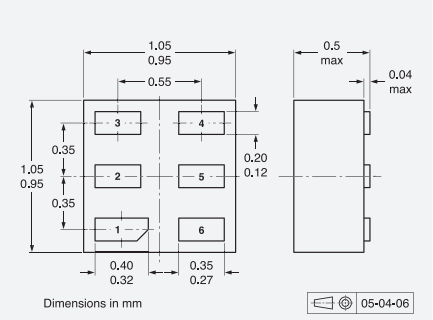
6-pin SMD packages



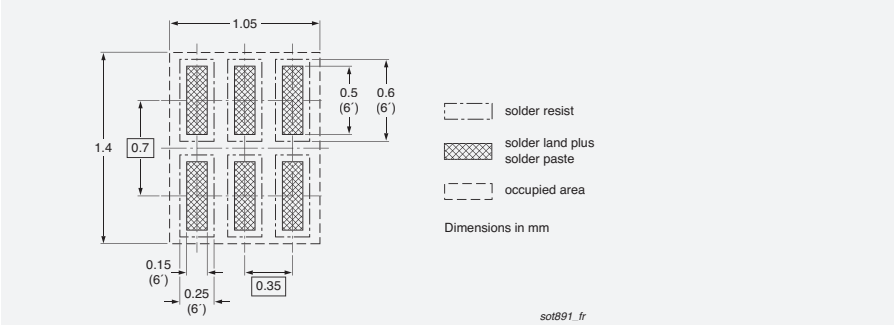
SOT886 GM



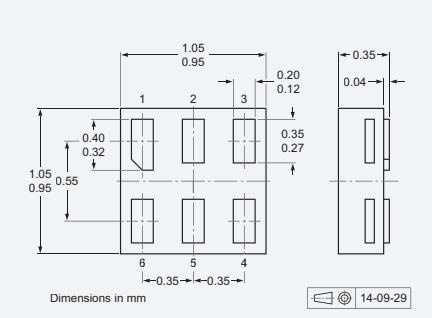
SOT886 GM



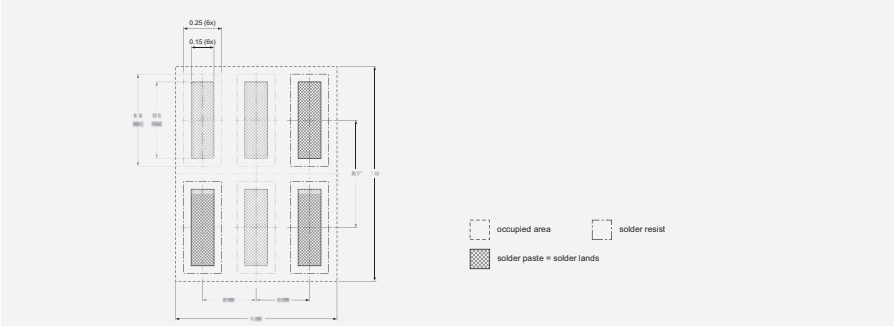
SOT891 GF



SOT891 GF

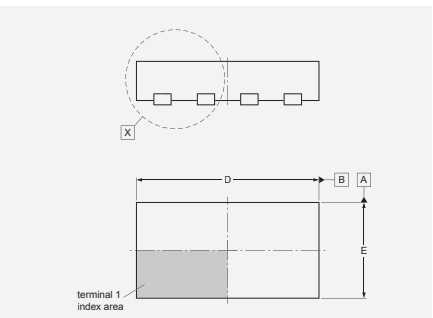


SOT1202 GS

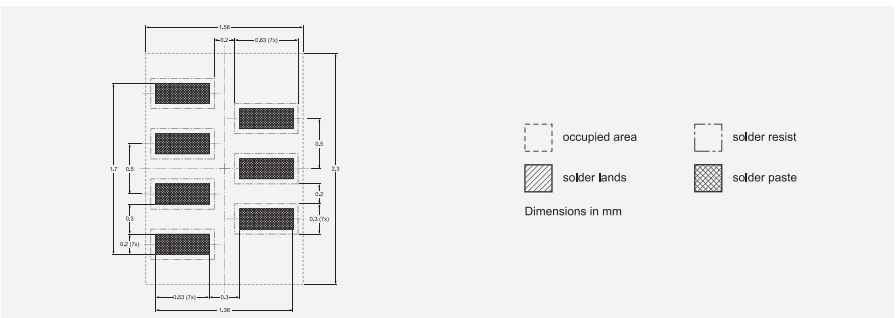


SOT1202 GS

7-pin SMD packages



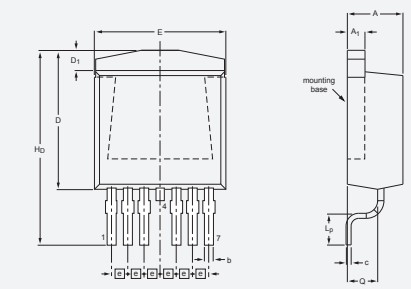
DFN2111-7 (SOT1358)



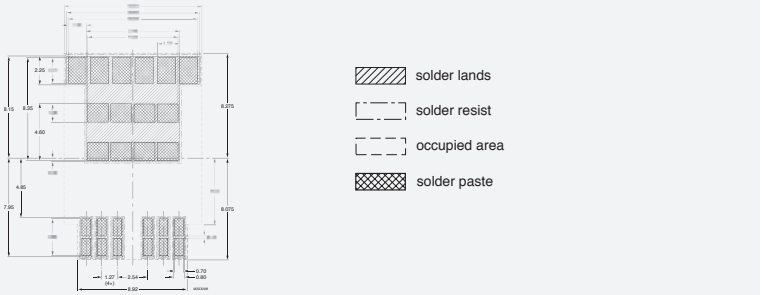
DFN2111-7 (SOT1358)

Dimensions in mm

7-pin SMD packages

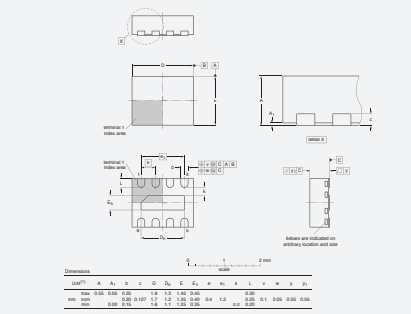


D2PAK-7 (SOT428)

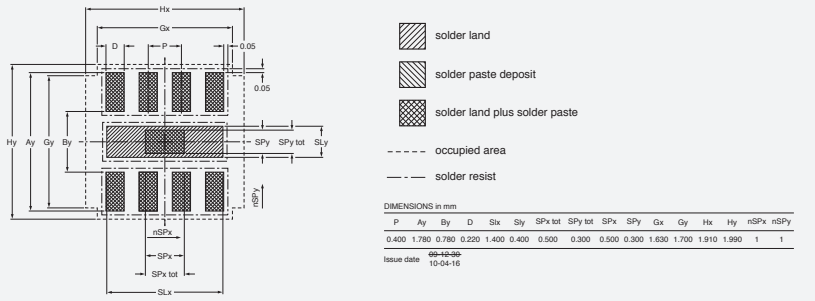


D2PAK-7 (SOT428)

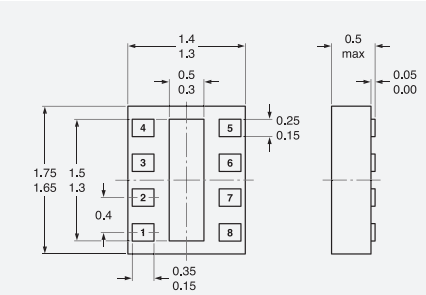
8-pin SMD packages



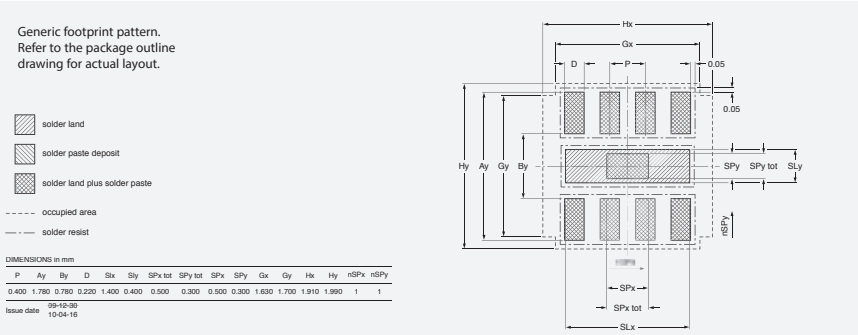
DFN1714-8 (SOT1166)



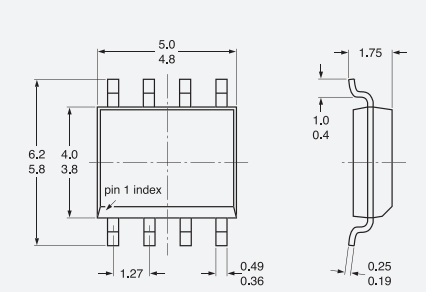
DFN1714-8 (SOT1166)



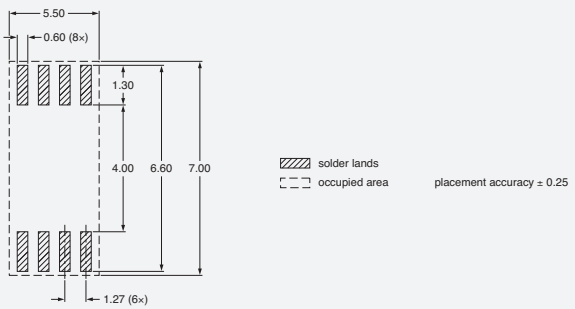
DFN1714U-8 (SOT983)



DFN1714U-8 (SOT983)



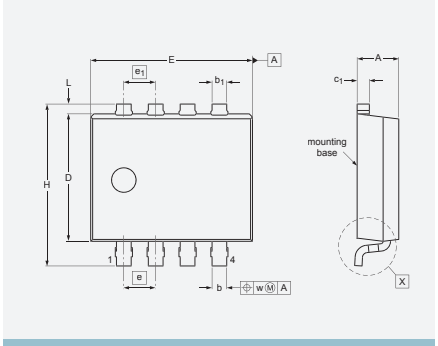
SOT96 (SO8)



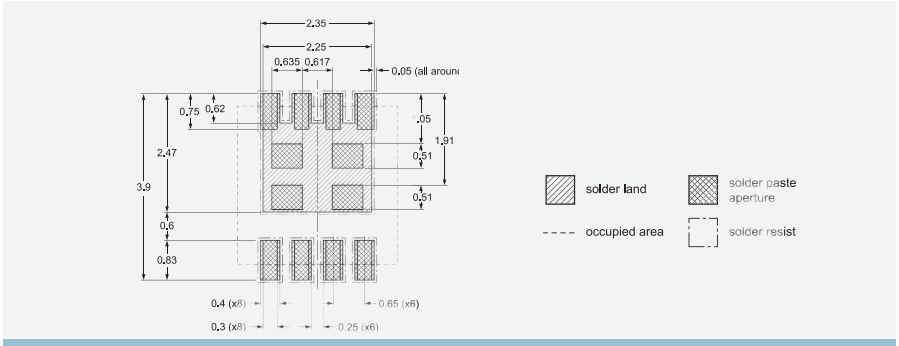
SOT96 (SO8)

Dimensions in mm

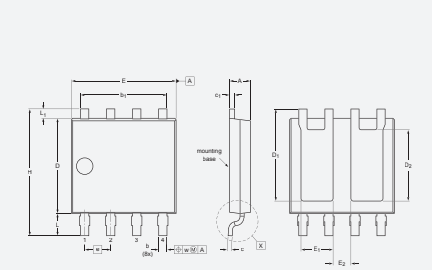
8-pin SMD packages



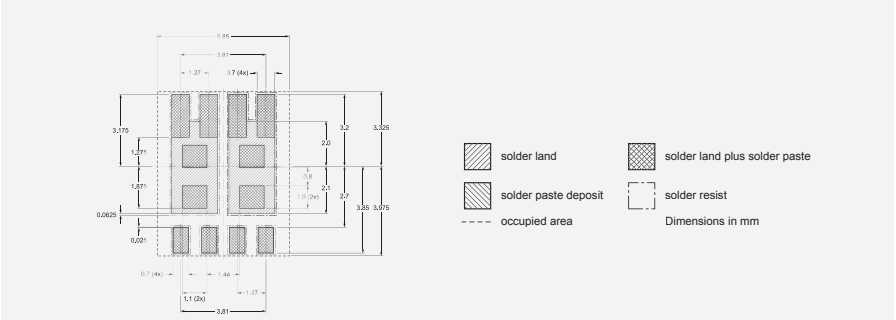
LFPAK33 (SOT1210)



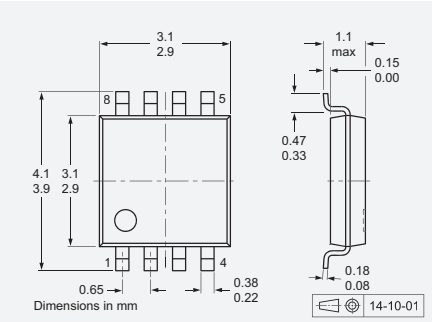
LFPAK33 (SOT1210)



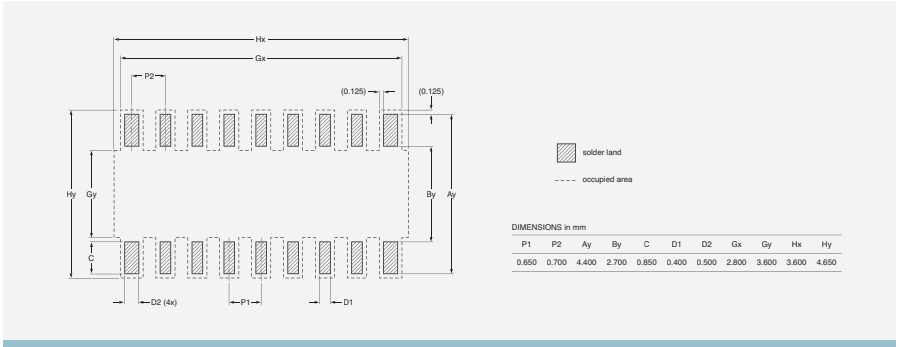
LFPAK56D (SOT1205)



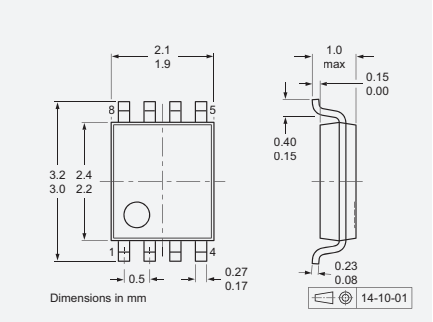
LFPAK56D (SOT1205)



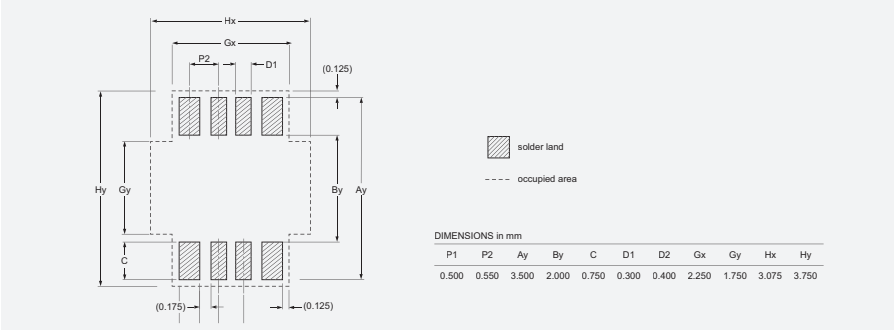
SOT505-2 DP



SOT505-2 DP



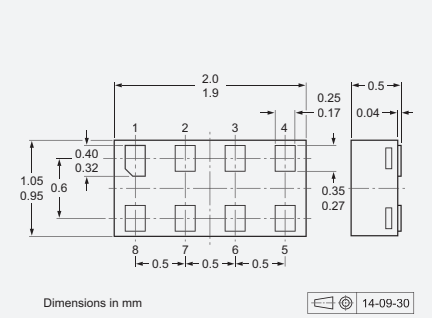
SOT765-1 DC



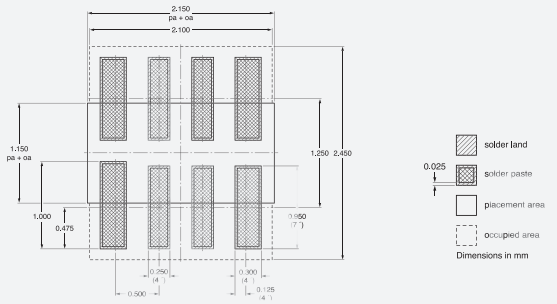
SOT765-1 DC

Dimensions in mm

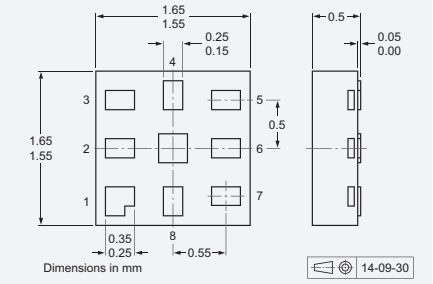
8-pin SMD packages



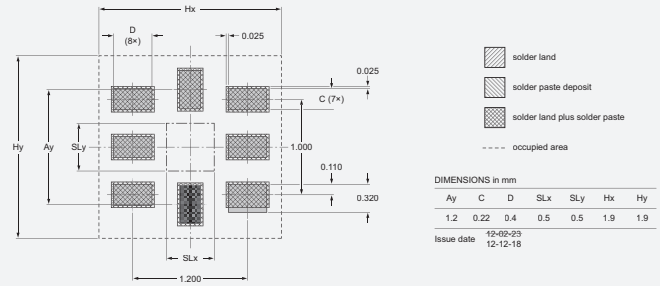
SOT833-1 GT



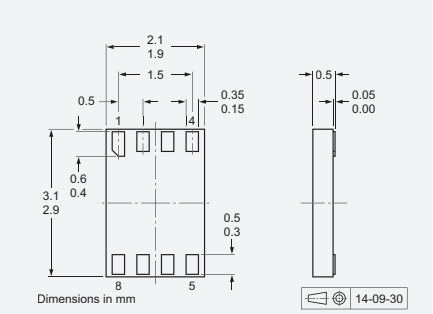
SOT833-1 GT



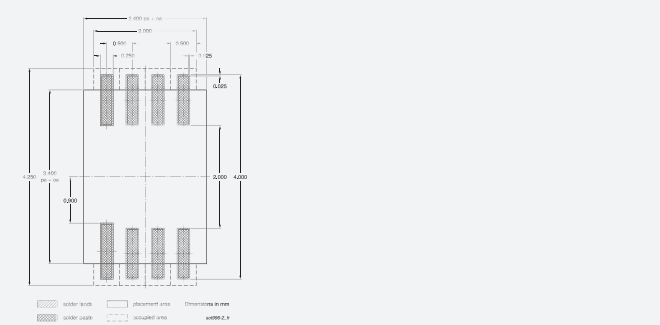
SOT902-2 GM



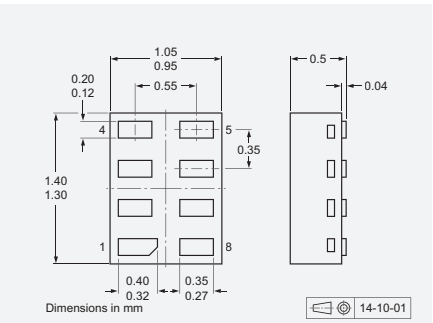
SOT902-2 GM



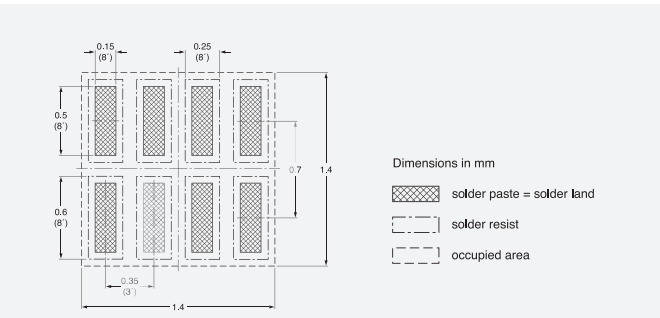
SOT996 GD



SOT996 GD



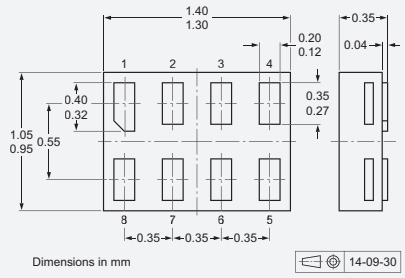
SOT1089 GF



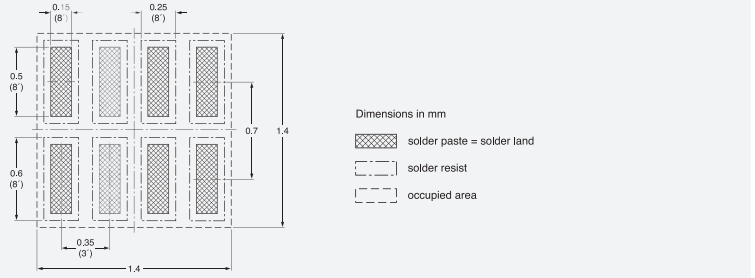
SOT1089 GF

Dimensions in mm

8-pin SMD packages

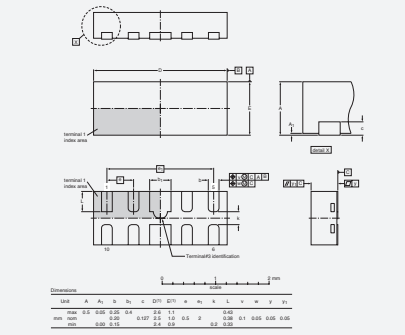


SOT1203 GS

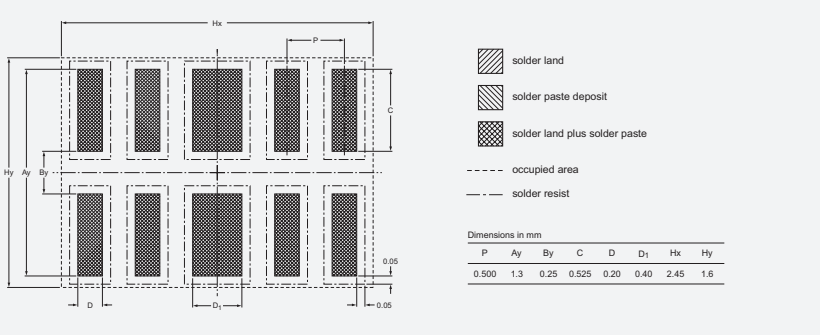


SOT1203 GS

More than 8-pin SMD packages

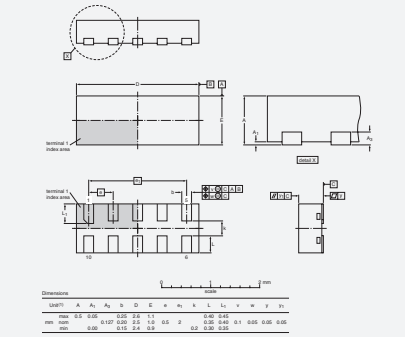


DFN2510-10 (SOT1165)

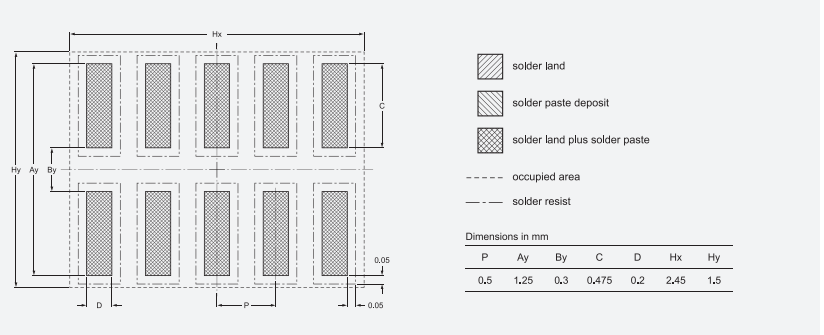


P	Ay	By	C	D	D_1	Hx	Hy
0.500	1.3	0.25	0.525	0.20	0.40	2.45	1.6

DFN2510-10 (SOT1165)

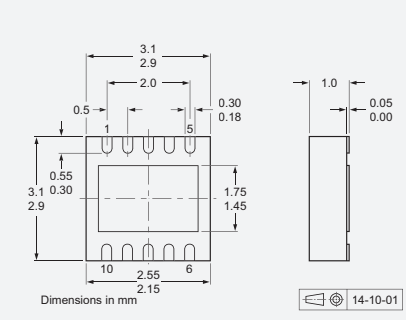


DFN2510A-10 (SOT1176)

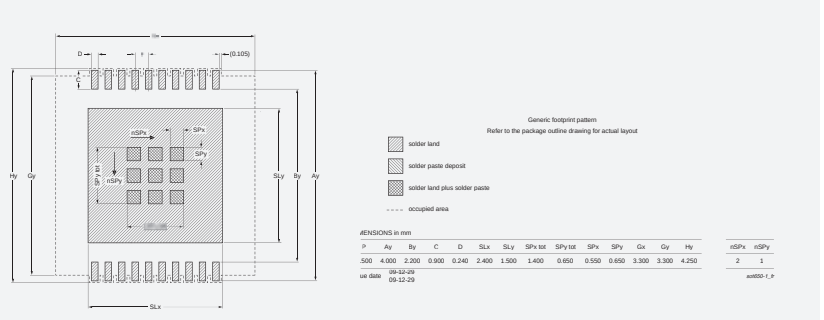


P	Ay	By	C	D	Hx	Hy
0.5	1.25	0.3	0.475	0.2	2.45	1.5

DFN2510A-10 (SOT1176)



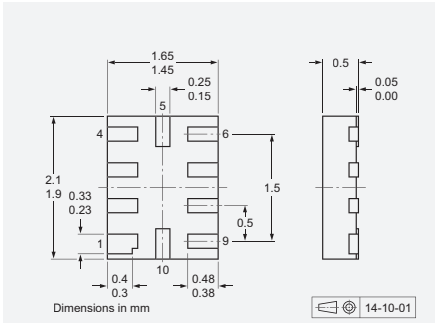
SOT650-1 TK



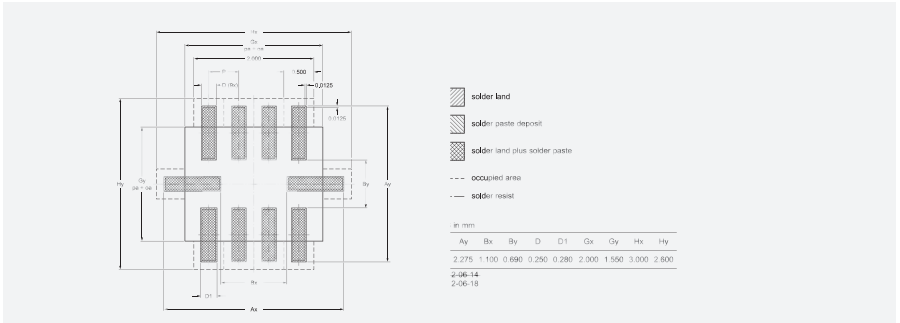
SOT650-1 TK

Dimensions in mm

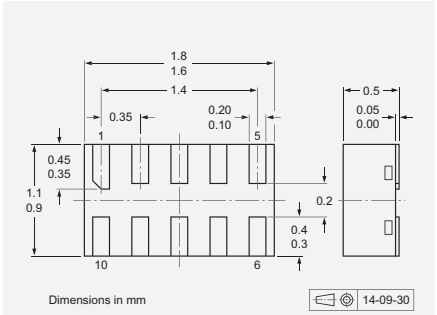
More than 8-pin SMD packages



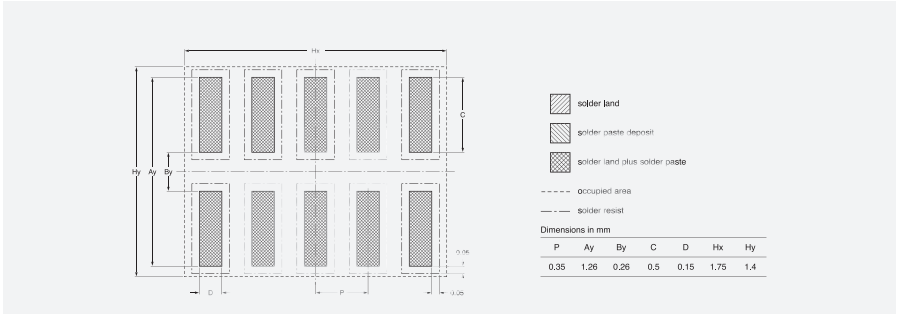
SOT1049-3 GM



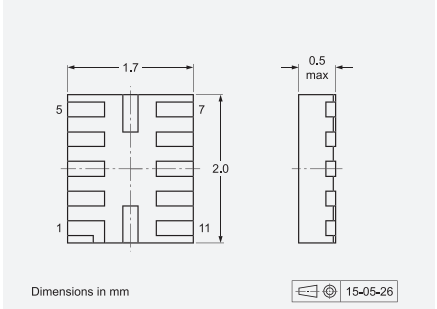
SOT1049-3 GM



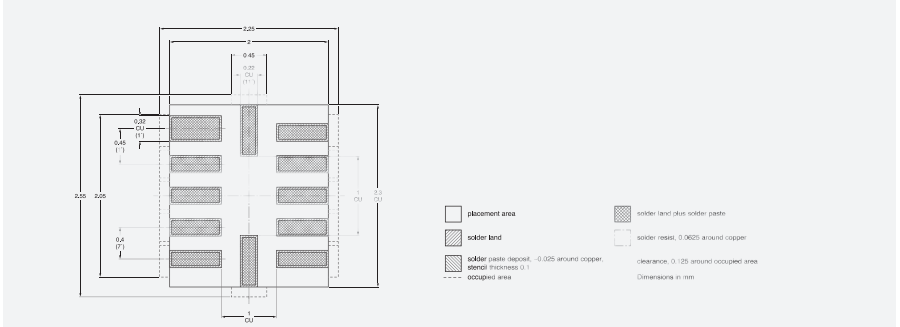
SOT1081-1/2 GF



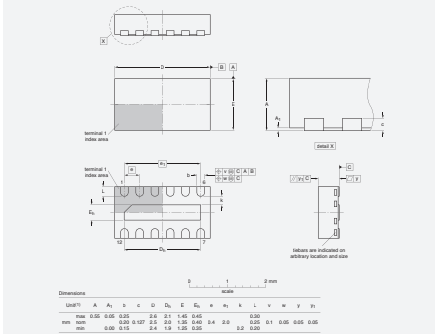
SOT1081-1/2 GF



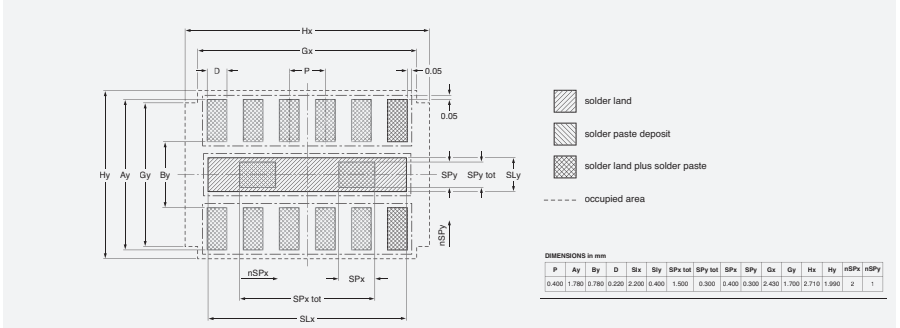
SOT1174 GM



SOT1174 GM



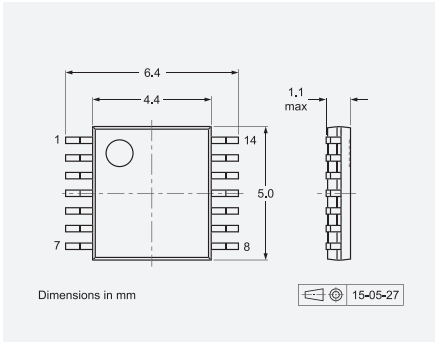
DFN2514-12 (SOT1167)



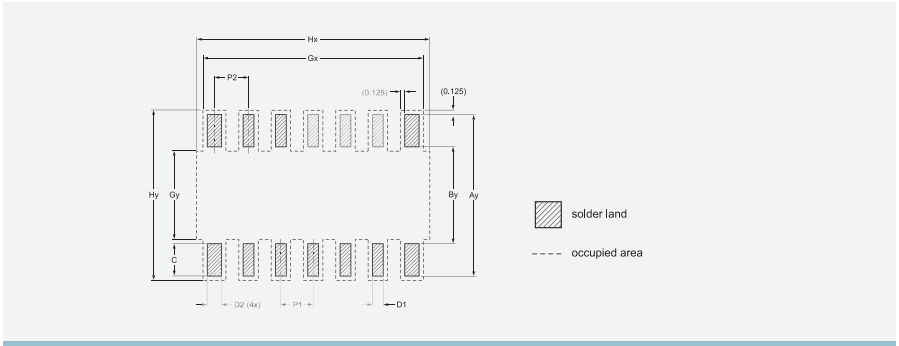
DFN2514-12 (SOT1167)

Dimensions in mm

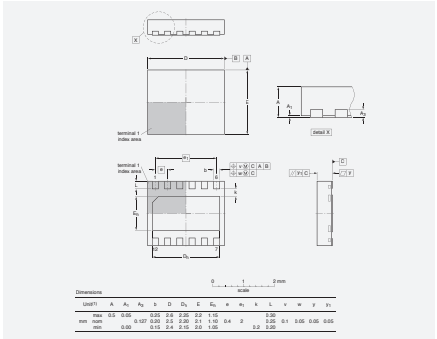
More than 8-pin SMD packages



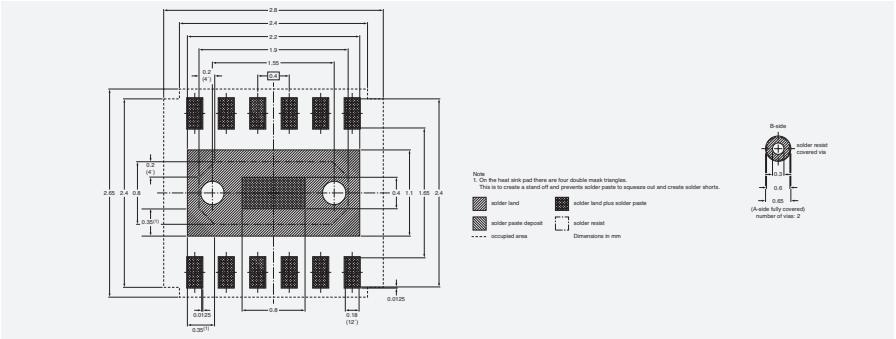
SOT402-1 PW



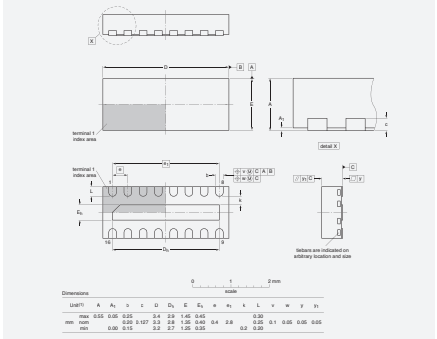
SOT402-1 PW



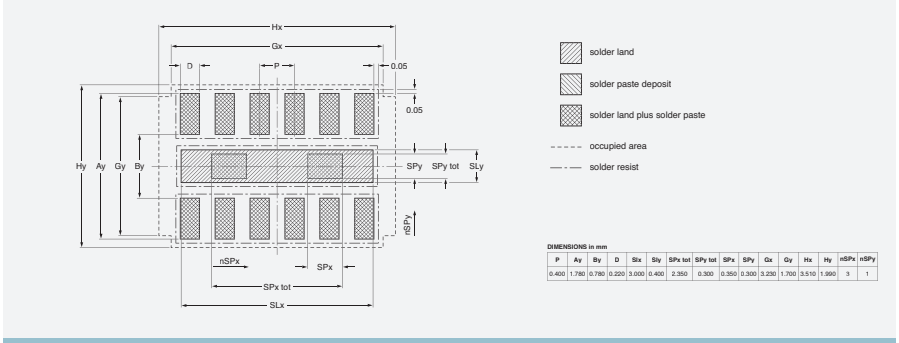
DFN2521-12 (SOT1156)



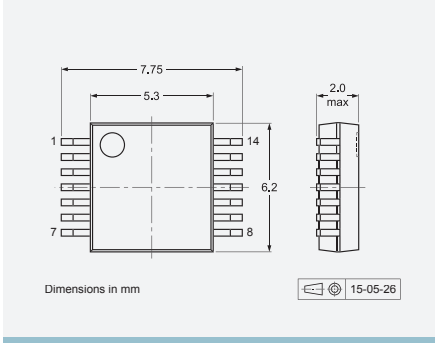
DFN2521-12 (SOT1156)



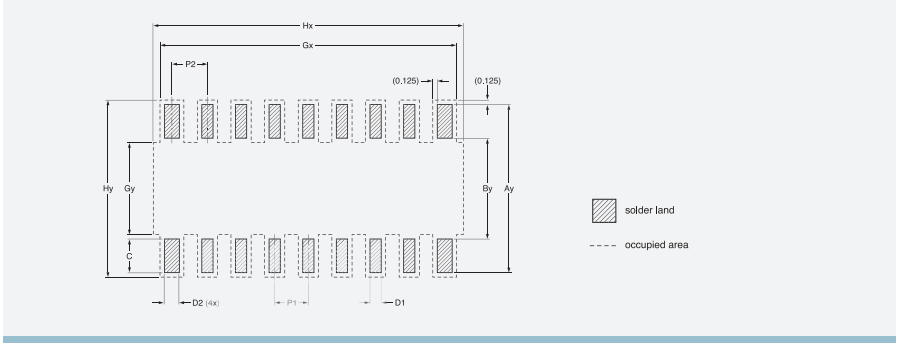
DFN3314-16 (SOT1168)



DFN3314-16 (SOT1168)



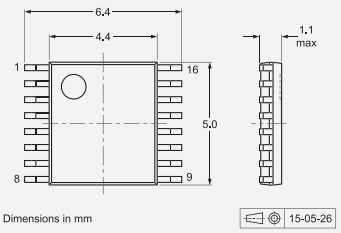
SOT337-1 DB



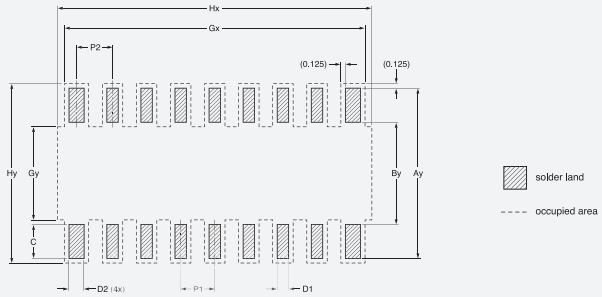
SOT337-1 DB

Dimensions in mm

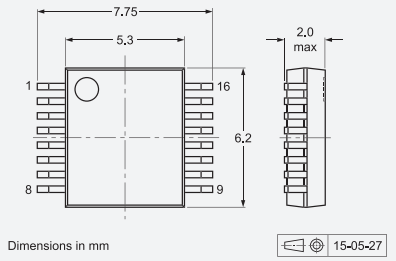
More than 8-pin SMD packages



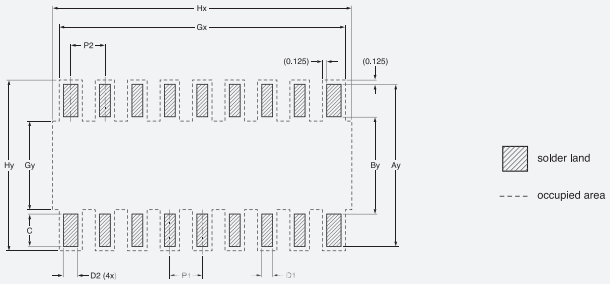
SOT403-1 PW



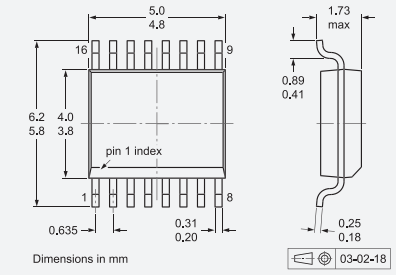
SOT403-1 PW



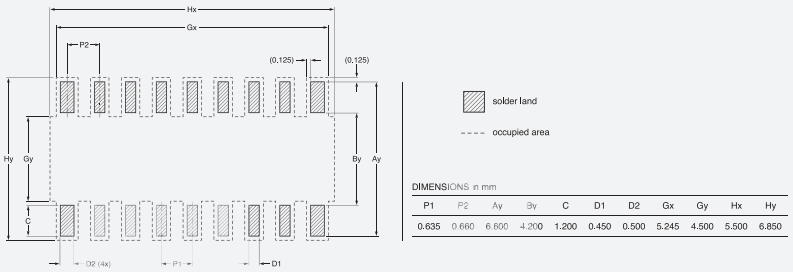
SOT338-1 DB



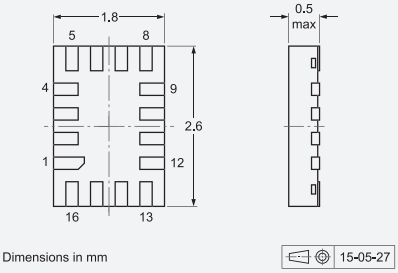
SOT338-1 DB



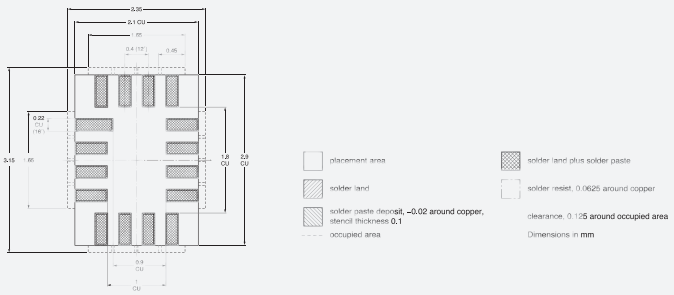
SOT519-1 DS



SOT519-1 DS



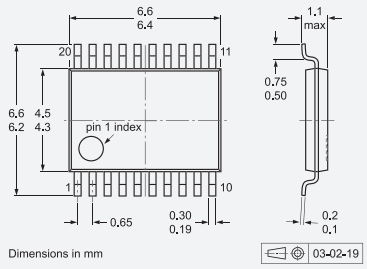
SOT1161 GU



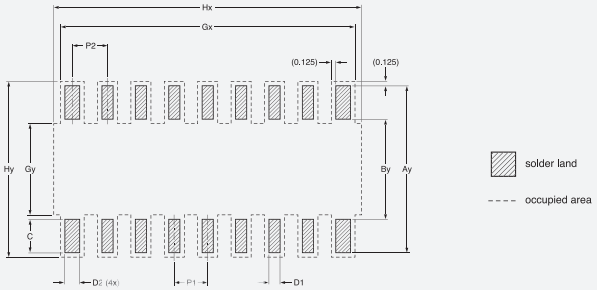
SOT1161 GU

Dimensions in mm

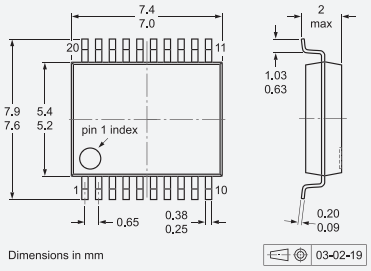
More than 8-pin SMD packages



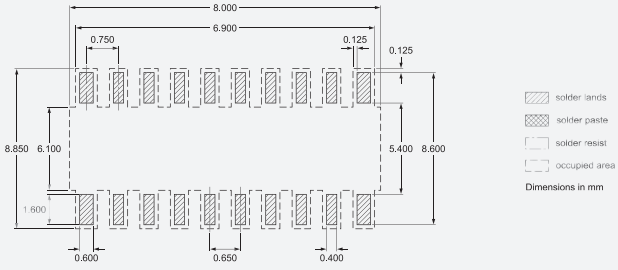
SOT360-1 PW



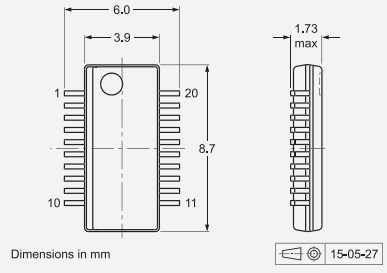
SOT360-1 PW



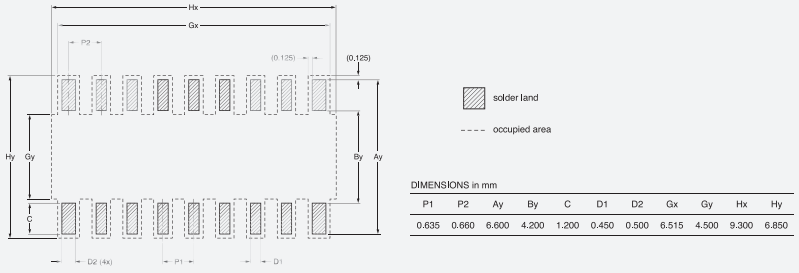
SOT339-1 DB



SOT339-1 DB

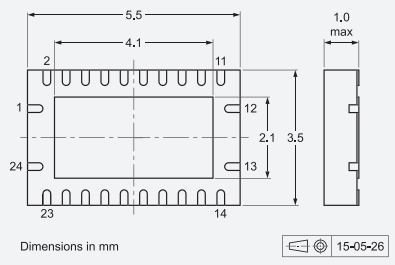


SOT724-1 DS

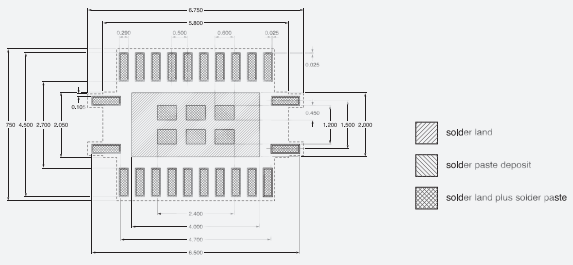


P1	P2	Ay	By	C	D1	D2	Gx	Gy	Hx	Hy
0.635	0.660	6.600	4.200	1.200	0.450	0.500	6.515	4.500	9.300	6.850

SOT724-1 DS



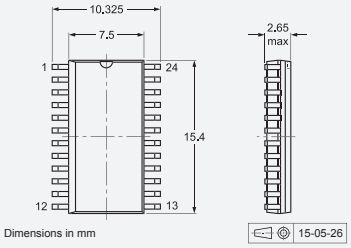
SOT815-1 BQ



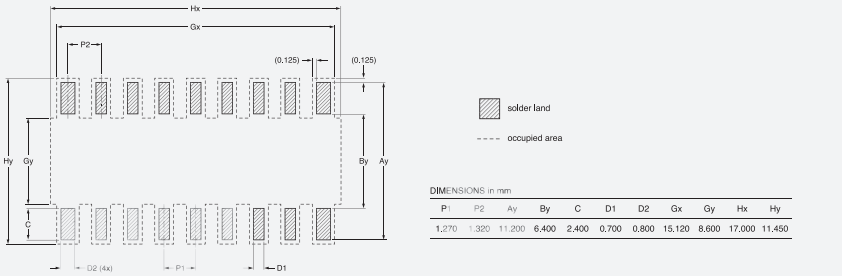
SOT815-1 BQ

Dimensions in mm

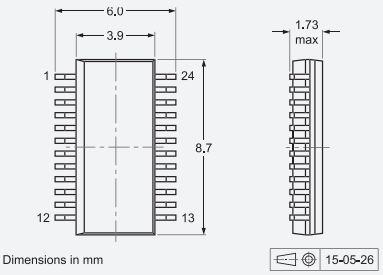
More than 8-pin SMD packages



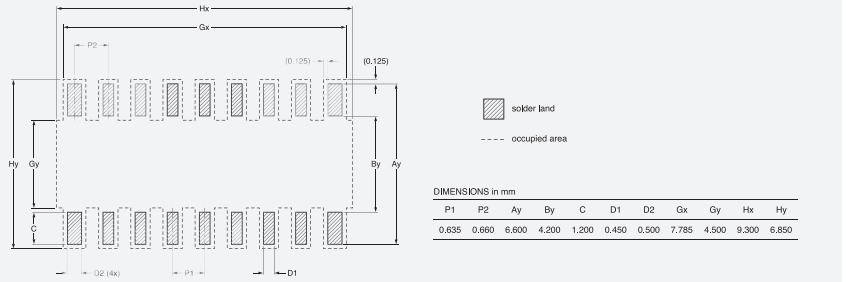
SOT137-1 D



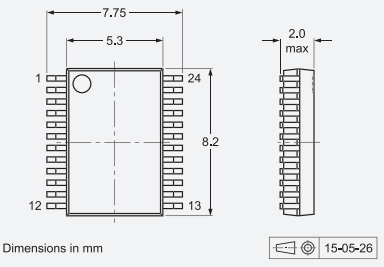
SOT137-1 D



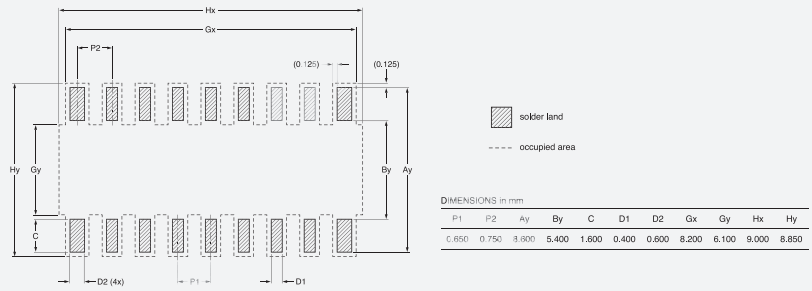
SOT556-1 DK



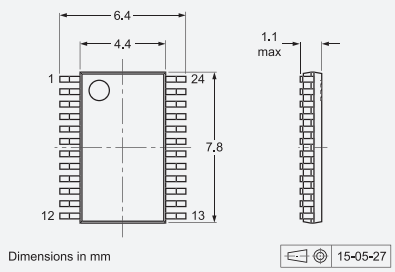
SOT556-1 DK



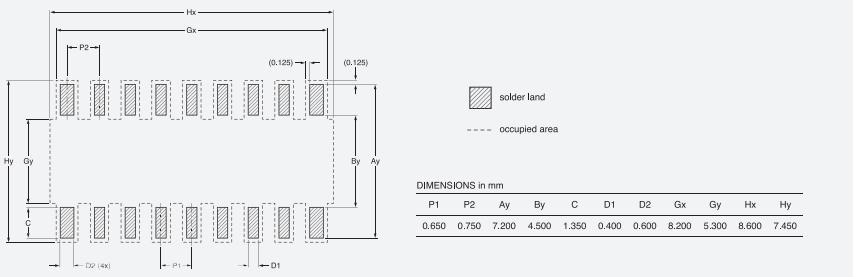
SOT340-1 DB



SOT340-1 DB



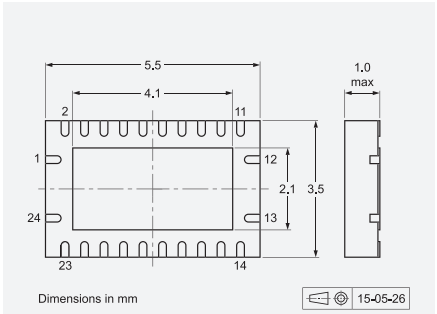
SOT355-1 PW



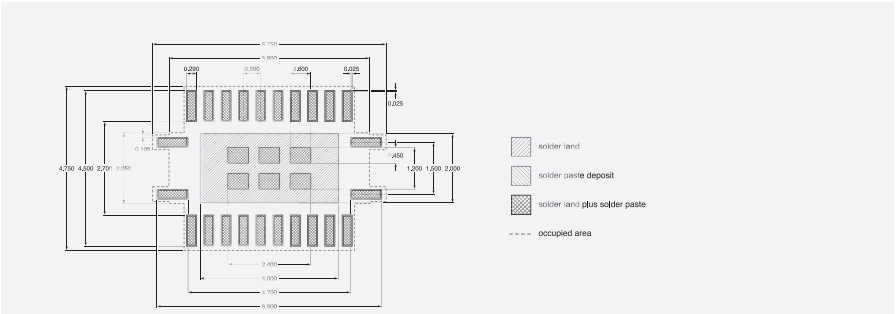
SOT355-1 PW

Dimensions in mm

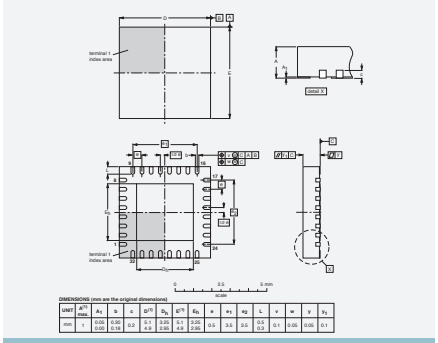
More than 8-pin SMD packages



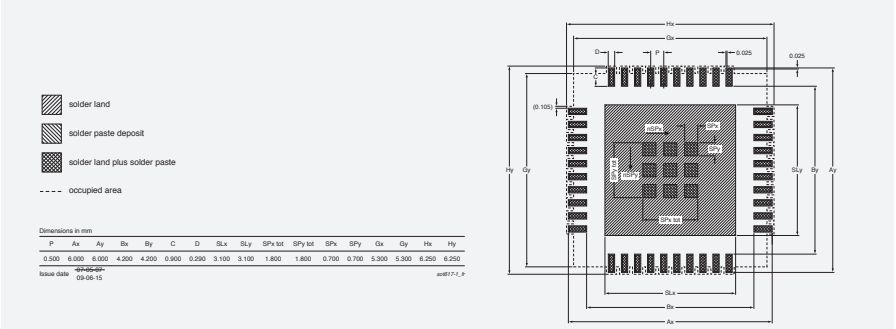
SOT815-1 BQ



SOT815-1 BQ

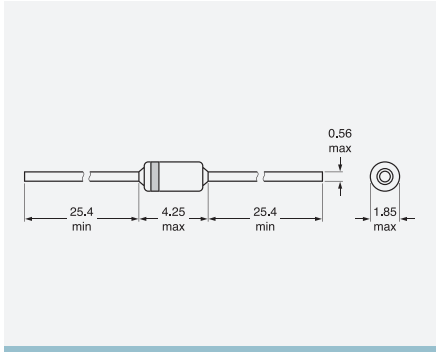


DFN5050-32 (SOT617)

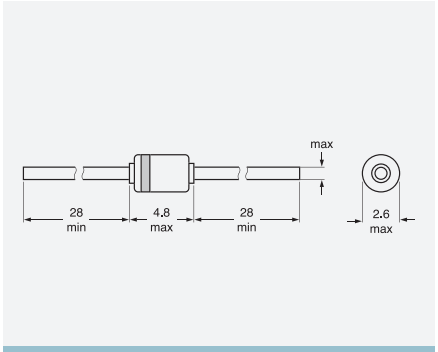


DFN5050-32 (SOT617)

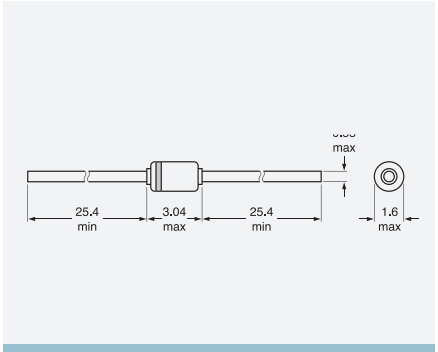
Glass diodes



SOD27 (DO-35)



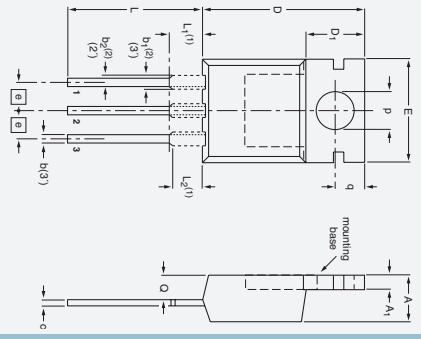
SOD66 (DO-41)



SOD68 (DO-34)

Dimensions in mm

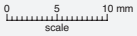
Single-ended and through-hole packages



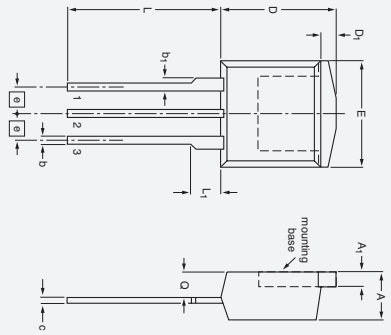
DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	b_1(2)	b_2(2)	c	D	D_1	E	e	L	L_1(1)	L_2(1) max.	p	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

Notes
1. Lead shoulder designs may vary.
2. Dimension includes excess dambar.

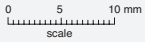


SOT78 (TO220AB)



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	b_1	c	D max	D_1	E	e	L	L_1	Q
mm	4.5 4.1	1.40 1.27	0.85 0.60	1.3 1.0	0.7 0.4	11	1.6 1.2	10.3 9.7	2.54	15.0 13.5	3.30 2.79	2.6 2.2



SOT226

Dimensions in mm

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